

WHAT IS CLAIMED IS:

1. A system configured to determine at least two properties of a specimen during use, comprising:

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a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

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an illumination system configured to direct energy toward a surface of the specimen during use; and

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a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

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a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises overlay misregistration of the specimen.

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2. The system of claim 1, wherein the stage is further configured to move laterally during use.

3. The system of claim 1, wherein the stage is further configured to move rotatably during use.

4. The system of claim 1, wherein the stage is further configured to move laterally and rotatably during use.

5 5. The system of claim 1, wherein the illumination system comprises a single energy source.

6. The system of claim 1, wherein the illumination system comprises more than one energy sources.

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7. The system of claim 1, wherein the detection system comprises a single energy sensitive device.

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8. The system of claim 1, wherein the detection system comprises more than one energy sensitive devices.

9. The system of claim 1, wherein the measurement device further comprises a non-imaging scatterometer.

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10. The system of claim 1, wherein the measurement device further comprises a scatterometer.

11. The system of claim 1, wherein the measurement device further comprises a spectroscopic scatterometer.

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12. The system of claim 1, wherein the measurement device further comprises a reflectometer.

13. The system of claim 1, wherein the measurement device further comprises a spectroscopic reflectometer.

14. The system of claim 1, wherein the measurement device further comprises an
5 ellipsometer.

15. The system of claim 1, wherein the measurement device further comprises a spectroscopic ellipsometer.

10 16. The system of claim 1, wherein the measurement device further comprises a bright field imaging device.

17. The system of claim 1, wherein the measurement device further comprises a dark field imaging device.

15 18. The system of claim 1, wherein the measurement device further comprises a bright field and a dark field imaging device.

19. The system of claim 1, wherein the measurement device further comprises a
20 bright field non-imaging device.

20. The system of claim 1, wherein the measurement device further comprises a dark field non-imaging device.

25 21. The system of claim 1, wherein the measurement device further comprises a bright field and a dark field non-imaging device.

22. The system of claim 1, wherein the measurement device further comprises a coherence probe microscope.

23. The system of claim 1, wherein the measurement device further comprises an interference microscope.

24. The system of claim 1, wherein the measurement device further comprises an optical profilometer.

25. The system of claim 1, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and a dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and a dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

26. The system of claim 1, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

27. The system of claim 1, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property comprises a presence of defects on the specimen.

28. The system of claim 27, wherein the defects comprise micro defects and macro defects.

29. The system of claim 27, wherein the illumination system is further configured to
5 direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the third property further comprises a presence of defects on the bottom surface of the specimen.

10 30. The system of claim 29, wherein the defects comprise macro defects.

31. The system of claim 1, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property comprises a flatness measurement of the specimen.

15 32. The system of claim 1, wherein the processor is further configured to determine a third property and a fourth property of the specimen from the one or more output signals during use, wherein the third property comprises a presence of defects on the specimen, and wherein the fourth property comprises a flatness measurement of the specimen.

20 33. The system of claim 1, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the
25 specimen.

34. The system of claim 33, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 35. The system of claim 1, wherein the system is further configured to determine at least two properties of the specimen simultaneously during use.

36. The system of claim 1, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially
10 simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

15 37. The system of claim 1, wherein the system is coupled to a process tool.

38. The system of claim 1, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

20 39. The system of claim 1, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

40. The system of claim 1, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to
25 the stage during use.

41. The system of claim 1, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

5 42. The system of claim 1, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

43. The system of claim 1, wherein the system is coupled to a process tool, and
10 wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

44. The system of claim 1, wherein the system is coupled to a process tool, wherein
15 the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

45. The system of claim 1, wherein the system is coupled to a process tool, wherein
20 the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

46. The system of claim 1, wherein the system is coupled to a process tool, and
25 wherein the process tool comprises a lithography tool.

47. The system of claim 1, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

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48. The system of claim 1, wherein the system comprises a measurement chamber,
wherein the stage and the measurement device are disposed within the measurement
chamber, wherein the measurement chamber is coupled to a process tool, and wherein the
5 measurement chamber is disposed within the process tool.

49. The system of claim 1, wherein the system comprises a measurement chamber,
wherein the stage and the measurement device are disposed within the measurement
chamber, wherein the measurement chamber is coupled to a process tool, and wherein the
10 measurement chamber is arranged laterally proximate to a process chamber of the process
tool.

50. The system of claim 1, wherein the system comprises a measurement chamber,
wherein the stage and the measurement device are disposed within the measurement
15 chamber, wherein the measurement chamber is coupled to a process tool, and wherein the
measurement chamber is arranged vertically proximate to a process chamber of the
process tool.

51. The system of claim 1, wherein a process tool comprises a process chamber,
20 wherein the stage is disposed within the process chamber, and wherein the stage is further
configured to support the specimen during a process step.

52. The system of claim 51, wherein the processor is further configured to determine
at least the two properties of the specimen during the process step.

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53. The system of claim 51, wherein the processor is further configured to obtain a
signature characterizing the process step during use, and wherein the signature comprises
at least one singularity representative of an end of the process step.

54. The system of claim 51, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique during use.

55. The system of claim 1, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

56. The system of claim 1, wherein a process tool comprises a first process chamber and a second process chamber, wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the processor is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

57. The system of claim 1, wherein a process tool comprises a first process chamber and a second process chamber, wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use, wherein the processor is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber, and wherein the process tool comprises a lithography tool.

58. The system of claim 57, wherein the first process chamber is configured to chill the specimen during use, and wherein the second process chamber is configured to apply resist to the specimen during use.

59. The system of claim 57, wherein the first process chamber is configured to chill the specimen subsequent to a post apply bake process step during use, and wherein the second process chamber is configured to expose the specimen during use.

5 60. The system of claim 57, wherein the first process chamber is configured to expose the specimen during use, and wherein the second process chamber is configured to bake the specimen subsequent to exposure of the specimen during use.

61. The system of claim 57, wherein the first process chamber is configured to chill
10 the specimen subsequent to a post exposure bake process step during use, and wherein the second process chamber is configured to develop the specimen during use.

62. The system of claim 57, wherein the first process chamber is configured to
develop the specimen during use, and wherein the second process chamber is configured
15 to bake the specimen subsequent to a develop process step during use.

63. The system of claim 57, wherein the first process chamber is configured to
develop the specimen during use, and wherein the second process chamber is configured
to receive the specimen in a wafer cassette during use.

20 64. The system of claim 1, wherein the processor is further configured to compare the determined properties of the specimen and properties of a plurality of specimens during use.

25 65. The system of claim 1, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property.

66. The system of claim 1, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property, and wherein the processor is further configured to generate an output signal if the determined property of the specimen is outside of the predetermined range during use.

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67. The system of claim 1, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

10 68. The system of claim 1, wherein the processor is further configured to alter a parameter of an instrument coupled to the measurement device in response to the determined first or second property using a feedback control technique during use.

15 69. The system of claim 1, wherein the processor is further configured to alter a parameter of an instrument coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

20 70. The system of claim 1, wherein the processor is further configured to generate a database during use, and wherein the database comprises the determined first and second properties of the specimen.

71. The system of claim 70, wherein the processor is further configured to calibrate the measurement device using the database during use.

25 72. The system of claim 70, wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

73. The system of claim 70, wherein the database further comprises first and second properties of a plurality of specimens.

74. The system of claim 73, wherein the first and second properties of the plurality of specimens are determined using the measurement device.

75. The system of claim 73, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

76. The system of claim 75, wherein the processor is further coupled to the plurality of measurement devices.

77. The system of claim 76, wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

78. The system of claim 76, wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

79. The system of claim 1, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

80. The system of claim 1, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is

further configured to calibrate the system and at least the one additional system during use.

5 81. The system of claim 1, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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82. The system of claim 1, wherein the processor is further coupled to a process tool.

83. The system of claim 82, wherein the process tool comprises a lithography tool.

15 84. The system of claim 82, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

20 85. The system of claim 82, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

86. The system of claim 82, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

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87. The system of claim 86, wherein the processor is further configured to determine a relationship between the determined properties and at least one of the monitored parameters during use.

88. The system of claim 87, wherein the processor is further configured to alter the parameter of the one or more instruments in response to the determined relationship during use.

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89. The system of claim 1, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

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90. The system of claim 1, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

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91. The system of claim 90, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

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92. The system of claim 90, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

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93. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

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generating one or more output signals responsive to the detected energy; and

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processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises overlay misregistration of the specimen.

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94. The method of claim 93, further comprising laterally moving the stage during said directing energy and said detecting energy.

95. The method of claim 93, further comprising rotatably moving the stage during said directing energy and said detecting energy.

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96. The method of claim 93, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

97. The method of claim 93, wherein the illumination system comprises a single energy source.

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98. The method of claim 93, wherein the illumination system comprises more than one energy source.

99. The method of claim 93, wherein the detection system comprises a single energy sensitive device.

100. The method of claim 93, wherein the detection system comprises more than one
5 energy sensitive devices.

101. The method of claim 93, wherein the measurement device further comprises a non-imaging scatterometer.

102. The method of claim 93, wherein the measurement device further comprises a
10 scatterometer.

103. The method of claim 93, wherein the measurement device further comprises a spectroscopic scatterometer.

104. The method of claim 93, wherein the measurement device further comprises a
15 reflectometer.

105. The method of claim 93, wherein the measurement device further comprises a
20 spectroscopic reflectometer.

106. The method of claim 93, wherein the measurement device further comprises an ellipsometer.

107. The method of claim 93, wherein the measurement device further comprises a
25 spectroscopic ellipsometer.

108. The method of claim 93, wherein the measurement device further comprises a bright field imaging device.

5 109. The method of claim 93, wherein the measurement device further comprises a dark field imaging device.

110. The method of claim 93, wherein the measurement device further comprises a bright field and dark field imaging device.

10 111. The method of claim 93, wherein the measurement device further comprises a bright field non-imaging device.

112. The method of claim 93, wherein the measurement device further comprises a dark field non-imaging device.

15 113. The method of claim 93, wherein the measurement device further comprises a bright field and dark field non-imaging device

20 114. The method of claim 93, wherein the measurement device further comprises a coherence probe microscope.

115. The method of claim 93, wherein the measurement device further comprises an interference microscope.

25 116. The method of claim 93, wherein the measurement device further comprises an optical profilometer.

117. The method of claim 93, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

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118. The method of claim 93, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

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119. The method of claim 93, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen.

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120. The method of claim 93, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen, and wherein the defects comprise micro defects and macro defects.

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121. The method of claim 93, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen, the method further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein
the third property further comprises a presence of defects on the bottom surface of
the specimen.

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122. The method of claim 121, wherein the defects comprise macro defects.

123. The method of claim 93, further comprising processing the one or more output
signals to determine a third property of the specimen, wherein the third property
comprises a flatness measurement of the specimen.

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124. The method of claim 93, further comprising processing the one or more output
signals to determine a third property and a fourth property of the specimen, wherein the
third property comprises a presence of defects on the specimen, and wherein the fourth
property comprises a flatness measurement of the specimen.

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125. The method of claim 93, further comprising processing the one or more output
signals to determine a third property of the specimen, wherein the third property is
selected from the group consisting of a roughness of the specimen, a roughness of a layer
on the specimen, and a roughness of a feature of the specimen.

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126. The method of claim 125, wherein the stage and the measurement device are
coupled to a process tool selected from the group consisting of a lithography tool, an
atomic layer deposition tool, a cleaning tool, and an etch tool.

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127. The method of claim 93, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

5 128. The method of claim 93, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

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129. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool.

130. The method of claim 93, wherein the stage and the measurement device are
15 coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

131. The method of claim 93, wherein the stage and the measurement device are
20 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

132. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

25 133. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

134. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

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135. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

10 136. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

15 137. The method of claim 93, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

20 138. The method of claim 93, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

25 139. The method of claim 93, wherein the stage and the measurement device are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

140. The method of claim 93, wherein the stage and the measurement device are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

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141. The method of claim 93, wherein the stage and the measurement device are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

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142. The method of claim 93, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

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143. The method of claim 142, further comprising performing said directing and said detecting during the process step.

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144. The method of claim 143, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

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145. The method of claim 143, further comprising altering a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique.

146. The method of claim 93, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

5 147. The method of claim 146, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

148. The method of claim 146, wherein the process tool comprises a lithography tool.

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149. The method of claim 148, further comprising:

chilling the specimen in the first process chamber; and

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applying resist to the specimen in the second process chamber.

150. The method of claim 148, further comprising:

chilling the specimen in the first process chamber subsequent to a post apply bake process step; and

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exposing the specimen in the second process chamber.

151. The method of claim 148, further comprising:

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exposing the specimen in the first process chamber; and

baking the specimen subsequent to exposure of the specimen in the second process chamber.

152. The method of claim 148, further comprising:

chilling the specimen in the first process chamber subsequent to a post exposure bake process step; and

developing the specimen in the second process chamber.

153. The method of claim 148, further comprising:

developing the specimen in the first process chamber; and

baking the specimen in the second process chamber subsequent to a develop process step.

154. The method of claim 148, further comprising:

developing the specimen in the first process chamber; and

receiving the specimen in a wafer cassette in the second process chamber.

155. The method of claim 93, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

156. The method of claim 93, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

157. The method of claim 93, further comprising comparing at least one of the
5 determined properties of the specimen to a predetermined range for the property and generating an output signal if the determined property of the specimen is outside of the predetermined range.

158. The method of claim 93, further comprising altering a sampling frequency of the
10 measurement device in response to the determined first or second property of the specimen.

159. The method of claim 93, further comprising altering a parameter of one or more
15 instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

160. The method of claim 93, further comprising altering a parameter of one or more
instruments coupled to the measurement device in response to the determined first or
20 second property using a feedforward control technique.

161. The method of claim 93, further comprising generating a database, wherein the
database comprises the determined first and second properties of the specimen.

162. The method of claim 161, further comprising calibrating the measurement device
25 using the database.

163. The method of claim 161, further comprising monitoring output signals generated
by the measurement device using the database.

164. The method of claim 161, wherein the database further comprises first and second properties of a plurality of specimens.

5 165. The method of claim 164, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

166. The method of claim 165, further comprising calibrating the plurality of measurement devices using the database.

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167. The method of claim 165, further comprising monitoring output signals generated by the plurality of measurement devices using the database.

15 168. The method of claim 93, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

20 169. The method of claim 93, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

25 170. The method of claim 93, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one

of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

171. The method of claim 93, further comprising altering a parameter of one or more
5 instruments coupled to a process tool in response to the determined first or second property of the specimen.

172. The method of claim 93, further comprising altering a parameter of one or more
instruments coupled to a process tool in response to the determined first or second
10 property of the specimen using a feedback control technique.

173. The method of claim 93, further comprising altering a parameter of one or more
instruments coupled to a process tool in response to the determined first or second
property of the specimen using a feedforward control technique.

15 174. The method of claim 93, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

175. The method of claim 93, further comprising monitoring a parameter of one or
20 more instruments coupled to a process tool and determining a relationship between the determined properties and at least one of the monitored parameters.

176. The method of claim 93, further comprising monitoring a parameter of one or
more instruments coupled to a process tool, determining a relationship between the
25 determined properties and at least one of the monitored parameters, and altering the parameter of the one or more instruments in response to the relationship.

177. The method of claim 93, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to the determined first or second property of the specimen.

5 178. The method of claim 93, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

179. The method of claim 178, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

20 180. The method of claim 178, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

25 181. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

5 controlling the illumination system to direct energy toward a surface of the specimen;

 controlling the detection system to detect energy propagating from the surface of the specimen; and

10 generating one or more output signals responsive to the detected energy; and

 processing the one or more output signals to determine a first property and a
15 second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises overlay misregistration of the specimen.

182. The method of claim 181, further comprising controlling the stage, wherein the
20 stage is configured to support the specimen.

183. The method of claim 181, further comprising controlling the stage to move laterally during said directing energy and said detecting energy.

25 184. The method of claim 181, further comprising controlling the stage to move rotatably during said directing energy and said detecting energy.

185. The method of claim 181, further comprising controlling the stage to move laterally and rotatably during said directing energy and said detecting energy.

186. The method of claim 181, wherein the illumination system comprises a single
5 energy source.

187. The method of claim 181, wherein the illumination system comprises more than one energy source.

10 188. The method of claim 181, wherein the detection system comprises a single energy sensitive device.

189. The method of claim 181, wherein the detection system comprises more than one energy sensitive devices.
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190. The method of claim 181, wherein the measurement device further comprises a non-imaging scatterometer.

191. The method of claim 181, wherein the measurement device further comprises a
20 scatterometer.

192. The method of claim 181, wherein the measurement device further comprises a spectroscopic scatterometer.

25 193. The method of claim 181, wherein the measurement device further comprises a reflectometer.

194. The method of claim 181, wherein the measurement device further comprises a spectroscopic reflectometer.

5 195. The method of claim 181, wherein the measurement device further comprises an ellipsometer.

196. The method of claim 181, wherein the measurement device further comprises a spectroscopic ellipsometer.

10 197. The method of claim 181, wherein the measurement device further comprises a bright field imaging device.

15 198. The method of claim 181, wherein the measurement device further comprises a dark field imaging device.

199. The method of claim 181, wherein the measurement device further comprises a bright field and dark field imaging device.

20 200. The method of claim 181, wherein the measurement device further comprises a bright field non-imaging device.

201. The method of claim 181, wherein the measurement device further comprises a dark field non-imaging device.

25 202. The method of claim 181, wherein the measurement device further comprises a bright field and dark field non-imaging device.

203. The method of claim 181, wherein the measurement device further comprises a coherence probe microscope.

204. The method of claim 181, wherein the measurement device further comprises an interference microscope.

205. The method of claim 181, wherein the measurement device further comprises an optical profilometer.

206. The method of claim 181, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

207. The method of claim 181, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

208. The method of claim 181, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen.

209. The method of claim 208, wherein the defects comprise micro defects and macro defects.

210. The method of claim 208, further comprising:

controlling the illumination system to direct energy toward a bottom surface of the specimen; and

controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the third property further comprises a presence of defects on the bottom surface of the specimen.

211. The method of claim 210, wherein the defects comprise macro defects.

212. The method of claim 181, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a flatness measurement of the specimen.

213. The method of claim 181, further comprising processing the one or more output signals to determine a third property and a fourth property of the specimen, wherein the third property comprises a presence of defects on the specimen, and wherein the fourth property comprises a flatness measurement of the specimen.

214. The method of claim 181, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

215. The method of claim 214, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

- 5 216. The method of claim 181, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

- 10 217. The method of claim 181, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

- 15 218. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool.

- 20 219. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

- 25 220. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

221. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

222. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

223. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

224. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

225. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

226. The method of claim 181, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

227. The method of claim 181, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

228. The method of claim 181, wherein the stage and the measurement device are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

229. The method of claim 181, wherein the stage and the measurement device are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

230. The method of claim 181, wherein the stage and the measurement device are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

231. The method of claim 181, wherein the stage comprises a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

232. The method of claim 231, further comprising controlling the illumination system and controlling the detection system during the process step.

233. The method of claim 231, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

234. The method of claim 231, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique.

5 235. The method of claim 181, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

236. The method of claim 235, further comprising controlling the illumination system
10 and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

237. The method of claim 235, wherein the process tool comprises a lithography tool.

15 238. The method of claim 237, further comprising:

chilling the specimen in the first process chamber; and

applying resist to the specimen in the second process chamber.

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239. The method of claim 237, further comprising:

chilling the specimen in the first process chamber subsequent to a post apply bake
process step; and

25

exposing the specimen in the second process chamber.

240. The method of claim 237, further comprising:

exposing the specimen in the first process chamber; and

baking the specimen subsequent to exposure of the specimen in the second
process chamber.

241. The method of claim 237, further comprising:

chilling the specimen in the first process chamber subsequent to a post exposure
bake process step; and

developing the specimen in the second process chamber.

242. The method of claim 237, further comprising:

developing the specimen in the first process chamber; and

baking the specimen in the second process chamber subsequent to a develop
process step.

243. The method of claim 237, further comprising:

developing the specimen in the first process chamber; and

receiving the specimen in a wafer cassette in the second process chamber.

244. The method of claim 181, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 5 245. The method of claim 181, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

246. The method of claim 245, further comprising generating an output signal if the determined property of the specimen is outside of the predetermined range.

10

247. The method of claim 181, further comprising altering a sampling frequency of the measurement device in response to the determined first or second properties of the specimen.

- 15 248. The method of claim 181, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

- 20 249. The method of claim 181, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique.

250. The method of claim 181, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

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251. The method of claim 250, further comprising calibrating the measurement device using the database.

252. The method of claim 250, further comprising monitoring output signals of the measurement device using the database.

253. The method of claim 250, wherein the database further comprises first and second properties of a plurality of specimens.

254. The method of claim 253, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

255. The method of claim 254, further comprising calibrating the plurality of measurement devices using the database.

256. The method of claim 254, further comprising monitoring output signals of the plurality of measurement devices using the database.

257. The method of claim 181, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

258. The method of claim 181, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

259. The method of claim 181, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and

wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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260. The method of claim 181, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen.

10 261. The method of claim 181, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen using a feedback control technique.

15 262. The method of claim 181, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen using a feedforward control technique.

20 263. The method of claim 181, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

264. The method of claim 181, further comprising monitoring a parameter of one or more instruments coupled to the process tool and determining a relationship between the determined properties and at least one of the monitored parameters.

25 265. The method of claim 181, further comprising monitoring a parameter of one or more instruments coupled to the process tool, determining a relationship between the determined properties and at least one of the monitored parameters, and altering the parameter of at least one of the instruments in response to the relationship.

266. The method of claim 181, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to the determined first or second property of the specimen.

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267. The method of claim 181, wherein processing the one or more output signals comprises:

10 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

15 further processing the partially processed one or more output signals using the remote controller computer.

268. The method of claim 267, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

20

269. The method of claim 267, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

25 270. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the portion of the semiconductor device, wherein the first property comprises a critical dimension of the portion of the semiconductor device, and wherein the second property comprises overlay misregistration of the portion of the semiconductor device.

20 271. The device of claim 270, wherein the illumination system comprises a single energy source.

272. The device of claim 270, wherein the illumination system comprises more than one energy source.

25 273. The device of claim 270, wherein the detection system comprises a single energy sensitive device.

274. The device of claim 270, wherein the detection system comprises more than one energy sensitive devices.

275. The device of claim 270, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

276. The device of claim 270, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

277. The device of claim 270, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

278. The device of claim 270, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen.

279. The device of claim 278, wherein the defects comprise micro defects and macro defects.

280. The device of claim 278, further comprising:

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directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein
the third property further comprises a presence of defects on the bottom surface of
the specimen.

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281. The device of claim 280, wherein the defects comprise macro defects.

282. The device of claim 270, further comprising processing the one or more output
signals to determine a third property of the specimen, wherein the third property
comprises a flatness measurement of the specimen.

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283. The device of claim 270, further comprising processing the one or more output
signals to determine a third property and a fourth property of the specimen, wherein the
third property comprises a presence of defects on the specimen, and wherein the fourth
property comprises a flatness measurement of the specimen.

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284. The device of claim 270, further comprising processing the one or more output
signals to determine a third property of the specimen, wherein the third property is
selected from the group consisting of a roughness of the specimen, a roughness of a layer
on the specimen, and a roughness of a feature of the specimen.

25

285. The device of claim 284, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 286. The device of claim 270, wherein the stage and the measurement device are coupled to a process tool.

287. The device of claim 270, wherein the stage and the measurement device are coupled to a lithography tool.

10

288. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

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disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

20

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

25

processing the one or more output signals to determine a first property and a second property of the portion of the semiconductor device, wherein the first property comprises a critical dimension of the portion of the semiconductor

device, and wherein the second property comprises overlay misregistration of the portion of the semiconductor device.

289. The method of claim 288, wherein the illumination system comprises a single
5 energy source.

290. The method of claim 288, wherein the illumination system comprises more than one energy source.

10 291. The method of claim 288, wherein the detection system comprises a single energy sensitive device.

292. The method of claim 288, wherein the detection system comprises more than one energy sensitive devices.

15 293. The method of claim 288, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a
20 bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

25 294. The method of claim 288, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field

imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

5 295. The method of claim 288, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 296. The method of claim 288, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen.

15 297. The method of claim 296, wherein the defects comprise micro defects and macro defects.

20 298. The method of claim 296, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein the third property further comprises a presence of defects on the bottom surface of the specimen.

25 299. The method of claim 298, wherein the defects comprise macro defects.

300. The method of claim 288, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property comprises a flatness measurement of the specimen.

5 301. The method of claim 288, further comprising processing the one or more output signals to determine a third property and a fourth property of the specimen, wherein the third property comprises a presence of defects on the specimen, and wherein the fourth property comprises a flatness measurement of the specimen.

10 302. The method of claim 288, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15 303. The method of claim 302, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20 304. The method of claim 288, wherein the stage and the measurement device are coupled to a process tool.

305. The method of claim 288, wherein the stage and the measurement device are coupled to a lithography tool.

25 306. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises overlay misregistration of the specimen.

307. The system of claim 306, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

308. The system of claim 306, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

309. The system of claim 306, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the illumination system of the first measurement device comprises the illumination system of the second measurement device.

310. The system of claim 306, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the detection system of the first measurement device comprises the detection system of the second measurement device.

311. The system of claim 306, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially processed one or more output signals during use, and wherein the third property comprises a presence of defects on the specimen.

312. The system of claim 311, wherein the defects comprise micro defects and macro defects.

313. The system of claim 311, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the third property further comprises a presence of defects on the bottom surface of the specimen.

314. The system of claim 313, wherein the defects comprise macro defects.

315. The system of claim 306, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially processed one or more output signals during use, and wherein the third property comprises a flatness measurement of the specimen.

316. The system of claim 306, wherein the remote controller computer is further configured to determine a third property and a fourth property of the specimen from the at least partially processed one or more output signals during use, wherein the third property comprises a presence of defects on the specimen, and wherein the fourth property comprises a flatness measurement of the specimen.

317. The system of claim 306, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially processed one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

318. The system of claim 317, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

319. The system of claim 306, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy
5 propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

320. The system of claim 306, wherein the remote controller computer is coupled to a
10 process tool.

321. The system of claim 320, wherein the process tool comprises a lithography tool.

322. The system of claim 320, wherein the remote controller computer is further
15 configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

323. The system of claim 320, wherein the remote controller computer is further
20 configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

324. The system of claim 320, wherein the remote controller computer is further
25 configured to monitor a parameter of one or more instruments coupled to the process tool during use.

325. The system of claim 324, wherein the remote controller computer is further configured to determine a relationship between the determined properties and at least one of the monitored parameters during use.

- 5 326. The system of claim 325, wherein the remote controller computer is further configured to alter the parameter of at least one of the instruments in response to the relationship during use.

10 327. The system of claim 320, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

15 328. The system of claim 327, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

20 329. The system of claim 327, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using an in situ control technique during use.

25 330. The system of claim 306, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to

move the specimen from the first process chamber to the second process chamber during use.

5 331. The system of claim 330, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during said moving.

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332. The system of claim 306, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

15 333. The system of claim 306, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

20 334. The system of claim 333, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

25 335. The system of claim 306, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

336. The system of claim 306, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement

device in response to the determined first or second property using a feedback control technique during use.

5 337. The system of claim 306, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

10 338. The system of claim 306, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

15 339. The system of claim 338, wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

340. The system of claim 338, wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

20 341. The system of claim 338, wherein the database further comprises first and second properties of a plurality of specimens.

342. The system of claim 341, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

25 343. The system of claim 342, wherein the remote controller computer is further coupled to the plurality of measurement devices.

344. The system of claim 343, wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

5 345. The system of claim 343, wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

346. The system of claim 343, wherein each of the plurality of measurement devices is
10 coupled to at least one of a plurality of process tools.

347. A method for determining at least two properties of a specimen, comprising:

15 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

20 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals in response to the detected energy; and

25 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises overlay

misregistration of the specimen, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

348. The method of claim 347, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

349. The method of claim 347, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a bright field non-imaging device, a dark field non-imaging device, a bright field and dark

field non-imaging device, a coherence probe microscope, an interference microscope, and an optical profilometer.

350. The method of claim 347, wherein the measurement device further comprises at
5 least a first measurement device and a second measurement device, and wherein an illumination system of the first measurement device comprises an illumination system of the second measurement device.

351. The method of claim 347, wherein the measurement device further comprises at
10 least a first measurement device and a second measurement device, and wherein a detection system of the first measurement device comprises a detection system of the second measurement device.

352. The method of claim 347, further comprising processing the one or more output
15 signals to determine a third property of the specimen, wherein the third property comprises a presence of defects on the specimen.

353. The method of claim 352, wherein the defects comprise micro defects and macro
20 defects.

354. The method of claim 352, further comprising:

directing energy toward a bottom surface of the specimen; and

25 detecting energy propagating from the bottom surface of the specimen, wherein the third property further comprises a presence of defects on the bottom surface of the specimen.

355. The method of claim 354, wherein the defects comprise macro defects.

356. The method of claim 347, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property

5 comprises a flatness measurement of the specimen.

357. The method of claim 347, further comprising processing the one or more output signals to determine a third property and a fourth property of the specimen, wherein the third property comprises a presence of defects on the specimen, and wherein the fourth

10 property comprises a flatness measurement of the specimen.

358. The method of claim 347, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer

15 on the specimen, and a roughness of a feature of the specimen.

359. The method of claim 358, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

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360. The method of claim 347, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple

25 locations substantially simultaneously.

361. The method of claim 347, wherein the remote controller computer is coupled to a process tool.

362. The method of claim 361, wherein the process tool comprises a lithography tool.

363. The method of claim 361, further comprising altering a parameter of one or more
5 instruments coupled to the process tool using the remote controller computer in response
to the determined first or second property of the specimen using a feedback control
technique.

364. The method of claim 361, further comprising altering a parameter of one or more
10 instruments coupled to the process tool using the remote controller computer in response
to the determined first or second property of the specimen using a feedforward control
technique.

365. The method of claim 361, further comprising monitoring a parameter of one or
15 more instruments coupled to the process tool using the remote controller computer.

366. The method of claim 365, further comprising determining a relationship between
the determined properties and at least one of the monitored parameters using the remote
controller computer.

20 367. The method of claim 366, further comprising altering a parameter of at least one
of the instruments in response to the relationship using the remote controller computer.

368. The method of claim 361, wherein the illumination system and the detection
25 system are coupled to a process chamber of the process tool, further comprising
performing said directing and said detecting during a process step.

369. The method of claim 368, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

5 370. The method of claim 368, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to the determined first or second property using an in situ control technique.

371. The method of claim 347, further comprising:

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moving the specimen from a first process chamber to a second process chamber using the stage;

performing said directing and said detecting during said moving the specimen.

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372. The method of claim 347, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

20 373. The method of claim 347, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

25 374. The method of claim 373, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

375. The method of claim 347, wherein the remote controller computer is coupled to the measurement device.

5 376. The method of claim 375, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to the determined first or second property of the specimen.

10 377. The method of claim 375, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to the determined first or second property using a feedback control technique.

15 378. The method of claim 375, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to the determined first or second property using a feedforward control technique.

20 379. The method of claim 347, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen.

380. The method of claim 379, further comprising calibrating the measurement device using the database and the remote controller computer.

25 381. The method of claim 379, further comprising monitoring output signals of the measurement device using the remote controller computer.

382. The method of claim 379, wherein the database further comprises first and second properties of a plurality of specimens.

383. The method of claim 382, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

384. The method of claim 383, further comprising calibrating the plurality of measurement devices using the remote controller computer.

385. The method of claim 383, further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer.

386. The method of claim 347, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

387. The method of claim 386, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to the determined first or second property of the specimen.

388. The method of claim 386, wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

389. The method of claim 388, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to the determined first or second property of the specimen.

390. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a presence of defects on the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

391. The system of claim 390, wherein the stage is further configured to move laterally during use.

392. The system of claim 390, wherein the stage is further configured to move rotatably during use.

393. The system of claim 390, wherein the stage is further configured to move laterally and rotatably during use.

5 394. The system of claim 390, wherein the illumination system comprises a single energy source.

395. The system of claim 390, wherein the illumination system comprises more than one energy source.

10 396. The system of claim 390, wherein the detection system comprises a single energy sensitive device.

15 397. The system of claim 390, wherein the detection system comprises more than one energy sensitive device.

398. The system of claim 390, wherein the measurement device further comprises a non-imaging dark field device.

20 399. The system of claim 390, wherein the measurement device further comprises a non-imaging bright field device.

400. The system of claim 390, wherein the measurement device further comprises a non-imaging dark field and bright field device.

25 401. The system of claim 390, wherein the measurement device further comprises a double dark field device.

402. The system of claim 390, wherein the measurement device further comprises a dark field imaging device.

403. The system of claim 390, wherein the measurement device further comprises a
5 bright field imaging device.

404. The system of claim 390, wherein the measurement device further comprises a dark field and bright field imaging device.

10 405. The system of claim 390, wherein the measurement device further comprises a scatterometer.

406. The system of claim 390, wherein the measurement device further comprises a spectroscopic scatterometer.

15 407. The system of claim 390, wherein the measurement device further comprises an ellipsometer.

408. The system of claim 390, wherein the measurement device further comprises a
20 spectroscopic ellipsometer.

409. The system of claim 390, wherein the measurement device further comprises a reflectometer.

25 410. The system of claim 390, wherein the measurement device further comprises a spectroscopic reflectometer.

411. The system of claim 390, wherein the measurement device further comprises a dual beam spectrophotometer.

412. The system of claim 390, wherein the measurement device further comprises a
5 beam profile ellipsometer.

413. The system of claim 390, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging
10 dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam
15 profile ellipsometer.

414. The system of claim 390, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
20 measurement device.

415. The system of claim 390, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.
25

416. The system of claim 390, wherein the defects comprise micro defects and macro defects.

417. The system of claim 390, wherein the defects comprise micro defects or macro defects.

418. The system of claim 390, wherein the thin film characteristic comprises a
5 thickness of a copper film, and wherein the defects comprise voids in the copper film.

419. The system of claim 390, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

10 420. The system of claim 390, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15 421. The system of claim 420, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20 422. The system of claim 390, wherein the system is further configured to determine at least two properties of the specimen substantially simultaneously during use.

25 423. The system of claim 390, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

424. The system of claim 390, wherein the system is coupled to a process tool.

425. The system of claim 390, wherein the system is coupled to a process tool, and
5 wherein the system is disposed within the process tool.

426. The system of claim 390, wherein the system is coupled to a process tool, and
wherein the system is arranged laterally proximate to the process tool.

10 427. The system of claim 390, wherein the system is coupled to a process tool, and
wherein the process tool comprises a wafer handler configured to move the specimen to
the stage during use.

428. The system of claim 390, wherein the system is coupled to a process tool, and
15 wherein the stage is further configured to move the specimen from the system to the
process tool during use.

429. The system of claim 390, wherein the system is coupled to a process tool, and
wherein the stage is further configured to move the specimen to a process chamber of the
20 process tool during use.

430. The system of claim 390, wherein the system is coupled to a process tool, and
wherein the system is further configured to determine at least the two properties of the
specimen while the specimen is waiting between process steps.
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431. The system of claim 390, wherein the system is coupled to a process tool, wherein
the process tool comprises a support device configured to support the specimen during a

process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

5 432. The system of claim 390, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

10 433. The system of claim 390, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

15 434. The system of claim 390, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

20 435. The system of claim 390, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

25 436. The system of claim 390, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

437. The system of claim 390, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement

chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

5 438. The system of claim 390, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

10 439. The system of claim 438, wherein the processor is further configured to determine at least the two properties of the specimen during the process step.

440. The system of claim 439, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

15 441. The system of claim 439, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique during use.

20 442. The system of claim 390, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

25 443. The system of claim 390, wherein a process tool comprises a first process chamber and a second process chamber, wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the system is further configured to determine at least the two properties of

the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

5 444. The system of claim 390, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

10 445. The system of claim 390, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

15 446. The system of claim 445, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

20 447. The system of claim 390, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

25 448. The system of claim 390, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique during use.

449. The system of claim 390, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

450. The system of claim 390, wherein the processor is further configured to generate a database during use, and wherein the database comprises the determined first and second properties of the specimen.

5 451. The system of claim 390, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

10 452. The system of claim 390, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

15 453. The system of claim 390, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

20 454. The system of claim 453, wherein the first and second properties of the plurality of specimens are determined using the measurement device.

455. The system of claim 453, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

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456. The system of claim 455, wherein the processor is further coupled to the plurality of measurement devices.

457. The system of claim 456, wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

458. The system of claim 456, wherein the processor is further configured to monitor
5 output signals generated by the plurality of measurement devices using the database during use.

459. The system of claim 390, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration
10 standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

460. The system of claim 390, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to
15 be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

461. The system of claim 390, wherein the system is further configured to determine at
20 least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

25 462. The system of claim 390, wherein the processor is further coupled to a process tool.

463. The system of claim 390, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

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464. The system of claim 390, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

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465. The system of claim 390, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

15 466. The system of claim 465, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

20 467. The system of claim 466, wherein the processor is further configured to alter the parameter of at least one of the instruments in response to the relationship during use.

468. The system of claim 390, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

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469. The system of claim 390, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or

more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

470. The system of claim 469, wherein the local processor is further configured to
5 determine the first property and the second property of the specimen during use.

471. The system of claim 469, wherein the remote controller computer is further
configured to determine the first property and the second property of the specimen during
use.

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472. A method for determining at least two properties of a specimen, comprising:

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disposing the specimen upon a stage, wherein the stage is coupled to a
measurement device, and wherein the measurement device comprises an
illumination system and a detection system;

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directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection
system;

25

generating one or more output signals in response to the detected energy; and

processing the one or more output signals to determine a first property and a
second property of the specimen, wherein the first property comprises a presence
of defects on the specimen, and wherein the second property comprises a thin film
characteristic of the specimen.

473. The method of claim 472, further comprising laterally moving the stage during said directing energy and said detecting energy.

5 474. The method of claim 472, further comprising rotatably moving the stage during said directing energy and said detecting energy.

475. The method of claim 472, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

10 476. The method of claim 472, wherein the illumination system comprises a single energy source.

477. The method of claim 472, wherein the illumination system comprises more than one energy source.

15 478. The method of claim 472, wherein the detection system comprises a single energy sensitive device.

20 479. The method of claim 472, wherein the detection system comprises more than one energy sensitive device.

480. The method of claim 472, wherein the measurement device further comprises a non-imaging dark field device.

25 481. The method of claim 472, wherein the measurement device further comprises a non-imaging bright field device.

482. The method of claim 472, wherein the measurement device further comprises a non-imaging dark field and bright field device.

5 483. The method of claim 472, wherein the measurement device further comprises a double dark field device.

484. The method of claim 472, wherein the measurement device further comprises a dark field imaging device.

10 485. The method of claim 472, wherein the measurement device further comprises a bright field imaging device.

486. The method of claim 472, wherein the measurement device further comprises a dark field and bright field imaging device.

15 487. The method of claim 472, wherein the measurement device further comprises a scatterometer.

20 488. The method of claim 472, wherein the measurement device further comprises a spectroscopic scatterometer.

489. The method of claim 472, wherein the measurement device further comprises an ellipsometer.

25 490. The method of claim 472, wherein the measurement device further comprises a spectroscopic ellipsometer.

491. The method of claim 472, wherein the measurement device further comprises a reflectometer.

492. The method of claim 472, wherein the measurement device further comprises a spectroscopic reflectometer.

493. The method of claim 472, wherein the measurement device further comprises a dual beam spectrophotometer.

494. The method of claim 472, wherein the measurement device further comprises a beam profile ellipsometer.

495. The method of claim 472, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

496. The method of claim 472, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

497. The method of claim 472, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

5 498. The method of claim 472, wherein the defects comprise micro defects and macro defects.

499. The method of claim 472, wherein the defects comprise micro defects or macro defects.

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500. The method of claim 472, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

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501. The method of claim 472, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

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502. The method of claim 472, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

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503. The method of claim 502, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

504. The method of claim 472, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

505. The method of claim 472, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

506. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool.

507. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

508. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

509. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

510. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

511. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.
- 5 512. The method of claim 472, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.
513. The method of claim 472, wherein the stage and the measurement device are
10 coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.
514. The method of claim 472, wherein the stage and the measurement device are
15 coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.
515. The method of claim 472, wherein the stage and the measurement device are
20 disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.
516. The method of claim 472, wherein the stage and the measurement device are
25 disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

517. The method of claim 472, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

5 518. The method of claim 472, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

10 519. The method of claim 472, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

15 520. The method of claim 472, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising performing said directing and said detecting during the process step.

20 521. The method of claim 520, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

25 522. The method of claim 520, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

523. The method of claim 472, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

5 524. The method of claim 472, further comprising moving the specimen from a first process chamber to a second process chamber using the stage and performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

10 525. The method of claim 472, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

15 526. The method of claim 472, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

527. The method of claim 526, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

20 528. The method of claim 472, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

25 529. The method of claim 472, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

530. The method of claim 472, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique.

5 531. The method of claim 472, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

532. The method of claim 472, further comprising calibrating the measurement device using the database.

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533. The method of claim 472, further comprising monitoring output signals generated by the measurement device using the database.

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534. The method of claim 472, wherein the database further comprises first and second properties of a plurality of specimens.

535. The method of claim 534, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

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536. The method of claim 535, further comprising calibrating the plurality of measurement devices using the database.

537. The method of claim 535, further comprising monitoring output signals generated by the plurality of measurement devices using the database.

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538. The method of claim 472, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system

with a calibration standard and calibrating the measurement device with the stand alone system.

539. The method of claim 472, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

540. The method of claim 472, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

541. The method of claim 472, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

542. The method of claim 472, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

543. The method of claim 472, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

544. The method of claim 543, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

545. The method of claim 544, further comprising altering a parameter of at least one of the instruments in response to the relationship.

546. The method of claim 472, further comprising altering a parameter of one or more instruments coupled to each of a plurality of process tools in response to at least one of the determined properties of the specimen.

547. The method of claim 472, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

548. The method of claim 547, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

549. The method of claim 547, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

550. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

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controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

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controlling the illumination system to direct energy toward a surface of the specimen;

controlling the detection system to detect energy propagating from the surface of the specimen; and

15

generating one or more output signals responsive to the detected energy; and

20

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of defects on the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

551. The method of claim 550, further comprising controlling the stage, wherein the stage is configured to support the specimen.

552. The method of claim 550, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

553. The method of claim 550, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

5 554. The method of claim 550, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

555. The method of claim 550, wherein the illumination system comprises a single energy source.

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556. The method of claim 550, wherein the illumination system comprises more than one energy source.

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557. The method of claim 550, wherein the detection system comprises a single energy sensitive device.

558. The method of claim 550, wherein the detection system comprises more than one energy sensitive devices.

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559. The method of claim 550, wherein the measurement device further comprises a non-imaging dark field device.

560. The method of claim 550, wherein the measurement device further comprises a non-imaging bright field device.

25

561. The method of claim 550, wherein the measurement device further comprises a non-imaging dark field and bright field device.

562. The method of claim 550, wherein the measurement device further comprises a double dark field device.

563. The method of claim 550, wherein the measurement device further comprises a dark field imaging device.

564. The method of claim 550, wherein the measurement device further comprises a bright field imaging device.

565. The method of claim 550, wherein the measurement device further comprises a dark field and bright field imaging device.

566. The method of claim 550, wherein the measurement device further comprises a scatterometer.

567. The method of claim 550, wherein the measurement device further comprises a spectroscopic scatterometer.

568. The method of claim 550, wherein the measurement device further comprises an ellipsometer.

569. The method of claim 550, wherein the measurement device further comprises a spectroscopic ellipsometer.

570. The method of claim 550, wherein the measurement device further comprises a reflectometer.

571. The method of claim 550, wherein the measurement device further comprises a spectroscopic reflectometer.

572. The method of claim 550, wherein the measurement device further comprises a
5 dual beam spectrophotometer.

573. The method of claim 550, wherein the measurement device further comprises a beam profile ellipsometer.

10 574. The method of claim 550, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field
15 imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

20 575. The method of claim 550, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

25 576. The method of claim 550, wherein the measurement device comprises non-optical components, and wherein controlling the detection system to detect energy comprises controlling the non-optical components to measure a non-optical characteristic of the surface of the specimen.

577. The method of claim 550, wherein the defects comprise micro defects and macro defects.

5 578. The method of claim 550, wherein the defects comprise micro defects or macro defects.

579. The method of claim 550, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

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580. The method of claim 550, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

15

581. The method of claim 550, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20

582. The method of claim 581, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

25

583. The method of claim 550, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

584. The method of claim 550, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially

simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

5

585. The method of claim 550, wherein the stage and the measurement device are coupled to a process tool.

586. The method of claim 550, wherein the stage and the measurement device are
10 coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

587. The method of claim 550, wherein the stage and the measurement device are
15 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

588. The method of claim 550, wherein the stage and the measurement device are
20 coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

589. The method of claim 550, wherein the stage and the measurement device are
25 coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

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590. The method of claim 550, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.
- 5 591. The method of claim 550, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.
- 10 592. The method of claim 550, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.
- 15 593. The method of claim 550, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.
- 20 594. The method of claim 550, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.
595. The method of claim 550, wherein the stage and the measurement device are
25 disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

596. The method of claim 550, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

5 597. The method of claim 550, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

598. The method of claim 550, further comprising disposing the specimen upon a
10 support device disposed within a process chamber of a process tool, wherein the support device is configured to support the specimen during a process step.

599. The method of claim 598, further comprising controlling the illumination system and controlling the detection system during the process step.

15 600. The method of claim 598, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

20 601. The method of claim 598, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique.

25 602. The method of claim 550, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

603. The method of claim 602, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

5 604. The method of claim 550, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

605. The method of claim 550, further comprising comparing at least one of the
10 determined properties of the specimen to a predetermined range for the property.

606. The method of claim 605, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

15 607. The method of claim 550, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties.

608. The method of claim 550, further comprising altering a parameter of one or more
20 instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

609. The method of claim 550, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the
25 determined properties using a feedforward control technique.

610. The method of claim 550, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

611. The method of claim 610, further comprising calibrating the measurement device using the database.

5 612. The method of claim 610, further comprising monitoring output signals of measurement device using the database.

613. The method of claim 610, wherein the database further comprises first and second properties of a plurality of specimens.

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614. The method of claim 613, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

15 615. The method of claim 613, further comprising calibrating the plurality of measurement devices using the database.

616. The method of claim 613, further comprising monitoring output signals of the plurality of measurement devices using the database.

20 617. The method of claim 550, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

25 618. The method of claim 550, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further

controlling the stand alone system to calibrate the system and at least the one additional system.

619. The method of claim 550, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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620. The method of claim 550, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

621. The method of claim 550, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

622. The method of claim 550, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

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623. The method of claim 622, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

624. The method of claim 623, further comprising altering a parameter of at least one of the instruments in response to the relationship.

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625. The method of claim 550, further comprising altering a parameter of one or more instruments coupled to each of a plurality of process tools in response to at least one of the determined properties of the specimen.

5 626. The method of claim 550, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

627. The method of claim 626, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

20 628. The method of claim 626, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

25

629. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals in response to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of defects on the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

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630. The device of claim 629, wherein the illumination system comprises a single energy source.

20 631. The device of claim 629, wherein the illumination system comprises more than one energy source.

632. The device of claim 629, wherein the detection system comprises a single energy sensitive device.

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633. The device of claim 629, wherein the detection system comprises more than one energy sensitive devices.

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634. The device of claim 629, wherein the measurement device further comprises a measurement device selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.
635. The device of claim 629, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.
636. The device of claim 629, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.
637. The device of claim 629, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

638. The device of claim 629, wherein the defects comprise micro defects and macro defects.

5 639. The device of claim 629, wherein the defects comprise micro defects or macro defects.

640. The device of claim 629, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

10 641. The device of claim 629, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

15 642. The device of claim 629, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20 643. The device of claim 642, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

644. The device of claim 629, wherein the stage and the measurement device are coupled to a process tool.

25 645. The device of claim 629, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

646. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

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disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

10

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

15

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of defects on the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

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647. The method of claim 646, wherein the illumination system comprises a single energy source.

25 648. The method of claim 646, wherein the illumination system comprises more than one energy source.

649. The method of claim 646, wherein the detection system comprises a single energy sensitive device.

650. The method of claim 646, wherein the detection system comprises more than one energy sensitive devices.

651. The method of claim 646, wherein the measurement device further comprises a measurement device selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

652. The method of claim 646, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

653. The method of claim 646, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical

elements of the first measurement device comprise optical elements of the second measurement device.

5 654. The method of claim 646, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

655. The method of claim 646, wherein the defects comprise micro defects and macro defects.

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656. The method of claim 646, wherein the defects comprise micro defects or macro defects.

15 657. The method of claim 646, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

658. The method of claim 646, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

20 659. The method of claim 646, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25 660. The method of claim 659, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

661. The method of claim 646, wherein the stage and the measurement device are coupled to a process tool.

5 662. The method of claim 646, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

10 663. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

15 a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

20 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

25 a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or

more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a presence of defects on the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

664. The system of claim 663, wherein the measurement device further comprises a measurement device selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

665. The system of claim 663, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

666. The system of claim 663, wherein the illumination system and the detection system comprise non-optical components, and the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

667. The system of claim 663, wherein the defects comprise micro defects and macro defects.

5 668. The system of claim 663, wherein the defects comprise micro defects or macro defects.

669. The system of claim 663, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

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670. The system of claim 663, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

671. The system of claim 663, wherein the remote controller computer is further
15 configured to determine a third property of the specimen from the at least partially processed one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20 672. The system of claim 671, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

25 673. The system of claim 663, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially

simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

5 674. The system of claim 663, wherein the stage and the measurement device are coupled to a process tool.

675. The system of claim 663, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical
10 polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

676. The system of claim 663, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least
15 one of the determined properties using a feedback control technique during use.

677. The system of claim 663, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least
20 one of the determined properties using a feedforward control technique during use.

678. The system of claim 663, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.
25

679. The system of claim 678, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

680. The system of claim 679, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

5

681. The system of claim 663, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

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682. The system of claim 681, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

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683. The system of claim 681, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

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684. The system of claim 663, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

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685. The system of claim 684, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further
5 configured to determine the first and second properties of the specimen during said moving.

686. The system of claim 663, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and
10 properties of a plurality of specimens during use.

687. The system of claim 663, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.
15

688. The system of claim 687, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

689. The system of claim 663, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.
20

690. The system of claim 663, wherein the remote controller computer is further
25 configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

691. The system of claim 663, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

5

692. The system of claim 663, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

10 693. The system of claim 692, wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

694. The system of claim 692, wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

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695. The system of claim 692, wherein the database further comprises first and second properties of a plurality of specimens.

20 696. The system of claim 695, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

697. The system of claim 696, wherein the remote controller computer is further coupled to the plurality of measurement devices.

25

698. The system of claim 697, wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

699. The system of claim 697, wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

5

700. The system of claim 663, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

10 701. The system of claim 663, wherein the remote controller computer is further coupled to a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

15 702. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

20

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

25

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of defects on the specimen, and wherein the second property comprises a thin film characteristic of the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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703. The method of claim 702, wherein the measurement device further comprises a measurement device selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

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704. The method of claim 702, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging dark field device, a non-imaging bright field device, a non-imaging dark field and bright

field device, a double dark field device, a dark field imaging device, a bright field imaging device, a dark field and bright field imaging device, a scatterometer, a spectroscopic scatterometer, an ellipsometer, a spectroscopic ellipsometer, a reflectometer, a spectroscopic reflectometer, a dual beam spectrophotometer, and a beam
5 profile ellipsometer.

705. The method of claim 702, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

706. The method of claim 702, wherein the defects comprise micro defects and macro defects.

707. The method of claim 702, wherein the defects comprise micro defects or macro
15 defects.

708. The method of claim 702, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

709. The method of claim 702, wherein the defects comprise macro defects on a back
20 side of the specimen, and wherein the macro defects comprise copper contamination.

710. The method of claim 702, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is
25 selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

711. The method of claim 710, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 712. The method of claim 702, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

10

713. The method of claim 702, wherein the stage and the measurement device are coupled to a process tool.

15

714. The method of claim 702, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

20

715. The method of claim 702, wherein the stage and the measurement device are coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedback control technique.

25

716. The method of claim 702, wherein the stage and the measurement device are coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in

response to at least one of the determined properties of the specimen using a feedforward control technique.

5 717. The method of claim 702, wherein the stage and the measurement device are coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

10 718. The method of claim 717, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

719. The method of claim 718, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

15 720. The method of claim 702, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, the method further comprising performing said directing and said detecting during a process step.

20 721. The method of claim 720, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

25 722. The method of claim 720, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

723. The method of claim 702, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage;

performing said directing and said detecting during said moving the specimen.

5

724. The method of claim 702, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

10 725. The method of claim 702, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

15 726. The method of claim 725, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

727. The method of claim 702, wherein the remote controller computer is coupled to the measurement device.

20

728. The method of claim 727, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to at least one of the determined properties of the specimen.

25 729. The method of claim 727, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

730. The method of claim 727, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.

5

731. The method of claim 702, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen.

10 732. The method of claim 731, further comprising calibrating the measurement device using the remote controller computer and the database.

733. The method of claim 731, further comprising monitoring output signals from the measurement device using the remote controller computer and the database.

15

734. The method of claim 731, wherein the database further comprises first and second properties of a plurality of specimens.

20

735. The method of claim 734, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

736. The method of claim 735, further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

25

737. The method of claim 735, further comprising monitoring the plurality of measurement devices using the remote controller computer and the database.

738. The method of claim 702, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

5

739. The method of claim 738, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to at least one of the determined properties of the specimen.

10

740. The method of claim 738, wherein each of the plurality of measurement devices is coupled to one of a plurality of process tools.

15

741. The method of claim 740, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to at least one of the determined properties of the specimen.

20

742. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

25

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

5

a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a presence of defects on the specimen.

10

743. The system of claim 742, wherein the stage is further configured to move laterally during use.

15

744. The system of claim 742, wherein the stage is further configured to move rotatably during use.

745. The system of claim 742, wherein the stage is further configured to move laterally and rotatably during use.

20

746. The system of claim 742, wherein the illumination system comprises a single energy source.

25

747. The system of claim 742, wherein the illumination system comprises more than one energy source.

748. The system of claim 742, wherein the detection system comprises a single energy sensitive device.

749. The system of claim 742, wherein the detection system comprises more than one energy sensitive devices.

5 750. The system of claim 742, wherein the measurement device further comprises a non-imaging scatterometer.

751. The system of claim 742, wherein the measurement device further comprises a scatterometer.

10

752. The system of claim 742, wherein the measurement device further comprises a spectroscopic scatterometer.

15

753. The system of claim 742, wherein the measurement device further comprises a reflectometer.

754. The system of claim 742, wherein the measurement device further comprises a spectroscopic reflectometer.

20

755. The system of claim 742, wherein the measurement device further comprises a coherence probe microscope.

756. The system of claim 742, wherein the measurement device further comprises an ellipsometer.

25

757. The system of claim 742, wherein the measurement device further comprises a spectroscopic ellipsometer.

758. The system of claim 742, wherein the measurement device further comprises a bright field imaging device.

759. The system of claim 742, wherein the measurement device further comprises a
5 dark field imaging device.

760. The system of claim 742, wherein the measurement device further comprises a bright field and dark field imaging device.

10 761. The system of claim 742, wherein the measurement device further comprises a non-imaging bright field device.

762. The system of claim 742, wherein the measurement device further comprises a non-imaging dark field device.

15 763. The system of claim 742, wherein the measurement device further comprises a non-imaging bright field and dark field device.

764. The system of claim 742, wherein the measurement device further comprises at
20 least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a
25 bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

765. The system of claim 742, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

5

766. The system of claim 742, wherein the defects comprise micro defects and macro defects.

10

767. The system of claim 742, wherein the defects comprises micro defects or macro defects.

15

768. The system of claim 742, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

20

769. The system of claim 768, wherein the defects comprise macro defects.

770. The system of claim 742, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25

771. The system of claim 770, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

772. The system of claim 742, wherein the system is further configured to determine at least two properties of the specimen substantially simultaneously during use.

5 773. The system of claim 742, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be
10 determined at the multiple locations substantially simultaneously.

774. The system of claim 742, wherein the system is coupled to a process tool.

775. The system of claim 742, wherein the system is coupled to a process tool, and
15 wherein the system is disposed within the process tool.

776. The system of claim 742, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

20 777. The system of claim 742, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

778. The system of claim 742, wherein the system is coupled to a process tool, and
25 wherein the stage is configured to move the specimen from the system to the process tool during use.

779. The system of claim 742, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

5 780. The system of claim 742, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

10 781. The system of claim 742, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

15 782. The system of claim 742, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

783. The system of claim 742, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement
20 chamber, and wherein the measurement chamber is coupled to a process tool.

784. The system of claim 742, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement
25 chamber, and wherein the measurement chamber is disposed within the process tool.

785. The system of claim 742, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement

chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

786. The system of claim 742, wherein the system comprises a measurement chamber,
5 wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

787. The system of claim 742, wherein a process tool comprises a process chamber,
10 wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

788. The system of claim 787, wherein the processor is further configured to determine
15 at least the two properties of the specimen during the process step.

789. The system of claim 788, wherein the processor is further configured to obtain a
signature characterizing the process step during use, and wherein the signature comprises
at least one singularity representative of an end of the process step.

790. The system of claim 788, wherein the processor is coupled to the process tool and
20 is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique during use.

791. The system of claim 742, wherein a process tool comprises a first process
25 chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

792. The system of claim 742, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the system is further configured to determine at least the two properties of the specimen as the stage is moving the specimen
5 from the first process chamber to the second process chamber.

793. The system of claim 742, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

10

794. The system of claim 742, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

15 795. The system of claim 794, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

796. The system of claim 742, wherein the processor is further configured to alter a
20 sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

797. The system of claim 742, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to
25 the determined first or second property using a feedback control technique during use.

798. The system of claim 742, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

5 799. The system of claim 742, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

10 800. The system of claim 799, wherein the processor is further configured to calibrate the measurement device using the database during use.

801. The system of claim 799, wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

15 802. The system of claim 799, wherein the database further comprises first and second properties of a plurality of specimens.

803. The system of claim 802, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

20

804. The system of claim 803, wherein the processor is further coupled to the plurality of measurement devices.

25 805. The system of claim 804, wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

806. The system of claim 804, wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

5 807. The system of claim 742, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

10 808. The system of claim 742, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

15 809. The system of claim 742, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to
20 at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

810. The system of claim 742, wherein the processor is further coupled to a process tool.

25 811. The system of claim 742, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more

instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

5 812. The system of claim 742, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

10 813. The system of claim 742, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

15 814. The system of claim 813, wherein the processor is further configured to determine a relationship between the determined properties and at least one of the monitored parameter during use.

815. The system of claim 814, wherein the processor is further configured to alter the parameter of at least one of the instruments in response to the relationship during use.

20 816. The system of claim 742, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

25 817. The system of claim 742, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

818. The system of claim 817, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

5 819. The system of claim 817, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

820. A method for determining at least two properties of a specimen, comprising:

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disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

15

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

20

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a presence of defects on the specimen.

25

821. The method of claim 820, further comprising laterally moving the stage during said directing energy and said detecting energy.

822. The method of claim 820, further comprising rotatably moving the stage during said directing energy and said detecting energy.

5 823. The method of claim 820, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

824. The method of claim 820, wherein the illumination system comprises a single energy source.

10

825. The method of claim 820, wherein the illumination system comprises more than one energy source.

15

826. The method of claim 820, wherein the detection system comprises a single energy sensitive device.

827. The method of claim 820, wherein the detection system comprises more than one energy sensitive devices.

20

828. The method of claim 820, wherein the measurement device further comprises a non-imaging scatterometer.

829. The method of claim 820, wherein the measurement device further comprises a scatterometer.

25

830. The method of claim 820, wherein the measurement device further comprises a spectroscopic scatterometer.

831. The method of claim 820, wherein the measurement device further comprises a reflectometer.

5 832. The method of claim 820, wherein the measurement device further comprises a spectroscopic reflectometer.

833. The method of claim 820, wherein the measurement device further comprises a coherence probe microscope.

10 834. The method of claim 820, wherein the measurement device further comprises an ellipsometer.

835. The method of claim 820, wherein the measurement device further comprises a spectroscopic ellipsometer.

15 836. The method of claim 820, wherein the measurement device further comprises a bright field imaging device.

20 837. The method of claim 820, wherein the measurement device further comprises a dark field imaging device.

838. The method of claim 820, wherein the measurement device further comprises a bright field and dark field imaging device.

25 839. The method of claim 820, wherein the measurement device further comprises a non-imaging bright field device.

840. The method of claim 820, wherein the measurement device further comprises a non-imaging dark field device.

841. The method of claim 820, wherein the measurement device further comprises and
5 a non-imaging bright field and dark field device.

842. The method of claim 820, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging
10 scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

843. The method of claim 820, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
15 measurement device.

844. The method of claim 820, wherein the defects comprise micro defects and macro defects.
20

845. The method of claim 820, wherein the defects comprises micro defects or macro
25 defects.

846. The method of claim 820, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein
the second property comprises a presence of defects on the bottom surface of the
specimen.

5

847. The method of claim 846, wherein the defects comprise macro defects.

848. The method of claim 820, further comprising processing the one or more output
signals to determine a third property of the specimen, wherein the third property is
selected from the group consisting of a roughness of the specimen, a roughness of a layer
on the specimen, and a roughness of a feature of the specimen.

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849. The method of claim 848, wherein the stage and the measurement device are
coupled to a process tool selected from the group consisting of a lithography tool, an
atomic layer deposition tool, a cleaning tool, and an etch tool.

15

850. The method of claim 820, wherein processing the one or more output signals to
determine the first and second properties of the specimen comprises substantially
simultaneously determining the first and second properties of the specimen.

20

851. The method of claim 820, further comprising directing energy toward multiple
locations on the surface of the specimen substantially simultaneously and detecting
energy propagating from the multiple locations substantially simultaneously such that one
or more of the at least two properties of the specimen can be determined at the multiple
locations substantially simultaneously.

25

852. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool.

853. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

854. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

855. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

856. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

857. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

858. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

859. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

5

860. The method of claim 820, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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861. The method of claim 820, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

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862. The method of claim 820, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within the process tool.

20

863. The method of claim 820, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

25

864. The method of claim 820, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

865. The method of claim 820, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process

chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

5 866. The method of claim 865, further comprising performing said directing and said detecting during the process step.

867. The method of claim 866, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

10 868. The method of claim 866, further comprising altering a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique.

15 869. The method of claim 820, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

20 870. The method of claim 869, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

25 871. The method of claim 820, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

872. The method of claim 820, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

873. The method of claim 872, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

5

874. The method of claim 820, further comprising altering a sampling frequency of the measurement device in response to the determined first or second property of the specimen.

10 875. The method of claim 820, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

15 876. The method of claim 820, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique.

877. The method of claim 820, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

20

878. The method of claim 877, further comprising calibrating the measurement device using the database.

25 879. The method of claim 877, further comprising monitoring output signals of the measurement device using the database.

880. The method of claim 877, wherein the database further comprises first and second properties of a plurality of specimens.

881. The method of claim 880, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

5 882. The method of claim 881, further comprising calibrating the plurality of measurement devices using the database.

883. The method of claim 881, further comprising monitoring output signals of the plurality of measurement devices using the database.

10

884. The method of claim 820, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

15

885. The method of claim 820, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

20

886. The method of claim 820, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

25

887. The method of claim 820, further comprising altering a parameter of one or more instrument coupled to a process tool in response to the determined first or second property of the specimen using a feedback control technique.

5 888. The method of claim 820, further comprising altering a parameter of one or more instrument coupled to a process tool in response to the determined first or second property of the specimen using a feedforward control technique.

889. The method of claim 820, further comprising monitoring a parameter of one or
10 more instruments coupled to a process tool.

890. The method of claim 889, further comprising determining a relationship between the determined properties and at least one of the monitored parameters.

15 891. The method of claim 890, further comprising altering the parameter of at least one of the instruments in response to the relationship.

892. The method of claim 820, further comprising altering a parameter of one or more instruments coupled to each of a plurality of process tools in response to the determined
20 first or second property of the specimen.

893. The method of claim 820, wherein processing the one or more output signals comprises:

25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

5 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

5 further processing the partially processed one or more output signals using the remote controller computer.

894. The method of claim 893, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

10 895. The method of claim 893, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

15 896. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

20 controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

controlling the illumination system to direct energy toward a surface of the specimen;

25 controlling the detection system to detect energy propagating from the surface of the specimen; and

generating one or more output signals responsive to the detected energy;
and

5 processing the one or more output signals to determine a first property and a
second property of the specimen, wherein the first property comprises a critical
dimension of the specimen, and wherein the second property comprises a presence
of defects on the specimen.

10 897. The method of claim 896, further comprising controlling the stage, wherein the
stage is configured to support the specimen.

898. The method of claim 896, further comprising controlling the stage to move
laterally during said directing energy and said detecting energy.

15 899. The method of claim 896, further comprising controlling the stage to move
rotatably during said directing energy and said detecting energy.

900. The method of claim 896, further comprising controlling the stage to move
laterally and rotatably during said directing energy and said detecting energy.

20 901. The method of claim 896, wherein the illumination system comprises a single
energy source.

25 902. The method of claim 896, wherein the illumination system comprises more than
one energy source.

903. The method of claim 896, wherein the detection system comprises a single energy
sensitive device.

904. The method of claim 896, wherein the detection system comprises more than one energy sensitive devices.

5 905. The method of claim 896, wherein the measurement device further comprises a non-imaging scatterometer.

906. The method of claim 896, wherein the measurement device further comprises a scatterometer.

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907. The method of claim 896, wherein the measurement device further comprises a spectroscopic scatterometer.

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908. The method of claim 896, wherein the measurement device further comprises a reflectometer.

909. The method of claim 896, wherein the measurement device further comprises a spectroscopic reflectometer.

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910. The method of claim 896, wherein the measurement device further comprises a coherence probe microscope.

911. The method of claim 896, wherein the measurement device further comprises an ellipsometer.

25

912. The method of claim 896, wherein the measurement device further comprises a spectroscopic ellipsometer.

913. The method of claim 896, wherein the measurement device further comprises a bright field imaging device.

914. The method of claim 896, wherein the measurement device further comprises a
5 dark field imaging device.

915. The method of claim 896, wherein the measurement device further comprises a bright field and dark field imaging device.

10 916. The method of claim 896, wherein the measurement device further comprises a non-imaging bright field device.

917. The method of claim 896, wherein the measurement device further comprises a non-imaging dark field device.

15 918. The method of claim 896, wherein the measurement device further comprises and a non-imaging bright field and dark field device.

919. The method of claim 896, wherein the measurement device further comprises at
20 least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a
25 bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

920. The method of claim 896, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

5

921. The method of claim 896, wherein the defects comprise micro defects and macro defects.

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922. The method of claim 896, wherein the defects comprises micro defects or macro defects.

923. The method of claim 896, further comprising:

15

controlling the illumination system to direct energy toward a bottom surface of the specimen; and

controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

20

924. The method of claim 923, wherein the defects comprise macro defects.

25

925. The method of claim 896, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

926. The method of claim 925, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

- 5 927. The method of claim 896, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

- 10 928. The method of claim 896, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

- 15 929. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool.

- 20 930. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

- 25 931. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

932. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

5 933. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

10 934. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

15 935. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

20 936. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

25 937. The method of claim 896, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

938. The method of claim 896, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

5 939. The method of claim 896, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

10 940. The method of claim 896, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

15 941. The method of claim 896, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

20 942. The method of claim 896, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

943. The method of claim 942, further comprising controlling the illumination system and controlling the detection system during the process step.

25 944. The method of claim 943, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

945. The method of claim 943, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique.

5 946. The method of claim 896, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

947. The method of claim 946, further comprising controlling the illumination system
10 and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

948. The method of claim 896, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of
15 specimens.

949. The method of claim 896, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

20 950. The method of claim 949, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

951. The method of claim 896, further comprising altering a sampling frequency of the
25 measurement device in response to the determined first or second property of the specimen.

952. The method of claim 896, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

- 5 953. The method of claim 896, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique.

954. The method of claim 896, further comprising generating a database, wherein the
10 database comprises the determined first and second properties of the specimen.

955. The method of claim 954, further comprising calibrating the measurement device using the database.

- 15 956. The method of claim 954, further comprising monitoring output signals of the measurement device using the database.

957. The method of claim 954, wherein the database further comprises first and second properties of a plurality of specimens.

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958. The method of claim 957, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

959. The method of claim 958, further comprising calibrating the plurality of
25 measurement devices using the database.

960. The method of claim 958, further comprising monitoring output signals of the plurality of measurement devices using the database.

961. The method of claim 896, wherein a stand alone system is coupled to the system,
the method further comprising controlling the stand alone system to calibrate the stand
alone system with a calibration standard and further controlling the stand alone system to
5 calibrate the system.

962. The method of claim 896, wherein a stand alone system is coupled to the system
and at least one additional system, the method further comprising controlling the stand
alone system to calibrate the stand alone system with a calibration standard and further
10 controlling the stand alone system to calibrate the system and at least the one additional
system.

963. The method of claim 896, wherein the system is further configured to determine at
least the two properties of the specimen at more than one position on the specimen, and
15 wherein the specimen comprises a wafer, the method further comprising altering at least
one parameter of one or more instruments coupled to a process tool in response to at least
one of the determined properties of the specimen at the more than one position on the
specimen to reduce within wafer variation of at least one of the determined properties.

964. The method of claim 896, further comprising altering a parameter of one or more
instruments coupled to a process tool in response to the determined first or second
20 property of the specimen using a feedback control technique.

965. The method of claim 896, further comprising altering a parameter of one or more
25 instruments coupled to a process tool in response to the determined first or second
property of the specimen using a feedforward control technique.

966. The method of claim 896, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

5 967. The method of claim 966, further comprising determining a relationship between the determined properties and at least one of the monitored parameters.

968. The method of claim 967, further comprising altering a parameter of one or more of the instruments in response to the relationship.

10 969. The method of claim 896, further comprising altering a parameter of one or more instruments coupled to each of a plurality of process tools in response to the determined first or second property of the specimen.

15 970. The method of claim 896, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

20 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

25 971. The method of claim 970, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

972. The method of claim 970, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

5 973. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

10 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

15 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

20 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the portion of the specimen, and wherein the second property comprises a presence of defects on the portion of the specimen.

25 974. The device of claim 973, wherein the illumination system comprises a single energy source.

975. The device of claim 973, wherein the illumination system comprises more than one energy source.

976. The device of claim 973, wherein the detection system comprises a single energy
5 sensitive device.

977. The device of claim 973, wherein the detection system comprises more than one energy sensitive devices.

10 978. The device of claim 973, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging
15 bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

979. The device of claim 973, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first
20 and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-
25 imaging dark field device, and a non-imaging bright field and dark field device.

980. The device of claim 973, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical

elements of the first measurement device comprise optical elements of the second measurement device.

5 981. The device of claim 973, wherein the defects comprise micro defects and macro defects.

982. The device of claim 973, wherein the defects comprises micro defects or macro defects.

10 983. The device of claim 973, further comprising:

directing energy toward a bottom surface of the specimen; and

15 detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

984. The device of claim 983, wherein the defects comprise macro defects.

20 985. The device of claim 973, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25 986. The device of claim 973, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

987. The device of claim 973, wherein the stage and the measurement device are coupled to a process tool.

988. The device of claim 973, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

989. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a presence of defects on the portion of the specimen.

990. The method of claim 989, wherein the illumination system comprises a single energy source.

991. The method of claim 989, wherein the illumination system comprises more than
5 one energy source.

992. The method of claim 989, wherein the detection system comprises a single energy sensitive device.

10 993. The method of claim 989, wherein the detection system comprises more than one energy sensitive devices.

994. The method of claim 989, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic
15 scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

20 995. The method of claim 989, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a
25 spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

996. The method of claim 989, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

997. The method of claim 989, wherein the defects comprise micro defects and macro defects.

998. The method of claim 989, wherein the defects comprises micro defects or macro defects.

999. The method of claim 989, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

1000. The method of claim 999, wherein the defects comprise macro defects.

1001. The method of claim 989, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1002. The method of claim 1001, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 1003. The method of claim 989, wherein the stage and the measurement device are coupled to a process tool.

1004. The method of claim 989, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group
10 consisting of a lithography tool and an etch tool.

1005. A system configured to determine at least two properties of a specimen during use, comprising:

15 a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

20 an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more
25 output *signals responsive* to the detected energy during use;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

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5 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a presence of defects on the specimen.

10 1006. The system of claim 1005, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a spectroscopic ellipsometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and
15 dark field device.

20 1007. The system of claim 1005, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

25 1008. The system of claim 1005, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical

elements of the first measurement device comprise optical elements of the second measurement device.

1009. The system of claim 1005, wherein the defects comprise micro defects and macro
5 defects.

1010. The system of claim 1005, wherein the defects comprises micro defects or macro defects.

10 1011. The system of claim 1005, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

15 1012. The system of claim 1011, wherein the defects comprise macro defects.

1013. The system of claim 1005, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially
20 processed one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1014. The system of claim 1013, wherein the system is coupled to a process tool
25 selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

1015. The system of claim 1005, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

1016. The system of claim 1005, wherein the remote controller computer is coupled to a process tool.

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1017. The system of claim 1005, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from a group consisting of a lithography tool, an etch tool, and a deposition tool.

1018. The system of claim 1005, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

1019. The system of claim 1005, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

1020. The system of claim 1005, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instrument coupled to the process tool during use.

1021. The system of claim 1005, wherein the remote controller computer is coupled to a process tool, wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use, and wherein the remote controller computer is further configured to determine a relationship between the determined properties and at least one of the monitored parameters during use.

1022. The system of claim 1005, wherein the remote controller computer is coupled to a process tool, wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use, wherein the remote controller computer is further configured to determine a relationship between the determined properties and the at least one of the monitored parameters during use, and wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

1023. The system of claim 1005, wherein the system and the remote controller computer are coupled to a process tool, wherein the process tool is configured to perform a step of a process, wherein the illumination system is further configured to direct energy toward the surface of the specimen during the process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

1024. The system of claim 1023, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

1025. The system of claim 1023, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using an in situ control technique during use.

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1026. The system of claim 1005, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

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1027. The system of claim 1026, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further
15 configured to determine the first and second properties of the specimen during said moving.

20

1028. The system of claim 1005, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

25

1029. The system of claim 1005, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

1030. The system of claim 1029, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

1031. The system of claim 1005, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

5

1032. The system of claim 1005, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique during use.

10

1033. The system of claim 1005, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

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1034. The system of claim 1005, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

20

1035. The system of claim 1034, wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

25

1036. The system of claim 1034, wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

1037. The system of claim 1034, wherein the database further comprises first and second properties of a plurality of specimens.

1038. The system of claim 1037, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

5 1039. The system of claim 1038, wherein the remote controller computer is further coupled to the plurality of measurement devices.

1040. The system of claim 1039, wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during
10 use.

1041. The system of claim 1039, wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

15 1042. The system of claim 1005, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

20 1043. The system of claim 1042, wherein the remote controller computer is further coupled to at least one of the plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

25 1044. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals in response to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a presence of defects on the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

25

further processing the partially processed one or more output signals using the remote controller computer.

1045. The method of claim 1044, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic

scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

1046. The method of claim 1044, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, and a non-imaging bright field and dark field device.

1047. The method of claim 1044, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1048. The method of claim 1044, wherein the defects comprise micro defects and macro defects.

1049. The method of claim 1044, wherein the defects comprises micro defects or macro defects.

1050. The method of claim 1044, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein
the second property comprises a presence of defects on the bottom surface of the
specimen.

5

1051. The method of claim 1050, wherein the defects comprise macro defects.

1052. The method of claim 1044, further comprising processing the one or more output
signals to determine a third property of the specimen, wherein the third property is
selected from the group consisting of a roughness of the specimen, a roughness of a layer
on the specimen, and a roughness of a feature of the specimen.

10

1053. The method of claim 1052, wherein the stage and the measurement device are
coupled to a process tool selected from the group consisting of a lithography tool, an
atomic layer deposition tool, a cleaning tool, and an etch tool.

15

1054. The method of claim 1044, further comprising directing energy toward multiple
locations on the surface of the specimen substantially simultaneously and detecting
energy propagating from the multiple locations substantially simultaneously such that one
or more of the at least two properties of the specimen can be determined at the multiple
locations substantially simultaneously.

20

1055. The method of claim 1044, wherein the remote controller computer is coupled to a
process tool.

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1056. The method of claim 1044, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

5 1057. The method of claim 1044, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to the determined first or second property of the specimen using a feedback control technique.

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1058. The method of claim 1044, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to the determined first or second property of the specimen using a feedforward control technique.

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1059. The method of claim 1044, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

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1060. The method of claim 1059, further comprising determining a relationship between the determined properties and the monitored parameters using the remote controller computer.

25 1061. The method of claim 1060, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

1062. The method of claim 1044, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, the method further comprising performing said directing and said detecting during a process step.

- 5 1063. The method of claim 1062, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

1064. The method of claim 1062, further comprising altering a parameter of one or more
10 instruments coupled to the process tool using the remote controller computer in response to the determined first or second property using an in situ control technique.

1065. The method of claim 1044, further comprising:

- 15 moving the specimen from a first process chamber to a second process chamber using the stage;
- performing said directing and said detecting during said moving the specimen.

- 20 1066. The method of claim 1044, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

1067. The method of claim 1044, further comprising comparing at least one of the
25 determined properties of the specimen to a predetermined range for the property using the remote controller computer.

1068. The method of claim 1067, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

5 1069. The method of claim 1044, wherein the remote controller computer is coupled to the measurement device.

1070. The method of claim 1069, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to the
10 determined first or second property of the specimen.

1071. The method of claim 1069, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to the determined first or second property using a feedback control technique.
15

1072. The method of claim 1069, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to the determined first or second property using a feedforward control technique.

20 1073. The method of claim 1044, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen.

1074. The method of claim 1073, further comprising calibrating the measurement device
25 using the database and the remote controller computer.

1075. The method of claim 1073, further comprising monitoring output signals of the measurement device using the database and the remote controller computer.

1076. The method of claim 1073, wherein the database further comprises first and second properties of a plurality of specimens.

5 1077. The method of claim 1076, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

1078. The method of claim 1077, further comprising calibrating the plurality of measurement devices using the database and the remote controller computer.

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1079. The method of claim 1077, further comprising monitoring output signals of the plurality of measurement devices using the database and the remote controller computer.

1080. The method of claim 1044, further comprising sending the at least partially
15 processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

1081. The method of claim 1080, wherein each of the plurality of measurement devices
20 is coupled to at least one of a plurality of process tools.

1082. The method of claim 1081, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to the determined first or second property of the
25 specimen.

1083. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

5

an illumination system configured to direct energy toward a surface of the specimen during use; and

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a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

15

a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

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1084. The system of claim 1083, wherein the stage is further configured to move laterally during use.

1085. The system of claim 1083, wherein the stage is further configured to move rotatably during use.

25

1086. The system of claim 1083, wherein the stage is further configured to move laterally and rotatably during use.

1087. The system of claim 1083, wherein the illumination system comprises a single energy source.

5 1088. The system of claim 1083, wherein the illumination system comprises more than one energy source.

1089. The system of claim 1083, wherein the detection system comprises a single energy sensitive device.

10 1090. The system of claim 1083, wherein the detection system comprises more than one energy sensitive devices.

1091. The system of claim 1083, wherein the measurement device further comprises a non-imaging scatterometer.

15 1092. The system of claim 1083, wherein the measurement device further comprises a scatterometer.

20 1093. The system of claim 1083, wherein the measurement device further comprises a spectroscopic scatterometer.

1094. The system of claim 1083, wherein the measurement device further comprises a reflectometer.

25 1095. The system of claim 1083, wherein the measurement device further comprises a spectroscopic reflectometer.

1096. The system of claim 1083, wherein the measurement device further comprises a coherence probe microscope.

5 1097. The system of claim 1083, wherein the measurement device further comprises a bright field imaging device.

1098. The system of claim 1083, wherein the measurement device further comprises a dark field imaging device.

10 1099. The system of claim 1083, wherein the measurement device further comprises a bright field and dark field imaging device.

1100. The system of claim 1083, wherein the measurement device further comprises an ellipsometer.

15 1101. The system of claim 1083, wherein the measurement device further comprises a spectroscopic ellipsometer.

20 1102. The system of claim 1083, wherein the measurement device further comprises a dual beam spectrophotometer.

1103. The system of claim 1083, wherein the measurement device further comprises a beam profile ellipsometer.

25 1104. The system of claim 1083, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a

spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grating X-ray reflectometer.

5

1105. The system of claim 1083, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10

1106. The system of claim 1083, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

15

1107. The system of claim 1083, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1108. The system of claim 1083, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the system is coupled to an atomic layer deposition tool.

20

1109. The system of claim 1083, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25

1110. The system of claim 1109, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

- 5 1111. The system of claim 1083, wherein the system is further configured to determine at least the two properties of the specimen substantially simultaneously during use.

1112. The system of claim 1083, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially
10 simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

- 15 1113. The system of claim 1083, wherein the system is coupled to a process tool.

1114. The system of claim 1083, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

- 20 1115. The system of claim 1083, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

1116. The system of claim 1083, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to
25 the stage during use.

1117. The system of claim 1083, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

- 5 1118. The system of claim 1083, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

- 10 1119. The system of claim 1083, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

- 15 1120. The system of claim 1083, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

- 20 1121. The system of claim 1083, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

- 25 1122. The system of claim 1083, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

1123. The system of claim 1083, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

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1124. The system of claim 1083, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

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1125. The system of claim 1083, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of is process tool.

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1126. The system of claim 1083, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

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1127. The system of claim 1126, wherein the processor is further configured to determine at least the two properties of the specimen during the process step.

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1128. The system of claim 1127, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

1129. The system of claim 1127, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the

process tool in response to the determined properties using an in situ control technique during use.

1130. The system of claim 1083, wherein a process tool comprises a first process
5 chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

1131. The system of claim 1130, wherein the system is further configured to determine
10 at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

1132. The system of claim 1083, wherein the processor is further configured to compare
15 at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

1133. The system of claim 1083, wherein the processor is further configured to compare
20 at least one of the determined properties of the specimen to a predetermined range for the property during use.

1134. The system of claim 1133, wherein the processor is further configured to generate
an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

1135. The system of claim 1083, wherein the processor is further configured to alter a
25 sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

1136. The system of claim 1083, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique during use.

- 5 1137. The system of claim 1083, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

- 10 1138. The system of claim 1083, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

- 15 1139. The system of claim 1138, wherein the processor is further configured to calibrate the measurement device using the database during use.

1140. The system of claim 1139, wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

- 20 1141. The system of claim 1139, wherein the database further comprises first and second properties of a plurality of specimens.

1142. The system of claim 1141, wherein the first and second properties of the plurality of specimens are determined using the measurement device.

- 25 1143. The system of claim 1141, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

1144. The system of claim 1143, wherein the processor is further coupled to the plurality of measurement devices.

5 1145. The system of claim 1144, wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

10 1146. The system of claim 1144, wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

15 1147. The system of claim 1083, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

20 1148. The system of claim 1083, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

25 1149. The system of claim 1083, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

1150. The system of claim 1083, wherein the processor is further coupled to a process tool.

5 1151. The system of claim 1150, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

10 1152. The system of claim 1150, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

1153. The system of claim 1150, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

15 1154. The system of claim 1153, wherein the processor is further configured to determine a relationship between the determined properties and the monitored parameters during use.

20 1155. The system of claim 1154, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the relationship during use.

25 1156. The system of claim 1083, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

1157. The system of claim 1083, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local

processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

- 5 1158. The system of claim 1157, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

1159. The system of claim 1157, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during
10 use.

1160. A method for determining at least two properties of a specimen, comprising:

15 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

20 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals in response to the detected energy; and

25 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

1161. The method of claim 1160, further comprising laterally moving the stage during said directing energy and said detecting energy.

5 1162. The method of claim 1160, further comprising rotatably moving the stage during said directing energy and said detecting energy.

1163. The method of claim 1160, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

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1164. The method of claim 1160, wherein the illumination system comprises a single energy source.

15 1165. The method of claim 1160, wherein the illumination system comprises more than one energy source.

1166. The method of claim 1160, wherein the detection system comprises a single energy sensitive device.

20 1167. The method of claim 1160, wherein the detection system comprises more than one energy sensitive devices.

1168. The method of claim 1160, wherein the measurement device further comprises a non-imaging scatterometer.

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1169. The method of claim 1160, wherein the measurement device further comprises a scatterometer.

1170. The method of claim 1160, wherein the measurement device further comprises a spectroscopic scatterometer.

5 1171. The method of claim 1160, wherein the measurement device further comprises a reflectometer.

1172. The method of claim 1160, wherein the measurement device further comprises a spectroscopic reflectometer.

10 1173. The method of claim 1160, wherein the measurement device further comprises a coherence probe microscope.

1174. The method of claim 1160, wherein the measurement device further comprises a bright field imaging device.

15 1175. The method of claim 1160, wherein the measurement device further comprises a dark field imaging device.

20 1176. The method of claim 1160, wherein the measurement device further comprises a bright field and dark field imaging device.

1177. The method of claim 1160, wherein the measurement device further comprises an ellipsometer.

25 1178. The method of claim 1160, wherein the measurement device further comprises a spectroscopic ellipsometer.

1179. The method of claim 1160, wherein the measurement device further comprises a dual beam spectrophotometer.

1180. The method of claim 1160, wherein the measurement device further comprises a
5 beam profile ellipsometer.

1181. The method of claim 1160, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging
10 scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grating X-ray reflectometer.

1182. The method of claim 1160, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
15 measurement device.

1183. The method of claim 1160, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical
20 characteristic of the surface of the specimen.

1184. The method of claim 1160, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1185. The method of claim 1160, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

5 1186. The method of claim 1160, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

10 1187. The method of claim 1186, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

15 1188. The method of claim 1160, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

20 1189. The method of claim 1160, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

25 1190. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool.

1191. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

5 1192. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

1193. The method of claim 1160, wherein the stage and the measurement device are
10 coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

1194. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and
15 wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

1195. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the
20 process tool subsequent to said directing and said detecting using the stage.

1196. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.
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1197. The method of claim 1160, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured

to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

1198. The method of claim 1160, wherein the stage and the measurement device are
5 coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

1199. The method of claim 1160, wherein the stage and the measurement device are
10 disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

1200. The method of claim 1160, wherein the stage and the measurement device are
15 disposed within a measurement chamber, and wherein the measurement chamber is disposed within the process tool.

1201. The method of claim 1160, wherein the stage and the measurement device are
20 disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

1202. The method of claim 1160, wherein the stage and the measurement device are
disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

25 1203. The method of claim 1160, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

1204. The method of claim 1203, further comprising performing said directing and said detecting during the process step.

- 5 1205. The method of claim 1204, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

1206. The method of claim 1204, further comprising altering a parameter of one or more
10 instrument coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

1207. The method of claim 1160, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process
15 chamber and the second process chamber are disposed within a process tool.

1208. The method of claim 1207, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

- 20 1209. The method of claim 1160, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 25 1210. The method of claim 1160, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

1211. The method of claim 1210, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

5 1212. The method of claim 1160, further comprising altering a sampling frequency of the measurement device in response to the determined first or second properties of the specimen.

10 1213. The method of claim 1160, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

15 1214. The method of claim 1160, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique.

1215. The method of claim 1160, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

20 1216. The method of claim 1215, further comprising calibrating the measurement device using the database.

1217. The method of claim 1215, further comprising monitoring output signals of the measurement device using the database.

25 1218. The method of claim 1215, wherein the database further comprises first and second properties of a plurality of specimens.

1219. The method of claim 1218, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

5 1220. The method of claim 1219, further comprising calibrating the plurality of measurement devices using the database.

1221. The method of claim 1219, further comprising monitoring output signals of the plurality of measurement devices using the database.

10 1222. The method of claim 1160, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

15 1223. The method of claim 1160, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

20 1224. The method of claim 1160, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one
25 of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

1225. The method of claim 1160, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen using a feedback control technique.

- 5 1226. The method of claim 1160, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen using a feedforward control technique.

- 10 1227. The method of claim 1160, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

1228. The method of claim 1227, further comprising determining a relationship between the determined properties and the monitored parameters.

- 15 1229. The method of claim 1228, further comprising altering a parameter of at least one of the instruments in response to the relationship.

- 20 1230. The method of claim 1160, further comprising altering a parameter of one or more instrument coupled to a plurality of process tools in response to the determined first or second property of the specimen.

1231. The method of claim 1160, wherein processing the one or more output signals comprises:

- 25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

5 further processing the partially processed one or more output signals using the remote controller computer.

1232. The method of claim 1231, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

10 1233. The method of claim 1231, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

1234. A computer-implemented method for controlling a system configured to
15 determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

controlling the measurement device, wherein the measurement device comprises
an illumination system and a detection system, and wherein the measurement
20 device is coupled to a stage, comprising:

controlling the illumination system to direct energy toward a surface of the specimen;

25 controlling the detection system to detect energy propagating from the surface of the specimen; and

generating one or more output signals responsive to the detected energy;
and

5 processing the one or more output signals to determine a first property and a
second property of the specimen, wherein the first property comprises a critical
dimension of the specimen, and wherein the second property comprises a thin film
characteristic of the specimen.

10 1235. The method of claim 1234, further comprising controlling the stage, wherein the
stage is configured to support the specimen.

1236. The method of claim 1234, further comprising controlling the stage to move
laterally during said directing energy and said detecting energy.

15 1237. The method of claim 1234, further comprising controlling the stage to move
rotatably during said directing energy and said detecting energy.

20 1238. The method of claim 1234, further comprising controlling the stage to move
laterally and rotatably during said directing energy and said detecting energy.

1239. The method of claim 1234, wherein the illumination system comprises a single
energy source.

25 1240. The method of claim 1234, wherein the illumination system comprises more than
one energy source.

1241. The method of claim 1234, wherein the detection system comprises a single
energy sensitive device.

1242. The method of claim 1234, wherein the detection system comprises more than one energy sensitive devices.

5 1243. The method of claim 1234, wherein the measurement device further comprises a non-imaging scatterometer.

1244. The method of claim 1234, wherein the measurement device further comprises a scatterometer.

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1245. The method of claim 1234, wherein the measurement device further comprises a spectroscopic scatterometer.

1246. The method of claim 1234, wherein the measurement device further comprises a reflectometer.

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1247. The method of claim 1234, wherein the measurement device further comprises a spectroscopic reflectometer.

20 1248. The method of claim 1234, wherein the measurement device further comprises a coherence probe microscope.

1249. The method of claim 1234, wherein the measurement device further comprises a bright field imaging device.

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1250. The method of claim 1234, wherein the measurement device further comprises a dark field imaging device.

1251. The method of claim 1234, wherein the measurement device further comprises a bright field and dark field imaging device.

5 1252. The method of claim 1234, wherein the measurement device further comprises an ellipsometer.

1253. The method of claim 1234, wherein the measurement device further comprises a spectroscopic ellipsometer.

10 1254. The method of claim 1234, wherein the measurement device further comprises a dual beam spectrophotometer.

1255. The method of claim 1234, wherein the measurement device further comprises a beam profile ellipsometer.

15 1256. The method of claim 1234, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

20 1257. The method of claim 1234, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1258. The method of claim 1234, wherein the measurement device further comprises non-optical components, and wherein controlling the detection system to detect energy comprises controlling the non-optical components to measure a non-optical characteristic of the surface of the specimen.

1259. The method of claim 1234, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1260. The method of claim 1234, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the system is coupled to an atomic layer deposition tool.

1261. The method of claim 1234, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1262. The method of claim 1261, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

1263. The method of claim 1234, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

1264. The method of claim 1234, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially

simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

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1265. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool.

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1266. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

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1267. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

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1268. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

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1269. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

1270. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

1271. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

1272. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

1273. The method of claim 1234, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

1274. The method of claim 1234, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

1275. The method of claim 1234, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within the process tool.

1276. The method of claim 1234, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

1277. The method of claim 1234, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

- 5 1278. The method of claim 1234, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

- 10 1279. The method of claim 1278, further comprising controlling the illumination system and controlling the detection system during the process step.

- 15 1280. The method of claim 1279, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

1281. The method of claim 1279, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique.

- 20 1282. The method of claim 1234, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 25 1283. The method of claim 1282, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

1284. The method of claim 1234, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 5 1285. The method of claim 1234, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

1286. The method of claim 1285, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined
10 range for the property.

1287. The method of claim 1234, further comprising altering a sampling frequency of the measurement device in response to the determined first or second property of the specimen.
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1288. The method of claim 1234, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique.

20 1289. The method of claim 1234, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique.

1290. The method of claim 1234, further comprising generating a database, wherein the
25 database comprises the determined first and second properties of the specimen.

1291. The method of claim 1290, further comprising calibrating the measurement device using the database.

1292. The method of claim 1290, further comprising monitoring output signals of the measurement device using the database.

5 1293. The method of claim 1290, wherein the database further comprises first and second properties of a plurality of specimens.

1294. The method of claim 1293, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

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1295. The method of claim 1294, further comprising calibrating the plurality of measurement devices using the database.

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1296. The method of claim 1294, further comprising monitoring output signals of the plurality of measurement devices using the database.

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1297. The method of claim 1234, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

25

1298. The method of claim 1234, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

1299. The method of claim 1234, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

1300. The method of claim 1234, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen using a feedback control technique.

1301. The method of claim 1234, further comprising altering a parameter of one or more instruments coupled to a process tool in response to the determined first or second property of the specimen using a feedforward control technique.

1302. The method of claim 1234, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

1303. The method of claim 1302, further comprising determining a relationship between the determined properties and the monitored parameters.

1304. The method of claim 1303, further comprising altering a parameter of at least one of the instruments in response to the relationship.

1305. The method of claim 1234, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to the determined first or second property of the specimen.

1306. The method of claim 1234, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

1307. The method of claim 1306, wherein at least partially processing the one or more
output signals comprises determining the first and second properties of the specimen.

1308. The method of claim 1306, wherein further processing the partially processed one
or more output signals comprises determining the first and second properties of the
specimen.

1309. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a
measurement device, and wherein the measurement device comprises an
illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

5 generating one or more output signals in response to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

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1310. The device of claim 1309, wherein the illumination system comprises a single energy source.

15 1311. The device of claim 1309, wherein the illumination system comprises more than one energy source.

1312. The device of claim 1309, wherein the detection system comprises a single energy sensitive device.

20 1313. The device of claim 1309, wherein the detection system comprises more than one energy sensitive devices.

1314. The device of claim 1309, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam

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spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1315. The device of claim 1309, wherein the measurement device comprises at least a
5 first measurement device and a second measurement device, and wherein the first and
second measurement devices are selected from the group consisting of a non-imaging
scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a
spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device,
a dark field imaging device, a bright field and dark field imaging device, an ellipsometer,
10 a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile
ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1316. The device of claim 1309, wherein the measurement device comprises at least a
15 first measurement device and a second measurement device, and wherein optical
elements of the first measurement device comprise optical elements of the second
measurement device.

1317. The device of claim 1309, wherein the measurement device further comprises
non-optical components, and wherein detecting energy comprises measuring a non-
20 optical characteristic of the surface of the specimen.

1318. The device of claim 1309, wherein the measurement device further comprises at
least an eddy current device and a spectroscopic ellipsometer.

25 1319. The device of claim 1309, wherein the measurement device further comprises at
least an eddy current device and a spectroscopic ellipsometer, and wherein the
measurement device is further coupled to an atomic layer deposition tool.

1320. The device of claim 1309, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

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1321. The device of claim 1320, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

10 1322. The device of claim 1309, wherein the stage and the measurement device are coupled to a process tool.

1323. The device of claim 1309, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group
15 consisting of a lithography tool, an etch tool, and a deposition tool.

1324. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

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disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

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directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals in response to the detected energy; and

5 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a thin film characteristic of the specimen.

10 1325. The method of claim 1324, wherein the illumination system comprises a single energy source.

1326. The method of claim 1324, wherein the illumination system comprises more than one energy source.

15 1327. The method of claim 1324, wherein the detection system comprises a single energy sensitive device.

1328. The method of claim 1324, wherein the detection system comprises more than one energy sensitive devices.

20 1329. The method of claim 1324, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and
25 dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1330. The method of claim 1324, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1331. The method of claim 1324, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1332. The method of claim 1324, wherein the measurement device further comprises non-optical components, and wherein measuring a non-optical characteristic of the surface of the specimen.

1333. The method of claim 1324, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1334. The method of claim 1324, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

1335. The method of claim 1324, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is

selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1336. The method of claim 1335, wherein the stage and the measurement device are
5 coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

1337. The method of claim 1324, wherein the stage and the measurement device are
10 coupled to a process tool.

1338. The method of claim 1324, wherein the stage and the measurement device are
coupled to a process tool, and wherein the process tool is selected from the group
consisting of a lithography tool, an etch tool, and a deposition tool.

1339. A system configured to determine at least two properties of a specimen during
15 use, comprising:

a stage configured to support the specimen during use;

20 a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the
specimen during use; and

25 a detection system coupled to the illumination system and configured to
detect energy propagating from the surface of the specimen during use,
wherein the measurement device is configured to generate one or more
output signals responsive to the detected energy;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

5 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, and
10 wherein the second property comprises a thin film characteristic of the specimen.

1340. The system of claim 1339, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe
15 microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

20 1341. The system of claim 1339, wherein the measurement device comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device,
25 a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1342. The system of claim 1339, wherein the measurement device comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

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1343. The system of claim 1339, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

10 1344. The system of claim 1339, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1345. The system of claim 1339, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the system is
15 coupled to an atomic layer deposition tool.

1346. The system of claim 1339, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially processed one or more output signals during use, and wherein the third property is
20 selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1347. The system of claim 1339, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a
25 cleaning tool, and an etch tool.

1348. The system of claim 1339, wherein the remote controller computer is coupled to a process tool.

1349. The system of claim 1339, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from a group consisting of a lithography tool, an etch tool, and a deposition tool.

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1350. The system of claim 1339, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedback control technique during use.

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1351. The system of claim 1339, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined first or second property using a feedforward control technique during use.

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1352. The system of claim 1339, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

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1353. The system of claim 1352, wherein the remote controller computer is further configured to determine a relationship between the determined properties and the monitored parameters during use.

25

1354. The system of claim 1353, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

1355. The system of claim 1339, wherein the system is coupled to a process tool,
wherein the illumination system is further configured to direct energy toward the surface
of the specimen during a process step, wherein the detection system is further configured
to detect energy propagating from the surface of the specimen during the process step,
5 and wherein the remote controller computer is further configured to determine the first
and second properties of the specimen during the process step.

1356. The system of claim 1355, wherein the remote controller computer is further
configured to obtain a signature characterizing the process step during use, and wherein
10 the signature comprises at least one singularity representative of an end of the process
step.

1357. The system of claim 1355, wherein the remote controller computer is further
configured to alter a parameter of one or more instruments coupled to the process tool in
15 response to the determined first or second property using an in situ control technique
during use.

1358. The system of claim 1339, wherein a process tool comprises a first process
chamber and a second process chamber, and wherein the stage is further configured to
20 move the specimen from the first process chamber to the second process chamber during
use.

1359. The system of claim 1358, wherein the illumination system is further configured
to direct energy toward the surface of the specimen during said moving, wherein the
25 detection system is further configured to detect energy propagating from the surface of
the specimen during said moving, and wherein the remote controller computer is further
configured to determine the first and second properties of the specimen during said
moving.

1360. The system of claim 1339, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

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1361. The system of claim 1339, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

10 1362. The system of claim 1361, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

15 1363. The system of claim 1339, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to the determined first or second property of the specimen during use.

20 1364. The system of claim 1339, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedback control technique during use.

25 1365. The system of claim 1339, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined first or second property using a feedforward control technique during use.

1366. The system of claim 1339, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

- 5 1367. The system of claim 1366, wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

1368. The system of claim 1366, wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database
10 during use.

1369. The system of claim 1366, wherein the database further comprises first and second properties of a plurality of specimens.

- 15 1370. The system of claim 1369, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

1371. The system of claim 1370, wherein the remote controller computer is further coupled to the plurality of measurement devices.
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1372. The system of claim 1371, wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

- 25 1373. The system of claim 1371, wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

1374. The system of claim 1339, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

5 1375. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

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directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

15

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a critical dimension of the specimen, and wherein the second property comprises a thin film characteristic of the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

5 1376. The method of claim 1375, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam
10 spectrophotometer, a beam profile ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1377. The method of claim 1375, wherein the measurement device comprises at least a first measurement device and a second measurement device, and wherein the first and
15 second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile
20 ellipsometer, a photo-acoustic device, and a grazing X-ray reflectometer.

1378. The method of claim 1375, wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

25 1379. The method of claim 1375, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

1380. The method of claim 1375, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1381. The method of claim 1375, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

1382. The method of claim 1375, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1383. The method of claim 1382, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

1384. The method of claim 1375, wherein the remote controller computer is coupled to a process tool.

1385. The method of claim 1375, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

1386. The method of claim 1375, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to the determined first or second property of the specimen using a feedback control technique.

1387. The method of claim 1375, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to the determined first or second property of the specimen using a feedforward control technique.

1388. The method of claim 1375, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

1389. The method of claim 1388, further comprising determining a relationship between the determined properties and at least one of the monitored parameters using the remote controller computer.

1390. The method of claim 1375, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

1391. The method of claim 1375, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, further comprising performing said directing and said detecting during a process step.

1392. The method of claim 1391, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

1393. The method of claim 1391, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to the determined first or second property using an in situ control technique.

5 1394. The method of claim 1375, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage;

10 performing said directing and said detecting during said moving the specimen.

1395. The method of claim 1375, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

15

1396. The method of claim 1375, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

20 1397. The method of claim 1396, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

25 1398. The method of claim 1375, wherein the remote controller computer is coupled to the measurement device.

1399. The method of claim 1398, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to the determined first or second property of the specimen.

5 1400. The method of claim 1398, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to the determined first or second property using a feedback control technique.

10 1401. The method of claim 1398, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to the determined first or second property using a feedforward control technique.

15 1402. The method of claim 1375, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen.

1403. The method of claim 1402, further comprising calibrating the measurement device using the database and the remote controller computer.

20 1404. The method of claim 1402, further comprising monitoring output signals generating by the measurement device using the database and the remote controller computer.

25 1405. The method of claim 1402, wherein the database further comprises first and second properties of a plurality of specimens.

1406. The method of claim 1405, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

1407. The method of claim 1406, further comprising calibrating the plurality of measurement devices using the database and the remote controller computer.

- 5 1408. The method of claim 1406, further comprising monitoring output signals generated by the plurality of measurement devices using the database and the remote controller computer.

- 10 1409. The method of claim 1375, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

- 15 1410. The method of claim 1409, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to the determined first or second property of the specimen.

- 20 1411. The method of claim 1410, wherein each of the plurality of measurement devices is coupled to one of a plurality of process tools.

- 25 1412. The method of claim 1411, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to the determined first or second property of the specimen.

1413. A system configured to determine at least three properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

5

an illumination system configured to direct energy toward a surface of the specimen during use; and

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a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

15

a processor coupled to the measurement device and configured to determine a first property, a second property, and a third property of the specimen from the one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

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1414. The system of claim 1413, wherein the stage is further configured to move laterally during use.

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1415. The system of claim 1413, wherein the stage is further configured to move rotatably during use.

1416. The system of claim 1413, wherein the stage is further configured to move laterally and rotatably during use.

1417. The system of claim 1413, wherein the illumination system comprises a single energy source.

5 1418. The system of claim 1413, wherein the illumination system comprises more than one energy source.

1419. The system of claim 1413, wherein the detection system comprises a single energy sensitive device.

10

1420. The system of claim 1413, wherein the detection system comprises more than one energy sensitive devices.

1421. The system of claim 1413, wherein the measurement device further comprises a
15 non-imaging scatterometer.

1422. The system of claim 1413, wherein the measurement device further comprises a scatterometer.

20 1423. The system of claim 1413, wherein the measurement device further comprises a spectroscopic scatterometer.

1424. The system of claim 1413, wherein the measurement device further comprises a reflectometer.

25

1425. The system of claim 1413, wherein the measurement device further comprises a spectroscopic reflectometer.

1426. The system of claim 1413, wherein the measurement device further comprises a coherence probe microscope.

5 1427. The system of claim 1413, wherein the measurement device further comprises a bright field imaging device.

1428. The system of claim 1413, wherein the measurement device further comprises a dark field imaging device.

10 1429. The system of claim 1413, wherein the measurement device further comprises a bright field and dark field imaging device.

1430. The system of claim 1413, wherein the measurement device further comprises a non-imaging bright field device.

15 1431. The system of claim 1413, wherein the measurement device further comprises a non-imaging dark field device.

20 1432. The system of claim 1413, wherein the measurement device further comprises a non-imaging bright field and dark field device.

1433. The system of claim 1413, wherein the measurement device further comprises an ellipsometer.

25 1434. The system of claim 1413, wherein the measurement device further comprises a spectroscopic ellipsometer.

1435. The system of claim 1413, wherein the measurement device further comprises a dual beam spectrophotometer.

1436. The system of claim 1413, wherein the measurement device further comprises a
5 beam profile ellipsometer.

1437. The system of claim 1413, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging
10 scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam
15 spectrophotometer, and a beam profile ellipsometer.

1438. The system of claim 1413, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
20 measurement device.

1439. The system of claim 1413, wherein the defects comprise micro defects and macro defects.

25 1440. The system of claim 1413, wherein the defects comprises micro defects or macro defects.

1441. The system of claim 1413, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

1442. The system of claim 1413, wherein the defects comprise macro defects on a back
5 side of the specimen, and wherein the macro defects comprise copper contamination.

1443. The system of claim 1413, wherein the processor is further configured to determine a fourth property of the specimen from the one or more output signals during use, and wherein the fourth property is selected from the group consisting of a roughness
10 of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1444. The system of claim 1443, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a
15 cleaning tool, and an etch tool.

1445. The system of claim 1413, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom
20 surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

1446. The system of claim 1445, wherein the defects comprise macro defects.

25 1447. The system of claim 1413, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

1448. The system of claim 1413, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1449. The system of claim 1413, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the system is coupled to an atomic layer deposition tool.

1450. The system of claim 1413, wherein the system is further configured to determine at least three properties of the specimen substantially simultaneously during use.

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1451. The system of claim 1413, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that the first, second, and third properties of the specimen at the multiple locations can be determined substantially simultaneously.

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1452. The system of claim 1413, wherein the system is coupled to a process tool.

1453. The system of claim 1413, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

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1454. The system of claim 1413, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

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1455. The system of claim 1413, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

1456. The system of claim 1413, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

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1457. The system of claim 1413, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

10 1458. The system of claim 1413, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

1459. The system of claim 1413, wherein the system is coupled to a process tool, and
15 wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

1460. The system of claim 1413, wherein the system is coupled to a process tool,
20 wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

1461. The system of claim 1413, wherein the system is coupled to a process tool, and
25 wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

1462. The system of claim 1413, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

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1463. The system of claim 1413, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

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1464. The system of claim 1413, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

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1465. The system of claim 1413, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

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1466. The system of claim 1413, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

25

1467. The system of claim 1466, wherein the processor is further configured to determine at least the three properties of the specimen during the process step.

1468. The system of claim 1467, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

5 1469. The system of claim 1467, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the determined properties using an in situ control technique during use.

10 1470. The system of claim 1413, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

15 1471. The system of claim 1470, wherein the system is further configured to determine at least the three properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

20 1472. The system of claim 1413, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

25 1473. The system of claim 1413, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

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1474. The system of claim 1473, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

- 5 1475. The system of claim 1413, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

- 10 1476. The system of claim 1413, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

- 15 1477. The system of claim 1413, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

- 20 1478. The system of claim 1413, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first, second, and third properties of the specimen.

1479. The system of claim 1478, wherein the processor is further configured to calibrate the measurement device using the database during use.

- 25 1480. The system of claim 1478, wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

1481. The system of claim 1478, wherein the database further comprises first, second, and third properties of a plurality of specimens.

5 1482. The system of claim 1481, wherein the first, second, and third properties of the plurality of specimens are determined using the measurement device.

1483. The system of claim 1481, wherein the first, second, and third properties of the plurality of specimens are determined using a plurality of measurement devices.

10 1484. The system of claim 1483, wherein the processor is further coupled to the plurality of measurement devices.

1485. The system of claim 1484, wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

15 1486. The system of claim 1485, wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

20 1487. The system of claim 1413, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

25 1488. The system of claim 1413, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is

further configured to calibrate the system and at least the one additional system during use.

1489. The system of claim 1413, wherein the system is further configured to determine
5 at least the two properties of the specimen at more than one position on the specimen,
wherein the specimen comprises a wafer, and wherein the processor is configured to alter
at least one parameter of one or more instruments coupled to a process tool in response to
at least one of the determined properties of the specimen at the more than one position on
the specimen to reduce within wafer variation of at least one of the determined properties.

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1490. The system of claim 1413, wherein the processor is further coupled to a process
tool.

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1491. The system of claim 1490, wherein the processor is further configured to alter a
parameter of one or more instruments coupled to the process tool in response to at least
one of the determined properties using a feedback control technique during use.

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1492. The system of claim 1490, wherein the processor is further configured to alter a
parameter of one or more instruments coupled to the process tool in response to at least
one of the determined properties using a feedforward control technique during use.

1493. The system of claim 1490, wherein the processor is further configured to monitor
a parameter of one or more instruments coupled to the process tool during use.

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1494. The system of claim 1493, wherein the processor is further configured to
determine a relationship between at least one of the determined properties and at least one
of the monitored parameters during use.

1495. The system of claim 1494, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

5 1496. The system of claim 1413, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

10 1497. The system of claim 1413, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

15 1498. The system of claim 1497, wherein the local processor is further configured to determine the first, second, and third properties of the specimen during use.

1499. The system of claim 1497, wherein the remote controller computer is further configured to determine the first, second, and properties of the specimen during use.

20 1500. A method for determining at least three properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

25

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

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processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a critical dimension of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property

10 comprises a thin film characteristic of the specimen.

1501. The method of claim 1500, further comprising laterally moving the stage during said directing energy and said detecting energy.

15 1502. The method of claim 1500, further comprising rotatably moving the stage during said directing energy and said detecting energy.

1503. The method of claim 1500, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

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1504. The method of claim 1500, wherein the illumination system comprises a single energy source.

1505. The method of claim 1500, wherein the illumination system comprises more than

25 one energy source.

1506. The method of claim 1500, wherein the detection system comprises a single energy sensitive device.

1507. The method of claim 1500, wherein the detection system comprises more than one energy sensitive devices.

5 1508. The method of claim 1500, wherein the measurement device further comprises a non-imaging scatterometer.

1509. The method of claim 1500, wherein the measurement device further comprises a scatterometer.

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1510. The method of claim 1500, wherein the measurement device further comprises a spectroscopic scatterometer.

1511. The method of claim 1500, wherein the measurement device further comprises a reflectometer.

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1512. The method of claim 1500, wherein the measurement device further comprises a spectroscopic reflectometer.

20 1513. The method of claim 1500, wherein the measurement device further comprises a coherence probe microscope.

1514. The method of claim 1500, wherein the measurement device further comprises a bright field imaging device.

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1515. The method of claim 1500, wherein the measurement device further comprises a dark field imaging device.

1516. The method of claim 1500, wherein the measurement device further comprises a bright field and dark field imaging device.

5 1517. The method of claim 1500, wherein the measurement device further comprises a non-imaging bright field device.

1518. The method of claim 1500, wherein the measurement device further comprises a non-imaging dark field device.

10 1519. The method of claim 1500, wherein the measurement device further comprises a non-imaging bright field and dark field device.

1520. The method of claim 1500, wherein the measurement device further comprises an ellipsometer.

15 1521. The method of claim 1500, wherein the measurement device further comprises a spectroscopic ellipsometer.

20 1522. The method of claim 1500, wherein the measurement device further comprises a dual beam spectrophotometer.

1523. The method of claim 1500, wherein the measurement device further comprises a beam profile ellipsometer.

25 1524. The method of claim 1500, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a

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spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam

5 spectrophotometer, and a beam profile ellipsometer.

1525. The method of claim 1500, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
10 measurement device.

1526. The method of claim 1500, wherein the defects comprise micro defects and macro defects.

15 1527. The method of claim 1500, wherein the defects comprises micro defects or macro defects.

1528. The method of claim 1500, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.
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1529. The method of claim 1500, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

1530. The method of claim 1500, further comprising processing the one or more output
25 signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1531. The method of claim 1530, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 1532. The method of claim 1500, further comprising:

directing energy toward a bottom surface of the specimen; and

10 detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

1533. The method of claim 1532, wherein the defects comprise macro defects.

15 1534. The method of claim 1500, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

20 1535. The method of claim 1500, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1536. The method of claim 1500, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

25 1537. The method of claim 1500, wherein processing the detected energy to determine the first, second, and third properties of the specimen comprises substantially simultaneously determining the first, second, and third properties of the specimen.

1538. The method of claim 1500, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that the first, second, and third properties of the specimen at the multiple locations can be determined substantially simultaneously.

1539. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool.

1540. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

1541. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

1542. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

1543. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

1544. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

- 5 1545. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

- 10 1546. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

- 15 1547. The method of claim 1500, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

- 20 1548. The method of claim 1500, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

- 25 1549. The method of claim 1500, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

1550. The method of claim 1500, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

- 5 1551. The method of claim 1500, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

- 10 1552. The method of claim 1500, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

- 15 1553. The method of claim 1552, further comprising performing said directing and said detecting during the process step.

- 20 1554. The method of claim 1553, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

1555. The method of claim 1553, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

- 25 1556. The method of claim 1500, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

1557. The method of claim 1556, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

5 1558. The method of claim 1500, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

10 1559. The method of claim 1500, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

15 1560. The method of claim 1559, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

1561. The method of claim 1500, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

20 1562. The method of claim 1500, further comprising altering a parameter of an instrument coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

25 1563. The method of claim 1500, further comprising altering a parameter of an instrument coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

1564. The method of claim 1500, further comprising generating a database, wherein the database comprises the determined first, second, and third properties of the specimen.

5 1565. The method of claim 1564, further comprising calibrating the measurement device using the database.

1566. The method of claim 1564, further comprising monitoring output signals of the measurement device using the database.

10 1567. The method of claim 1564, wherein the database further comprises first, second, and third properties of a plurality of specimens.

1568. The method of claim 1567, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices.

15 1569. The method of claim 1568, further comprising calibrating the plurality of measurement devices using the database.

20 1570. The method of claim 1568, further comprising monitoring output signals of the plurality of measurement devices using the database.

25 1571. The method of claim 1500, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

1572. The method of claim 1500, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further

comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

- 5 1573. The method of claim 1500, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the
10 specimen to reduce within wafer variation of at least one of the determined properties.

1574. The method of claim 1500, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

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1575. The method of claim 1500, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

- 20 1576. The method of claim 1500, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

1577. The method of claim 1576, further comprising determining a relationship between the determined properties and at least one of the monitored parameters.

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1578. The method of claim 1577, further comprising altering a parameter of at least one of the instruments in response to the relationship.

1579. The method of claim 1500, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to the at least one of the determined properties of the specimen.

- 5 1580. The method of claim 1500, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

1581. The method of claim 1580, wherein at least partially processing the one or more output signals comprises determining the first, second, and third properties of the specimen.

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1582. The method of claim 1580, wherein further processing the partially processed one or more output signals comprises determining the first, second, and third properties of the specimen.

- 25 1583. A computer-implemented method for controlling a system configured to determine at least three properties of a specimen during use, wherein the system comprises a measurement device, comprising:

controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

5 controlling the illumination system to direct energy toward a surface of the specimen;

 controlling the detection system to detect energy propagating from the surface of the specimen; and

10 generating one or more output signals in response to the detected energy; and

 processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a critical dimension of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

20 1584. The method of claim 1583, further comprising controlling the stage, wherein the stage is configured to support the specimen.

1585. The method of claim 1583, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

25 1586. The method of claim 1583, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

1587. The method of claim 1583, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

5 1588. The method of claim 1583, wherein the illumination system comprises a single energy source.

1589. The method of claim 1583, wherein the illumination system comprises more than one energy source.

10 1590. The method of claim 1583, wherein the detection system comprises a single energy sensitive device.

1591. The method of claim 1583, wherein the detection system comprises more than one energy sensitive devices.

15 1592. The method of claim 1583, wherein the measurement device further comprises a non-imaging scatterometer.

20 1593. The method of claim 1583, wherein the measurement device further comprises a scatterometer.

1594. The method of claim 1583, wherein the measurement device further comprises a spectroscopic scatterometer.

25 1595. The method of claim 1583, wherein the measurement device further comprises a reflectometer.

1596. The method of claim 1583, wherein the measurement device further comprises a spectroscopic reflectometer.

5 1597. The method of claim 1583, wherein the measurement device further comprises a coherence probe microscope.

1598. The method of claim 1583, wherein the measurement device further comprises a bright field imaging device.

10 1599. The method of claim 1583, wherein the measurement device further comprises a dark field imaging device.

1600. The method of claim 1583, wherein the measurement device further comprises a bright field and dark field imaging device.

15 1601. The method of claim 1583, wherein the measurement device further comprises a non-imaging bright field device.

20 1602. The method of claim 1583, wherein the measurement device further comprises a non-imaging dark field device.

1603. The method of claim 1583, wherein the measurement device further comprises a non-imaging bright field and dark field device.

25 1604. The method of claim 1583, wherein the measurement device further comprises an ellipsometer.

1605. The method of claim 1583, wherein the measurement device further comprises a spectroscopic ellipsometer.

1606. The method of claim 1583, wherein the measurement device further comprises a
5 dual beam spectrophotometer.

1607. The method of claim 1583, wherein the measurement device further comprises a beam profile ellipsometer.

10 1608. The method of claim 1583, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device,
15 a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

20 1609. The method of claim 1583, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

25 1610. The method of claim 1583, wherein the defects comprise micro defects and macro defects.

1611. The method of claim 1583, wherein the defects comprises micro defects or macro defects.

1612. The method of claim 1583, wherein the thin film characteristic comprises a
5 thickness of a copper film, and wherein the defects comprise voids in the copper film.

1613. The method of claim 1583, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

10 1614. The method of claim 1583, further comprising processing the one or more output signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15 1615. The method of claim 1614, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20 1616. The method of claim 1583, further comprising:

controlling the illumination system to direct energy toward a bottom surface of the specimen; and

25 controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

1617. The method of claim 1616, wherein the defects comprise macro defects.

1618. The method of claim 1583, wherein the measurement device further comprises non-optical components, and wherein controlling the detection system comprises controlling the detection system to measure a non-optical characteristic of the surface of the specimen.

1619. The method of claim 1583, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1620. The method of claim 1583, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the system is coupled to an atomic layer deposition tool.

1621. The method of claim 1583, wherein processing the one or more output signals to determine the first, second, and third properties of the specimen comprises substantially simultaneously determining the first, second, and third properties of the specimen.

1622. The method of claim 1583, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that the first, second, and third properties of the specimen at the multiple locations can be determined substantially simultaneously.

1623. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool.

1624. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

5 1625. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

10 1626. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

15 1627. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

20 1628. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

25 1629. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

1630. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured

to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

5 1631. The method of claim 1583, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

10 1632. The method of claim 1583, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

15 1633. The method of claim 1583, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

20 1634. The method of claim 1583, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

1635. The method of claim 1583, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

25 1636. The method of claim 1583, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

1637. The method of claim 1636, further comprising controlling the illumination system and controlling the detection system during the process step.

5 1638. The method of claim 1637, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

10 1639. The method of claim 1637, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

15 1640. The method of claim 1583, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

1641. The method of claim 1640, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

20 1642. The method of claim 1583, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

25 1643. The method of claim 1583, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

1644. The method of claim 1643, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 5 1645. The method of claim 1583, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

- 10 1646. The method of claim 1583, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

- 15 1647. The method of claim 1583, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

1648. The method of claim 1583, further comprising generating a database, wherein the database comprises the determined first, second, and third properties of the specimen.

- 20 1649. The method of claim 1648, further comprising calibrating the measurement device using the database.

- 25 1650. The method of claim 1648, further comprising monitoring output signals of the measurement device using the database.

1651. The method of claim 1648, wherein the database further comprises first, second, and third properties of a plurality of specimens.

1652. The method of claim 1648, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices.
1653. The method of claim 1652, further comprising calibrating the plurality of measurement devices using the database.
1654. The method of claim 1652, further comprising monitoring output signals of the plurality of measurement devices using the database.
1655. The method of claim 1583, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.
1656. The method of claim 1583, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.
1657. The method of claim 1583, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

1658. The method of claim 1583, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

- 5 1659. The method of claim 1583, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

- 10 1660. The method of claim 1583, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

1661. The method of claim 1660, further comprising determining a relationship between the determined properties and at least one of the monitored parameters.

- 15 1662. The method of claim 1661, further comprising altering a parameter of at least one of the instruments in response to the relationship.

- 20 1663. The method of claim 1583, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

1664. The method of claim 1583, wherein processing the one or more output signals comprises:

- 25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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5 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

10 further processing the partially processed one or more output signals using the remote controller computer.

1665. The method of claim 1664, wherein at least partially processing the one or more output signals comprises determining the first, second, and third properties of the specimen.

10 1666. The method of claim 1664, wherein further processing the partially processed one or more output signals comprises determining the first, second, and third properties of the specimen.

15 1667. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

20 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

25 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a critical dimension of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

1668. The device of claim 1667, wherein the illumination system comprises a single energy source.

1669. The device of claim 1667, wherein the illumination system comprises more than one energy source.

1670. The device of claim 1667, wherein the detection system comprises a single energy sensitive device.

1671. The device of claim 1667, wherein the detection system comprises more than one energy sensitive devices.

1672. The device of claim 1667, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

1673. The device of claim 1667, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

1674. The device of claim 1667, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1675. The device of claim 1667, wherein the defects comprise micro defects and macro defects.

1676. The device of claim 1667, wherein the defects comprises micro defects or macro defects.

1677. The device of claim 1667, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

1678. The device of claim 1667, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

1679. The device of claim 1667, further comprising processing the one or more output signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

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1680. The device of claim 1679, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

10 1681. The device of claim 1667, further comprising:

directing energy toward a bottom surface of the specimen; and

15 detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

1682. The device of claim 1681, wherein the defects comprise macro defects.

20 1683. The device of claim 1667, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

25 1684. The device of claim 1667, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1685. The device of claim 1667, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

5 1686. The device of claim 1667, wherein the stage and the measurement device are coupled to a process tool.

1687. The device of claim 1667, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group
10 consisting of a lithography tool, an etch tool, and a deposition tool.

1688. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;
15

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

20 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

25 generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property

comprises a critical dimension of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the portion of the specimen.

5 1689. The method of claim 1688, wherein the illumination system comprises a single energy source.

1690. The method of claim 1688, wherein the illumination system comprises more than one energy source.

10

1691. The method of claim 1688, wherein the detection system comprises a single energy sensitive device.

15

1692. The method of claim 1688, wherein the detection system comprises more than one energy sensitive devices.

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1693. The method of claim 1688, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

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1694. The method of claim 1688, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a

spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam

5 spectrophotometer, and a beam profile ellipsometer.

1695. The method of claim 1688, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
10 measurement device.

1696. The method of claim 1688, wherein the defects comprise micro defects and macro defects.

15 1697. The method of claim 1688, wherein the defects comprises micro defects or macro defects.

1698. The method of claim 1688, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

20 1699. The method of claim 1688, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

1700. The method of claim 1688, further comprising processing the one or more output
25 signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1701. The method of claim 1700, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 1702. The method of claim 1688, further comprising:

directing energy toward a bottom surface of the specimen; and

10 detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

1703. The method of claim 1702, wherein the defects comprise macro defects.

15 1704. The method of claim 1688, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

20 1705. The method of claim 1688, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1706. The method of claim 1688, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

25

1707. The method of claim 1688, wherein the stage and the measurement device are coupled to a process tool.

1708. The method of claim 1688, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

- 5 1709. A system configured to determine at least three properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

- 10 a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

- 15 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

- 20 a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

- 25 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property, a second property, and a third property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a critical dimension of the specimen, wherein the second property comprises a presence of

defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

5 1710. The system of claim 1709, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

15 1711. The system of claim 1709, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

25 1712. The system of claim 1709, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1713. The system of claim 1709, wherein the defects comprise micro defects and macro defects.

1714. The system of claim 1709, wherein the defects comprises micro defects or macro defects.

5 1715. The system of claim 1709, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

1716. The system of claim 1709, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

10

1717. The system of claim 1709, wherein the remote controller computer is further configured to determine a fourth property of the specimen from the at least partially processed one or more output signals during use, and wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15

1718. The system of claim 1717, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20

1719. The system of claim 1709, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

25

1720. The system of claim 1719, wherein the defects comprise macro defects.

1721. The system of claim 1709, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

5 1722. The system of claim 1709, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

1723. The system of claim 1709, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the system is
10 coupled to an atomic layer deposition tool.

1724. The system of claim 1709, wherein the remote controller computer is coupled to a process tool.

15 1725. The system of claim 1709, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from a group consisting of a lithography tool, an etch tool, and a deposition tool.

1726. The system of claim 1709, wherein the remote controller computer is coupled to a
20 process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

1727. The system of claim 1709, wherein the remote controller computer is coupled to a
25 process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

1728. The system of claim 1709, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

- 5 1729. The system of claim 1728, wherein the remote controller computer is further configured to determine a relationship between the determined properties and at least one of the monitored parameters during use.

- 10 1730. The system of claim 1729, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

- 15 1731. The system of claim 1709, wherein the remote controller computer is coupled to a process tool, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first, second, and third properties of the specimen during the process step.

- 20 1732. The system of claim 1731, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

- 25 1733. The system of claim 1731, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

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5 1734. The system of claim 1709, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

10 1735. The system of claim 1734, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first, second, and third properties of the specimen during said moving.

15 1736. The system of claim 1709, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

20 1737. The system of claim 1709, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

25 1738. The system of claim 1737, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

1739. The system of claim 1709, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

1740. The system of claim 1709, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control
5 technique during use.

1741. The system of claim 1709, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control
10 technique during use.

1742. The system of claim 1709, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first, second, and third properties of the specimen.
15

1743. The system of claim 1742, wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

1744. The system of claim 1742, wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.
20

1745. The system of claim 1742, wherein the database further comprises first, second, and third properties of a plurality of specimens.
25

1746. The system of claim 1745, wherein the first, second, and third properties of the plurality of specimens are determined using a plurality of measurement devices.

1747. The system of claim 1746, wherein the remote controller computer is further coupled to the plurality of measurement devices.

1748. The system of claim 1747, wherein the remote controller computer is further
5 configured to calibrate the plurality of measurement devices using the database during use.

1749. The system of claim 1747, wherein the remote controller computer is further
10 configured to monitor output signals generated by the plurality of measurement devices using the database during use.

1750. The system of claim 1709, wherein the remote controller computer is further
15 coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to one of a plurality of process tools.

1751. A method for determining at least three properties of a specimen, comprising:

20 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

25 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a critical dimension of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen, comprising:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

1752. The method of claim 1751, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

1753. The method of claim 1751, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a

5 spectroscopic reflectometer, a coherence probe microscope, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, an ellipsometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer.

10 1754. The method of claim 1751, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1755. The method of claim 1751, wherein the defects comprise micro defects and macro defects.

15 1756. The method of claim 1751, wherein the defects comprises micro defects or macro defects.

20 1757. The method of claim 1751, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

1758. The method of claim 1751, wherein the defects comprise macro defects on a back side of the specimen, and wherein the macro defects comprise copper contamination.

25 1759. The method of claim 1751, further comprising processing the one or more output signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1760. The method of claim 1759, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 1761. The method of claim 1751, further comprising:

directing energy toward a bottom surface of the specimen; and

10 detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

1762. The method of claim 1761, wherein the defects comprise macro defects.

15 1763. The method of claim 1751, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprising measuring a non-optical characteristic of the specimen.

20 1764. The method of claim 1751, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer.

25 1765. The method of claim 1751, wherein the measurement device further comprises at least an eddy current device and a spectroscopic ellipsometer, and wherein the measurement device is further coupled to an atomic layer deposition tool.

1766. The method of claim 1751, wherein the remote controller computer is coupled to a process tool.

1767. The method of claim 1751, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, and a deposition tool.

- 5 1768. The method of claim 1751, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedback control technique.

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1769. The method of claim 1751, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

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1770. The method of claim 1751, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

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1771. The method of claim 1770, further comprising determining a relationship between the determined properties and at least one of the monitored parameters using the remote controller computer.

- 25 1772. The method of claim 1771, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

1773. The method of claim 1751, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, the method further comprising performing said directing and said detecting during a process step.

- 5 1774. The method of claim 1773, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

- 10 1775. The method of claim 1773, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

1776. The method of claim 1751, further comprising:

- 15 moving the specimen from a first process chamber to a second process chamber using the stage; and

performing said directing and said detecting during said moving the specimen.

- 20 1777. The method of claim 1751, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

- 25 1778. The method of claim 1751, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

1779. The method of claim 1778, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 5 1780. The method of claim 1751, wherein the remote controller computer is coupled to the measurement device.

1781. The method of claim 1780, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to at least one
10 of the determined properties of the specimen.

1782. The method of claim 1780, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.
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1783. The method of claim 1780, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.
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1784. The method of claim 1751, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first, second, and third properties of the specimen.

- 25 1785. The method of claim 1784, further comprising calibrating the measurement device using the database and the remote controller computer.

1786. The method of claim 1784, further comprising monitoring output signals of the measurement device using the database and the remote controller computer.

5 1787. The method of claim 1784, wherein the database further comprises first, second, and third properties of a plurality of specimens.

1788. The method of claim 1787, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices.

10 1789. The method of claim 1788, further comprising calibrating the plurality of measurement devices using the database and the remote controller computer.

1790. The method of claim 1788, further comprising monitoring output signals of the plurality of measurement devices using the database and the remote controller computer.

15 1791. The method of claim 1751, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

20 1792. The method of claim 1751, further comprising altering a parameter of one or more instruments coupled to at least one of a plurality of process tools using the remote controller computer in response to at least one of the determined properties of the specimen.

25 1793. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

5 an illumination system configured to direct energy toward a surface of the specimen during use; and

 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use,
10 wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

 a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output
15 signals during use, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen.

1794. The system of claim 1793, wherein the stage is further configured to move
20 laterally during use.

1795. The system of claim 1793, wherein the stage is further configured to move rotatably during use.

25 1796. The system of claim 1793, wherein the stage is further configured to move laterally and rotatably during use.

1797. The system of claim 1793, wherein the illumination system comprises a single energy source.

5 1798. The system of claim 1793, wherein the illumination system comprises more than one energy source.

1799. The system of claim 1793, wherein the detection system comprises a single energy sensitive device.

10 1800. The system of claim 1793, wherein the detection system comprises more than one energy sensitive devices.

15 1801 The system of claim 1793, wherein the measurement device further comprises a non-imaging scatterometer.

1802. The system of claim 1793, wherein the measurement device further comprises a scatterometer.

20 1803. The system of claim 1793, wherein the measurement device further comprises a spectroscopic scatterometer.

1804. The system of claim 1793, wherein the measurement device further comprises a reflectometer.

25 1805. The system of claim 1793, wherein the measurement device further comprises a spectroscopic reflectometer.

1806. The system of claim 1793, wherein the measurement device further comprises an ellipsometer.

5 1807. The system of claim 1793, wherein the measurement device further comprises a spectroscopic ellipsometer.

1808. The system of claim 1793, wherein the measurement device further comprises a bright field imaging device.

10 1809. The system of claim 1793, wherein the measurement device further comprises a dark field imaging device.

1810. The system of claim 1793, wherein the measurement device further comprises a bright field and dark field imaging device.

15 1811. The system of claim 1793, wherein the measurement device further comprises a non-imaging bright field device.

20 1812. The system of claim 1793, wherein the measurement device further comprises a non-imaging dark field device.

1813. The system of claim 1793, wherein the measurement device further comprises a non-imaging bright field and dark field device.

25 1814. The system of claim 1793, wherein the measurement device further comprises a double dark field device.

1815. The system of claim 1793, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

1816. The system of claim 1793, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1817. The system of claim 1793, wherein the processor is further configured to determine a third property from the one or more output signals during use, wherein the third property comprises a thickness of a copper film, and wherein the macro defects or the micro defects comprise voids in the copper film.

1818. The system of claim 1793, wherein the macro defects comprise copper contamination on a back side of the specimen.

1819. The system of claim 1793, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of

the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1820. The system of claim 1819, wherein the system is coupled to a process tool
5 selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

1821. The system of claim 1793, wherein the illumination system is further configured
to direct energy toward a bottom surface of the specimen during use, wherein the
10 detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

1822. The system of claim 1793, wherein the system is further configured to determine
15 at least two properties of the specimen substantially simultaneously during use.

1823. The system of claim 1793, wherein the illumination system is further configured
to direct energy to multiple locations on the surface of the specimen substantially
simultaneously, and wherein the detection system is further configured to detect energy
20 propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

1824. The system of claim 1793, wherein the system is coupled to a process tool.
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1825. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

1826. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

1827. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

1828. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

1829. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

1830. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

1831. The system of claim 1793, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

1832. The system of claim 1793, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

1833. The system of claim 1793, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

1834. The system of claim 1793, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

1835. The system of claim 1793, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

1836. The system of claim 1793, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

1837. The system of claim 1793, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

1838. The system of claim 1793, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

5 1839. The system of claim 1838, wherein the processor is further configured to determine at least the first and second properties of the specimen during the process step.

1840. The system of claim 1839, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises
10 at least one singularity representative of an end of the process step.

1841. The system of claim 1839, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ
15 control technique during use.

1842. The system of claim 1793, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during
20 use.

1843. The system of claim 1842, wherein the system is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.
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1844. The system of claim 1793, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

1845. The system of claim 1793, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

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1846. The system of claim 1845, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

10 1847. The system of claim 1793, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

15 1848. The system of claim 1793, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

20 1849. The system of claim 1793, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

25 1850. The system of claim 1793, wherein the processor is further configured to generate a database during use, and wherein the database comprises the determined first and second properties of the specimen.

1851. The system of claim 1850, wherein the processor is further configured to calibrate the measurement device using the database during use.

1852. The system of claim 1850, wherein the processor is further configured to monitor the determined properties generated by measurement device using the database during use.

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1853. The system of claim 1850, wherein the database further comprises first and second properties of a plurality of specimens.

1854. The system of claim 1853, wherein the first and second properties of the plurality of specimens are determined using the measurement device.

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1855. The system of claim 1853, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

1856. The system of claim 1855, wherein the processor is further coupled to the plurality of measurement devices.

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1857. The system of claim 1856, wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

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1858. The system of claim 1856, wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

1859. The system of claim 1793, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

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1860. The system of claim 1793, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

1861. The system of claim 1793, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

1862. The system of claim 1793, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

1863. The system of claim 1793, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

1864. The system of claim 1793, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

1865. The system of claim 1864, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

- 5 1866. The system of claim 1864, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

1867. The system of claim 1793, wherein the processor is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices
10 is coupled to at least one of a plurality of process tools.

1868. The system of claim 1793, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

- 15 1869. The system of claim 1793, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured
20 to further process the at least partially processed one or more output signals during use.

1870. The system of claim 1869, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

- 25 1871. The system of claim 1869, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

1872. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen.

1873. The method of claim 1872, further comprising laterally moving the stage during said directing energy and said detecting energy.

1874. The method of claim 1872, further comprising rotatably moving the stage during said directing energy and said detecting energy.

1875. The method of claim 1872, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

1876. The method of claim 1872, wherein the illumination system comprises a single energy source.

5 1877. The method of claim 1872, wherein the illumination system comprises more than one energy source.

1878. The method of claim 1872, wherein the detection system comprises a single energy sensitive device.

10 1879. The method of claim 1872, wherein the detection system comprises more than one energy sensitive devices.

15 1880. The method of claim 1872, wherein detecting light comprises detecting dark field light propagating along a dark field path from the surface of the specimen.

1881. The method of claim 1872, wherein the measurement device further comprises a non-imaging scatterometer.

20 1882. The method of claim 1872, wherein the measurement device further comprises a scatterometer.

1883. The method of claim 1872, wherein the measurement device further comprises a spectroscopic scatterometer.

25 1884. The method of claim 1872, wherein the measurement device further comprises a reflectometer.

1885. The method of claim 1872, wherein the measurement device further comprises a spectroscopic reflectometer.

5 1886. The method of claim 1872, wherein the measurement device further comprises an ellipsometer.

1887. The method of claim 1872, wherein the measurement device further comprises a spectroscopic ellipsometer.

10 1888. The method of claim 1872, wherein the measurement device further comprises a bright field imaging device.

15 1889. The method of claim 1872, wherein the measurement device further comprises a dark field imaging device.

1890. The method of claim 1872, wherein the measurement device further comprises a bright field and dark field imaging device.

20 1891. The method of claim 1872, wherein the measurement device further comprises a non-imaging bright field device.

1892. The method of claim 1872, wherein the measurement device further comprises a non-imaging dark field device.

25 1893. The method of claim 1872, wherein the measurement device further comprises a non-imaging bright field and dark field device.

1894. The method of claim 1872, wherein the measurement device further comprises a double dark field device.

1895. The method of claim 1872, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

1896. The method of claim 1872, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

1897. The method of claim 1872, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

1898. The method of claim 1872, further comprising processing the one or more output signals to determine a thickness of a copper film, and wherein the macro defects or the micro defects comprise voids in the copper film.

5 1899. The method of claim 1872, wherein the macro defects comprise copper contamination on a back side of the specimen.

1900. The method of claim 1872, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is
10 selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1901. The method of claim 1900, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an
15 atomic layer deposition tool, a cleaning tool, and an etch tool.

1902. The method of claim 1872, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially
20 simultaneously determining the first and second properties of the specimen.

1903. The method of claim 1872, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple
25 locations substantially simultaneously.

1904. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool.

1905. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

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1906. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

10 1907. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

15 1908. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

20 1909. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

25 1910. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

1911. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

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1912. The method of claim 1872, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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1913. The method of claim 1872, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

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1914. The method of claim 1872, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

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1915. The method of claim 1872, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

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1916. The method of claim 1872, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

1917. The method of claim 1872, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process

chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

5 1918. The method of claim 1917, further comprising performing said directing and said detecting during the process step.

1919. The method of claim 1917, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

10 1920. The method of claim 1917, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

15 1921. The method of claim 1872, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

20 1922. The method of claim 1921, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

25 1923. The method of claim 1872, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

1924. The method of claim 1872, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

1925. The method of claim 1924, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

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1926. The method of claim 1872, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

10 1927. The method of claim 1872, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

15 1928. The method of claim 1872, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

1929. The method of claim 1872, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

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1930. The method of claim 1929, further comprising calibrating the measurement device using the database.

25 1931. The method of claim 1929, further comprising monitoring output signals generated by the measurement device using the database.

1932. The method of claim 1929, wherein the database further comprises first and second properties of a plurality of specimens.

1933. The method of claim 1932, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

5 1934. The method of claim 1933, further comprising calibrating the plurality of measurement devices using the database.

1935. The method of claim 1933, further comprising monitoring output signals generated by the plurality of measurement devices using the database.

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1936. The method of claim 1872, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

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1937. The method of claim 1872, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand
20 alone system.

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1938. The method of claim 1872, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one
25 parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

1939. The method of claim 1872, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

- 5 1940. The method of claim 1872, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

- 10 1941. The method of claim 1872, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

1942. The method of claim 1941, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

- 15 1943. The method of claim 1942, further comprising altering a parameter of at least one of the instruments in response to the relationship.

- 20 1944. The method of claim 1872, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

- 25 1945. The method of claim 1872, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

1946. The method of claim 1872, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 1947. The method of claim 1946, wherein at least partially processing the one or more
output signals comprises determining the first and second properties of the specimen.

15 1948. The method of claim 1946, wherein further processing the partially processed one
or more output signals comprises determining the first and second properties of the
specimen.

20 1949. A computer-implemented method for controlling a system configured to
determine at least two properties of a specimen during use, wherein the system comprises
a measurement device, comprising:

controlling the measurement device, wherein the measurement device comprises
an illumination system and a detection system, and wherein the measurement
device is coupled to a stage, comprising:

25 controlling the illumination system to direct energy toward a surface of the
specimen;

controlling the detection system to detect energy propagating from the surface of the specimen; and

generating one or more output signals responsive to the detected energy;
and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen.

1950. The method of claim 1949, further comprising controlling the stage, wherein the stage is configured to support the specimen.

1951. The method of claim 1949, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

1952. The method of claim 1949, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

1953. The method of claim 1949, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

1954. The method of claim 1949, wherein the illumination system comprises a single energy source.

1955. The method of claim 1949, wherein the illumination system comprises more than one energy source.

1956. The method of claim 1949, wherein the detection system comprises a single energy sensitive device.

5 1957. The method of claim 1949, wherein the detection system comprises more than one energy sensitive devices.

1958. The method of claim 1949, wherein the measurement device further comprises a non-imaging scatterometer.

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1959. The method of claim 1949, wherein the measurement device further comprises a scatterometer.

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1960. The method of claim 1949, wherein the measurement device further comprises a spectroscopic scatterometer.

1961. The method of claim 1949, wherein the measurement device further comprises a reflectometer.

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1962. The method of claim 1949, wherein the measurement device further comprises a spectroscopic reflectometer

1963. The method of claim 1949, wherein the measurement device further comprises an ellipsometer.

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1964. The method of claim 1949, wherein the measurement device further comprises a spectroscopic ellipsometer.

1965. The method of claim 1949, wherein the measurement device further comprises a bright field imaging device.

5 1966. The method of claim 1949, wherein the measurement device further comprises a dark field imaging device.

1967. The method of claim 1949, wherein the measurement device further comprises a bright field and dark field imaging device.

10 1968. The method of claim 1949, wherein the measurement device further comprises a non-imaging bright field device.

1969. The method of claim 1949, wherein the measurement device further comprises a non-imaging dark field device.

15 1970. The method of claim 1949, wherein the measurement device further comprises a non-imaging bright field and dark field device.

20 1971. The method of claim 1949, wherein the measurement device further comprises a double dark field device.

1972. The method of claim 1949, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright

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field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

5 1973. The method of claim 1949, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 1974. The method of claim 1949, further comprising:

controlling the illumination system to direct energy toward a bottom surface of the specimen; and

15 controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the first property comprises a presence of defects on the bottom surface of the specimen.

20 1975. The method of claim 1949, further comprising processing the one or more output signals to determine a thickness of a copper film, and wherein the macro defects or the micro defects comprise voids in the copper film.

25 1976. The method of claim 1949, wherein the macro defects comprise copper contamination on a back side of the specimen.

1977. The method of claim 1949, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is

selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

1978. The method of claim 1977, wherein the stage and the measurement device are
5 coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

1979. The method of claim 1949, wherein processing the one or more output signals to
10 determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

1980. The method of claim 1949, further comprising controlling the illumination system
to direct energy toward multiple locations on the surface of the specimen substantially
15 simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

1981. The method of claim 1949, wherein the stage and the measurement device are
20 coupled to a process tool.

1982. The method of claim 1949, wherein the stage and the measurement device are
coupled to a process tool, and wherein the stage and the measurement device are arranged
laterally proximate to the process tool.

25 1983. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

1984. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

1985. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

1986. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

1987. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

1988. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

1989. The method of claim 1949, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured

to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

5 1990. The method of claim 1949, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 1991. The method of claim 1949, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 1992. The method of claim 1949, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

20 1993. The method of claim 1949, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

25 1994. The method of claim 1949, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

1995. The method of claim 1994, further comprising controlling the illumination system and controlling the detection system during the process step.

1996. The method of claim 1995, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

- 5 1997. The method of claim 1995, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

- 10 1998. The method of claim 1949, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 15 1999. The method of claim 1998, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

- 20 2000. The method of claim 1949, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

2001. The method of claim 1949, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

- 25 2002. The method of claim 2001, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

2003. The method of claim 1949, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties.

2004. The method of claim 1949, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

2005. The method of claim 1949, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

2006. The method of claim 1949, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

2007. The method of claim 1949, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals generated by the measurement device using the database.

2008. The method of claim 1949, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

2009. The method of claim 1949, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and

wherein the database further comprises first and second properties of a plurality of specimens generated using a plurality of measurement devices.

2010. The method of claim 2009, further comprising calibrating the plurality of measurement devices using the database.

2011. The method of claim 2009, further comprising monitoring output signals generated by the plurality of measurement devices using the database.

2012. The method of claim 1949, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

2013. The method of claim 1949, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

2014. The method of claim 1949, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

2015. The method of claim 1949, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

5 2016. The method of claim 1949, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

10 2017. The method of claim 1949, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

15 2018. The method of claim 1949, further comprising monitoring a parameter of one or more instruments coupled to a process tool and determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

20 2019. The method of claim 1949, further comprising monitoring a parameter of one or more instruments coupled to a process tool, determining a relationship between at least one of the determined properties and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

2020. The method of claim 1949, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

25 2021. The method of claim 1949, wherein the measurement device comprises non-optical components, and wherein controlling the detection system to detect energy comprises controlling the non-optical components to measure a non-optical characteristic of the surface of the specimen.

2022. The method of claim 1949, wherein processing the one or more output signals comprises:

5 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

10 further processing the partially processed one or more output signals using the remote controller computer.

2023. The method of claim 2022, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

2024. The method of claim 2022, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

2025. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

25 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

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generating one or more output signals in response to the detected energy; and

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processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen.

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2026. The device of claim 2025, wherein the illumination system comprises a single energy source.

2027. The device of claim 2025, wherein the illumination system comprises more than one energy source.

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2028. The device of claim 2025, wherein the detection system comprises a single energy sensitive device.

2029. The device of claim 2025, wherein the detection system comprises more than one energy sensitive devices.

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2030. The device of claim 2025, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a

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bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2031. The device of claim 2025, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2032. The device of claim 2025, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2033. The device of claim 2025, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

5 2034. The device of claim 2025, further comprising processing the one or more output signals to determine a thickness of a copper film, and wherein the macro defects or the micro defects comprise voids in the copper film.

10 2035. The device of claim 2025, wherein the macro defects comprise copper contamination on a back side of the specimen.

15 2036. The device of claim 2025, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20 2037. The device of claim 2036, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

2038. The device of claim 2025, wherein the stage and the measurement device are coupled to a process tool.

25 2039. The device of claim 2025, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

2040. The device of claim 2025, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

5 2041. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

10 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

15 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

20 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen.

25 2042. The method of claim 2041, wherein the illumination system comprises a single energy source.

2043. The method of claim 2041, wherein the illumination system comprises more than one energy source.

2044. The method of claim 2041, wherein the detection system comprises a single
5 energy sensitive device.

2045. The method of claim 2041, wherein the detection system comprises more than one energy sensitive devices.

10 2046. The method of claim 2041, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-
15 imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

20 2047. The method of claim 2041, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field
25 imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray

fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2048. The method of claim 2041, wherein the measurement device further comprises at
5 least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2049. The method of claim 2041, further comprising:
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directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein
the first property further comprises a presence of macro defects on the bottom
15 surface of the specimen.

2050. The method of claim 2041, further comprising processing the one or more output
signals to determine a thickness of a copper film, and wherein the macro defects or the
micro defects comprise voids in the copper film.
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2051. The method of claim 2041, wherein the macro defects comprise copper
contamination on a back side of the specimen.

2052. The method of claim 2041, further comprising processing the one or more output
25 signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

2053. The method of claim 2052, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 2054. The method of claim 2041, wherein the stage and the measurement device are coupled to a process tool.

2055. The method of claim 2041, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group
10 consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

2056. The method of claim 2041, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical
15 characteristic of the surface of the specimen.

2057. A system configured to determine at least two properties of a specimen during use, comprising:

20 a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

25 an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use,

wherein the measurement device is configured to generate one or more output signals responsive to the detected energy;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen.

2058. The system of claim 2057, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2059. The system of claim 2057, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a

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spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray
5 fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2060. The system of claim 2057, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical
10 elements of the first measurement device comprise optical elements of the second measurement device.

2061. The system of claim 2057, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the
15 detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

2062. The system of claim 2057, wherein the remote controller computer is configured to determine a third property from the at least partially processed one or more output
20 signals during use, wherein the third property comprises a thickness of a copper film, and wherein the macro defects or the micro defects comprise voids in the copper film.

2063. The system of claim 2057, wherein the macro defects comprise copper
25 contamination on a back side of the specimen.

2064. The system of claim 2057, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially

processed one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

- 5 2065. The system of claim 2064, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

- 10 2066. The system of claim 2057, wherein the remote controller computer is coupled to a process tool.

- 15 2067. The system of claim 2057, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

- 20 2068. The system of claim 2057, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

- 25 2069. The system of claim 2057, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

2070. The system of claim 2057, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

- 5 2071. The system of claim 2070, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

- 10 2072. The system of claim 2071, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

- 15 2073. The system of claim 2057, wherein the remote controller computer is coupled to a process tool, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

- 20 2074. The system of claim 2073, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

- 25 2075. The system of claim 2073, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

2076. The system of claim 2057, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

2077. The system of claim 2076, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during said moving.

2078. The system of claim 2057, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

2079. The system of claim 2057, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

2080. The system of claim 2079, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

2081. The system of claim 2057, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

2082. The system of claim 2057, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

2083. The system of claim 2057, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

2084. The system of claim 2057, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

2085. The system of claim 2057, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

2086. The system of claim 2057, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

2087. The system of claim 2057, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens determined using a plurality of measurement devices.

2088. The system of claim 2087, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

2089. The system of claim 2087, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

2090. The system of claim 2057, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

2091. The system of claim 2057, wherein the remote controller computer is further coupled to a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

2092. The system of claim 2057, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the surface of the specimen.

2093. A method for determining at least two properties of a specimen, comprising:

5 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

10 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

15 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises a presence of micro defects on the specimen, comprising:

20 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

25 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

2094. The method of claim 2093, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2095. The method of claim 2093, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a double dark field device, an X-ray reflectometer, an X-ray fluorescence device, an optical fluorescence device, an eddy current imaging device, and a relatively large spot e-beam device.

2096. The method of claim 2093, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2097. The method of claim 2093, further comprising:

lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

5 2104. The method of claim 2093, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedback control technique.

10 2105. The method of claim 2093, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

15 2106. The method of claim 2093, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

20 2107. The method of claim 2093, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer and determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

25 2108. The method of claim 2093, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer, determining

a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer, and altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

5

2109. The method of claim 2093, wherein the illumination system and the detection system are coupled to a process chamber of a process tool, the method further comprising performing said directing and said detecting during a process step.

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2110. The method of claim 2109, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

15

2111. The method of claim 2109, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

2112. The method of claim 2093, further comprising:

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moving the specimen from a first process chamber to a second process chamber using the stage; and

performing said directing and said detecting during said moving the specimen.

25

2113. The method of claim 2093, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

2114. The method of claim 2093, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

- 5 2115. The method of claim 2114, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 10 2116. The method of claim 2093, wherein the remote controller computer is coupled to the measurement device.

- 15 2117. The method of claim 2116, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to at least one of the determined properties of the specimen.

2118. The method of claim 2116, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

- 20 2119. The method of claim 2116, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.

- 25 2120. The method of claim 2093, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen.

2121. The method of claim 2093, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

5

2122. The method of claim 2093, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals generated by the measurement device using the remote controller computer and the database.

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2123. The method of claim 2093, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

15

2124. The method of claim 2123, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices.

20

2125. The method of claim 2124, further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

2126. The method of claim 2124, further comprising monitoring output signals generated by the plurality of measurement devices using the remote controller computer and the database.

25

2127. The method of claim 2093, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote

controller computer, wherein each of the plurality of local processors is coupled to a measurement device.

2128. The method of claim 2127, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to at least one of the determined properties of the specimen.

2129. The method of claim 2127, wherein at least one of the plurality of measurement devices is coupled to one of a plurality of process tools.

2130. The method of claim 2129, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to at least one of the determined properties of the specimen.

2131. The method of claim 2093, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the surface of the specimen.

2132. A system configured to determine at least three properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

5 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

10 a processor coupled to the measurement device and configured to determine a first property, a second property, and a third property of the specimen from the one or more output signals during use, wherein the first property comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

15 2133. The system of claim 2132, wherein the stage is further configured to move laterally during use.

20 2134. The system of claim 2132, wherein the stage is further configured to move rotatably during use.

2135. The system of claim 2132, wherein the stage is further configured to move laterally and rotatably during use.

25 2136. The system of claim 2132, wherein the illumination system comprises a single energy source.

2137. The system of claim 2132, wherein the illumination system comprises more than one energy source.

2138. The system of claim 2132, wherein the detection system comprises a single energy
5 sensitive device.

2139. The system of claim 2132, wherein the detection system comprises more than one energy sensitive devices.

10 2140. The system of claim 2132, wherein the measurement device further comprises an optical profilometer.

2141. The system of claim 2132, wherein the measurement device further comprises an interferometer.

15 2142. The system of claim 2132, wherein the measurement device further comprises a spectroscopic reflectometer.

20 2143. The system of claim 2132, wherein the measurement device further comprises a spectroscopic ellipsometer.

2144. The system of claim 2132, wherein the measurement device further comprises a dual beam spectrophotometer.

25 2145. The system of claim 2132, wherein the measurement device further comprises a beam profile ellipsometer.

2146. The system of claim 2132, wherein the measurement device further comprises a non-imaging scatterometer.

5 2147. The system of claim 2132, wherein the measurement device further comprises a scatterometer.

2148. The system of claim 2132, wherein the measurement device further comprises a spectroscopic scatterometer.

10 2149. The system of claim 2132, wherein the measurement device further comprises a reflectometer.

2150. The system of claim 2132, wherein the measurement device further comprises an ellipsometer.

15 2151. The system of claim 2132, wherein the measurement device further comprises a bright field imaging device.

20 2152. The system of claim 2132, wherein the measurement device further comprises a dark field imaging device.

2153. The system of claim 2132, wherein the measurement device further comprises a bright field and dark field imaging device.

25 2154. The system of claim 2132, wherein the measurement device further comprises a non-imaging bright field device.

2155. The system of claim 2132, wherein the measurement device further comprises a non-imaging dark field device.

2156. The system of claim 2132, wherein the measurement device further comprises a non-imaging bright field and dark field device.

2157. The system of claim 2132, wherein the measurement device further comprises a double dark field device.

2158. The system of claim 2132, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

2159. The system of claim 2132, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2160. The system of claim 2132, wherein the defects comprise micro defects and macro defects.

2161. The system of claim 2132, wherein the defects comprises micro defects or macro defects.

5 2162. The system of claim 2132, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

2163. The system of claim 2132, wherein the defects comprise copper contamination on a back side of the specimen.

10 2164. The system of claim 2132, wherein the processor is further configured to determine a fourth property of the specimen from the one or more output signals during use, and wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15 2165. The system of claim 2164, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20 2166. The system of claim 2132, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

25 2167. The system of claim 2166, wherein the defects comprise macro defects.

2168. The system of claim 2132, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the specimen.

- 5 2169. The system of claim 2132, wherein the system is further configured to determine at least the three properties of the specimen substantially simultaneously during use.

2170. The system of claim 2132, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that the first, second, and third properties of the specimen at the multiple locations can be determined substantially simultaneously.
- 10

- 15 2171. The system of claim 2132, wherein the system is coupled to a semiconductor fabrication process tool.

2172. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.
- 20

2173. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

2174. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.
- 25

2175. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

- 5 2176. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

- 10 2177. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

- 15 2178. The system of claim 2132, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

- 20 2179. The system of claim 2132, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

- 25 2180. The system of claim 2132, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a chemical-mechanical polishing tool, and a thermal tool.

2181. The system of claim 2132, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the

measurement chamber, and wherein the measurement chamber is coupled to a process tool.

2182. The system of claim 2132, wherein the system further comprises a measurement
5 chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

2183. The system of claim 2132, wherein the system further comprises a measurement
10 chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

2184. The system of claim 2132, wherein the system further comprises a measurement
15 chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

2185. The system of claim 2132, wherein a process tool comprises a process chamber,
20 wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

2186. The system of claim 2185, wherein the processor is further configured to
25 determine at least the three properties of the specimen during the process step.

2187. The system of claim 2186, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

2188. The system of claim 2186, wherein the processor is further coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

2189. The system of claim 2132, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

2190. The system of claim 2189, wherein the system is further configured to determine at least the three properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

2191. The system of claim 2132, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

2192. The system of claim 2132, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

2193. The system of claim 2192, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

2194. The system of claim 2132, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

- 5 2195. The system of claim 2132, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

- 10 2196. The system of claim 2132, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

- 15 2197. The system of claim 2132, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

- 20 2198. The system of claim 2132, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

- 25 2199. The system of claim 2132, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined properties of the specimen, and wherein the database further comprises first, second, and third properties of a plurality of specimens.

2200. The system of claim 2199, wherein the first, second, and third properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

2201. The system of claim 2199, wherein the first, second, and third properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

2202. The system of claim 2132, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

2203. The system of claim 2132, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

2204. The system of claim 2132, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to

2211. The system of claim 2132, wherein the processor is further coupled to a plurality of process tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

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2212. The system of claim 2132, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

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2213. The system of claim 2212, wherein the local processor is further configured to determine the first, second, and third properties of the specimen during use.

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2214. The system of claim 2212, wherein the remote controller computer is further configured to determine the first, second, and third properties of the specimen during use.

2215. A method for determining at least three properties of a specimen, comprising:

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disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

25

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property
5 comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

2216. The method of claim 2215, further comprising laterally moving the stage during
10 said directing energy and said detecting energy.

2217. The method of claim 2215, further comprising rotatably moving the stage during said directing energy and said detecting energy.

15 2218. The method of claim 2215, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

2219. The method of claim 2215, wherein the illumination system comprises a single energy source.

20 2220. The method of claim 2215, wherein the illumination system comprises more than one energy source.

2221. The method of claim 2215, wherein the detection system comprises a single
25 energy sensitive device.

2222. The method of claim 2215, wherein the detection system comprises more than one energy sensitive devices.

2223. The method of claim 2215, wherein the measurement device further comprises an optical profilometer.

5 2224. The method of claim 2215, wherein the measurement device further comprises an interferometer.

2225. The method of claim 2215, wherein the measurement device further comprises a spectroscopic reflectometer.

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2226. The method of claim 2215, wherein the measurement device further comprises a spectroscopic ellipsometer.

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2227. The method of claim 2215, wherein the measurement device further comprises a dual beam spectrophotometer.

2228. The method of claim 2215, wherein the measurement device further comprises a beam profile ellipsometer.

20

2229. The method of claim 2215, wherein the measurement device further comprises a non-imaging scatterometer.

2230. The method of claim 2215, wherein the measurement device further comprises a scatterometer.

25

2231. The method of claim 2215, wherein the measurement device further comprises a spectroscopic scatterometer.

2232. The method of claim 2215, wherein the measurement device further comprises a reflectometer.

2233. The method of claim 2215, wherein the measurement device further comprises an
5 ellipsometer.

2234. The method of claim 2215, wherein the measurement device further comprises a bright field imaging device.

10 2235. The method of claim 2215, wherein the measurement device further comprises a dark field imaging device.

2236. The method of claim 2215, wherein the measurement device further comprises a bright field and dark field imaging device.

15 2237. The method of claim 2215, wherein the measurement device further comprises a non-imaging bright field device.

2238. The method of claim 2215, wherein the measurement device further comprises a
20 non-imaging dark field device.

2239. The method of claim 2215, wherein the measurement device further comprises a non-imaging bright field and dark field device.

25 2240. The method of claim 2215, wherein the measurement device further comprises a double dark field device.

2241. The method of claim 2215, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.
2242. The method of claim 2215, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.
2243. The method of claim 2215, wherein the defects comprise micro defects and macro defects.
2244. The method of claim 2215, wherein the defects comprises micro defects or macro defects.
2245. The method of claim 2215, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.
2246. The method of claim 2215, wherein the defects comprise copper contamination on a back side of the specimen.

2247. The method of claim 2215, further comprising processing the one or more output signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5

2248. The method of claim 2247, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

10 2249. The method of claim 2215, further comprising:

directing energy toward a bottom surface of the specimen; and

15 detecting energy propagating from the bottom surface of the specimen, wherein the second property comprises a presence of defects on the bottom surface of the specimen.

2250. The method of claim 2249, wherein the defects comprise macro defects.

20 2251. The method of claim 2215, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the specimen.

2252. The method of claim 2215, wherein processing the one or more output signals to
25 determine the first, second, and properties of the specimen comprises substantially simultaneously determining the first, second, and third properties of the specimen.

2253. The method of claim 2215, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that the first, second, and third properties of the specimen at the multiple locations can be
5 determined substantially simultaneously.

2254. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool.

10 2255. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

2256. The method of claim 2215, wherein the stage and the measurement device are
15 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

2257. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, and wherein the semiconductor fabrication process tool is
20 selected from the group consisting of a lithography tool, an etch tool, a chemical-mechanical polishing tool, and a thermal tool.

2258. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and
25 wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

2259. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

- 5 2260. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

- 10 2261. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

- 15 2262. The method of claim 2215, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

- 20 2263. The method of claim 2215, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

- 25 2264. The method of claim 2215, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

2265. The method of claim 2215, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

- 5 2266. The method of claim 2215, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

- 10 2267. The method of claim 2215, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

- 15 2268. The method of claim 2267, further comprising performing said directing and said detecting during the process step.

- 20 2269. The method of claim 2268, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

2270. The method of claim 2268, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

- 25 2271. The method of claim 2215, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

2272. The method of claim 2271, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

- 5 2273. The method of claim 2215, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 10 2274. The method of claim 2215, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

- 15 2275. The method of claim 2274, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 20 2276. The method of claim 2215, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

- 25 2277. The method of claim 2215, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

2278. The method of claim 2215, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

2279. The method of claim 2215, further comprising generating a database, wherein the database comprises the determined properties of the specimen, the method further comprising calibrating the measurement device using the database.

5 2280. The method of claim 2215, further comprising generating a database, wherein the database comprises the determined properties of the specimen, the method further comprising monitoring output signals generated by the measurement device using the database.

10 2281. The method of claim 2215, further comprising generating a database, wherein the database comprises the determined properties of the specimen, and wherein the database further comprises first, second, and third properties of a plurality of specimens.

15 2282. The method of claim 2281, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

20 2283. The method of claim 2281, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the database.

25 2284. The method of claim 2215, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

2285. The method of claim 2215, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device and at least the one additional measurement device with the stand alone system.

2286. The method of claim 2215, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

2287. The method of claim 2215, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

2288. The method of claim 2215, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

2289. The method of claim 2215, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

2290. The method of claim 2215, further comprising monitoring a parameter of an instrument coupled to a process tool and determining a relationship between the at least one of the determined properties and at least one of the monitored parameters.

2291. The method of claim 2215, further comprising monitoring a parameter of an instrument coupled to a process tool, determining a relationship between the at least one of the determined properties and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

5

2292. The method of claim 2215, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

10 2293. The method of claim 2215, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

20

further processing the partially processed one or more output signals using the remote controller computer.

2294. The method of claim 2293, wherein at least partially processing the one or more output signals comprises determining the first, second, and third properties of the specimen.

25

2295. The method of claim 2293, wherein further processing the partially processed one or more output signals comprises determining the first, second, and third properties of the specimen.

2296. A computer-implemented method for controlling a system configured to determine at least three properties of a specimen during use, wherein the system comprises a measurement device, comprising:

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controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

10

controlling the illumination system to direct energy toward a surface of the specimen;

controlling the detection system to detect energy propagating from the surface of the specimen; and

15

generating one or more output signals responsive to the detected energy; and

20

processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

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2297. The method of claim 2296, further comprising controlling the stage, wherein the stage is configured to support the specimen.

2307. The method of claim 2296, wherein the measurement device further comprises a spectroscopic reflectometer.

5 2308. The method of claim 2296, wherein the measurement device further comprises a spectroscopic ellipsometer.

2309. The method of claim 2296, wherein the measurement device further comprises a dual beam spectrophotometer.

10 2310. The method of claim 2296, wherein the measurement device further comprises a beam profile ellipsometer.

2311. The method of claim 2296, wherein the measurement device further comprises a non-imaging scatterometer.

15 2312. The method of claim 2296, wherein the measurement device further comprises a scatterometer.

20 2313. The method of claim 2296, wherein the measurement device further comprises a spectroscopic scatterometer.

2314. The method of claim 2296, wherein the measurement device further comprises a reflectometer.

25 2315. The method of claim 2296, wherein the measurement device further comprises an ellipsometer.

2316. The method of claim 2296, wherein the measurement device further comprises a bright field imaging device.

2317. The method of claim 2296, wherein the measurement device further comprises a
5 dark field imaging device.

2318. The method of claim 2296, wherein the measurement device further comprises a bright field and dark field imaging device.

10 2319. The method of claim 2296, wherein the measurement device further comprises a non-imaging bright field device.

2320. The method of claim 2296, wherein the measurement device further comprises a non-imaging dark field device.

15 2321. The method of claim 2296, wherein the measurement device further comprises a non-imaging bright field and dark field device.

2322. The method of claim 2296, wherein the measurement device further comprises a
20 double dark field device.

2323. The method of claim 2296, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of an optical
25 profilometer, an interferometer, a spectroscopic reflectometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging

device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

2324. The method of claim 2296, wherein the measurement device further comprises at
5 least a first measurement device and a second measurement device, and wherein optical
elements of the first measurement device comprise optical elements of the second
measurement device.

2325. The method of claim 2296, wherein the defects comprise micro defects and macro
10 defects.

2326. The method of claim 2296, wherein the defects comprises micro defects or macro
defects.

2327. The method of claim 2296, wherein the thin film characteristic comprises a
15 thickness of a copper film, and wherein the defects comprise voids in the copper film.

2328. The method of claim 2296, wherein the defects comprise copper contamination on
a back side of the specimen.
20

2329. The method of claim 2296, further comprising processing the one or more output
signals to determine a fourth property of the specimen, wherein the fourth property is
selected from the group consisting of a roughness of the specimen, a roughness of a layer
on the specimen, and a roughness of a feature of the specimen.
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2330. The method of claim 2329, wherein the stage and the measurement device are
coupled to a process tool selected from the group consisting of a lithography tool, an
atomic layer deposition tool, a cleaning tool, and an etch tool.

2331. The method of claim 2296, further comprising:

5 controlling the illumination system to direct energy toward a bottom surface of the specimen; and

controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

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2332. The method of claim 2331, wherein the defects comprise macro defects.

2333. The method of claim 2296, wherein the measurement device further comprises non-optical components, and wherein controlling the detection system to detect energy
15 comprises controlling the non-optical components to measure a non-optical characteristic of the specimen.

2334. The method of claim 2296, wherein processing the one or more output signals to determine the first, second, and third properties of the specimen comprises substantially
20 simultaneously determining the first, second, and third properties of the specimen.

2335. The method of claim 2296, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the
25 multiple locations substantially simultaneously such that the first, second, and third properties of the specimen at the multiple locations can be determined substantially simultaneously.

2336. The method of claim 2296, wherein the stage and the measurement device are coupled to a process tool.

2337. The method of claim 2296, wherein the stage and the measurement device are
5 coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

2338. The method of claim 2296, wherein the stage and the measurement device are
10 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

2339. The method of claim 2296, wherein the stage and the measurement device are
15 coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, and etch tool, a chemical-mechanical polishing tool, and a thermal tool.

2340. The method of claim 2296, further comprising controlling a wafer handler to
20 move the specimen from a process tool to the stage, wherein the wafer handler is coupled to the process tool.

2341. The method of claim 2296, further comprising controlling the stage to move the
specimen from the system to a process tool.

2342. The method of claim 2296, wherein the stage and the measurement device are
25 coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

2343. The method of claim 2296, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

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2344. The method of claim 2296, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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2345. The method of claim 2296, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

15

2346. The method of claim 2296, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

20

2347. The method of claim 2296, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

25

2348. The method of claim 2296, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

2349. The method of claim 2296, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

5 2350. The method of claim 2349, further comprising controlling the illumination system and controlling the detection system during the process step.

2351. The method of claim 2350, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one
10 singularity representative of an end of the process step.

2352. The method of claim 2350, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.
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2353. The method of claim 2296, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

20 2354. The method of claim 2353, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

2355. The method of claim 2296, further comprising comparing at least one of the
25 determined properties of the specimen and determined properties of a plurality of specimens.

2356. The method of claim 2296, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

5 2357. The method of claim 2356, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

10 2358. The method of claim 2296, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

15 2359. The method of claim 2296, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

20 2360. The method of claim 2296, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

25 2361. The method of claim 2296, further comprising generating a database, wherein the database comprises the determined first, second, and third properties of the specimen, the method further comprising calibrating the measurement device using the database.

2362. The method of claim 2296, further comprising generating a database, wherein the database comprises the determined first, second, and third properties of the specimen, the method further comprising monitoring output signals generated by the measurement device using the database.

2363. The method of claim 2296, further comprising generating a database, wherein the database comprises the determined first, second, and third properties of the specimen, and wherein the database further comprises first, second, and third properties of a plurality of specimens.

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2364. The method of claim 2363, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

10 2365. The method of claim 2363, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the database.

15 2366. The method of claim 2296, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

20 2367. The method of claim 2296, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

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2368. The method of claim 2296, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least

one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

- 5 2369. The method of claim 2296, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

- 10 2370. The method of claim 2296, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

2371. The method of claim 2296, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

- 15 2372. The method of claim 2371, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

- 20 2373. The method of claim 2372, further comprising altering a parameter of at least one of the instruments in response to the relationship.

2374. The method of claim 2296, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

- 25 2375. The method of claim 2296, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 2376. The method of claim 2375, wherein at least partially processing the one or more
output signals comprises determining the first, second, and third properties of the
specimen.

15 2377. The method of claim 2375, wherein further processing the partially processed one
or more output signals comprises determining the first, second, and third properties of the
specimen.

20 2378. A semiconductor device fabricated by a method, the method comprising:
forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a
measurement device, and wherein the measurement device comprises an
illumination system and a detection system;

25 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

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processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property

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comprises a thin film characteristic of the specimen.

2379. The device of claim 2378, wherein the illumination system comprises a single energy source.

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2380. The device of claim 2378, wherein the illumination system comprises more than one energy source.

2381. The device of claim 2378, wherein the detection system comprises a single energy sensitive device.

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2382. The device of claim 2378, wherein the detection system comprises more than one energy sensitive devices.

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2383. The device of claim 2378, wherein the measurement device is selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field

imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

5 2384. The device of claim 2378, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-
10 imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

15 2385. The device of claim 2378, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

20 2386. The device of claim 2378, wherein the defects comprise micro defects and macro defects.

2387. The device of claim 2378, wherein the defects comprises micro defects or macro defects.

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2388. The device of claim 2378, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

2389. The device of claim 2378, wherein the defects comprise copper contamination on a back side of the specimen.

2390. The device of claim 2378, further comprising processing the one or more output
5 signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

2391. The device of claim 2390, wherein the stage and the measurement device are
10 coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

2392. The device of claim 2378, further comprising:
15 directing energy toward a bottom surface of the specimen; and
detecting energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

20 2393. The device of claim 2392, wherein the defects comprise macro defects.

2394. The device of claim 2378, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical
25 characteristic of the specimen.

2395. The device of claim 2378, wherein the stage and the measurement device are coupled to a process tool.

2396. The device of claim 2378, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a chemical-mechanical polishing tool, and a thermal tool.

2397. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals in response to the detected energy; and

processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

2398. The method of claim 2397, wherein the illumination system comprises a single energy source.

2399. The method of claim 2397, wherein the illumination system comprises more than
5 one energy source.

2400. The method of claim 2397, wherein the detection system comprises a single energy sensitive device.

10 2401. The method of claim 2397, wherein the detection system comprises more than one energy sensitive devices.

2402. The method of claim 2397, wherein the measurement device is selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic
15 reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device,
20 and a double dark field device.

2403. The method of claim 2397, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first
and second measurement devices are selected from the group consisting of an optical
25 profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and

dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

2404. The method of claim 2397, wherein the measurement device further comprises at
5 least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2405. The method of claim 2397, wherein the defects comprise micro defects and macro
10 defects.

2406. The method of claim 2397, wherein the defects comprises micro defects or macro defects.

15 2407. The method of claim 2397, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

2408. The method of claim 2397, wherein the defects comprise copper contamination on a back side of the specimen.

20 2409. The method of claim 2397, further comprising processing the one or more output signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25 2410. The method of claim 2409, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

2411. The method of claim 2397, further comprising:

directing energy toward a bottom surface of the specimen; and

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detecting energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

10 2412. The method of claim 2411, wherein the defects comprise macro defects.

2413. The method of claim 2397, wherein the measurement device comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the specimen.

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2414. The method of claim 2397, wherein the stage and the measurement device are coupled to a process tool.

2415. The method of claim 2397, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a chemical-mechanical polishing tool, and a thermal tool.

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2416. A system configured to determine at least three properties of a specimen during use, comprising:

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a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property, a second property, and a third property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen.

2417. The system of claim 2416, wherein the measurement device is selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field

device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

2418. The system of claim 2416, wherein the measurement device further comprises at
5 least a first measurement device and a second measurement device, and wherein the first
and second measurement devices are selected from the group consisting of an optical
profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic
ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-
imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an
10 ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and
dark field imaging device, a non-imaging bright field device, a non-imaging dark field
device, a non-imaging bright field and dark field device, and a double dark field device.

2419. The system of claim 2416, wherein the measurement device further comprises at
15 least a first measurement device and a second measurement device, and wherein optical
elements of the first measurement device comprise optical elements of the second
measurement device.

2420. The system of claim 2416, wherein the defects comprise micro defects and macro
20 defects.

2421. The system of claim 2416, wherein the defects comprises micro defects or macro
defects.

25 2422. The system of claim 2416, wherein the thin film characteristic comprises a
thickness of a copper film, and wherein the defects comprise voids in the copper film.

2423. The system of claim 2416, wherein the defects comprise copper contamination on a back side of the specimen.

5 2424. The system of claim 2416, wherein the remote controller computer is further configured to determine a fourth property of the specimen from the at least partially processed one or more output signals during use, and wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

10 2425. The system of claim 2424, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

15 2426. The system of claim 2416, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

20 2427. The system of claim 2426, wherein the defects comprise macro defects.

2428. The system of claim 2416, wherein the illumination system and the detection system comprise non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the specimen.

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2429. The system of claim 2416, wherein the remote controller computer is coupled to a process tool.

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2430. The system of claim 2416, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from a group consisting of a lithography tool, an etch tool, a chemical-mechanical polishing tool, and a thermal tool.

5 2431. The system of claim 2416, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

10 2432. The system of claim 2416, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

15 2433. The system of claim 2416, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

20 2434. The system of claim 2433, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

25 2435. The system of claim 2434, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

2436. The system of claim 2416, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the

detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first, second, and third properties of the specimen during the process step.

5

2437. The system of claim 2436, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

10

2438. The system of claim 2436, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

15

2439. The system of claim 2416, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

20

2440. The system of claim 2439, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first, second, and third properties of the specimen during said moving.

25

2441. The system of claim 2416, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

5 2442. The system of claim 2416, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

2443. The system of claim 2442, wherein the remote controller computer is further
10 configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

2444. The system of claim 2416, wherein the remote controller computer is further
15 configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

2445. The system of claim 2416, wherein the remote controller computer is further
20 configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

2446. The system of claim 2416, wherein the remote controller computer is further
25 configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

2447. The system of claim 2416, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the

determined first, second, and third properties of the specimen, and wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

- 5 2448. The system of claim 2416, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first, second, and third properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

10

2449. The system of claim 2416, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first, second, and third properties of the specimen, and wherein the database further comprises first, second, and third properties of a plurality of specimens.

15

2450. The system of claim 2449, wherein the first, second, and third properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality
20 of measurement devices using the database during use.

25

2451. The system of claim 2449, wherein the first, second, and third properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

2452. The system of claim 2416, wherein the remote controller computer is further coupled to a plurality of measurement devices, wherein each of the plurality of measurement devices is coupled to one of a plurality of process tools.

- 5 2453. The system of claim 2416, wherein the remote controller computer is coupled to at least one of a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

- 10 2454. A method for determining at least three properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

15

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

20

generating one or more output signals responsive to the detected energy; and

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processing the one or more output signals to determine a first property, a second property, and a third property of the specimen, wherein the first property comprises a flatness measurement of the specimen, wherein the second property comprises a presence of defects on the specimen, and wherein the third property comprises a thin film characteristic of the specimen, comprising:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

5 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

10

2455. The method of claim 2454, wherein the measurement device is selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-imaging scatterometer, a scatterometer, a spectroscopic
15 scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

20 2456. The method of claim 2454, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of an optical profilometer, an interferometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, and a beam profile ellipsometer a non-
25 imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, and a double dark field device.

2457. The method of claim 2454, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2458. The method of claim 2454, wherein the defects comprise micro defects and macro defects.

2459. The method of claim 2454, wherein the defects comprises micro defects or macro defects.

2460. The method of claim 2454, wherein the thin film characteristic comprises a thickness of a copper film, and wherein the defects comprise voids in the copper film.

2461. The method of claim 2454, wherein the defects comprise copper contamination on a back side of the specimen.

2462. The method of claim 2454, further comprising processing the one or more output signals to determine a fourth property of the specimen, wherein the fourth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

2463. The method of claim 2462, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

2464. The method of claim 2454, further comprising:

directing energy toward a bottom surface of the specimen; and

5 detecting energy propagating from the bottom surface of the specimen, wherein
the second property further comprises a presence of defects on the bottom surface
of the specimen.

2465. The method of claim 2464, wherein the defects comprise macro defects.

10 2466. The method of claim 2454, wherein the measurement device comprises non-
optical components, and wherein detecting energy comprises measuring a non-optical
characteristic of the specimen.

15 2467. The method of claim 2454, wherein the remote controller computer is coupled to a
process tool.

2468. The method of claim 2454, wherein the remote controller computer is coupled to a
process tool, and wherein the process tool is selected from the group consisting of a
lithography tool, an etch tool, a chemical-mechanical polishing tool, and a thermal tool.

20 2469. The method of claim 2454, wherein the remote controller computer is coupled to a
process tool, the method further comprising altering a parameter of one or more
instruments coupled to the process tool using the remote controller computer in response
to at least one of the determined properties of the specimen comprises using a feedback
25 control technique.

2470. The method of claim 2454, wherein the remote controller computer is coupled to a
process tool, the method further comprising altering a parameter of one or more

instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen comprises using a feedforward control technique.

5 2471. The method of claim 2454, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

10 2472. The method of claim 2471, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

15 2473. The method of claim 2472, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

2474. The method of claim 2454, wherein the illumination system and the detection system are coupled to a process chamber of a process tool, the method further comprising performing said directing and said detecting during a process step.

20 2475. The method of claim 2474, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

25 2476. The method of claim 2474, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

2477. The method of claim 2454, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage; and

5 performing said directing and said detecting during said moving the specimen.

2478. The method of claim 2454, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

10

2479. The method of claim 2454, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

15 2480. The method of claim 2479, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

20 2481. The method of claim 2454, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to at least one of the determined properties of the specimen.

25 2482. The method of claim 2454, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

2483. The method of claim 2454, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller
5 computer in response to at least one of the determined properties using a feedforward control technique.

2484. The method of claim 2454, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first, second
10 and third properties of the specimen.

2485. The method of claim 2454, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first, second and third properties of the specimen, the method further comprising calibrating the
15 measurement device using the remote controller computer.

2486. The method of claim 2454, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first, second and third properties of the specimen, the method further comprising monitoring output
20 signals generated by the measurement device using the remote controller computer.

2487. The method of claim 2454, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first, second and third properties of the specimen, and wherein the database further comprises first,
25 second, and third properties of a plurality of specimens.

2488. The method of claim 2487, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices, the method

further comprising calibrating the plurality of measurement devices using the remote controller computer.

5 2489. The method of claim 2487, wherein the first, second, and third properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the remote controller computer.

10 2490. The method of claim 2454, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

15 2491. The method of claim 2490, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to at least one of the determined properties of the specimen.

20 2492. The method of claim 2490, wherein at least one of the plurality of measurement devices is coupled to one of a plurality of process tools.

25 2493. The method of claim 2492, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to at least one of the determined properties of the specimen.

2494. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

5

an illumination system configured to direct energy toward a surface of the specimen during use; and

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a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

15

a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen.

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2495. The system of claim 2494, wherein the stage is further configured to move laterally during use.

2496. The system of claim 2494, wherein the stage is further configured to move rotatably during use.

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2497. The system of claim 2494, wherein the stage is further configured to move laterally and rotatably during use.

2498. The system of claim 2494, wherein the illumination system comprises a single energy source.

2499. The system of claim 2494, wherein the illumination system comprises more than
5 one energy source.

2500. The system of claim 2494, wherein the detection system comprises a single energy sensitive device.

10 2501. The system of claim 2494, wherein the detection system comprises more than one energy sensitive devices.

2502. The system of claim 2494, wherein the measurement device further comprises a coherence probe microscope.

15 2503. The system of claim 2494, wherein the measurement device further comprises an interferometer.

2504. The system of claim 2494, wherein the measurement device further comprises an
20 optical profilometer.

2505. The system of claim 2494, wherein the measurement device further comprises a spectroscopic reflectometer.

25 2506. The system of claim 2494, wherein the measurement device further comprises a spectroscopic ellipsometer.

2507. The system of claim 2494, wherein the measurement device further comprises a dual beam spectrophotometer.

5 2508. The system of claim 2494, wherein the measurement device further comprises a beam profile ellipsometer.

2509. The system of claim 2494, wherein the measurement device further comprises a non-imaging scatterometer.

10 2510. The system of claim 2494, wherein the measurement device further comprises a scatterometer.

15 2511. The system of claim 2494, wherein the measurement device further comprises a spectroscopic scatterometer.

2512. The system of claim 2494, wherein the measurement device further comprises a reflectometer.

20 2513. The system of claim 2494, wherein the measurement device further comprises a bright field imaging device.

2514. The system of claim 2494, wherein the measurement device further comprises a dark field imaging device.

25 2515. The system of claim 2494, wherein the measurement device further comprises a bright field and dark field imaging device.

2516. The system of claim 2494, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2517. The system of claim 2494, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2518. The system of claim 2494, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

2519. The system of claim 2494, wherein the system is coupled to a process tool.

2520. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

2521. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

2522. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

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2523. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

10 2524. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

15 2525. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

20 2526. The system of claim 2494, wherein the system is coupled to a lithography tool, wherein the system is configured to determine the flatness measurement of the specimen prior to an exposure step of the lithography process, and wherein the system is configured to determine the overlay misregistration subsequent to the exposure step of the lithography process.

25 2527. The system of claim 2494, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

2528. The system of claim 2494, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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2529. The system of claim 2494, wherein the system is coupled to a process tool, and wherein the process tool comprises a lithography tool.

2530. The system of claim 2494, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

2531. The system of claim 2494, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

2532. The system of claim 2494, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

2533. The system of claim 2494, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

2534. The system of claim 2494, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

5 2535. The system of claim 2534, wherein the processor is further configured to determine at least the two properties of the specimen during the process step.

2536. The system of claim 2535, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises
10 at least one singularity representative of an end of the process step.

2537. The system of claim 2535, wherein the processor is further coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ
15 control technique during use.

2538. The system of claim 2494, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during
20 use.

2539. The system of claim 2538, wherein the system is further configured to determine at least one of the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.
25

2540. The system of claim 2494, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

2541. The system of claim 2494, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

5

2542. The system of claim 2541, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

10 2543. The system of claim 2494, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

15 2544. The system of claim 2494, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

20 2545. The system of claim 2494, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

25 2546. The system of claim 2494, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

2547. The system of claim 2494, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

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2548. The system of claim 2494, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens determined using a plurality of measurement devices.

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2549. The system of claim 2548, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

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2550. The system of claim 2548, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

20

2551. The system of claim 2494, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

25

2552. The system of claim 2494, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is

further configured to calibrate the system and at least the one additional system during use.

5 2553. The system of claim 2494, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

10

2554. The system of claim 2494, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

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2555. The system of claim 2494, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

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2556. The system of claim 2494, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

25 2557. The system of claim 2556, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

2558. The system of claim 2557, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

5 2559. The system of claim 2494, wherein the processor is further coupled to a plurality of measurement devices, and wherein the plurality of measurement devices is coupled to a plurality of process tools.

10 2560. The system of claim 2494, wherein the processor is further coupled to a plurality of process tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

15 2561. The system of claim 2494, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

20 2562. The system of claim 2561, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

25 2563. The system of claim 2561, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

2564. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen.

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2565. The method of claim 2564, further comprising laterally moving the stage during said directing energy and said detecting energy.

20 2566. The method of claim 2564, further comprising rotatably moving the stage during said directing energy and said detecting energy.

2567. The method of claim 2564, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

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2568. The method of claim 2564, wherein the illumination system comprises a single energy source.

2569. The method of claim 2564, wherein the illumination system comprises more than one energy source.

5 2570. The method of claim 2564, wherein the detection system comprises a single energy sensitive device.

2571. The method of claim 2564, wherein the detection system comprises more than one energy sensitive devices.

10 2572. The method of claim 2564, wherein the measurement device further comprises a coherence probe microscope.

2573. The method of claim 2564, wherein the measurement device further comprises an interferometer.

15 2574. The method of claim 2564, wherein the measurement device further comprises an optical profilometer.

20 2575. The method of claim 2564, wherein the measurement device further comprises a spectroscopic reflectometer.

2576. The method of claim 2564, wherein the measurement device further comprises a spectroscopic ellipsometer.

25 2577. The method of claim 2564, wherein the measurement device further comprises a dual beam spectrophotometer.

2578. The method of claim 2564, wherein the measurement device further comprises a beam profile ellipsometer.

5 2579. The method of claim 2564, wherein the measurement device further comprises a non-imaging scatterometer.

2580. The method of claim 2564, wherein the measurement device further comprises a scatterometer.

10 2581. The method of claim 2564, wherein the measurement device further comprises a spectroscopic scatterometer.

2582. The method of claim 2564, wherein the measurement device further comprises a reflectometer.

15 2583. The method of claim 2564, wherein the measurement device further comprises a bright field imaging device.

20 2584. The method of claim 2564, wherein the measurement device further comprises a dark field imaging device.

2585. The method of claim 2564, wherein the measurement device further comprises a bright field and dark field imaging device.

25 2586. The method of claim 2564, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic

reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

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2587. The method of claim 2564, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10

2588. The method of claim 2564, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

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2589. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool.

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2590. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

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2591. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

2592. The method of claim 2564, wherein the stage and the measurement device are coupled to a lithography tool.

5 2593. The method of claim 2564, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the flatness measurement of the specimen prior to an exposure step of the lithography process and determining the overlay misregistration subsequent to the exposure step of the lithography process.

10 2594. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

15 2595. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

20 2596. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

25 2597. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

2598. The method of claim 2564, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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2599. The method of claim 2564, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 2600. The method of claim 2564, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 2601. The method of claim 2564, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

20 2602. The method of claim 2564, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

25 2603. The method of claim 2564, wherein the stage and the measurement device are disposed within a measurement chamber, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

2604. The method of claim 2603, further comprising performing said directing and said detecting during the process step.

2605. The method of claim 2604, further comprising obtaining a signature
5 characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

2606. The method of claim 2604, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined
10 properties using an in situ control technique.

2607. The method of claim 2564, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.
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2608. The method of claim 2607, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

2609. The method of claim 2564, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.
20

2610. The method of claim 2564, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.
25

2611. The method of claim 2610, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 5 2612. The method of claim 2564, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

- 10 2613. The method of claim 2564, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

- 15 2614. The method of claim 2564, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

2615. The method of claim 2564, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

- 20 2616. The method of claim 2564, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

- 25 2617. The method of claim 2564, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

2618. The method of claim 2564, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

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2619. The method of claim 2618, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

10 2620. The method of claim 2618, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

15 2621. The method of claim 2564, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

20 2622. The method of claim 2564, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

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2623. The method of claim 2564, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one

parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

- 5 2624. The method of claim 2564, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedback control technique.

- 10 2625. The method of claim 2564, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedforward control technique.

- 15 2626. The method of claim 2564, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

- 20 2627. The method of claim 2626, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

- 25 2628. The method of claim 2627, further comprising altering a parameter of at least one of the instruments in response to the relationship.

- 30 2629. The method of claim 2564, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

- 35 2630. The method of claim 2564, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 2631. The method of claim 2630, wherein at least partially processing the one or more
output signals comprises determining the first and second properties of the specimen.

15 2632. The method of claim 2630, wherein further processing the partially processed one
or more output signals comprises determining the first and second properties of the
specimen.

20 2633. A computer-implemented method for controlling a system configured to
determine at least two properties of a specimen during use, wherein the system comprises
a measurement device, the method comprising:

controlling the measurement device, wherein the measurement device comprises
an illumination system and a detection system, and wherein the measurement
device is coupled to a stage, comprising:

25 controlling the illumination system to direct energy toward a surface of the
specimen;

controlling the detection system to detect energy propagating from the surface of the specimen; and

generating one or more output signals responsive to the detected energy;
and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen.

2634. The method of claim 2633, further comprising controlling the stage, wherein the stage is configured to support the specimen.

2635. The method of claim 2633, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

2636. The method of claim 2633, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

2637. The method of claim 2633, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

2638. The method of claim 2633, wherein the illumination system comprises a single energy source.

2639. The method of claim 2633, wherein the illumination system comprises more than one energy source.

2640. The method of claim 2633, wherein the detection system comprises a single energy sensitive device.

- 5 2641. The method of claim 2633, wherein the detection system comprises more than one energy sensitive devices.

2642. The method of claim 2633, wherein the measurement device further comprises a coherence probe microscope.

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2643. The method of claim 2633, wherein the measurement device further comprises an interferometer.

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2644. The method of claim 2633, wherein the measurement device further comprises an optical profilometer.

2645. The method of claim 2633, wherein the measurement device further comprises a spectroscopic reflectometer.

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2646. The method of claim 2633, wherein the measurement device further comprises a spectroscopic ellipsometer.

2647. The method of claim 2633, wherein the measurement device further comprises a dual beam spectrophotometer.

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2648. The method of claim 2633, wherein the measurement device further comprises a beam profile ellipsometer.

2649. The method of claim 2633, wherein the measurement device further comprises a non-imaging scatterometer.

5 2650. The method of claim 2633, wherein the measurement device further comprises a scatterometer.

2651. The method of claim 2633, wherein the measurement device further comprises a spectroscopic scatterometer.

10 2652. The method of claim 2633, wherein the measurement device further comprises a reflectometer.

2653. The method of claim 2633, wherein the measurement device further comprises a bright field imaging device.

15 2654. The method of claim 2633, wherein the measurement device further comprises a dark field imaging device.

20 2655. The method of claim 2633, wherein the measurement device further comprises a bright field and dark field imaging device.

25 2656. The method of claim 2633, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic

scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

5 2657. The method of claim 2633, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 2658. The method of claim 2633, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

15 2659. The method of claim 2633, wherein the stage and the measurement device are coupled to a process tool.

20 2660. The method of claim 2633, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

25 2661. The method of claim 2633, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

2662. The method of claim 2633, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

2663. The method of claim 2633, wherein the system is coupled to a lithography tool,
the method further comprising controlling the system to determine the flatness
measurement of the specimen prior to an exposure step of the lithography process and
5 controlling the system to determine the overlay misregistration subsequent to the
exposure step of the lithography process.

2664. The method of claim 2633, wherein the stage and the measurement device are
coupled to a process tool, the method further comprising controlling a wafer handler to
10 move the specimen from the process tool to the stage, and wherein the wafer handler is
coupled to the process tool.

2665. The method of claim 2633, wherein the stage and the measurement device are
coupled to a process tool, the method further comprising controlling the stage to move the
15 specimen from the system to the process tool.

2666. The method of claim 2633, wherein the stage and the measurement device are
coupled to a process tool, the method further comprising controlling a wafer handler to
move the specimen from the process tool to the stage such that at least the two properties
20 of the specimen can be determined while the specimen is waiting between process steps.

2667. The method of claim 2633, wherein the stage and the measurement device are
coupled to a process tool, wherein the process tool comprises a support device configured
to support the specimen during a process step, and wherein an upper surface of the
25 support device is substantially parallel to an upper surface of the stage.

2668. The method of claim 2633, wherein the stage and the measurement device are
coupled to a process tool, wherein the process tool comprises a support device configured

to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

5 2669. The method of claim 2633, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 2670. The method of claim 2633, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 2671. The method of claim 2633, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

2672. The method of claim 2633, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

20 2673. The method of claim 2633, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

25 2674. The method of claim 2673, further comprising controlling the illumination system and controlling the detection system during the process step to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

2675. The method of claim 2673, further comprising controlling the illumination system and controlling the detection system during the process step to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

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2676. The method of claim 2633, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

10 2677. The method of claim 2676, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

15 2678. The method of claim 2633, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

20 2679. The method of claim 2633, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

2680. The method of claim 2679, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

25 2681. The method of claim 2633, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

2682. The method of claim 2633, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

5 2683. The method of claim 2633, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

10 2684. The method of claim 2633, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

15 2685. The method of claim 2633, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

20 2686. The method of claim 2633, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises determined first and second properties of a plurality of specimens.

25 2687. The method of claim 2686, wherein the determined first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

2688. The method of claim 2686, wherein the determined first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

5

2689. The method of claim 2633, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

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2690. The method of claim 2633, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

15

2691. The method of claim 2633, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more *instruments* coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

20

2692. The method of claim 2633, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedback control technique.

25

2693. The method of claim 2633, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedforward control technique.

5 2694. The method of claim 2633, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

2695. The method of claim 2694, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

10

2696. The method of claim 2695, further comprising altering a parameter of at least one of the instruments in response to the relationship.

15

2697. The method of claim 2633, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

20

2698. The method of claim 2633, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

2699. The method of claim 2698, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

5 2700. The method of claim 2698, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

2701. A semiconductor device fabricated by a method, the method comprising:

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forming a portion of the semiconductor device upon a specimen;

15

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

20

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

25

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen.

2702. The device of claim 2701, wherein the illumination system comprises a single energy source.

5 2703. The device of claim 2701, wherein the illumination system comprises more than one energy source.

2704. The device of claim 2701, wherein the detection system comprises a single energy sensitive device.

10 2705. The device of claim 2701, wherein the detection system comprises more than one energy sensitive devices.

2706. The device of claim 2701, wherein the measurement device is selected from the group consisting of a coherence probe microscope, an interferometer, an optical
15 profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

20 2707. The device of claim 2701, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam
25 profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2708. The device of claim 2701, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

5

2709. The device of claim 2701, wherein the stage and the measurement device are coupled to a process tool.

2710. The device of claim 2701, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

2711. The device of claim 2701, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the flatness measurement of the specimen prior to an exposure step of the lithography process and determining the overlay misregistration subsequent to the exposure step of the lithography process.

2712. A method for fabricating a semiconductor device, comprising:
forming a portion of the semiconductor device upon a specimen;

20

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

25

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen.

2713. The method of claim 2712, wherein the illumination system comprises a single energy source.

2714. The method of claim 2712, wherein the illumination system comprises more than one energy source.

2715. The method of claim 2712, wherein the detection system comprises a single energy sensitive device.

2716. The method of claim 2712, wherein the detection system comprises more than one energy sensitive devices.

2717. The method of claim 2712, wherein the measurement device is selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2718. The method of claim 2712, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2719. The method of claim 2712, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2720. The method of claim 2712, wherein the stage and the measurement device are coupled to a process tool.

2721. The method of claim 2712, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

2722. The method of claim 2712, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the flatness measurement of the specimen prior to an exposure step of the lithography process and determining the overlay misregistration subsequent to the exposure step of the lithography process.

2723. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen.

2724. The system of claim 2723, wherein the measurement device is selected from the group consisting of a coherence probe microscope, an interferometer, an optical

profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

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2725. The system of claim 2723, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic

10 reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

15 2726. The system of claim 2723, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

20 2727. The system of claim 2723, wherein the remote controller computer is further coupled to a process tool.

2728. The system of claim 2723, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool comprises a lithography tool.

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2729. The system of claim 2723, wherein the system is coupled to a lithography tool, wherein the system is configured to determine the flatness measurement of the specimen prior to an exposure step of the lithography process, and wherein the system is configured

to determine the overlay misregistration subsequent to the exposure step of the lithography process.

2730. The system of claim 2723, wherein the remote controller computer is further
5 coupled to a process tool, and wherein the remote controller computer is further
configured to alter a parameter of one or more instruments coupled to the process tool in
response to at least one of the determined properties using a feedback control technique
during use.

10 2731. The system of claim 2723, wherein the remote controller computer is further
coupled to a process tool, and wherein the remote controller computer is further
configured to alter a parameter of one or more instruments coupled to the process tool in
response to at least one of the determined properties using a feedforward control
technique during use.

15 2732. The system of claim 2723, wherein the remote controller computer is further
coupled to a process tool, and wherein the remote controller computer is further
configured to monitor a parameter of one or more instruments coupled to the process tool
during use.

20 2733. The system of claim 2732, wherein the remote controller computer is further
configured to determine a relationship between at least one of the determined properties
and at least one of the monitored parameters during use.

25 2734. The system of claim 2733, wherein the remote controller computer is further
configured to alter a parameter of one or more instruments in response to the relationship
during use.

2735. The system of claim 2723, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is
5 further configured to determine the first and second properties of the specimen during the process step.

2736. The system of claim 2735, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein
10 the signature comprises at least one singularity representative of an end of the process step.

2737. The system of claim 2735, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in
15 response to at least one of the determined properties using an in situ control technique during use.

2738. The system of claim 2723, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to
20 move the specimen from the first process chamber to the second process chamber during use.

2739. The system of claim 2723, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the
25 detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during said moving.

2740. The system of claim 2723, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

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2741. The system of claim 2723, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

10 2742. The system of claim 2741, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

15 2743. The system of claim 2723, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

20 2744. The system of claim 2723, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

25 2745. The system of claim 2723, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

2746. The system of claim 2723, wherein the remote controller computer is further configured to generate a database during use, and wherein the database comprises the determined first and second properties of the specimen.

5 2747. The system of claim 2723, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

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2748. The system of claim 2723, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by measurement
15 device using the database during use.

2749. The system of claim 2723, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further
20 comprises first and second properties of a plurality of specimens.

2750. The system of claim 2749, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices,
25 and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

2751. The system of claim 2749, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

2752. The system of claim 2723, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein the plurality of measurement devices is coupled to at least one of a plurality of process tools.

2753. The system of claim 2723, wherein the remote controller computer is further coupled to a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the plurality of process tools during use.

2754. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises overlay misregistration of the specimen, and wherein the second property comprises a flatness measurement of the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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2755. The method of claim 2754, wherein the measurement device is selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

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2756. The method of claim 2754, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a coherence probe microscope, an interferometer, an optical profilometer, a spectroscopic reflectometer, a spectroscopic ellipsometer, a dual beam spectrophotometer, a beam profile ellipsometer, a non-imaging scatterometer, a scatterometer, a spectroscopic

scatterometer, a reflectometer, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2757. The method of claim 2754, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2758. The method of claim 2754, wherein the remote controller computer is further coupled to a process tool.

2759. The method of claim 2754, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool is comprises a lithography tool.

2760. The method of claim 2754, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the flatness measurement of the specimen prior to an exposure step of the lithography process and determining the overlay misregistration subsequent to the exposure step of the lithography process.

2761. The method of claim 2754, wherein the remote controller computer is further coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedback control technique.

2762. The method of claim 2754, wherein the remote controller computer is further coupled to a process tool, the method further comprising altering a parameter of one or

more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

- 5 2763. The method of claim 2754, wherein the remote controller computer is further coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

- 10 2764. The method of claim 2763, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

- 15 2765. The method of claim 2764, further comprising altering a parameter of one or more instruments coupled to the process tool in response to the relationship using the remote controller computer.

- 20 2766. The method of claim 2754, wherein the illumination system and the detection system are coupled to a process chamber of a process tool, the method further comprising performing said directing and said detecting during a process step.

2767. The method of claim 2766, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

- 25 2768. The method of claim 2766, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

2769. The method of claim 2754, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage; and

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performing said directing and said detecting during said moving the specimen.

2770. The method of claim 2754, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

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2771. The method of claim 2754, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

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2772. The method of claim 2771, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

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2773. The method of claim 2754, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

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2774. The method of claim 2754, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

2775. The method of claim 2754, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.

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2776. The method of claim 2754, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

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2777. The method of claim 2754, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring the measurement device using the remote controller computer and the database.

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2778. The method of claim 2754, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

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2779. The method of claim 2778, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

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2780. The method of claim 2778, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further

comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

2781. The method of claim 2754, further comprising sending the at least partially
5 processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

2782. The method of claim 2781, wherein at least one of the plurality of measurement
10 devices is coupled to a process tool.

2783. The method of claim 2782, further comprising altering a parameter of one or more
instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen.

2784. A system configured to determine at least two properties of a specimen during
15 use, comprising:

a stage configured to support the specimen during use;

20 a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the
specimen during use; and

25 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use,

wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on the specimen.

2785. The system of claim 2784, wherein the stage is further configured to move laterally during use.

2786. The system of claim 2784, wherein the stage is further configured to move rotatably during use.

2787. The system of claim 2784, wherein the stage is further configured to move laterally and rotatably during use.

2788. The system of claim 2784, wherein the illumination system comprises a single energy source.

2789. The system of claim 2784, wherein the illumination system comprises more than one energy source.

2790. The system of claim 2784, wherein the detection system comprises a single energy sensitive device.

2791. The system of claim 2784, wherein the detection system comprises more than one energy sensitive devices.

5 2792. The system of claim 2784, wherein the measurement device further comprises a modulated optical reflectometer.

2793. The system of claim 2784, wherein the measurement device further comprises an X-ray reflectance device.

10 2794. The system of claim 2784, wherein the measurement device further comprises an eddy current device.

2795. The system of claim 2784, wherein the measurement device further comprises a photo-acoustic device.

15 2796. The system of claim 2784, wherein the measurement device further comprises a spectroscopic ellipsometer.

20 2797. The system of claim 2784, wherein the measurement device further comprises a spectroscopic reflectometer.

2798. The system of claim 2784, wherein the measurement device further comprises a dual beam spectrophotometer.

25 2799. The system of claim 2784, wherein the measurement device further comprises a non-imaging scatterometer.

2800. The system of claim 2784, wherein the measurement device further comprises a scatterometer.

5 2801. The system of claim 2784, wherein the measurement device further comprises a spectroscopic scatterometer.

2802. The system of claim 2784, wherein the measurement device further comprises a reflectometer.

10 2803. The system of claim 2784, wherein the measurement device further comprises an ellipsometer.

2804. The system of claim 2784, wherein the measurement device further comprises a non-imaging bright field device.

15 2805. The system of claim 2784, wherein the measurement device further comprises a non-imaging dark field device.

20 2806. The system of claim 2784, wherein the measurement device further comprises a non-imaging bright field and dark field device.

2807. The system of claim 2784, wherein the measurement device further comprises a bright field imaging device.

25 2808. The system of claim 2784, wherein the measurement device further comprises a dark field imaging device.

2809. The system of claim 2784, wherein the measurement device further comprises a bright field and dark field imaging device.

2810. The system of claim 2784, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2811. The system of claim 2784, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

2812. The system of claim 2784, wherein the measurement device further comprises non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the specimen.

2813. The system of claim 2784, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a concentration of ions in the implanted region, a depth of the implanted region, and a distribution profile of the implanted region.

2814. The system of claim 2784, wherein the defects comprise micro defects and macro defects.

5 2815. The system of claim 2784, wherein the defects comprises micro defects or macro defects.

2816. The system of claim 2784, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom
10 surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

2817. The system of claim 2816, wherein the defects comprise macro defects.

15 2818. The system of claim 2784, wherein the system is further configured to determine at least the two properties of the specimen substantially simultaneously during use.

2819. The system of claim 2784, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially
20 simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

25 2820. The system of claim 2784, wherein the system is coupled to a process tool.

2821. The system of claim 2784, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

2822. The system of claim 2784, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

5 2823. The system of claim 2784, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

2824. The system of claim 2784, wherein the system is coupled to a process tool, and
10 wherein the stage is configured to move the specimen from the system to the process tool during use.

2825. The system of claim 2784, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the
15 process tool during use.

2826. The system of claim 2784, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.
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2827. The system of claim 2784, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.
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2828. The system of claim 2784, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen

during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

5 2829. The system of claim 2784, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

10 2830. The system of claim 2784, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

15 2831. The system of claim 2784, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

20 2832. The system of claim 2784, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

25 2833. The system of claim 2784, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

2834. The system of claim 2784, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

- 5 2835. The system of claim 2834, wherein the processor is further configured to determine at least the two properties of the specimen during the process step.

2836. The system of claim 2835, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises
10 at least one singularity representative of an end of the process step.

2837. The system of claim 2835, wherein the processor is further coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ
15 control technique during use.

2838. The system of claim 2784, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during
20 use.

2839. The system of claim 2838, wherein the system is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.
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2840. The system of claim 2784, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

2841. The system of claim 2784, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

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2842. The system of claim 2841, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

10 2843. The system of claim 2784, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

15 2844. The system of claim 2784, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

20 2845. The system of claim 2784, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

25 2846. The system of claim 2784, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen.

2847. The system of claim 2784, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second

properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

5 2848. The system of claim 2784, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

10 2849. The system of claim 2784, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

15 2850. The system of claim 2849, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

20 2851. The system of claim 2849, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

25 2852. The system of claim 2784, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration

standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

5 2853. The system of claim 2784, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

10 2854. The system of claim 2784, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on
15 the specimen to reduce within wafer variation of at least one of the determined properties.

20 2855. The system of claim 2784, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

25 2856. The system of claim 2784, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

2857. The system of claim 2784, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

- 5 2858. The system of claim 2857, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

2859. The system of claim 2858, wherein the processor is further configured to alter a
10 parameter of one or more instruments in response to the relationship during use.

2860. The system of claim 2784, wherein the processor is further coupled to a plurality of measurement devices, and wherein the processor is further configured to alter a
15 parameter of one or more instruments coupled to at least one of the plurality of measurement devices during use.

2861. The system of claim 2784, wherein the processor is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to at least one of a plurality of process tools.
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2862. The system of claim 2861, wherein the processor is further coupled to at least one of the plurality of process tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.
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2863. The system of claim 2784, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or

more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

5 2864. The system of claim 2863, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

2865. The system of claim 2863, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

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2866. A method for determining at least two properties of a specimen, comprising:

15 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

20 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

25 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on the specimen.

2867. The method of claim 2866, further comprising laterally moving the stage during said directing energy and said detecting energy.

5 2868. The method of claim 2866, further comprising rotatably moving the stage during said directing energy and said detecting energy.

2869. The method of claim 2866, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

10 2870. The method of claim 2866, wherein the illumination system comprises a single energy source.

2871. The method of claim 2866, wherein the illumination system comprises more than one energy source.

15 2872. The method of claim 2866, wherein the detection system comprises a single energy sensitive device.

20 2873. The method of claim 2866, wherein the detection system comprises more than one energy sensitive devices.

2874. The method of claim 2866, wherein the measurement device further comprises a modulated optical reflectometer.

25 2875. The method of claim 2866, wherein the measurement device further comprises an X-ray reflectance device.

2876. The method of claim 2866, wherein the measurement device further comprises an eddy current device.

5 2877. The method of claim 2866, wherein the measurement device further comprises a photo-acoustic device.

2878. The method of claim 2866, wherein the measurement device further comprises a spectroscopic ellipsometer.

10 2879. The method of claim 2866, wherein the measurement device further comprises a spectroscopic reflectometer.

2880. The method of claim 2866, wherein the measurement device further comprises a dual beam spectrophotometer.

15 2881. The method of claim 2866, wherein the measurement device further comprises a non-imaging scatterometer.

20 2882. The method of claim 2866, wherein the measurement device further comprises a scatterometer.

2883. The method of claim 2866, wherein the measurement device further comprises a spectroscopic scatterometer.

25 2884. The method of claim 2866, wherein the measurement device further comprises a reflectometer.

2885. The method of claim 2866, wherein the measurement device further comprises an ellipsometer.

5 2886. The method of claim 2866, wherein the measurement device further comprises a non-imaging bright field device.

2887. The method of claim 2866, wherein the measurement device further comprises a non-imaging dark field device.

10 2888. The method of claim 2866, wherein the measurement device further comprises a non-imaging bright field and dark field device.

2889. The method of claim 2866, wherein the measurement device further comprises a bright field imaging device.

15 2890. The method of claim 2866, wherein the measurement device further comprises a dark field imaging device.

20 2891. The method of claim 2866, wherein the measurement device further comprises a bright field and dark field imaging device.

2892. The method of claim 2866, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-

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imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

5 2893. The method of claim 2866, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 2894. The method of claim 2866, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the specimen.

15 2895. The method of claim 2866, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a concentration of ions in the implanted region, a depth of ions in the implanted region, and a distribution profile of the implanted region.

20 2896. The method of claim 2866, wherein the defects comprise micro defects and macro defects.

2897. The method of claim 2866, wherein the defects comprises micro defects or macro defects.

25 2898. The method of claim 2866, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

5 2899. The method of claim 2898, wherein the defects comprise macro defects.

2900. The method of claim 2866, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

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2901. The method of claim 2866, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple

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2902. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool.

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2903. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

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2904. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

2905. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

5 2906. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

10 2907. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

15 2908. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

20 2909. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

25 2910. The method of claim 2866, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

2911. The method of claim 2866, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

- 5 2912. The method of claim 2866, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

- 10 2913. The method of claim 2866, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

- 15 2914. The method of claim 2866, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

- 20 2915. The method of claim 2866, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

2916. The method of claim 2915, further comprising performing said directing and said detecting during the process step.

- 25 2917. The method of claim 2916, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

2918. The method of claim 2916, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

5 2919. The method of claim 2866, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

10 2920. The method of claim 2919, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

15 2921. The method of claim 2866, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

2922. The method of claim 2866, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

20 2923. The method of claim 2922, further comprising generating an output signal if at least one of the determined properties of the specimen are outside of the predetermined range for the property.

25 2924. The method of claim 2866, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

2925. The method of claim 2866, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

- 5 2926. The method of claim 2866, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

- 10 2927. The method of claim 2866, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

- 15 2928. The method of claim 2866, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

- 20 2929. The method of claim 2866, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

- 25 2930. The method of claim 2929, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

2931. The method of claim 2929, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further

comprising monitoring output signals of the plurality of measurement devices using the database.

2932. The method of claim 2866, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

2933. The method of claim 2866, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

2934. The method of claim 2866, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

2935. The method of claim 2866, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedback control technique.

2936. The method of claim 2866, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedforward control technique.

2937. The method of claim 2866, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

- 5 2938. The method of claim 2937, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

2939. The method of claim 2938, further comprising altering the parameter of the instrument in response to the relationship.

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2940. The method of claim 2866, further comprising altering a parameter of one or more instruments coupled to each of a plurality of process tools in response to at least one of the determined properties.

- 15 2941. The method of claim 2866, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

2942. The method of claim 2941, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

2943. The method of claim 2941, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

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2944. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

10 controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

15 controlling the illumination system to direct energy toward a surface of the specimen;

 controlling the detection system to detect energy propagating from the surface of the specimen; and

20 generating one or more output signals responsive to the detected energy; and

 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a
25 characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on the specimen.

2945. The method of claim 2944, further comprising controlling the stage, wherein the stage is configured to support the specimen.

5 2946. The method of claim 2944, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

2947. The method of claim 2944, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

10 2948. The method of claim 2944, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

2949. The method of claim 2944, wherein the illumination system comprises a single energy source.

15 2950. The method of claim 2944, wherein the illumination system comprises more than one energy source.

20 2951. The method of claim 2944, wherein the detection system comprises a single energy sensitive device.

2952. The method of claim 2944, wherein the detection system comprises more than one energy sensitive devices.

25 2953. The method of claim 2944, wherein the measurement device further comprises a modulated optical reflectometer.

2954. The method of claim 2944, wherein the measurement device further comprises an X-ray reflectance device.

5 2955. The method of claim 2944, wherein the measurement device further comprises an eddy current device.

2956. The method of claim 2944, wherein the measurement device further comprises a photo-acoustic device.

10 2957. The method of claim 2944, wherein the measurement device further comprises a spectroscopic ellipsometer.

2958. The method of claim 2944, wherein the measurement device further comprises a spectroscopic reflectometer.

15 2959. The method of claim 2944, wherein the measurement device further comprises a dual beam spectrophotometer.

20 2960. The method of claim 2944, wherein the measurement device further comprises a non-imaging scatterometer.

2961. The method of claim 2944, wherein the measurement device further comprises a scatterometer.

25 2962. The method of claim 2944, wherein the measurement device further comprises a spectroscopic scatterometer.

2963. The method of claim 2944, wherein the measurement device further comprises a reflectometer.

5 2964. The method of claim 2944, wherein the measurement device further comprises an ellipsometer.

2965. The method of claim 2944, wherein the measurement device further comprises a non-imaging bright field device.

10 2966. The method of claim 2944, wherein the measurement device further comprises a non-imaging dark field device.

2967. The method of claim 2944, wherein the measurement device further comprises a non-imaging bright field and dark field device.

15 2968. The method of claim 2944, wherein the measurement device further comprises a bright field imaging device.

20 2969. The method of claim 2944, wherein the measurement device further comprises a dark field imaging device.

2970. The method of claim 2944, wherein the measurement device further comprises a bright field and dark field imaging device.

25 2971. The method of claim 2944, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-

acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field
5 imaging device, a dark field imaging device, and a bright field and dark field imaging device.

2972. The method of claim 2944, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical
10 elements of the first measurement device comprise optical elements of the second measurement device.

2973. The method of claim 2944, wherein the measurement device further comprises non-optical components, and wherein controlling the detection system to detect energy
15 comprises controlling the non-optical components to measure a non-optical characteristic of the specimen.

2974. The method of claim 2944, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a
20 concentration of ions in the implanted region, a depth of the implanted region, and a distribution profile of the implanted region.

2975. The method of claim 2944, wherein the defects comprise micro defects and macro defects.
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2976. The method of claim 2944, wherein the defects comprises micro defects or macro defects.

2977. The method of claim 2944, further comprising:

controlling the illumination system to direct energy toward a bottom surface of the specimen; and

controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

10 2978. The method of claim 2977, wherein the defects comprise macro defects.

2979. The method of claim 2944, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

15 2980. The method of claim 2944, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two
20 properties of the specimen can be determined at the multiple locations substantially simultaneously.

2981. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool.

2982. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

2983. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

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2984. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

10 2985. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

15 2986. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

20 2987. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

25 2988. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

2989. The method of claim 2944, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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2990. The method of claim 2944, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 2991. The method of claim 2944, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 2992. The method of claim 2944, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

20 2993. The method of claim 2944, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

2994. The method of claim 2944, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

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2995. The method of claim 2994, further comprising controlling the illumination system and controlling the detection system during the process step.

2996. The method of claim 2994, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

- 5 2997. The method of claim 2994, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

- 10 2998. The method of claim 2944, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 15 2999. The method of claim 2998, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

- 20 3000. The method of claim 2944, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

3001. The method of claim 2944, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

- 25 3002. The method of claim 3001, further comprising generating an output signal if at least one of the determined properties of the specimen are outside of the predetermined range for the property.

3003. The method of claim 2944, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

5 3004. The method of claim 2944, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

10 3005. The method of claim 2944, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

15 3006. The method of claim 2944, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

20 3007. The method of claim 2944, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

25 3008. The method of claim 2944, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

3009. The method of claim 3008, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

5 3010. The method of claim 3008, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

10 3011. The method of claim 2944, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

15 3012. The method of claim 2944, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

20 3013. The method of claim 2944, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least
25 one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3014. The method of claim 2944, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedback control technique.

- 5 3015. The method of claim 2944, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedforward control technique.

3016. The method of claim 2944, further comprising monitoring a parameter of one or
10 more instruments coupled to the process tool.

3017. The method of claim 3016, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

- 15 3018. The method of claim 3017, further comprising altering a parameter of at least one of the instruments in response to the relationship.

3019. The method of claim 2944, further comprising altering a parameter of one or more instruments coupled to each of a plurality of process tools in response to at least one of
20 the determined properties of the specimen.

3020. The method of claim 2944, wherein processing the one or more output signals comprises:

- 25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

3021. The method of claim 3020, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

3022. The method of claim 3020, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

3023. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on the specimen.

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3024. The device of claim 3023, wherein the illumination system comprises a single energy source.

3025. The device of claim 3023, wherein the illumination system comprises more than
10 one energy source.

3026. The device of claim 3023, wherein the detection system comprises a single energy sensitive device.

15 3027. The device of claim 3023, wherein the detection system comprises more than one energy sensitive devices.

3028. The device of claim 3023, wherein the measurement device further comprises a modulated optical reflectometer.

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3029. The device of claim 3023, wherein the measurement device further comprises an X-ray reflectance device.

25 3030. The device of claim 3023, wherein the measurement device further comprises an eddy current device.

3031. The device of claim 3023, wherein the measurement device further comprises a photo-acoustic device.

3032. The device of claim 3023, wherein the measurement device further comprises a spectroscopic ellipsometer.

5 3033. The device of claim 3023, wherein the measurement device further comprises a spectroscopic reflectometer.

3034. The device of claim 3023, wherein the measurement device further comprises a dual beam spectrophotometer.

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3035. The device of claim 3023, wherein the measurement device further comprises a non-imaging scatterometer.

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3036. The device of claim 3023, wherein the measurement device further comprises a scatterometer.

3037. The device of claim 3023, wherein the measurement device further comprises a spectroscopic scatterometer.

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3038. The device of claim 3023, wherein the measurement device further comprises a reflectometer.

3039. The device of claim 3023, wherein the measurement device further comprises an ellipsometer.

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3040. The device of claim 3023, wherein the measurement device further comprises a non-imaging bright field device.

3041. The device of claim 3023, wherein the measurement device further comprises a non-imaging dark field device.

5 3042. The device of claim 3023, wherein the measurement device further comprises a non-imaging bright field and dark field device.

3043. The device of claim 3023, wherein the measurement device further comprises a bright field imaging device.

10 3044. The device of claim 3023, wherein the measurement device further comprises a dark field imaging device.

3045. The device of claim 3023, wherein the measurement device further comprises a bright field and dark field imaging device.

15 3046. The device of claim 3023, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-
20 acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging
25 device.

3047. The device of claim 3023, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical

elements of the first measurement device comprise optical elements of the second measurement device.

5 3048. The device of claim 3023, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the specimen.

10 3049. The device of claim 3023, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a concentration of ions in the implanted region, a depth of the implanted region, and a distribution profile of the implanted region.

15 3050. The device of claim 3023, wherein the defects comprise micro defects and macro defects.

3051. The device of claim 3023, wherein the defects comprises micro defects or macro defects.

20 3052. The device of claim 3023, further comprising:

directing energy toward a bottom surface of the specimen; and

25 detecting energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

3053. The device of claim 3052, wherein the defects comprise macro defects.

3054. The device of claim 3023, wherein the stage and the measurement device are coupled to a process tool.

3055. The device of claim 3023, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

3056. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on the specimen.

3057. The method of claim 3056, wherein the illumination system comprises a single energy source.

5 3058. The method of claim 3056, wherein the illumination system comprises more than one energy source.

3059. The method of claim 3056, wherein the detection system comprises a single energy sensitive device.

10 3060. The method of claim 3056, wherein the detection system comprises more than one energy sensitive devices.

3061. The method of claim 3056, wherein the measurement device is selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a
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20 bright field and dark field imaging device.

3062. The method of claim 3056, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated
25 optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-

imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

5 3063. The method of claim 3056, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 3064. The method of claim 3056, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the specimen.

15 3065. The method of claim 3056, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a concentration of ions in the implanted region, a depth of the implanted region, and a distribution profile of the implanted region.

20 3066. The method of claim 3056, wherein the defects comprise micro defects and macro defects.

3067. The method of claim 3056, wherein the defects comprises micro defects or macro defects.

25 3068. The method of claim 3056, further comprising:

directing energy toward a bottom surface of the specimen; and

detecting energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

5 3069. The method of claim 3068, wherein the defects comprise macro defects.

3070. The method of claim 3056, wherein the stage and the measurement device are coupled to a process tool.

10 3071. The method of claim 3056, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

15 3072. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

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an illumination system configured to direct energy toward a surface of the specimen during use; and

25

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

5 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on
10 the specimen.

3073. The system of claim 3072, wherein the measurement device is selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a
15 spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

20 3074. The system of claim 3072, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-
25 acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field

imaging device, a dark field imaging device, and a bright field and dark field imaging device.

5 3075. The system of claim 3072, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 3076. The system of claim 3072, wherein the measurement device further comprises non-optical components, and wherein the detected energy is responsive to a non-optical characteristic of the specimen.

15 3077. The system of claim 3072, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a concentration of ions in the implanted region, a depth of the implanted region, and a distribution of the implanted region.

20 3078. The system of claim 3072, wherein the defects comprise micro defects and macro defects.

3079. The system of claim 3072, wherein the defects comprises micro defects or macro defects.

25 3080. The system of claim 3072, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

3081. The system of claim 3072, wherein the defects comprise macro defects.

5 3082. The system of claim 3072, wherein the remote controller computer is further coupled to a process tool.

10 3083. The system of claim 3072, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

15 3084. The system of claim 3072, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

20 3085. The system of claim 3072, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

25 3086. The system of claim 3072, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

3087. The system of claim 3086, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

5 3088. The system of claim 3087, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

10 3089. The system of claim 3072, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

15 3090. The system of claim 3089, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

20 3091. The system of claim 3089, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

25 3092. The system of claim 3072, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to

move the specimen from the first process chamber to the second process chamber during use.

3093. The system of claim 3092, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during said moving.

3094. The system of claim 3072, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

3095. The system of claim 3072, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

3096. The system of claim 3095, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

3097. The system of claim 3072, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

3098. The system of claim 3072, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement

device in response to at least one of the determined properties using a feedback control technique during use.

5 3099. The system of claim 3072, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

10 3100. The system of claim 3072, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

15 3101. The system of claim 3072, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

20 3102. The system of claim 3072, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, wherein the database further comprises first and second properties of a plurality of specimens, and wherein the first
25 and second properties of the plurality of specimens are determined using a plurality of measurement devices.

3103. The system of claim 3102, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

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3104. The system of claim 3102, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

10

3105. The system of claim 3072, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to a process tool.

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3106. The system of claim 3072, wherein the remote controller computer is further coupled to a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

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3107. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

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directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

5

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a characteristic of an implanted region of the specimen, and wherein the second property comprises a presence of defects on the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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3108. The method of claim 3107, wherein the measurement device is selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, a dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

25

3109. The method of claim 3107, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a modulated optical reflectometer, an X-ray reflectance device, an eddy current device, a photo-acoustic device, a spectroscopic ellipsometer, a spectroscopic reflectometer, a dual beam spectrophotometer, a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, an ellipsometer, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a bright field imaging device, a dark field imaging device, and a bright field and dark field imaging device.

3110. The method of claim 3107, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

3111. The method of claim 3107, wherein the measurement device further comprises non-optical components, and wherein detecting energy comprises measuring a non-optical characteristic of the specimen.

3112. The method of claim 3107, wherein the characteristic of the implanted region is selected from the group consisting of a presence of ions in the implanted region, a concentration of ions in the implanted region, a depth of the implanted region, and a distribution profile of the implanted region.

3113. The method of claim 3107, wherein the defects comprise micro defects and macro defects.

3114. The method of claim 3107, wherein the defects comprises micro defects or macro defects.

5 3115. The method of claim 3107, further comprising:

directing energy toward a bottom surface of the specimen; and

10 detecting energy propagating from the bottom surface of the specimen, wherein the second property further comprises a presence of defects on the bottom surface of the specimen.

3116. The method of claim 3115, wherein the defects comprise macro defects.

15 3117. The method of claim 3107, wherein the remote controller computer is coupled to a process tool.

20 3118. The method of claim 3107, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of an ion implanter and a thermal tool.

3119. The method of claim 3107, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedback control technique.

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3120. The method of claim 3107, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

3121. The method of claim 3107, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

3122. The method of claim 3121, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

3123. The method of claim 3122, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

3124. The method of claim 3107, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, the method further comprising performing said directing and said detecting during a process step.

3125. The method of claim 3124, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

3126. The method of claim 3124, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

3127. The method of claim 3107, further comprising:

moving the specimen from a first process chamber to a second process chamber
using the stage; and

performing said directing and said detecting during said moving the specimen.

3128. The method of claim 3107, further comprising comparing at least one of the
determined properties of the specimen and determined properties of a plurality of
specimens using the remote controller computer.

3129. The method of claim 3107, further comprising comparing at least one of the
determined properties to a predetermined range for the property using the remote
controller computer.

3130. The method of claim 3129, further comprising generating an output signal using
the remote controller computer if at least one of the determined properties of the
specimen is outside of the predetermined range for the property.

3131. The method of claim 3107, wherein the remote controller computer is coupled to
the measurement device.

3132. The method of claim 3107, wherein the remote controller computer is coupled to
the measurement device, the method further comprising altering a sampling frequency of
the measurement device using the remote controller computer in response to at least one
of the determined properties of the specimen.

3133. The method of claim 3107, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control
5 technique.

3134. The method of claim 3107, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller
10 computer in response to at least one of the determined properties using a feedforward control technique.

3135. The method of claim 3107, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and
15 second properties of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

3136. The method of claim 3107, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and
20 second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the remote controller computer and the database.

3137. The method of claim 3107, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and
25 second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

3138. The method of claim 3137, wherein the determined first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

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3139. The method of claim 3137, wherein the determined first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

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3140. The method of claim 3107, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

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3141. The method of claim 3140, wherein at least one of the plurality of measurement devices is coupled to a process tool.

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3142. The method of claim 3107, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools using the remote controller computer in response to at least one of the determined properties of the specimen.

3143. A system configured to determine at least two properties of a specimen during use, comprising:

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a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

5 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

10 a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises an adhesion characteristic of the specimen, and wherein the second property comprises a thickness of the specimen.

15 3144. The system of claim 3143, wherein the stage is further configured to move laterally during use.

20 3145. The system of claim 3143, wherein the stage is further configured to move rotatably during use.

3146. The system of claim 3143, wherein the stage is further configured to move laterally and rotatably during use.

25 3147. The system of claim 3143, wherein the measurement device further comprises a photo-acoustic device.

3148. The system of claim 3143, wherein the measurement device further comprises a spectroscopic ellipsometer.

5 3149. The system of claim 3143, wherein the measurement device further comprises an ellipsometer.

3150. The system of claim 3143, wherein the measurement device further comprises an X-ray reflectometer.

10 3151. The system of claim 3143, wherein the measurement device further comprises a grazing X-ray reflectometer.

15 3152. The system of claim 3143, wherein the measurement device further comprises an X-ray diffractometer.

3153. The system of claim 3143, wherein the measurement device further comprises a photo-acoustic device and an ellipsometer.

20 3154. The system of claim 3143, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

25 3155. The system of claim 3143, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein elements of the first measurement device comprise elements of the second measurement device.

3156. The system of claim 3143, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3157. The system of claim 3156, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

3158. The system of claim 3143, wherein the system is further configured to determine at least two properties of the specimen substantially simultaneously during use.

3159. The system of claim 3143, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

3160. The system of claim 3143, wherein the system is coupled to a process tool.

3161. The system of claim 3143, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

3162. The system of claim 3143, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

3163. The system of claim 3143, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

5 3164. The system of claim 3143, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

3165. The system of claim 3143, wherein the system is coupled to a process tool, and
10 wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

3166. The system of claim 3143, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the
15 specimen while the specimen is waiting between process steps.

3167. The system of claim 3143, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially
20 parallel to an upper surface of the stage.

3168. The system of claim 3143, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to
25 an upper surface of the support device.

3169. The system of claim 3143, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion

implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

5 3170. The system of claim 3143, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 3171. The system of claim 3143, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 3172. The system of claim 3143, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

20 3173. The system of claim 3143, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

25 3174. The system of claim 3143, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

3175. The system of claim 3174, wherein the processor is further configured to determine at least the two properties of the specimen during the process step.

5 3176. The system of claim 3174, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

10 3177. The system of claim 3174, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

15 3178. The system of claim 3143, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

20 3179. The system of claim 3178, wherein the system is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

25 3180. The system of claim 3143, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

3181. The system of claim 3143, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

3182. The system of claim 3181, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

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3183. The system of claim 3143, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

10 3184. The system of claim 3143, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

15 3185. The system of claim 3143, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

20 3186. The system of claim 3143, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

25 3187. The system of claim 3143, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

3188. The system of claim 3143, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

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3189. The system of claim 3188, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

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3190. The system of claim 3188, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

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3191. The system of claim 3143, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

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3192. The system of claim 3143, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

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3193. The system of claim 3143, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3194. The system of claim 3143, wherein the processor is further coupled to a process tool.

3195. The system of claim 3143, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

3196. The system of claim 3143, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

3197. The system of claim 3143, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

3198. The system of claim 3197, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

3199. The system of claim 3198, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

3200. The system of claim 3143, wherein the processor is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to a process tool.

3201. The system of claim 3143, wherein the processor is further coupled to a plurality of process tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

3202. The system of claim 3143, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

3203. The system of claim 3202, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

3204. The system of claim 3202, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

3205. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises an adhesion characteristic of the specimen, and wherein the second property comprises a thickness of the specimen.

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3206. The method of claim 3205, further comprising laterally moving the stage during said directing energy and said detecting energy.

20 3207. The method of claim 3205, further comprising rotatably moving the stage during said directing energy and said detecting energy.

3208. The method of claim 3205, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

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3209. The method of claim 3205, wherein the measurement device further comprises a photo-acoustic device.

3210. The method of claim 3205, wherein the measurement device further comprises a spectroscopic ellipsometer.

5 3211. The method of claim 3205, wherein the measurement device further comprises an ellipsometer.

3212. The method of claim 3205, wherein the measurement device further comprises an X-ray reflectometer.

10 3213. The method of claim 3205, wherein the measurement device further comprises a grazing X-ray reflectometer.

3214. The method of claim 3205, wherein the measurement device further comprises an X-ray diffractometer.

15 3215. The method of claim 3205, wherein the measurement device further comprises a photo-acoustic device and an ellipsometer.

20 3216. The method of claim 3205, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

25 3217. The method of claim 3205, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

3218. The method of claim 3205, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3219. The method of claim 3218, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

3220. The method of claim 3205, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

3221. The method of claim 3205, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

3222. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool.

3223. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

3224. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

5 3225. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

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3226. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

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3227. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

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3228. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

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3229. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

3230. The method of claim 3205, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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3231. The method of claim 3205, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 3232. The method of claim 3205, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 3233. The method of claim 3205, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

20 3234. The method of claim 3205, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

25 3235. The method of claim 3205, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

3236. The method of claim 3235, further comprising performing said directing and said detecting during the process step.

3237. The method of claim 3236, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

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3238. The method of claim 3236, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

10 3239. The method of claim 3205, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

15 3240. The method of claim 3239, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

20 3241. The method of claim 3205, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

3242. The method of claim 3205, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

25 3243. The method of claim 3242, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

3244. The method of claim 3205, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

5 3245. The method of claim 3205, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

3246. The method of claim 3205, further comprising altering a parameter of one or more
10 instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

3247. The method of claim 3205, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the
15 method further comprising calibrating the measurement device using the database.

3248. The method of claim 3205, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using
20 the database.

3249. The method of claim 3205, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of
25 specimens.

3250. The method of claim 3249, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

5 3251. The method of claim 3249, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

10 3252. The method of claim 3205, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

15 3253. The method of claim 3205, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

20 3254. The method of claim 3205, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one
25 of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3255. The method of claim 3205, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

- 5 3256. The method of claim 3205, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

3257. The method of claim 3205, further comprising monitoring a parameter of one or
10 more instruments coupled to the process tool.

3258. The method of claim 3257, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

- 15 3259. The method of claim 3258, further comprising altering a parameter of at least one of the instruments in response to the relationship.

3260. The method of claim 3205, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the
20 determined properties of the specimen.

3261. The method of claim 3205, wherein processing the one or more output signals comprises:

- 25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

5 further processing the partially processed one or more output signals using the remote controller computer.

3262. The method of claim 3261, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

10 3263. The method of claim 3261, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

15 3264. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

20 controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

controlling the illumination system to direct energy toward a surface of the specimen;

25 controlling the detection system to detect energy propagating from the surface of the specimen; and

generating one or more output signals responsive to the detected energy;
and

5 processing the one or more output signals to determine a first property and a
second property of the specimen, wherein the first property comprises an adhesion
characteristic of the specimen, and wherein the second property comprises a
thickness of the specimen.

10 3265. The method of claim 3264, further comprising controlling the stage, wherein the
stage is configured to support the specimen.

3266. The method of claim 3264, further comprising controlling the stage to laterally
move the stage during said directing energy and said detecting energy.

15 3267. The method of claim 3264, further comprising controlling the stage to rotatably
move the stage during said directing energy and said detecting energy.

3268. The method of claim 3264, further comprising controlling the stage to laterally
and rotatably move the stage during said directing energy and said detecting energy.

20 3269. The method of claim 3264, wherein the measurement device further comprises a
photo-acoustic device.

25 3270. The method of claim 3264, wherein the measurement device further comprises a
spectroscopic ellipsometer.

3271. The method of claim 3264, wherein the measurement device further comprises an
ellipsometer.

3272. The method of claim 3264, wherein the measurement device further comprises an X-ray reflectometer.

5 3273. The method of claim 3264, wherein the measurement device further comprises a grazing X-ray reflectometer.

3274. The method of claim 3264, wherein the measurement device further comprises an X-ray diffractometer.

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3275. The method of claim 3264, wherein the measurement device further comprises a photo-acoustic device and an ellipsometer.

15

3276. The method of claim 3264, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

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3277. The method of claim 3264, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

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3278. The method of claim 3264, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3279. The method of claim 3278, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

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3280. The method of claim 3264, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

10 3281. The method of claim 3264, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially
15 simultaneously.

3282. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool.

20 3283. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

3284. The method of claim 3264, wherein the stage and the measurement device are
25 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

3285. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, and ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3286. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

3287. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

3288. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

3289. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

3290. The method of claim 3264, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured

to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

5 3291. The method of claim 3264, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

10 3292. The method of claim 3264, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

15 3293. The method of claim 3264, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

20 3294. The method of claim 3264, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

25 3295. The method of claim 3264, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

3296. The method of claim 3295, further comprising controlling the illumination system and controlling the detection system during the process step.

3297. The method of claim 3296, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

- 5 3298. The method of claim 3264, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

- 10 3299. The method of claim 3264, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 15 3300. The method of claim 3299, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

- 20 3301. The method of claim 3264, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

3302. The method of claim 3264, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

- 25 3303. The method of claim 3302, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

3304. The method of claim 3264, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

5 3305. The method of claim 3264, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

10 3306. The method of claim 3264, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

15 3307. The method of claim 3264, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

20 3308. The method of claim 3264, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

25 3309. The method of claim 3264, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

3310. The method of claim 3309, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

5 3311. The method of claim 3309, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

10 3312. The method of claim 3264, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

15 3313. The method of claim 3264, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

20 3314. The method of claim 3264, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least
25 one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3315. The method of claim 3264, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

- 5 3316. The method of claim 3264, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

- 10 3317. The method of claim 3264, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

3318. The method of claim 3317, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

- 15 3319. The method of claim 3317, further comprising altering a parameter of at least one of the instruments in response to the relationship.

- 20 3320. The method of claim 3264, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

3321. The method of claim 3264, wherein processing the one or more output signals comprises:

- 25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

3322. The method of claim 3321, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

3323. The method of claim 3321, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

3324. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the portion of the semiconductor device, wherein the first property comprises an adhesion characteristic on the portion of the specimen, and wherein the second property comprises a thickness of the portion of the specimen.

5

3325. The device of claim 3324, wherein the measurement device further comprises a photo-acoustic device.

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3326. The device of claim 3324, wherein the measurement device further comprises a spectroscopic ellipsometer.

3327. The device of claim 3324, wherein the measurement device further comprises an ellipsometer.

15

3328. The device of claim 3324, wherein the measurement device further comprises an X-ray reflectometer.

3329. The device of claim 3324, wherein the measurement device further comprises a grazing X-ray reflectometer.

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3330. The device of claim 3324, wherein the measurement device further comprises an X-ray diffractometer.

25

3331. The device of claim 3324, wherein the measurement device further comprises a photo-acoustic device and an ellipsometer.

3332. The device of claim 3324, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first

and second measurement devices are selected from the group consisting of a photo-acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

5 3333. The device of claim 3324, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

10 3334. The method of claim 3324, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15 3335. The method of claim 3334, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20 3336. The device of claim 3324, wherein the stage and the measurement device are coupled to a process tool.

3337. The device of claim 3324, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical
25 vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3338. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a
5 measurement device, and wherein the measurement device comprises an
illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

10 detecting energy propagating from the surface of the specimen using the detection
system;

generating one or more output signals responsive to the detected energy during
use; and

15 processing the one or more output signals to determine a first property and a
second property of the portion of the semiconductor device, wherein the first
property comprises an adhesion characteristic of the portion of the specimen, and
wherein the second property comprises a thickness of the portion of the specimen.

20 3339. The method of claim 3338, wherein the measurement device further comprises a
photo-acoustic device.

3340. The method of claim 3338, wherein the measurement device further comprises a
25 spectroscopic ellipsometer.

3341. The method of claim 3338, wherein the measurement device further comprises an
ellipsometer.

3342. The method of claim 3338, wherein the measurement device further comprises an X-ray reflectometer.

5 3343. The method of claim 3338, wherein the measurement device further comprises a grazing X-ray reflectometer.

3344. The method of claim 3338, wherein the measurement device further comprises an X-ray diffractometer.

10

3345. The method of claim 3338, wherein the measurement device further comprises a photo-acoustic device and an ellipsometer.

15

3346. The method of claim 3338, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

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3347. The method of claim 3338, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

25

3348. The method of claim 3338, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3349. The method of claim 3348, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5

3350. The method of claim 3338, wherein the stage and the measurement device are coupled to a process tool.

3351. The method of claim 3338, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3352. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

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a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

5 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises an adhesion characteristic of the
10 specimen, and wherein the second property comprises a thickness of the specimen.

3353. The system of claim 3352, wherein the measurement device further comprises a photo-acoustic device.

15 3354. The system of claim 3352, wherein the measurement device further comprises a spectroscopic ellipsometer.

3355. The system of claim 3352, wherein the measurement device further comprises an
20 ellipsometer.

3356. The system of claim 3352, wherein the measurement device further comprises an X-ray reflectometer.

25 3357. The system of claim 3352, wherein the measurement device further comprises a grazing X-ray reflectometer.

3358. The system of claim 3352, wherein the measurement device further comprises an X-ray diffractometer.

3359. The system of claim 3352, wherein the measurement device further comprises a
5 photo-acoustic device and an ellipsometer.

3360. The system of claim 3352, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-
10 acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

3361. The system of claim 3352, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least
15 one element of the first measurement device comprises at least one element of the second measurement device.

3362. The system of claim 3352, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially
20 processed one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3363. The system of claim 3362, wherein the system is coupled to a process tool
25 selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

3364. The system of claim 3352, wherein the remote controller computer is further coupled to a process tool.

5 3365. The system of claim 3352, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool is selected from a group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

10 3366. The system of claim 3352, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

15 3367. The system of claim 3352, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control
20 technique during use.

3368. The system of claim 3352, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool
25 during use.

3369. The system of claim 3352, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

5 3370. The system of claim 3369, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

10 3371. The system of claim 3352, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

15 3372. The system of claim 3371, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

20 3373. The system of claim 3371, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

25 3374. The system of claim 3352, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to

move the specimen from the first process chamber to the second process chamber during use.

5 3375. The system of claim 3374, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during said moving.

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3376. The system of claim 3352, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

15 3377. The system of claim 3352, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

20 3378. The system of claim 3377, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen are outside of the predetermined range for the property during use.

25 3379. The system of claim 3352, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

3380. The system of claim 3352, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement

device in response to at least one of the determined properties using a feedback control technique during use.

5 3381. The system of claim 3352, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

10 3382. The system of claim 3352, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

15 3383. The system of claim 3352, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

20 3384. The system of claim 3352, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

25 3385. The system of claim 3384, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, and wherein the remote controller computer is further coupled to the plurality of measurement devices.

3386. The system of claim 3385, wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

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3387. The system of claim 3385, wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

10 3388. The system of claim 3352, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to a process tool.

15 3389. The system of claim 3352, wherein the remote controller computer is further coupled to a plurality of process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

20 3390. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

25 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

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generating one or more output signals responsive to the detected energy; and

5 processing the one or more output signals to determine a first property and a
second property of the specimen, wherein the first property comprises an adhesion
characteristic of the specimen, and wherein the second property comprises a
thickness of the specimen, comprising:

10 at least partially processing the one or more output signals using a local
processor, wherein the local processor is coupled to the measurement
device;

15 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

 further processing the partially processed one or more output signals using
the remote controller computer.

20 3391. The method of claim 3390, wherein the measurement device further comprises a
photo-acoustic device.

3392. The method of claim 3390, wherein the measurement device further comprises a
spectroscopic ellipsometer.

25 3393. The method of claim 3390, wherein the measurement device further comprises an
ellipsometer.

3394. The method of claim 3390, wherein the measurement device further comprises an X-ray reflectometer.

5 3395. The method of claim 3390, wherein the measurement device further comprises a grazing X-ray reflectometer.

3396. The method of claim 3390, wherein the measurement device further comprises an X-ray diffractometer.

10 3397. The method of claim 3390, wherein the measurement device further comprises a photo-acoustic device and an ellipsometer.

15 3398. The method of claim 3390, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, a spectroscopic ellipsometer, an ellipsometer, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, and an eddy current device.

20 3399. The method of claim 3390, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

25 3400. The method of claim 3390, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3401. The method of claim 3400, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 3402. The method of claim 3390, wherein the remote controller computer is coupled to a process tool.

3403. The method of claim 3390, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch
10 tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3404. The method of claim 3390, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more
15 instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedback control technique.

3405. The method of claim 3390, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more
20 instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

25 3406. The method of claim 3390, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

3407. The method of claim 3406, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

- 5 3408. The method of claim 3407, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

3409. The method of claim 3390, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, the method further
10 comprising performing said directing and said detecting during a process step.

3410. The method of claim 3409, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

- 15 3411. The method of claim 3409, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

- 20 3412. The method of claim 3390, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage; and

- 25 performing said directing and said detecting during said moving the specimen.

3413. The method of claim 3390, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

- 5 3414. The method of claim 3390, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

- 10 3415. The method of claim 3414, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen are outside of the predetermined range for the property.

3416. The method of claim 3390, wherein the remote controller computer is coupled to the measurement device.

- 15 3417. The method of claim 3416, further comprising altering a sampling frequency of the measurement device using the remote controller computer in response to at least one of the determined properties of the specimen.

- 20 3418. The method of claim 3416, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

- 25 3419. The method of claim 3416, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.

3420. The method of claim 3390, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

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3421. The method of claim 3390, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the remote controller computer and the database.

10

3422. The method of claim 3390, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

15

3423. The method of claim 3422, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

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3424. The method of claim 3422, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

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3425. The method of claim 3390, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote

controller computer, wherein at least one of the plurality of local processors is coupled to one of a plurality of measurement devices.

5 3426. The method of claim 3425, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to at least one of the determined properties of the specimen.

10 3427. The method of claim 3425, wherein at least one of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

15 3428. The method of claim 3427, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote controller computer in response to at least one of the determined properties of the specimen.

3429. A system configured to determine at least two properties of a specimen during use, comprising:

20 a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

25 an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use,

wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

5 a processor coupled to the measurement device and configured to determine at least a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen.

10 3430. The system of claim 3429, wherein the stage is further configured to move laterally during use.

3431. The system of claim 3429, wherein the stage is further configured to move rotatably during use.

15 3432. The system of claim 3429, wherein the stage is further configured to move laterally and rotatably during use.

20 3433. The system of claim 3429, wherein the measurement device further comprises a photo-acoustic device.

3434. The system of claim 3429, wherein the measurement device further comprises an X-ray reflectometer.

25 3435. The system of claim 3429, wherein the measurement device further comprises a grazing X-ray reflectometer.

3436. The system of claim 3429, wherein the measurement device further comprises an X-ray diffractometer.

5 3437. The system of claim 3429, wherein the measurement device further comprises an eddy current device.

3438. The system of claim 3429, wherein the measurement device further comprises a spectroscopic ellipsometer.

10 3439. The system of claim 3429, wherein the measurement device further comprises an ellipsometer.

3440. The system of claim 3429, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

15 3441. The system of claim 3429, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray
20 diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

3442. The system of claim 3429, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second
25 measurement device.

3443. The system of claim 3429, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during

use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

- 5 3444. The system of claim 3443, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

- 10 3445. The system of claim 3429, wherein the system is further configured to determine at least two properties of the specimen substantially simultaneously during use.

- 15 3446. The system of claim 3429, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

- 20 3447. The system of claim 3429, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool configured to grow an epitaxial layer of silicon on the specimen.

3448. The system of claim 3429, wherein the system is coupled to a process tool.

- 25 3449. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

3450. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

3451. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

3452. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

3453. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

3454. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

3455. The system of claim 3429, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

3456. The system of claim 3429, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

3457. The system of claim 3429, wherein the system is coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3458. The system of claim 3429, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

3459. The system of claim 3429, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

3460. The system of claim 3429, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

3461. The system of claim 3429, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

3462. The system of claim 3429, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

- 5 3463. The system of claim 3462, wherein the processor is further configured to determine at least the two properties of the specimen during the process step.

3464. The system of claim 3463, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises
10 at least one singularity representative of an end of the process step.

3465. The system of claim 3463, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ
15 control technique during use.

3466. The system of claim 3429, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during
20 use.

3467. The system of claim 3466, wherein the system is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.
25

3468. The system of claim 3429, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

3469. The system of claim 3429, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

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3470. The system of claim 3469, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

10 3471. The system of claim 3429, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

15 3472. The system of claim 3429, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

20 3473. The system of claim 3429, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

25 3474. The system of claim 3429, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

3475. The system of claim 3429, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

5

3476. The system of claim 3429, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, wherein the database further comprises first and second properties of a plurality of specimens, and wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices.

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3477. The system of claim 3476, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

15

3478. The system of claim 3476, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

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3479. The system of claim 3429, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

25

3480. The system of claim 3429, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is

further configured to calibrate the system and at least the one additional system during use.

5 3481. The system of claim 3429, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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3482. The system of claim 3429, wherein the processor is further coupled to a process tool.

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3483. The system of claim 3429, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

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3484. The system of claim 3429, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

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3485. The system of claim 3429, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

3486. The system of claim 3485, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

- 5 3487. The system of claim 3486, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

3488. The system of claim 3429, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is
10 coupled to a process tool.

3489. The system of claim 3429, wherein the processor is further coupled to a plurality of process tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during
15 use.

3490. The system of claim 3429, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or
20 more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

3491. The system of claim 3490, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.
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3492. The system of claim 3490, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

3493. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen.

3494. The method of claim 3493, further comprising laterally moving the stage during said directing energy and said detecting energy.

3495. The method of claim 3493, further comprising rotatably moving the stage during said directing energy and said detecting energy.

3496. The method of claim 3493, further comprising laterally and rotatably moving the stage during said directing energy and said detecting energy.

3497. The method of claim 3493, wherein the measurement device further comprises a photo-acoustic device.

5 3498. The method of claim 3493, wherein the measurement device further comprises an X-ray reflectometer.

3499. The method of claim 3493, wherein the measurement device further comprises a grazing X-ray reflectometer.

10 3500. The method of claim 3493, wherein the measurement device further comprises an X-ray diffractometer.

3501. The method of claim 3493, wherein the measurement device further comprises an eddy current device.

15 3502. The method of claim 3493, wherein the measurement device further comprises a spectroscopic ellipsometer.

20 3503. The method of claim 3493, wherein the measurement device further comprises an ellipsometer.

3504. The method of claim 3493, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

25 3505. The method of claim 3493, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-

acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

5 3506. The method of claim 3493, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

10 3507. The method of claim 3493, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

15 3508. The method of claim 3507, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

20 3509. The method of claim 3493, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

25 3510. The method of claim 3493, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

3511. The method of claim 3493, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool configured to grow an epitaxial layer of silicon on the specimen.

5 3512. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool.

3513. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged
10 laterally proximate to the process tool.

3514. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

15 3515. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and
20 a plating tool.

3516. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the
25 process tool to the stage using the wafer handler.

3517. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

- 5 3518. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

- 10 3519. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

- 15 3520. The method of claim 3493, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

- 20 3521. The method of claim 3493, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

- 25 3522. The method of claim 3493, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

3523. The method of claim 3493, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

- 5 3524. The method of claim 3493, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

- 10 3525. The method of claim 3493, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

- 15 3526. The method of claim 3525, further comprising performing said directing and said detecting during the process step.

- 20 3527. The method of claim 3526, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

3528. The method of claim 3526, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

- 25 3529. The method of claim 3493, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

3530. The method of claim 3529, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

- 5 3531. The method of claim 3493, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 10 3532. The method of claim 3493, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

- 15 3533. The method of claim 3532, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 20 3534. The method of claim 3493, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined first and second properties of the specimen.

- 25 3535. The method of claim 3493, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

3536. The method of claim 3493, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

3537. The method of claim 3493, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

5 3538. The method of claim 3493, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

10 3539. The method of claim 3493, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

15 3540. The method of claim 3539, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

20 3541. The method of claim 3539, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

25 3542. The method of claim 3493, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

3543. The method of claim 3493, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

3544. The method of claim 3493, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3545. The method of claim 3493, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

3546. The method of claim 3493, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

3547. The method of claim 3493, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

3548. The method of claim 3547, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

3549. The method of claim 3548, further comprising altering a parameter of at least one of the instruments in response to the relationship.

5 3550. The method of claim 3493, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

3551. The method of claim 3493, wherein processing the one or more output signals comprises:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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3552. The method of claim 3551, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

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3553. The method of claim 3551, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

3554. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, comprising:

5 controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

10 controlling the illumination system to direct energy toward a surface of the specimen;

 controlling the detection system to detect energy propagating from the surface of the specimen; and

15 generating one or more output signals responsive to the detected energy; and

20 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen.

3555. The method of claim 3554, further comprising controlling the stage, wherein the stage is configured to support the specimen.

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3556. The method of claim 3554, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

3557. The method of claim 3554, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

5 3558. The method of claim 3554, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

3559. The method of claim 3554, wherein the measurement device further comprises a photo-acoustic device.

10 3560. The method of claim 3554, wherein the measurement device further comprises an X-ray reflectometer.

3561. The method of claim 3554, wherein the measurement device further comprises a grazing X-ray reflectometer.

15 3562. The method of claim 3554, wherein the measurement device further comprises an X-ray diffractometer.

20 3563. The method of claim 3554, wherein the measurement device further comprises an eddy current device.

3564. The method of claim 3554, wherein the measurement device further comprises a spectroscopic ellipsometer.

25 3565. The method of claim 3554, wherein the measurement device further comprises an ellipsometer.

3566. The method of claim 3554, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

5 3567. The method of claim 3554, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

10 3568. The method of claim 3554, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

15 3569. The method of claim 3554, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20 3570. The method of claim 3569, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

25 3571. The method of claim 3554, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

3572. The method of claim 3554, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two
5 properties of the specimen can be determined at the multiple locations substantially simultaneously.

3573. The method of claim 3554, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool
10 configured to grow an epitaxial layer of silicon on the specimen.

3574. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool.

15 3575. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

3576. The method of claim 3554, wherein the stage and the measurement device are
20 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

3577. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group
25 consisting of an etch tool, an ion implanter, a chemical vapor deposition too, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3578. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

5

3579. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

10 3580. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

15 3581. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

20 3582. The method of claim 3554, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

25 3583. The method of claim 3554, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

3584. The method of claim 3554, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

- 5 3585. The method of claim 3554, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

3586. The method of claim 3554, wherein the stage and the measurement device are
10 disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

3587. The method of claim 3554, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the
15 support device is configured to support the specimen during a process step.

3588. The method of claim 3587, further comprising controlling the illumination system and controlling the detection system during the process step.

- 20 3589. The method of claim 3588, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

3590. The method of claim 3588, further comprising controlling the system to alter a
25 parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

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3591. The method of claim 3554, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 5 3592. The method of claim 3591, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

- 10 3593. The method of claim 3554, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 15 3594. The method of claim 3554, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

3595. The method of claim 3594, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 20 3596. The method of claim 3554, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

- 25 3597. The method of claim 3554, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

3598. The method of claim 3554, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

5 3599. The method of claim 3554, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

10 3600. The method of claim 3554, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

15 3601. The method of claim 3554, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, wherein the database further comprises first and second properties of a plurality of specimens.

20 3602. The method of claim 3601, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

25 3603. The method of claim 3601, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

3604. The method of claim 3554, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand

alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

5 3605. The method of claim 3554, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

10 3606. The method of claim 3554, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the
15 specimen to reduce within wafer variation of at least one of the determined properties.

3607. The method of claim 3554, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedback control technique.

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3608. The method of claim 3554, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen using a feedforward control technique.

25 3609. The method of claim 3554, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

3610. The method of claim 3609, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

5 3611. The method of claim 3610, further comprising altering a parameter of at least one of the instruments in response to the relationship.

3612. The method of claim 3554, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

10 3613. The method of claim 3554, wherein processing the one or more output signals comprises:

15 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

20 further processing the partially processed one or more output signals using the remote controller computer.

3614. The method of claim 3613, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

25 3615. The method of claim 3613, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

3616. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen.

3617. The device of claim 3616, wherein the measurement device further comprises a photo-acoustic device.

3618. The device of claim 3616, wherein the measurement device further comprises an X-ray reflectometer.

3619. The device of claim 3616, wherein the measurement device further comprises a grazing X-ray reflectometer.

5 3620. The device of claim 3616, wherein the measurement device further comprises an X-ray diffractometer.

3621. The device of claim 3616, wherein the measurement device further comprises an eddy current device.

10 3622. The device of claim 3616, wherein the measurement device further comprises a spectroscopic ellipsometer.

3623. The device of claim 3616, wherein the measurement device further comprises an ellipsometer.

15 3624. The device of claim 3616, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

20 3625. The device of claim 3616, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

25 3626. The device of claim 3616, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

3627. The device of claim 3616, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3628. The device of claim 3627, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

3629. The device of claim 3616, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool configured to grow an epitaxial layer of silicon on the specimen.

3630. The device of claim 3616, wherein the stage and the measurement device are coupled to a process tool.

3631. The device of claim 3616, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3632. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen.

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3633. The method of claim 3632, wherein the measurement device further comprises a photo-acoustic device.

20 3634. The method of claim 3632, wherein the measurement device further comprises an X-ray reflectometer.

3635. The method of claim 3632, wherein the measurement device further comprises a grazing X-ray reflectometer.

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3636. The method of claim 3632, wherein the measurement device further comprises an X-ray diffractometer.

3637. The method of claim 3632, wherein the measurement device further comprises an eddy current device.

5 3638. The method of claim 3632, wherein the measurement device further comprises a spectroscopic ellipsometer.

3639. The method of claim 3632, wherein the measurement device further comprises an ellipsometer.

10 3640. The method of claim 3632, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

15 3641. The method of claim 3632, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

20 3642. The method of claim 3632, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

25 3643. The method of claim 3632, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool configured to grow an epitaxial layer of silicon on the specimen.

3644. The method of claim 3632, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

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3645. The method of claim 3644, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

10 3646. The method of claim 3632, wherein the stage and the measurement device are coupled to a process tool.

3647. The method of claim 3632, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group

15 consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3648. A system configured to determine at least two properties of a specimen during
20 use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

25

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

5

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

10

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during use, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen.

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3649. The system of claim 3648, wherein the measurement device further comprises a photo-acoustic device.

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3650. The system of claim 3648, wherein the measurement device further comprises an X-ray reflectometer.

3651. The system of claim 3648, wherein the measurement device further comprises a grazing X-ray reflectometer.

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3652. The system of claim 3648, wherein the measurement device further comprises an X-ray diffractometer.

3653. The system of claim 3648, wherein the measurement device further comprises an eddy current device.

5 3654. The system of claim 3648, wherein the measurement device further comprises a spectroscopic ellipsometer.

3655. The system of claim 3648, wherein the measurement device further comprises an ellipsometer.

10 3656. The system of claim 3648, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

15 3657. The system of claim 3648, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

20 3658. The system of claim 3648, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

25 3659. The system of claim 3648, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially processed one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3660. The system of claim 3659, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5

3661. The system of claim 3648, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool configured to grow an epitaxial layer of silicon on the specimen.

10 3662. The system of claim 3648, wherein the remote controller computer is further coupled to a process tool.

3663. The system of claim 3648, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool is selected from a group consisting
15 of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

3664. The system of claim 3648, wherein the remote controller computer is further
20 coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

25 3665. The system of claim 3648, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in

response to at least one of the determined properties using a feedforward control technique during use.

5 3666. The system of claim 3648, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

10 3667. The system of claim 3666, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

15 3668. The system of claim 3667, wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

20 3669. The system of claim 3648, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

25 3670. The system of claim 3669, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

3671. The system of claim 3669, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

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3672. The system of claim 3648, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

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3673. The system of claim 3672, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during said moving.

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3674. The system of claim 3648, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

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3675. The system of claim 3648, wherein the remote controller computer is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

25

3676. The system of claim 3675, wherein the remote controller computer is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

3677. The system of claim 3648, wherein the remote controller computer is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

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3678. The system of claim 3648, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

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3679. The system of claim 3648, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

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3680. The system of claim 3648, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to calibrate the measurement device using the database during use.

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3681. The system of claim 3648, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by measurement device using the database during use.

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3682. The system of claim 3648, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

5

3683. The system of claim 3682, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

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3684. The system of claim 3682, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

15

3685. The system of claim 3648, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to a process tool.

20

3686. The system of claim 3648, wherein the remote controller computer is further coupled to a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of process tools during use.

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3687. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

5 directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

10 generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a concentration of an element in the specimen, and wherein the second property comprises a thickness of the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

3688. The method of claim 3687, wherein the measurement device further comprises a photo-acoustic device.

3689. The method of claim 3687, wherein the measurement device further comprises an X-ray reflectometer.

5 3690. The method of claim 3687, wherein the measurement device further comprises a grazing X-ray reflectometer.

3691. The method of claim 3687, wherein the measurement device further comprises an X-ray diffractometer.

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3692. The method of claim 3687, wherein the measurement device further comprises an eddy current device.

15 3693. The method of claim 3687, wherein the measurement device further comprises a spectroscopic ellipsometer.

3694. The method of claim 3687, wherein the measurement device further comprises an ellipsometer.

20 3695. The method of claim 3687, wherein the measurement device further comprises a grazing X-ray reflectometer and an optical measurement device.

25 3696. The method of claim 3687, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a photo-acoustic device, an X-ray reflectometer, a grazing X-ray reflectometer, an X-ray diffractometer, an eddy current device, a spectroscopic ellipsometer, and an ellipsometer.

3697. The method of claim 3687, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

5

3698. The method of claim 3687, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

10

3699. The method of claim 3698, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

15 3700. The method of claim 3687, wherein the measurement device further comprises an X-ray diffractometer, and wherein the X-ray diffractometer is coupled to a process tool configured to grow an epitaxial layer of silicon on the specimen.

20 3701. The method of claim 3687, wherein the remote controller computer is coupled to a process tool.

3702. The method of claim 3687, wherein the remote controller computer is coupled to a process tool, and wherein the process tool is selected from the group consisting of an etch tool, an ion implanter, a chemical vapor deposition tool, a physical vapor deposition tool, an atomic layer deposition tool, a thermal tool, a cleaning tool, and a plating tool.

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3703. The method of claim 3687, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more

instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

5 3704. The method of claim 3687, wherein the remote controller computer is coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

10 3705. The method of claim 3687, wherein the remote controller computer is coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

15 3706. The method of claim 3705, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

20 3707. The method of claim 3705, further comprising altering a parameter of at least one of the instruments in response to the relationship using the remote controller computer.

3708. The method of claim 3687, wherein the illumination system and the detection system are coupled to a process chamber of the process tool, the method further comprising performing said directing and said detecting during a process step.

25 3709. The method of claim 3708, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

3710. The method of claim 3708, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

5 3711. The method of claim 3687, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage; and

10 performing said directing and said detecting during said moving the specimen.

3712. The method of claim 3687, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

15

3713. The method of claim 3687, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

20 3714. The method of claim 3713, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

25 3715. The method of claim 3687, wherein the remote controller computer is coupled to the measurement device.

3716. The method of claim 3687, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a sampling frequency of

the measurement device using the remote controller computer in response to at least one of the determined properties of the specimen.

5 3717. The method of claim 3687, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

10 3718. The method of claim 3687, wherein the remote controller computer is coupled to the measurement device, the method further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.

15 3719. The method of claim 3687, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

20 3720. The method of claim 3687, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the remote controller computer and the database.

25 3721. The method of claim 3687, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and

second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

5 3722. The method of claim 3721, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

10 3723. The method of claim 3721, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

15 3724. The method of claim 3687, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein at least one of the plurality of local processors is coupled a measurement device.

20 3725. The method of claim 3724, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to at least one of the determined properties of the specimen.

25 3726. The method of claim 3725, wherein at least one of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

3727. The method of claim 3725, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote

controller computer in response to at least one of the determined properties of the specimen.

3728. A system configured to determine at least one characteristic of a layer on a
5 specimen during use, comprising:

a deposition tool configured to form the layer of material on the specimen during use;

10 a measurement device coupled to the deposition tool, comprising:

an illumination system configured to direct light toward a surface of the specimen use;

15 a detection system coupled to the illumination system and configured to detect light propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected light during use; and

20 wherein the illumination system and the detection system are further configured such that the measurement device comprises at least a spectroscopic reflectometer and a spectroscopic ellipsometer; and

25 a processor coupled to the measurement device and configured to determine a characteristic of the layer from the one or more output signals during use.

3729. The system of claim 3728, further comprising a stage coupled to the measurement device, and wherein the stage is configured to move laterally during use.

3730. The system of claim 3728, further comprising a stage coupled to the measurement device, and wherein the stage is configured to move rotatably during use.

5 3731. The system of claim 3728, further comprising a stage coupled to the measurement device, and wherein the stage is configured to move laterally and rotatably during use.

3732. The system of claim 3728, wherein the illumination system comprises a single light source.

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3733. The system of claim 3728, wherein the illumination system comprises more than one light source.

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3734. The system of claim 3728, wherein the detection system comprises a single light sensitive device.

3735. The system of claim 3728, wherein the detection system comprises more than one light sensitive devices.

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3736. The system of claim 3728, wherein optical elements of the spectroscopic reflectometer comprise optical elements of the spectroscopic ellipsometer.

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3737. The system of claim 3728, wherein the characteristic is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

3738. The system of claim 3728, wherein the processor is further configured to determine one or more characteristics of the layer, and wherein the one or more

characteristics are selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

5 3739. The system of claim 3728, wherein the processor is further configured to determine an additional characteristic of the specimen from the one or more output signals during use, and wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

10 3740. The system of claim 3739, wherein the deposition tool comprises an atomic layer deposition tool.

15 3741. The system of claim 3728, wherein the measurement device further comprises an eddy current device.

3742. The system of claim 3728, wherein the measurement device further comprises an eddy current device, and wherein the deposition tool comprises an atomic layer deposition tool.

20 3743. The system of claim 3728, wherein the processor is further configured to determine at least two characteristics of the layer substantially simultaneously during use.

25 3744. The system of claim 3728, wherein the illumination system is further configured to direct light to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect light propagating from the multiple locations on the surface of the specimen substantially simultaneously such that at least the one characteristic of the layer on the specimen can be determined at the multiple locations substantially simultaneously.

3745. The system of claim 3728, wherein the measurement device is further coupled to a process chamber of the deposition tool.

5 3746. The system of claim 3728, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool.

3747. The system of claim 3728, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, and wherein the deposition tool
10 comprises a wafer handler configured to move the specimen to a stage coupled to the measurement device during use.

3748. The system of claim 3728, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, and wherein a stage coupled to the
15 measurement device is configured to move the specimen from the measurement device to the deposition tool during use.

3749. The system of claim 3728, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, and wherein a stage coupled to the
20 measurement device is configured to move the specimen to the process chamber of the deposition tool during use.

3750. The system of claim 3728, wherein the system is further configured to determine
25 at least the one characteristic of the layer on the specimen while the specimen is waiting between process steps.

3751. The system of claim 3728, wherein the deposition tool comprises a support device configured to support the specimen during a deposition process step, and wherein an

upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the measurement device.

5 3752. The system of claim 3728, wherein the deposition tool comprises a support device configured to support the specimen during a deposition process step, and wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the measurement device.

10 3753. The system of claim 3728, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the deposition tool.

15 3754. The system of claim 3728, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the deposition tool.

20 3755. The system of claim 3728, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, and wherein the stage is configured to support the specimen during a deposition process step.

25 3756. The system of claim 3728, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, and wherein the processor is further configured to determine the characteristic of the specimen during a deposition process step.

3757. The system of claim 3728, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, and wherein the processor is further configured to obtain a signature characterizing formation of the layer during

use, wherein the signature comprises at least one singularity representative of an end of the formation of the layer.

5 3758. The system of claim 3728, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, wherein the processor is coupled to the deposition tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using an in situ control technique during use.

10 3759. The system of claim 3728, wherein the deposition tool comprises a first process chamber and a second process chamber, and wherein a stage coupled to the measurement device is configured to move the specimen from the first process chamber to the second process chamber during use.

15 3760. The system of claim 3728, wherein the deposition tool comprises a first process chamber and a second process chamber, wherein a stage coupled to the measurement device is configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the processor is further configured to determine the characteristic of the layer as the stage is moving the specimen from the first process
20 chamber to the second process chamber.

3761. The system of claim 3728, wherein the processor is further configured to compare the determined characteristic of the layer and characteristics of a plurality of layers during use.

25 3762. The system of claim 3728, wherein the processor is further configured to compare the determined characteristic of the layer to a predetermined range for the characteristic during use.

3763. The system of claim 3728, wherein the processor is further configured to compare the determined characteristic of the layer to a predetermined range for the characteristic during use, and wherein the processor is further configured to generate an output signal if
5 the determined characteristic of the layer is outside of the predetermined range for the characteristic during use.

3764. The system of claim 3728, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to the determined
10 characteristic of the layer during use.

3765. The system of claim 3728, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedback control technique during use.
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3766. The system of claim 3728, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedforward control technique during use.

20 3767. The system of claim 3728, wherein the processor is further configured to generate a database during use, and wherein the database comprises the determined characteristic of the layer.

25 3768. The system of claim 3728, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to calibrate the measurement device using the database during use.

3769. The system of claim 3728, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

5 3770. The system of claim 3728, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined characteristic of the layer and characteristics of a plurality of layers, and wherein the characteristics of the plurality of layers are determined using the measurement device.

10 3771. The system of claim 3728, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined characteristic of the layer and characteristics of a plurality of layers, and wherein the characteristics of the plurality of layers are determined using a plurality of measurement devices.

15 3772. The system of claim 3771, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

20 3773. The system of claim 3771, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

25 3774. The system of claim 3728, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

3775. The system of claim 3728, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during
5 use.

3776. The system of claim 3728, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter
10 at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3777. The system of claim 3728, wherein the processor is further coupled to the
15 deposition tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using a feedback control technique during use.

3778. The system of claim 3728, wherein the processor is further coupled to the
20 deposition tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using a feedforward control technique during use.

3779. The system of claim 3728, wherein the processor is further coupled to the
25 deposition tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the deposition tool during use.

3780. The system of claim 3728, wherein the processor is further coupled to the deposition tool, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the deposition tool during use, and wherein the processor is further configured to determine a relationship between the determined characteristic and at least one of the monitored parameters during use.

3781. The system of claim 3728, wherein the processor is further coupled to the deposition tool, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the deposition tool during use, wherein the processor is further configured to determine a relationship between the determined characteristic and at least one of the monitored parameters during use, and wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

3782. The system of claim 3728, wherein the processor is further coupled to a plurality of measurement devices, and wherein each of the plurality of measurement devices is coupled to one of a plurality of semiconductor fabrication process tools.

3783. The system of claim 3728, wherein the processor is further coupled to a plurality of deposition tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the plurality of deposition tools during use.

3784. The system of claim 3728, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

3785. The system of claim 3784, wherein the local processor is further configured to determine the characteristic of the layer during use.

3786. The system of claim 3784, wherein the remote controller computer is further
5 configured to determine the characteristic of the layer during use.

3787. A method for determining at least one characteristic of a layer on a specimen,
comprising:

10 forming the layer of material upon the specimen with a deposition tool;

directing light toward a surface of the specimen using an illumination system;

15 detecting light propagating from the surface of the specimen using a detection
system, wherein the illumination system and the detection system are arranged in
a measurement device comprising at least a spectroscopic reflectometer and a
spectroscopic ellipsometer, and wherein the measurement device is coupled to the
deposition tool;

20 generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine a characteristic of the
layer.

25 3788. The method of claim 3787, further comprising laterally moving the stage during
said directing light and said detecting light.

3789. The method of claim 3787, further comprising rotatably moving the stage during said directing light and said detecting light.

5 3790. The method of claim 3787, further comprising laterally and rotatably moving the stage during said directing light and said detecting light.

3791. The method of claim 3787, wherein the illumination system comprises a single light source.

10 3792. The method of claim 3787, wherein the illumination system comprises more than one light source.

3793. The method of claim 3787, wherein the detection system comprises a single light sensitive device.

15 3794. The method of claim 3787, wherein the detection system comprises more than one light sensitive device.

20 3795. The method of claim 3787, wherein optical elements of the spectroscopic reflectometer comprise optical elements of the spectroscopic ellipsometer.

3796. The method of claim 3787, wherein the characteristic is selected from the group comprising a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

25 3797. The method of claim 3787, wherein the processor is further configured to determine one or more characteristics of the layer, and wherein the one or more

characteristics are selected from the group comprising a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

5 3798. The method of claim 3787, further comprising processing the one or more output signals to determine an additional characteristic of the specimen, wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

10 3799. The method of claim 3798, wherein the deposition tool comprises an atomic layer deposition tool.

3800. The method of claim 3787, wherein the measurement device further comprises an eddy current device.

15 3801. The method of claim 3787, wherein the measurement device further comprises an eddy current device, and wherein the deposition tool comprises an atomic layer deposition tool.

20 3802. The method of claim 3787, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of the layer substantially simultaneously.

25 3803. The method of claim 3787, further comprising directing light toward multiple locations on the surface of the specimen substantially simultaneously and detecting light propagating from the multiple locations substantially simultaneously such that the at least one characteristic of the layer on the specimen can be determined at the multiple locations substantially simultaneously.

3804. The method of claim 3787, wherein the measurement device is further coupled to a process chamber of the deposition tool.

5 3805. The method of claim 3787, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool.

10 3806. The method of claim 3787, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, the method further comprising moving the specimen to a stage coupled to the measurement device with a wafer handler of the deposition tool.

15 3807. The method of claim 3787, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, the method further comprising moving the specimen from the measurement device to the deposition tool with a stage coupled to the measurement device.

20 3808. The method of claim 3787, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, the method further comprising moving the specimen to the process chamber of the deposition tool with a stage coupled to the measurement device.

3809. The method of claim 3787, further comprising determining at least the one characteristic of the layer while the specimen is waiting between process steps.

25 3810. The method of claim 3787, further comprising supporting the specimen during a deposition process step with a support device of the deposition tool, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the measurement device.

3811. The method of claim 3787, further comprising supporting the specimen during a deposition process step with a support device of the deposition tool, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the measurement device.

3812. The method of claim 3787, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the deposition tool.

3813. The method of claim 3787, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the deposition tool.

3814. The method of claim 3787, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising supporting the specimen during a deposition process step with the stage.

3815. The method of claim 3787, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, and wherein processing the one or more output signals comprises determining the characteristic of the specimen during a deposition process.

3816. The method of claim 3787, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising obtaining a signature characterizing the formation of the layer, wherein the signature comprises at least one singularity representative of an end of the formation of the layer.

3817. The method of claim 3787, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising altering a parameter of one or more instruments coupled to the deposition tool
5 in response to the determined characteristic using an in situ control technique.

3818. The method of claim 3787, wherein the deposition tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage
10 coupled to the measurement device.

3819. The method of claim 3787, wherein the deposition tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage
15 coupled to the measurement device, directing light during said moving, and detecting light during said moving.

3820. The method of claim 3787, further comprising comparing the determined characteristic and determined characteristics of a plurality of specimens.
20

3821. The method of claim 3787, further comprising comparing the determined characteristic to a predetermined range for the characteristic.

3822. The method of claim 3787, further comprising comparing the determined
25 characteristic to a predetermined range for the characteristic and generating an output signal if the determined characteristic is outside of the predetermined range.

3823. The method of claim 3787, further comprising altering a sampling frequency of the measurement device in response to the determined characteristic of the layer.

3824. The method of claim 3787, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedback control technique.

3825. The method of claim 3787, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedforward control technique.

3826. The method of claim 3787, further comprising generating a database, wherein the database comprises the determined characteristic of the layer.

3827. The method of claim 3787, further comprising generating a database comprising the determined characteristic of the layer and calibrating the measurement device using the database.

3828. The method of claim 3787, further comprising generating a database comprising the determined characteristic of the layer and monitoring output signals of the measurement device using the database.

3829. The method of claim 3787, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of layers.

3830. The method of claim 3787, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of

layers, wherein the determined characteristics of the plurality of layers are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

5 3831. The method of claim 3787, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of layers, wherein the determined characteristics of the plurality of layers are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

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3832. The method of claim 3787, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

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3833. The method of claim 3787, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

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3834. The method of claim 3787, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one
25 parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3835. The method of claim 3787, further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using a feedback control technique.

- 5 3836. The method of claim 3787, further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using a feedforward control technique.

- 10 3837. The method of claim 3787, further comprising monitoring a parameter of one or more instruments coupled to the deposition tool.

- 15 3838. The method of claim 3787, further comprising monitoring a parameter of one or more instruments coupled to the deposition tool and determining a relationship between the determined characteristic and at least one of the monitored parameters.

- 20 3839. The method of claim 3787, further comprising monitoring a parameter of one or more instruments coupled to the deposition tool, determining a relationship between the determined characteristic and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

- 25 3840. The method of claim 3787, further comprising altering a parameter of one or more instruments coupled to at least one semiconductor fabrication process tool in response to the determined characteristic of the layer.

3841. The method of claim 3787, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 3842. The method of claim 3841, wherein at least partially processing the one or more
output signals comprises determining the characteristic of the layer.

3843. The method of claim 3841, wherein further processing the partially processed one
or more output signals comprises determining the characteristic of the layer.

15 3844. A computer-implemented method for controlling a system configured to
determine at least one characteristic of a layer on a specimen during use, wherein the
system comprises a measurement device coupled to a deposition tool, and wherein the
deposition tool is configured to form the layer of material on the specimen during use, the
20 method comprising:

controlling the measurement device, wherein the measurement device comprises
an illumination system and a detection system, and wherein the illumination
system and the detection system are configured such that the measurement device
25 comprises a spectroscopic reflectometer and a spectroscopic ellipsometer,
comprising:

controlling the illumination system to direct light toward a surface of the specimen;

controlling the detection system to detect light propagating from the surface of the specimen; and

generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine a characteristic of the layer.

3845. The method of claim 3844, wherein the system further comprises a stage coupled to the measurement device, the method further comprising supporting the specimen with the stage and controlling the stage to move laterally during said controlling the illumination system and said controlling the detection system.

3846. The method of claim 3844, wherein the system further comprises a stage coupled to the measurement device, the method further comprising supporting the specimen with the stage and controlling the stage to move rotatably during said controlling the illumination system and said controlling the detection system.

3847. The method of claim 3844, wherein the system further comprises a stage coupled to the measurement device, the method further comprising supporting the specimen with the stage and controlling the stage to move laterally and rotatably during said controlling the illumination system and said controlling the detection system.

3848. The method of claim 3844, wherein the illumination system comprises a single light source.

3849. The method of claim 3844, wherein the illumination system comprises more than one light sources.

5 3850. The method of claim 3844, wherein the detection system comprises a single light sensitive device.

3851. The method of claim 3844, wherein the detection system comprises more than one light sensitive devices.

10

3852. The method of claim 3844, wherein optical elements of the spectroscopic reflectometer comprise optical elements of the spectroscopic ellipsometer.

3853. The method of claim 3844, wherein the characteristic is selected from the group
15 consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

3854. The method of claim 3844, further comprising processing the one or more output signals to determine one or more characteristics of the layers, and wherein the one or
20 more characteristics of the layer are selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

3855. The method of claim 3844, further comprising processing the one or more output
25 signals to determine an additional characteristic of the specimen, wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

3856. The method of claim 3855, wherein the deposition tool comprises an atomic layer deposition tool.

5 3857. The method of claim 3844, wherein the measurement device further comprises an eddy current device.

3858. The method of claim 3844, wherein the measurement device further comprises an eddy current device, and wherein the deposition tool comprises an atomic layer deposition tool.

10

3859. The method of claim 3844, wherein processing the one or more output signals to determine the characteristic of the layer comprises substantially simultaneously determining at least two characteristics of the layer.

15 3860. The method of claim 3844, further comprising controlling the illumination system to direct light toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect light propagating from the multiple locations substantially simultaneously such that the at least one characteristic of the layer on the specimen can be determined at the multiple locations substantially
20 simultaneously.

3861. The method of claim 3844, wherein the measurement device is further coupled to a process chamber of the deposition tool.

25 3862. The method of claim 3844, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool.

3863. The method of claim 3844, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, the method further comprising controlling a wafer handler coupled to the deposition tool to move the specimen to a stage coupled to the measurement device.

5

3864. The method of claim 3844, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the measurement device to the deposition tool.

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3865. The method of claim 3844, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool, the method further comprising controlling a stage coupled to the measurement device to move the specimen to a process chamber of the deposition tool.

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3866. The method of claim 3844, the method further comprising controlling a wafer handler to move the specimen to a stage coupled to the measurement device such that at least the one characteristic of the layer of the specimen can be determined while the specimen is waiting between process steps.

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3867. The method of claim 3844, further comprising supporting the specimen during a deposition process step with a support device of the deposition tool, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the measurement device.

25

3868. The method of claim 3844, further comprising supporting the specimen during a deposition process step with a support device of the deposition tool, wherein an upper

surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the measurement device.

5 3869. The method of claim 3844, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the deposition tool.

10 3870. The method of claim 3844, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the deposition tool.

15 3871. The method of claim 3844, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising controlling the stage to support the specimen during a deposition process step.

20 3872. The method of claim 3844, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising processing the one or more output signals to determine the characteristic of the specimen during a deposition process step.

25 3873. The method of claim 3844, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising controlling the measurement device to obtain a signature characterizing the formation of the layer, wherein the signature comprises at least one singularity representative of an end of the formation of the layer.

3874. The method of claim 3844, further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using an in situ control technique.

5 3875. The method of claim 3844, wherein the deposition tool comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber.

10 3876. The method of claim 3844, wherein the deposition tool comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber, controlling the illumination system during said moving, and controlling the detection system during said moving.

15 3877. The method of claim 3844, further comprising comparing the determined characteristic of the layer and determined characteristics of a plurality of layers.

20 3878. The method of claim 3844, further comprising comparing the determined characteristic of the layer to a predetermined range for the characteristic.

25 3879. The method of claim 3844, further comprising comparing the determined characteristic of the layer to a predetermined range for the characteristic and generating an output signal if the determined characteristic is outside of the predetermined range for the characteristic.

3880. The method of claim 3844, further comprising altering a sampling frequency of the measurement device in response to the determined characteristic of the layer.

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3881. The method of claim 3844, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedback control technique.
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3882. The method of claim 3844, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedforward control technique.
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3883. The method of claim 3844, further comprising generating a database, wherein the database comprises the determined characteristic of the layer.
3884. The method of claim 3844, further comprising generating a database comprising the determined characteristic of the layer and calibrating the measurement device using
- 15
- the database.
3885. The method of claim 3844, further comprising generating a database comprising the determined characteristic of the layer and monitoring output signals generated by the measurement device using the database.
- 20
3886. The method of claim 3844, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of layers.
- 25
3887. The method of claim 3844, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of layers, wherein the determined characteristics of the plurality of layers are generated using a plurality of measurement devices.

3888. The method of claim 3844, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of layers, wherein the determined characteristics of the plurality of layers are generated
5 using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

3889. The method of claim 3844, further comprising generating a database comprising the determined characteristic of the layer and determined characteristics of a plurality of
10 layers, wherein the determined characteristics of the plurality of layers are generated using a plurality of measurement devices, the method further comprising monitoring output signals generating by the plurality of measurement devices using the database.

3890. The method of claim 3844, wherein a stand alone system is coupled to the system,
15 the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

3891. The method of claim 3844, wherein a stand alone system is coupled to the system
20 and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

25 3892. The method of claim 3844, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least

one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

3893. The method of claim 3844, further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic of the layer using a feedback control technique.

3894. The method of claim 3844, further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic of the layer using a feedforward control technique.

3895. The method of claim 3844, further comprising monitoring a parameter of one or more instruments coupled to the deposition tool.

3896. The method of claim 3844, further comprising monitoring a parameter of one or more instruments coupled to the deposition tool and determining a relationship between the determined characteristic and at least one of the monitored parameters.

3897. The method of claim 3844, further comprising monitoring a parameter of one or more instruments coupled to the deposition tool, determining a relationship between the determined characteristic and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

3898. The method of claim 3844, further comprising altering a parameter of one or more instruments coupled to a plurality of semiconductor fabrication process tools in response to the determined characteristic of the layer.

3899. The method of claim 3844, wherein processing the one or more output signals comprises:

5 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

10 further processing the partially processed one or more output signals using the remote controller computer.

3900. The method of claim 3899, wherein at least partially processing the one or more output signals comprises determining the characteristic of the layer.

15 3901. The method of claim 3899, wherein further processing the partially processed one or more output signals comprises determining the characteristic of the layer.

3902. A semiconductor device fabricated by a method, the method comprising:

20 disposing the specimen in a deposition tool configured to form a layer of material on a specimen, wherein the deposition tool is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

25 forming a layer of material upon a specimen, wherein the formed layer comprises a portion of the semiconductor device;

directing light toward a surface of the specimen using the illumination system;

detecting light propagating from the surface of the specimen using the detection system, wherein the illumination system and the detection system comprise at least a spectroscopic reflectometer and a spectroscopic ellipsometer;

generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine a characteristic of the layer.

3903. The device of claim 3902, wherein optical elements of the spectroscopic reflectometer comprise optical elements of the spectroscopic ellipsometer.

3904. The device of claim 3902, wherein the characteristic is selected from the group comprising a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

3905. The device of claim 3902, wherein the processor is further configured to determine one or more characteristics of the layer, and wherein the one or more characteristics are selected from the group comprising a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

3906. The device of claim 3902, further comprising processing the one or more output signals to determine an additional characteristic of the specimen, wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

3907. The device of claim 3902, wherein the deposition tool comprises an atomic layer deposition tool.

5 3908. The device of claim 3902, wherein the illumination system and the detection system further comprise an eddy current device.

3909. The device of claim 3902, wherein the illumination system and the detection system further comprise an eddy current device, and wherein the deposition tool comprises an atomic layer deposition tool.

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3910. The device of claim 3902, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of the layer substantially simultaneously.

15 3911. The device of claim 3902, further comprising directing light toward multiple locations on the surface of the specimen substantially simultaneously and detecting light propagating from the multiple locations substantially simultaneously such that the at least one characteristic of the layer on the specimen can be determined at the multiple locations substantially simultaneously.

20

3912. The device of claim 3902, wherein the measurement device is further coupled to a process chamber of the deposition tool.

25 3913. The device of claim 3902, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool.

3914. The device of claim 3902, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, and wherein processing

the one or more output signals comprises determining the characteristic of the specimen during a deposition process.

5 3915. The device of claim 3902, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising obtaining a signature characterizing the formation of the layer, wherein the signature comprises at least one singularity representative of an end of the formation of the layer.

10 3916. The device of claim 3902, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using an in situ control technique.

15 3917. The device of claim 3902, wherein the deposition tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the measurement device, directing light during said moving, and detecting light during said moving.

20

3918. A method for fabricating a semiconductor device, comprising:

25 disposing the specimen in a deposition tool configured to form a layer of material on a specimen, wherein the deposition tool is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

forming a layer of material upon a specimen, wherein the formed layer comprises a portion of the semiconductor device;

directing light toward a surface of the specimen using the illumination system;

5

detecting light propagating from the surface of the specimen using the detection system, wherein the illumination system and the detection system comprise at least a spectroscopic reflectometer and a spectroscopic ellipsometer;

10

generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine a characteristic of the layer.

15

3919. The method of claim 3918, wherein optical elements of the spectroscopic reflectometer comprise optical elements of the spectroscopic ellipsometer.

3920. The method of claim 3918, wherein the characteristic is selected from the group comprising a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

20

3921. The method of claim 3918, wherein the processor is further configured to determine one or more characteristics of the layer, and wherein the one or more characteristics are selected from the group comprising a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a presence of defects.

25

3922. The method of claim 3918, further comprising processing the one or more output signals to determine an additional characteristic of the specimen, wherein the additional

characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

5 3923. The method of claim 3922, wherein the deposition tool comprises an atomic layer deposition tool.

3924. The method of claim 3918, wherein the illumination system and the detection system further comprise an eddy current device.

10 3925. The method of claim 3918, wherein the illumination system and the detection system further comprise an eddy current device, and wherein the deposition tool comprises an atomic layer deposition tool.

15 3926. The method of claim 3918, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of the layer substantially simultaneously.

20 3927. The method of claim 3918, further comprising directing light toward multiple locations on the surface of the specimen substantially simultaneously and detecting light propagating from the multiple locations substantially simultaneously such that the at least one characteristic of the layer on the specimen can be determined at the multiple locations substantially simultaneously.

25 3928. The method of claim 3918, wherein the measurement device is further coupled to a process chamber of the deposition tool.

3929. The method of claim 3918, wherein the measurement device is arranged laterally proximate to a process chamber of the deposition tool.

3930. The method of claim 3918, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, and wherein processing the one or more output signals comprises determining the characteristic of the specimen during a deposition process.

3931. The method of claim 3918, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising obtaining a signature characterizing the formation of the layer, wherein the signature comprises at least one singularity representative of an end of the formation of the layer.

3932. The method of claim 3918, wherein the measurement device is further coupled to a stage disposed within a process chamber of the deposition tool, the method further comprising altering a parameter of one or more instruments coupled to the deposition tool in response to the determined characteristic using an in situ control technique.

3933. The method of claim 3918, wherein the deposition tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the measurement device, directing light during said moving, and detecting light during said moving.

3934. A system configured to determine at least one characteristic of a layer on a specimen during use, comprising:

a deposition tool configured to form the layer of material on the specimen during use;

a measurement device coupled to the deposition tool, comprising:

an illumination system configured to direct light toward a surface of the specimen during use;

a detection system coupled to the illumination system and configured to detect light propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy; and

wherein the illumination system and the detection system are further configured such that the measurement device comprises at least a spectroscopic reflectometer and a spectroscopic ellipsometer;

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a characteristic of the layer from the one or more output signals during use.

3935. A method for determining at least one characteristic of a layer on a specimen, comprising:

forming the layer of material upon the specimen;

directing light toward a surface of the specimen using the illumination system;

detecting light propagating from the surface of the specimen using the detection system, wherein the illumination system and the detection system comprise at least a spectroscopic reflectometer and a spectroscopic ellipsometer;

generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine a characteristic of the layer, comprising:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

3936. A system configured to determine at least one property of a specimen during use, comprising:

an etch tool configured to etch the specimen during use;

a beam profile ellipsometer coupled to the etch tool, comprising:

an illumination system configured to direct an incident beam of light having a known polarization state to the specimen during use; and

5 a detection system coupled to the illumination system and configured to detect light returned from the specimen during use, wherein the beam profile ellipsometer is configured to generate one or more output signals responsive to the detected light during use; and

10 a processor coupled to the beam profile ellipsometer and configured to determine a property of the specimen from the one or more output signals during use.

3937. The system of claim 3936, further comprising a stage coupled to the beam profile ellipsometer, and wherein the stage is configured to move laterally during use.

15 3938. The system of claim 3936, further comprising a stage coupled to the beam profile ellipsometer, and wherein the stage is configured to move rotatably during use.

3939. The system of claim 3936, further comprising a stage coupled to the beam profile ellipsometer, and wherein the stage is configured to move laterally and rotatably during
20 use.

3940. The system of claim 3936, further comprising an additional measurement device coupled to the etch tool, wherein the processor is further coupled to the additional measurement device, and wherein the processor is further configured to determine an
25 additional property of the specimen from one or more output signals generated by the additional measurement device.

3941. The system of claim 3936, wherein the processor is further configured to determine an additional property of the specimen from the one or more output signals during use, and wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

3942. The system of claim 3936, further comprising an eddy current device coupled to the etch tool, wherein the processor is further coupled to the eddy current device, and wherein the processor is further configured to determine a thickness of the specimen from one or more output signals generated by the eddy current device.

3943. The system of claim 3936, wherein the property is selected from the group consisting of a thickness, an index of refraction, and an extinction coefficient.

3944. The system of claim 3936, wherein the processor is further configured to determine at least two properties of the specimen substantially simultaneously during use.

3945. The system of claim 3936, wherein the illumination system is further configured to direct the incident beam of light to multiple locations on the surface of the specimen substantially simultaneously, and wherein the detection system is further configured to detect light returned from the multiple locations on the surface of the specimen substantially simultaneously such that at least the one property of the specimen can be determined at the multiple locations substantially simultaneously.

3946. The system of claim 3936, wherein the beam profile ellipsometer is further coupled to a process chamber of the etch tool.

3947. The system of claim 3936, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool.

5 3948. The system of claim 3936, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, and wherein the etch tool comprises a wafer handler configured to move the specimen to a stage coupled to the beam profile ellipsometer during use.

10 3949. The system of claim 3936, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, and wherein a stage coupled to the beam profile ellipsometer is configured to move the specimen from the beam profile ellipsometer to the etch tool during use.

15 3950. The system of claim 3936, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, and wherein a stage coupled to the beam profile ellipsometer is configured to move the specimen to the process chamber of the etch tool during use.

20 3951. The system of claim 3936, wherein the system is further configured to determine at least the one property of the specimen while the specimen is waiting between process steps.

25 3952. The system of claim 3936, wherein the etch tool comprises a support device configured to support the specimen during an etch process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the beam profile ellipsometer.

3953. The system of claim 3936, wherein the etch tool comprises a support device configured to support the specimen during an etch process step, and wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the beam profile ellipsometer.

5

3954. The system of claim 3936, wherein the beam profile ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the etch tool.

10 3955. The system of claim 3936, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the etch tool.

15 3956. The system of claim 3936, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, and wherein the stage is configured to support the specimen during an etch process step.

20 3957. The system of claim 3936, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, and wherein the processor is further configured to determine the characteristic of the specimen during an etch process step.

25 3958. The system of claim 3936, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, wherein the processor is further configured to obtain a signature characterizing etching of the specimen during use, and wherein the signature comprises at least one singularity representative of an end of the etching of the specimen.

3959. The system of claim 3936, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, wherein the processor is coupled to the etch tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the etch tool in response to the determined property using an in situ control technique during use.

3960. The system of claim 3936, wherein the etch tool comprises a first process chamber and a second process chamber, wherein a stage coupled to the beam profile ellipsometer is configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the processor is further configured to determine the property of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

3961. The system of claim 3936, wherein the processor is further configured to compare the determined property of the specimen and properties of a plurality of specimens during use.

3962. The system of claim 3936, wherein the processor is further configured to compare the determined property of the specimen to a predetermined range for the property during use.

3963. The system of claim 3936, wherein the processor is further configured to compare the determined property of the specimen to a predetermined range for the property during use, and wherein the processor is further configured to generate an output signal if the determined property is outside of the predetermined range for the property during use.

3964. The system of claim 3936, wherein the processor is further configured to alter a sampling frequency of the beam profile ellipsometer in response to the determined property during use.

- 5 3965. The system of claim 3936, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the beam profile ellipsometer in response to the determined property using a feedback control technique during use.

- 10 3966. The system of claim 3936, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the beam profile ellipsometer in response to the determined property using a feedforward control technique during use.

3967. The system of claim 3936, wherein the processor is further configured to generate a database during use, and wherein the database comprises the determined property.

- 15 3968. The system of claim 3936, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to calibrate the beam profile ellipsometer using the database during use.

- 20 3969. The system of claim 3936, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to monitor output signals generated by beam profile ellipsometer using the database during use.

- 25 3970. The system of claim 3936, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined property and properties of a plurality of specimens, and wherein the properties of the plurality of specimens are determined using the beam profile ellipsometer.

3971. The system of claim 3936, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined property and properties of a plurality of specimens, and wherein the properties of the plurality of specimens are determined using a plurality of beam profile ellipsometers.

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3972. The system of claim 3971, wherein the processor is further coupled to the plurality of beam profile ellipsometers, and wherein the processor is further configured to calibrate the plurality of beam profile ellipsometers using the database during use.

10 3973. The system of claim 3971, wherein the processor is further coupled to the plurality of beam profile ellipsometers, and wherein the processor is further configured to monitor output signals generated by the plurality of beam profile ellipsometers using the database during use.

15 3974. The system of claim 3936, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

20 3975. The system of claim 3936, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

25

3976. The system of claim 3936, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter

at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

5 3977. The system of claim 3936, wherein the processor is further coupled to the etch tool.

3978. The system of claim 3936, wherein the processor is further coupled to the etch tool, and wherein the processor is further configured to alter a parameter of one or more
10 instruments coupled to the etch tool in response to the determined property using a feedback control technique during use.

3979. The system of claim 3936, wherein the processor is further coupled to the etch tool, and wherein the processor is further configured to alter a parameter of one or more
15 instruments coupled to the etch tool in response to the determined property using a feedforward control technique during use.

3980. The system of claim 3936, wherein the processor is further coupled to the etch tool, and wherein the processor is further configured to monitor a parameter of one or
20 more instruments coupled to the etch tool during use.

3981. The system of claim 3936, wherein the processor is further coupled to the etch tool, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the etch tool during use, and wherein the processor is further
25 configured to determine a relationship between the determined property and at least one of the monitored parameters during use.

3982. The system of claim 3936, wherein the processor is further coupled to the etch tool, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the etch tool during use, wherein the processor is further configured to determine a relationship between the determined property and at least one of the monitored parameters during use, and wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

3983. The system of claim 3936, wherein the processor is further coupled to a plurality of beam profile ellipsometers, and wherein at least one of the plurality of beam profile ellipsometers is coupled to an etch tool.

3984. The system of claim 3936, wherein the processor is further coupled to a plurality of etch tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the plurality of etch tools during use.

3985. The system of claim 3936, wherein the processor comprises a local processor coupled to the beam profile ellipsometer and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

3986. The system of claim 3985, wherein the local processor is further configured to determine the property during use.

3987. The system of claim 3985, wherein the remote controller computer is further configured to determine the property during use.

3988. A method for determining at least one property of a specimen, comprising:

etching the specimen in an etch tool;

5

directing an incident beam of light having a known polarization state to the specimen using an illumination system;

10

detecting light returned from the surface of the specimen using a detection system, wherein the illumination system and the detection system comprise a beam profile ellipsometer, and wherein the beam profile ellipsometer is coupled to the etch tool;

15

generating one or more output signals representative of the detected light; and processing the one or more output signals to determine a property of the specimen.

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3989. The method of claim 3988, wherein a stage is coupled to the beam profile ellipsometer, the method further comprising laterally moving the stage during said directing light and said detecting light.

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3990. The method of claim 3988, wherein a stage is coupled to the beam profile ellipsometer, the method further comprising rotatably moving the stage during said directing light and said detecting light.

3991. The method of claim 3988, wherein a stage is coupled to the beam profile ellipsometer, the method further comprising laterally and rotatably moving the stage during said directing light and detecting light.

- 5 3992. The method of claim 3988, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the etch tool, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

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3993. The method of claim 3988, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

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3994. The method of claim 3988, wherein an eddy current device is coupled to the etch tool, the method further comprising processing one or more output signals generated by the eddy current device to determine a thickness of the specimen.

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3995. The method of claim 3988, wherein the property is selected from the group comprising a thickness, an index of refraction, and an extinction coefficient.

25

3996. The method of claim 3988, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

3997. The method of claim 3988, further comprising directing the incident beam of light toward multiple locations on the surface of the specimen substantially simultaneously and

detecting light returned from the multiple locations substantially simultaneously such that the at least one property of the specimen can be determined at the multiple locations substantially simultaneously.

- 5 3998. The method of claim 3988, wherein the beam profile ellipsometer is further coupled to a process chamber of the etch tool.

3999. The method of claim 3988, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool.

10

4000. The method of claim 3988, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, the method further comprising moving the specimen to a stage coupled to the beam profile ellipsometer with a wafer handler of the etch tool.

15

4001. The method of claim 3988, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, the method further comprising moving the specimen from the beam profile ellipsometer to the etch tool with a stage coupled to the beam profile ellipsometer.

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4002. The method of claim 3988, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, the method further comprising moving the specimen to the process chamber of the etch tool with a stage coupled to the beam profile ellipsometer.

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4003. The method of claim 3988, further comprising determining at least the one property of the specimen while the specimen is waiting between process steps.

4004. The method of claim 3988, further comprising supporting the specimen during an etch process step with a support device of the etch tool, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the beam profile ellipsometer.

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4005. The method of claim 3988, further comprising supporting the specimen during an etch process step with a support device of the etch tool, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the beam profile ellipsometer.

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4006. The method of claim 3988, wherein the beam profile ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the etch tool.

15

4007. The method of claim 3988, wherein the beam profile ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the etch tool.

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4008. The method of claim 3988, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising supporting the specimen during an etch process step with the stage.

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4009. The method of claim 3988, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, and wherein processing the one or more output signals comprises determining the property of the specimen during an etch process.

4010. The method of claim 3988, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising obtaining a signature characterizing etching of the specimen, wherein the signature comprises at least one singularity representative of an end of the etching of the specimen.

4011. The method of claim 3988, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using an in situ control technique.

4012. The method of claim 3988, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the beam profile ellipsometer.

4013. The method of claim 3988, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the beam profile ellipsometer, directing light during said moving, and detecting light during said moving.

4014. The method of claim 3988, further comprising comparing the determined property and properties of a plurality of etched regions.

4015. The method of claim 3988, further comprising comparing the determined property to a predetermined range for the property.

4016. The method of claim 4015, further comprising generating an output signal if the determined property is outside of the predetermined range.

5 4017. The method of claim 3988, further comprising altering a sampling frequency of the beam profile ellipsometer in response to the determined property of the layer.

4018. The method of claim 3988, further comprising altering a parameter of one or more instruments coupled to the beam profile ellipsometer in response to the determined property using a feedback control technique.

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4019. The method of claim 3988, further comprising altering a parameter of one or more instruments coupled to the beam profile ellipsometer in response to the determined property using a feedforward control technique.

15 4020. The method of claim 3988, further comprising generating a database, wherein the database comprises the determined property of the specimen.

4021. The method of claim 3988, further comprising generating a database comprising the determined property of the specimen and calibrating the beam profile ellipsometer
20 using the database.

4022. The method of claim 3988, further comprising generating a database comprising the determined property of the specimen and monitoring output signals generated by the beam profile ellipsometer using the database.

25

4023. The method of claim 3988, further comprising generating a database comprising the determined property of the specimen and properties of a plurality of specimen.

4024. The method of claim 3988, further comprising generating a database comprising the determined property of the specimen and properties of a plurality of specimen, wherein the properties of the plurality of specimen are generated using a plurality of beam profile ellipsometers, the method further comprising calibrating the plurality of beam
5 profile ellipsometers using the database.

4025. The method of claim 3988, further comprising generating a database comprising the determined property of the specimen and properties of a plurality of specimen, wherein the properties of the plurality of specimen are generated using a plurality of beam
10 profile ellipsometers, the method further comprising monitoring the plurality of beam profile ellipsometers using the database.

4026. The method of claim 3988, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system
15 with a calibration standard and calibrating the measurement device with the stand alone system.

4027. The method of claim 3988, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further
20 comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

4028. The method of claim 3988, further comprising determining at least the two
25 properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one

of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

5 4029. The method of claim 3988, further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using a feedback control technique.

10 4030. The method of claim 3988, further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using a feedforward control technique.

4031. The method of claim 3988, further comprising monitoring a parameter of one or more instruments coupled to the etch tool.

15 4032. The method of claim 3988, further comprising monitoring a parameter of one or more instruments coupled to the etch tool and determining a relationship between the determined property and at least one of the monitored parameters.

20 4033. The method of claim 3988, further comprising monitoring a parameter of one or more instruments coupled to the etch tool, determining a relationship between the determined property and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

25 4034. The method of claim 3988, further comprising altering a parameter of one or more instruments coupled to at least one semiconductor fabrication process tool in response to the determined property of the layer.

4035. The method of claim 3988, wherein processing the one or more output signals comprises:

5 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the beam profile ellipsometer;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

10 further processing the partially processed one or more output signals using the remote controller computer.

4036. The method of claim 4035, wherein at least partially processing the one or more output signals comprises determining the property.

15 4037. The method of claim 4035, wherein further processing the partially processed one or more output signals comprises determining the property.

4038. A computer-implemented method for controlling a system configured to
20 determine at least one property of a specimen during use, wherein the system comprises a beam profile ellipsometer coupled to an etch tool, and wherein the etch tool is configured to etch the specimen during use, the method comprising:

25 controlling the beam profile ellipsometer, wherein the beam profile ellipsometer comprises an illumination system and a detection system, comprising:

controlling the illumination system to direct light toward a surface of the specimen;

controlling the detection system to detect light propagating from the surface of the specimen; and

5 generating one or more output signals representative of detected light; and

processing the one or more output signals to determine a property of the specimen.

10 4039. The method of claim 4038, wherein the system further comprises a stage coupled to the beam profile ellipsometer, the method further comprising supporting the specimen with the stage and controlling the stage to move laterally during said controlling the illumination system and said controlling the detection system.

15 4040. The method of claim 4038, wherein the system further comprises a stage coupled to the beam profile ellipsometer, the method further comprising supporting the specimen with the stage and controlling the stage to move rotatably during said controlling the illumination system and said controlling the detection system.

20 4041. The method of claim 4038, wherein the system further comprises a stage coupled to the beam profile ellipsometer, the method further comprising supporting the specimen with the stage and controlling the stage to move laterally and rotatably during said controlling the illumination system and said controlling the detection system.

25 4042. The method of claim 4038, wherein the system further comprises an additional measurement device coupled to the etch tool, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

4043. The method of claim 4038, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

4044. The method of claim 4038, wherein the system further comprises an eddy current device coupled to the etch tool, the method further comprising processing one or more output signals generated by the eddy current device to determine a thickness of the specimen.

4045. The method of claim 4038, wherein the property is selected from the group consisting of a thickness, an index of refraction, and an extinction coefficient.

4046. The method of claim 4038, wherein processing the one or more output signals to determine the property of the specimen comprises substantially simultaneously determining at least two properties of the specimen.

4047. The method of claim 4038, further comprising controlling the illumination system to direct light toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect light propagating from the multiple locations substantially simultaneously such that the at least one property of the specimen can be determined at the multiple locations substantially simultaneously.

4048. The method of claim 4038, wherein the beam profile ellipsometer is further coupled to a process chamber of the etch tool.

4049. The method of claim 4038, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool.

5 4050. The method of claim 4038, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, the method further comprising controlling a wafer handler coupled to the etch tool to move the specimen to a stage coupled to the beam profile ellipsometer.

10 4051. The method of claim 4038, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, the method further comprising controlling a stage coupled to the beam profile ellipsometer to move the specimen from the beam profile ellipsometer to the etch tool.

15 4052. The method of claim 4038, wherein the beam profile ellipsometer is arranged laterally proximate to a process chamber of the etch tool, the method further comprising controlling a stage coupled to the beam profile ellipsometer to move the specimen to a process chamber of the etch tool.

20 4053. The method of claim 4038, the method further comprising controlling a wafer handler to move the specimen to a stage coupled to the beam profile ellipsometer such that at least the one property of the specimen can be determined while the specimen is waiting between process steps.

25 4054. The method of claim 4038, further comprising supporting the specimen during an etch process step with a support device of the etch tool, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the beam profile ellipsometer.

4055. The method of claim 4038, further comprising supporting the specimen during an etch process step with a support device of the etch tool, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the beam profile ellipsometer.

5

4056. The method of claim 4038, wherein the beam profile ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the etch tool.

10 4057. The method of claim 4038, wherein the beam profile ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the etch tool.

15 4058. The method of claim 4038, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising controlling the stage to support the specimen during an etch process step.

20 4059. The method of claim 4038, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising processing the one or more output signals to determine the characteristic of the specimen during an etch process step.

25 4060. The method of claim 4038, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising controlling the beam profile ellipsometer to obtain a signature characterizing etching of the specimen, wherein the signature comprises at least one singularity representative of an end of the etching of the specimen.

4061. The method of claim 4038, further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using an in situ control technique.

5 4062. The method of claim 4038, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the beam profile ellipsometer to move the specimen from the first process chamber to the second process chamber.

10 4063. The method of claim 4038, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber, controlling the illumination system during said moving, and controlling the detection system during said moving.

15 4064. The method of claim 4038, further comprising comparing the determined property and properties of a plurality of specimens.

20 4065. The method of claim 4038, further comprising comparing the determined property to a predetermined range for the property.

4066. The method of claim 4038, further comprising generating an output signal if the determined property is outside of the predetermined range for the property.

25 4067. The method of claim 4038, further comprising altering a sampling frequency of the beam profile ellipsometer in response to the determined property.

4068. The method of claim 4038, further comprising altering a parameter of one or more instruments coupled to the beam profile ellipsometer in response to the determined property using a feedback control technique.

- 5 4069. The method of claim 4038, further comprising altering a parameter of one or more instruments coupled to the beam profile ellipsometer in response to the determined property using a feedforward control technique.

4070. The method of claim 4038, further comprising generating a database, wherein the
10 database comprises the determined property.

4071. The method of claim 4038, further comprising generating a database, wherein the database comprises the determined property, and calibrating the beam profile ellipsometer using the database.

- 15 4072. The method of claim 4038, further comprising generating a database, wherein the database comprises the determined property, and monitoring output signals of the beam profile ellipsometer using the database.

- 20 4073. The method of claim 4038, further comprising generating a database, wherein the database comprises the determined property, and wherein the database further comprises properties of a plurality of specimens.

4074. The method of claim 4038, further comprising generating a database, wherein the
25 database comprises the determined property, wherein the database further comprises properties of a plurality of specimens, and wherein the properties of the plurality of specimens are generated using a plurality of beam profile ellipsometers.

4075. The method of claim 4074, further comprising calibrating the plurality of beam profile ellipsometers using the database.

5 4076. The method of claim 4074, further comprising monitoring output signals of the plurality of beam profile ellipsometers using the database.

4077. The method of claim 4038, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to
10 calibrate the system.

4078. The method of claim 4038, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further
15 controlling the stand alone system to calibrate the system and at least the one additional system.

4079. The method of claim 4038, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and
20 wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

25 4080. The method of claim 4038, further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using a feedback control technique.

4081. The method of claim 4038, further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using a feedforward control technique.

5 4082. The method of claim 4038, further comprising monitoring a parameter of one or more instruments coupled to the etch tool.

4083. The method of claim 4038, further comprising monitoring a parameter of one or more instruments coupled to the etch tool and determining a relationship between the
10 determined property and at least one of the monitored parameters.

4084. The method of claim 4038, further comprising monitoring a parameter of one or more instruments coupled to the etch tool, determining a relationship between the determined property and at least one of the monitored parameters, and altering a
15 parameter of at least one of the instruments in response to the relationship.

4085. The method of claim 4038, further comprising altering a parameter of one or more instruments coupled to at least one of a plurality of semiconductor fabrication process tools in response to the determined property.

20 4086. The method of claim 4038, wherein processing the one or more output signals comprises:

25 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the beam profile ellipsometer;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

5 4087. The method of claim 4086, wherein at least partially processing the one or more output signals comprises determining the property.

4088. The method of claim 4086, wherein further processing the partially processed one or more output signals comprises determining the property.

10

4089. A semiconductor device fabricated by a method, the method comprising:

etching a specimen using an etch tool;

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directing an incident beam of light having a known polarization state to the specimen using an illumination system;

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detecting light returned from the surface of the specimen using a detection system, wherein the illumination system and the detection system comprise a beam profile ellipsometer, and wherein the beam profile ellipsometer is coupled to the etch tool;

generating one or more output signals representative of the detected light; and

25

processing the one or more output signals to determine a property of the specimen.

4090. The device of claim 4089, wherein the property is selected from the group consisting of a thickness, an index of refraction, and an extinction coefficient.

5 4091. The device of claim 4089, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the etch tool, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

10 4092. The device of claim 4089, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

15 4093. The device of claim 4089, wherein an eddy current device is coupled to the etch tool, the method further comprising processing one or more output signals generated by the eddy current device to determine a thickness of the specimen.

20 4094. The device of claim 4089, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

25 4095. The device of claim 4089, further comprising directing the incident beam of light toward multiple locations on the surface of the specimen substantially simultaneously and detecting light returned from the multiple locations substantially simultaneously such that the at least one property of the specimen can be determined at the multiple locations substantially simultaneously.

4096. The device of claim 4089, wherein the beam profile ellipsometer is further coupled to a process chamber of the etch tool.

4097. The device of claim 4089, wherein the beam profile ellipsometer is arranged
5 laterally proximate to a process chamber of the etch tool.

4098. The device of claim 4089, wherein the beam profile ellipsometer is arranged vertically proximate to a process chamber of the etch tool.

10 4099. The device of claim 4089, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, and wherein processing the one or more output signals comprises determining the property of the specimen during an etch process.

15 4100. The device of claim 4089, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising obtaining a signature characterizing etching of the specimen, wherein the signature comprises at least one singularity representative of an end of etching of the specimen.

20 4101. The device of claim 4089, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using an in situ control technique.

25 4102. The device of claim 4089, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the

beam profile ellipsometer, directing light during said moving, and detecting light during said moving.

4103. A method for fabricating a semiconductor device, comprising:

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etching a specimen using an etch tool;

directing an incident beam of light having a known polarization state to the specimen using an illumination system;

10

detecting light returned from the surface of the specimen using a detection system, wherein the illumination system and the detection system comprise a beam profile ellipsometer, and wherein the beam profile ellipsometer is coupled to the etch tool;

15

generating one or more output signals representative of the detected light; and

processing the one or more output signals to determine a property of the specimen.

20

4104. The method of claim 4103, wherein the property is selected from the group consisting of a thickness, an index of refraction, and an extinction coefficient.

25

4105. The method of claim 4103, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the etch tool, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

4106. The method of claim 4103, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a
5 roughness of the layer on the specimen, and a roughness of a feature of the specimen.

4107. The method of claim 4103, wherein an eddy current device is coupled to the etch tool, the method further comprising processing one or more output signals generated by the eddy current device to determine a thickness of the specimen.

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4108. The method of claim 4103, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

15 4109. The method of claim 4103, further comprising directing the incident beam of light toward multiple locations on the surface of the specimen substantially simultaneously and detecting light returned from the multiple locations substantially simultaneously such that the at least one property of the specimen can be determined at the multiple locations substantially simultaneously.

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4110. The method of claim 4103, wherein the beam profile ellipsometer is further coupled to a process chamber of the etch tool.

4111. The method of claim 4103, wherein the beam profile ellipsometer is arranged
25 laterally proximate to a process chamber of the etch tool.

4112. The method of claim 4103, wherein the beam profile ellipsometer is arranged vertically proximate to a process chamber of the etch tool.

4113. The method of claim 4103, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, and wherein processing the one or more output signals comprises determining the property of the specimen during an etch process.

4114. The method of claim 4103, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising obtaining a signature characterizing etching of the specimen, wherein the signature comprises at least one singularity representative of an end of etching of the specimen.

4115. The method of claim 4103, wherein the beam profile ellipsometer is further coupled to a stage disposed within a process chamber of the etch tool, the method further comprising altering a parameter of one or more instruments coupled to the etch tool in response to the determined property using an in situ control technique.

4116. The method of claim 4103, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the beam profile ellipsometer, directing light during said moving, and detecting light during said moving.

4117. A system configured to determine at least one property of a specimen during use, comprising:

an etch tool configured to etch the specimen during use;

a beam profile ellipsometer coupled to the etch tool, comprising:

an illumination system configured to direct an incident beam of light having a known polarization state to the specimen during use; and

a detection system coupled to the illumination system and configured to detect light returned from the specimen during use, wherein the beam profile ellipsometer is configured to generate one or more output signals responsive to the detected light during use;

a local processor coupled to the beam profile ellipsometer and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to further process the one or more output signals to determine a property of the specimen during use.

4118. A method for determining at least one property of a specimen, comprising:

etching the specimen using an etch tool;

directing an incident beam of light having a known polarization state to the specimen using an illumination system;

detecting light returned from the surface of the specimen using a detection system, wherein the illumination system and the detection system comprise a beam profile

ellipsometer, and wherein the beam profile ellipsometer is coupled to the etch tool;

generating one or more output signals responsive to the detected light; and

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processing the one or more output signals to determine a property of the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the beam profile ellipsometer;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

15

further processing the partially processed one or more output signals using the remote controller computer.

4119. A system configured to a characteristic of a specimen during use, comprising:

20

an ion implanter configured to direct ions toward the specimen during use;

a measurement device coupled to the ion implanter, wherein the measurement device is configured:

25

to periodically direct an incident beam of light to a region of the specimen to periodically excite the region of the specimen during use;

to direct a sample beam of light to the periodically excited region of the specimen during use;

5 to measure an intensity of the sample beam reflected from the periodically excited region of the specimen during use; and

to generate one or more output signals responsive to the measured intensity of the reflected sample beam; and

10 a processor coupled to the measurement device and configured to determine a characteristic of the region of the specimen from the one or more output signals during use.

4120. The system of claim 4119, further comprising a stage coupled to the measurement
15 device, wherein the stage is configured to move laterally during use.

4121. The system of claim 4119, further comprising a stage coupled to the measurement device, wherein the stage is configured to move rotatably during use.

20 4122. The system of claim 4119, further comprising a stage coupled to the measurement device, wherein the stage is configured to move laterally and rotatably during use.

4123. The system of claim 4119, further comprising an additional measurement device coupled to the ion implanter, wherein the processor is further configured to determine an
25 additional property of the specimen from one or more output signals generated by the additional measurement device.

4124. The system of claim 4119, wherein the characteristic is selected from the group consisting of a presence of ions in the region, a concentration of ions in the region, a depth of the region, and a distribution profile of the region.

5 4125. The system of claim 4119, wherein the processor is further configured to determine at least two characteristics of the implanted region substantially simultaneously during use.

10 4126. The system of claim 4119, wherein the measurement device is further configured to periodically direct the incident beam of light to multiple regions of the specimen substantially simultaneously during use, to direct the sample beam of light to the multiple periodically excited regions of the specimen substantially simultaneously during use, and to measure the intensity of the sample beam reflected from the multiple periodically excited regions of the specimen substantially simultaneously during use such that the
15 characteristic of multiple regions of the specimen can be determined substantially simultaneously.

4127. The system of claim 4119, wherein the measurement device is further coupled to a process chamber of the ion implanter.
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4128. The system of claim 4119, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter.

25 4129. The system of claim 4119, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, and wherein the ion implanter comprises a wafer handler configured to move the specimen to a stage coupled to the measurement device during use.

4136. The system of claim 4119, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the etch tool.

5 4137. The system of claim 4119, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, and wherein the stage is configured to support the specimen during and ion implantation process step.

10 4138. The system of claim 4119, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, and wherein the processor is further configured to determine the characteristic of the region during an ion implantation process step.

15 4139. The system of claim 4119, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, and wherein the processor is further configured to obtain a signature characterizing the implantation of ions during use, and wherein the signature comprises at least one singularity representative of an end of the implantation of ions.

20 4140. The system of claim 4119, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, wherein the processor is coupled to the ion implanter, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the ion implanter in response to the determined characteristic using an in situ control technique during use.

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4141. The system of claim 4119, wherein the ion implanter comprises a first process chamber and a second process chamber, and wherein a stage coupled to the measurement

device is configured to move the specimen from the first process chamber to the second process chamber during use.

5 4142. The system of claim 4119, wherein the ion implanter comprises a first process chamber and a second process chamber, wherein a stage coupled to the measurement device is configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the processor is further configured to determine the property of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

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4143. The system of claim 4119, wherein the processor is further configured to compare the determined characteristic of the region and characteristics of a plurality of regions during use.

15 4144. The system of claim 4119, wherein the processor is further configured to compare the determined characteristic of the region to a predetermined range for the characteristic during use.

20 4145. The system of claim 4144, wherein the processor is further configured to generate an output signal if the determined characteristic of the region is outside of the predetermined range for the characteristic during use.

25 4146. The system of claim 4119, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to the determined characteristic of the region during use.

4147. The system of claim 4119, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedback control technique during use.

- 5 4148. The system of claim 4119, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedforward control technique during use.

- 10 4149. The system of claim 4119, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined characteristic of the region.

- 15 4150. The system of claim 4119, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to calibrate the measurement device using the database during use.

- 20 4151. The system of claim 4119, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

- 25 4152. The system of claim 4119, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined characteristic of the region and characteristics of a plurality of regions, and wherein the characteristics of the plurality of regions are determined using the measurement device.

4153. The system of claim 4119, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined characteristic of

the region and characteristics of a plurality of regions, and wherein the characteristics of the plurality of regions are determined using a plurality of measurement devices.

5 4154. The system of claim 4153, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

10 4155. The system of claim 4153, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

15 4156. The system of claim 4119, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

20 4157. The system of claim 4119, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

25 4158. The system of claim 4119, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to

at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

5 4159. The system of claim 4119, wherein the processor is further coupled to the ion implanter.

4160. The system of claim 4119, wherein the processor is further coupled to the ion implanter, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the ion implanter in response to the determined
10 characteristic using a feedback control technique during use.

4161. The system of claim 4119, wherein the processor is further coupled to the ion implanter, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the ion implanter in response to the determined
15 characteristic using a feedforward control technique during use.

4162. The system of claim 4119, wherein the processor is further coupled to the ion implanter, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the ion implanter during use.
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4163. The system of claim 4119, wherein the processor is further coupled to the ion implanter, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the ion implanter during use, and wherein the processor is further configured to determine a relationship between the determined characteristic and
25 at least one of the monitored parameters during use.

4164. The system of claim 4119, wherein the processor is further coupled to the ion implanter, wherein the processor is further configured to monitor a parameter of one or

more instruments coupled to the ion implanter during use, wherein the processor is further configured to determine a relationship between the determined characteristic and at least one of the monitored parameters during use, and wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

4165. The system of claim 4119, wherein the processor is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to an ion implanter.

4166. The system of claim 4119, wherein the processor is further coupled to a plurality of ion implanters, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the plurality of ion implanters during use.

4167. The system of claim 4119, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

4168. The system of claim 4167, wherein the local processor is further configured to determine the characteristic of the region during use.

4169. The system of claim 4167, wherein the remote controller computer is further configured to determine the characteristic of the region during use.

4170. A method for determining a characteristic of a specimen, comprising:

implanting ions into the specimen using an ion implanter;

periodically directing an incident beam of light to a region of the specimen to
periodically excite the region of the specimen using an illumination system of a
5 measurement device, wherein the measurement device is coupled to the ion
implanter;

directing a sample beam of light to the periodically excited region of the specimen
using the illumination system;

10 measuring an intensity of the sample beam reflected from the periodically excited
region of the specimen using a detection system of the measurement device;

generating one or more output signals responsive to the measured intensity of the
15 reflected sample beam; and

processing the one or more output signals to determine a characteristic of the
region of the specimen.

20 4171. The method of claim 4170, wherein a stage is coupled to the measurement device,
the method further comprising laterally moving the stage during said periodically
directing, said directing, and said measuring.

4172. The method of claim 4170, wherein a stage is coupled to the measurement device,
25 the method further comprising rotatably moving the stage during said periodically
directing, said directing, and said measuring.

4173. The method of claim 4170, wherein a stage is coupled to the measurement device, the method further comprising laterally and rotatably moving the stage during said periodically directing, said directing, and said measuring.

5 4174. The method of claim 4170, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the ion implanter, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

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4175. The method of claim 4170, wherein the characteristic is selected from the group comprising a presence of ions in the region, a depth of the region, a concentration of ions in the region, and a distribution profile of the region.

15 4176. The method of claim 4170, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of the region substantially simultaneously.

4177. The method of claim 4170, further comprising periodically directing the incident
20 beam of light toward multiple regions of the specimen substantially simultaneously, directing the sample beam of light to the multiple periodically excited regions of the specimen substantially simultaneously, and measuring the intensity of the sample beam reflected from the multiple periodically excited regions of the specimen substantially simultaneously such that the characteristic of the multiple regions of the specimen can be
25 determined substantially simultaneously.

4178. The method of claim 4170, wherein the measurement device is further coupled to a process chamber of the ion implanter.

4179. The method of claim 4170, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter.

5 4180. The method of claim 4170, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, the method further comprising moving the specimen to a stage coupled to the measurement device with a wafer handler of the ion implanter.

10 4181. The method of claim 4170, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, the method further comprising moving the specimen from the measurement device to the ion implanter with a stage coupled to the measurement device.

15 4182. The method of claim 4170, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, the method further comprising moving the specimen to the process chamber of the ion implanter with a stage coupled to the measurement device.

20 4183. The method of claim 4170, further comprising determining the characteristic of the specimen while the specimen is waiting between process steps.

4184. The method of claim 4170, further comprising supporting the specimen during an ion implantation process step with a support device of the ion implanter, wherein an
25 upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the measurement device.

4185. The method of claim 4170, further comprising supporting the specimen during an ion implantation process step with a support device of the ion implanter, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the measurement device.

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4186. The method of claim 4170, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the ion implanter.

10 4187. The method of claim 4170, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the ion implanter.

15 4188. The method of claim 4170, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising supporting the specimen during an ion implantation process step with the stage.

20 4189. The method of claim 4170, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, and wherein processing the one or more output signals comprises determining the property of the specimen during an ion implantation process.

25 4190. The method of claim 4170, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising obtaining a signature characterizing the implantation of ions into the specimen, wherein the signature comprises at least one singularity representative of an end of the implantation of ions.

4191. The method of claim 4170, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising altering a parameter of one or more instruments coupled to the ion implanter
5 in response to the determined characteristic using an in situ control technique.

4192. The method of claim 4170, wherein the ion implanter comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage
10 coupled to the measurement device.

4193. The method of claim 4170, wherein the ion implanter comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage
15 coupled to the measurement device during said periodically directing, said directing, and said measuring.

4194. The method of claim 4170, further comprising comparing the determined characteristic and characteristics of a plurality of regions.
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4195. The method of claim 4170, further comprising comparing the determined characteristic to a predetermined range for the characteristic.

4196. The method of claim 4195, further comprising generating an output signal if the
25 determined characteristic is outside of the predetermined range.

4197. The method of claim 4170, further comprising altering a sampling frequency of the measurement device in response to the determined characteristic of the region.

4198. The method of claim 4170, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedback control technique.

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4199. The method of claim 4170, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedforward control technique.

10 4200. The method of claim 4170, further comprising generating a database, wherein the database comprises the determined characteristic of the region.

4201. The method of claim 4170, further comprising generating a database, wherein the database comprises the determined characteristic of the region, the method further
15 comprising calibrating the measurement device using the database.

4202. The method of claim 4170, further comprising generating a database, wherein the database comprises the determined characteristic of the region, the method further comprising monitoring output signals of the measurement device using the database.

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4203. The method of claim 4170, further comprising generating a database, wherein the database comprises the determined characteristic of the region and characteristics of a plurality of regions.

25 4204. The method of claim 4170, further comprising generating a database, wherein the database comprises the determined characteristic of the region and characteristics of a plurality of regions, wherein the characteristics of the plurality of regions are generated

using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

5 4205. The method of claim 4170, further comprising generating a database, wherein the database comprises the determined characteristic of the region and characteristics of a plurality of regions, wherein the characteristics of the plurality of regions are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

10 4206. The method of claim 4170, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

15 4207. The method of claim 4170, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

20 4208. The method of claim 4170, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one
25 of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

4209. The method of claim 4170, further comprising altering a parameter of one or more instruments coupled to the ion implanter in response to the determined characteristic using a feedback control technique.

5 4210. The method of claim 4170, further comprising altering a parameter of one or more instruments coupled to the ion implanter in response to the determined characteristic using a feedforward control technique.

4211. The method of claim 4170, further comprising monitoring a parameter of one or
10 more instruments coupled to the ion implanter.

4212. The method of claim 4170, further comprising monitoring a parameter of one or
more instruments coupled to the ion implanter and determining a relationship between the
determined characteristic and at least one of the monitored parameters.

15 4213. The method of claim 4170, further comprising monitoring a parameter of one or
more instruments coupled to the ion implanter, determining a relationship between the
determined characteristic and at least one of the monitored parameters, and altering a
parameter of at least one of the instruments in response to the relationship.

20 4214. The method of claim 4170, further comprising altering a parameter of one or more
instruments coupled to at least one semiconductor fabrication process tool in response to
the determined characteristic of the region.

25 4215. The method of claim 4170, wherein processing the one or more output signals
comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

4216. The method of claim 4215, wherein at least partially processing the one or more
output signals comprises determining the characteristic of the region.

4217. The method of claim 4215, wherein further processing the partially processed one
or more output signals comprises determining the characteristic of the region.

4218. A computer-implemented method for controlling a system configured to
determine a characteristic of a specimen during use, wherein the system comprises a
measurement device coupled to an ion implanter, and wherein the ion implanter is
configured to direct ions toward the specimen during use, the method comprising:

controlling the measurement device, wherein the measurement device comprises
an illumination system and a detection system, comprising:

controlling the illumination system to periodically direct an incident beam
of light to a region of the specimen to periodically excite the region of the
specimen;

controlling the illumination system to direct a sample beam of light to the periodically excited region of the specimen;

5 controlling the detection system to measure an intensity of the sample beam reflected from the periodically excited region of the specimen; and

generating one or more output signals responsive to the measured intensity; and

10 processing the one or more output signals to determine a characteristic of the region of the specimen.

4219. The method of claim 4218, wherein the system further comprises a stage coupled to the measurement device, the method further comprising supporting the specimen with
15 the stage and controlling the stage to move laterally during said controlling the measurement device.

4220. The method of claim 4218, wherein the system further comprises a stage coupled to the measurement device, the method further comprising supporting the specimen with
20 the stage and controlling the stage to move rotatably during said controlling the measurement device.

4221. The method of claim 4218, wherein the system further comprises a stage coupled to the measurement device, the method further comprising supporting the specimen with
25 the stage and controlling the stage to move laterally and rotatably during said controlling the measurement device.

4222. The method of claim 4218, wherein the system further comprises an additional measurement device coupled to the ion implanter, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

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4223. The method of claim 4218, wherein the characteristic is selected from the group consisting of a presence of ions in the region, a depth of the region, a concentration of ions in the region, and a distribution profile of the region.

10 4224. The method of claim 4218, wherein processing the one or more output signals to determine the characteristic of the region comprises substantially simultaneously determining at least two characteristics of the region.

4225. The method of claim 4218, further comprising controlling the illumination system
15 to periodically direct the incident beam of light to multiple regions of the specimen substantially simultaneously, controlling the illumination system to direct the sample beam of light to the multiple periodically excited regions of the specimen, and controlling the detection system to measure the intensity of the sample beam reflected from the multiple periodically excited regions of the specimen substantially simultaneously such
20 that the characteristic of the multiple regions of the specimen can be determined substantially simultaneously.

4226. The method of claim 4218, wherein the measurement device is further coupled to a process chamber of the ion implanter.

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4227. The method of claim 4218, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter.

4228. The method of claim 4218, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, the method further comprising controlling a wafer handler coupled to the ion implanter to move the specimen to a stage coupled to the measurement device.

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4229. The method of claim 4218, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the measurement device to the ion implanter.

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4230. The method of claim 4218, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter, the method further comprising controlling a stage coupled to the measurement device to move the specimen to a process chamber of the ion implanter.

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4231. The method of claim 4218, the method further comprising controlling a wafer handler to move the specimen to a stage coupled to the measurement device such that at least the one characteristic of the layer of the specimen can be determined while the specimen is waiting between process steps.

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4232. The method of claim 4218, further comprising supporting the specimen during an ion implantation process step with a support device of the ion implanter, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the measurement device.

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4233. The method of claim 4218, further comprising supporting the specimen during an ion implantation process step with a support device of the ion implanter, wherein an

upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the measurement device.

4234. The method of claim 4218, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the ion implanter.

4235. The method of claim 4218, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the ion implanter.

4236. The method of claim 4218, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising controlling the stage to support the specimen during an ion implantation process step.

4237. The method of claim 4218, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising processing the one or more output signals to determine the characteristic of the region during an ion implantation process step.

4238. The method of claim 4218, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising controlling the measurement device to obtain a signature characterizing the implantation of ions, wherein the signature comprises at least one singularity representative of an end of the implantation of ions.

4239. The method of claim 4218, further comprising altering a parameter of one or more instruments coupled to the ion implanter in response to the determined characteristic using an in situ control technique.

5 4240. The method of claim 4218, wherein the ion implanter comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber.

10 4241. The method of claim 4218, wherein the ion implanter comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber and controlling the measurement device during said moving.

15 4242. The method of claim 4218, further comprising comparing the determined characteristic of the region and characteristics of a plurality of regions.

20 4243. The method of claim 4218, further comprising comparing the determined characteristic of the region to a predetermined range for the characteristic.

4244. The method of claim 4243, further comprising generating an output signal if the determined characteristic is outside of the predetermined range for the characteristic.

25 4245. The method of claim 4218, further comprising altering a sampling frequency of the measurement device in response to the determined characteristic of the region.

4246. The method of claim 4218, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedback control technique.

- 5 4247. The method of claim 4218, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to the determined characteristic using a feedforward control technique.

- 10 4248. The method of claim 4218, further comprising generating a database, wherein the database comprises the determined characteristic of the region.

- 15 4249. The method of claim 4218, further comprising generating a database, wherein the database comprises the determined characteristic of the region, and calibrating the measurement device using the database.

4250. The method of claim 4218, further comprising generating a database, wherein the database comprises the determined characteristic of the region, and monitoring output signals of the measurement device using the database.

- 20 4251. The method of claim 4218, further comprising generating a database, wherein the database comprises the determined characteristic of the region, and wherein the database further comprises characteristics of a plurality of regions.

- 25 4252. The method of claim 4218, further comprising generating a database, wherein the database comprises the determined characteristic of the region, wherein the database further comprises characteristics of a plurality of regions, and wherein the determined characteristics of the plurality of regions are generated using a plurality of measurement devices.

4253. The method of claim 4252, further comprising calibrating the plurality of measurement devices using the database.

5 4254. The method of claim 4252, further comprising monitoring output signals of the plurality of measurement devices using the database.

4255. The method of claim 4218, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand
10 alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

4256. The method of claim 4218, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand
15 alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

4257. The method of claim 4218, wherein the system is further configured to determine
20 at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

25 4258. The method of claim 4218, further comprising altering a parameter of one or more instruments coupled to an ion implanter in response to the determined characteristic of the region using a feedback control technique.

4259. The method of claim 4218, further comprising altering a parameter of one or more instruments coupled to an ion implanter in response to the determined characteristic of the region using a feedforward control technique.

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4260. The method of claim 4218, further comprising monitoring a parameter of one or more instruments coupled to the ion implanter.

4261. The method of claim 4218, further comprising monitoring a parameter of one or more instruments coupled to the ion implanter and determining a relationship between the determined characteristic and at least one of the monitored parameters.

4262. The method of claim 4218, further comprising monitoring a parameter of one or more instruments coupled to the ion implanter, determining a relationship between the determined characteristic and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

4263. The method of claim 4218, further comprising altering a parameter of one or more instruments coupled to at least one of a plurality of semiconductor fabrication process tools in response to the determined characteristic of the region.

4264. The method of claim 4218, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

5 further processing the partially processed one or more output signals using the remote controller computer.

4265. The method of claim 4264, wherein at least partially processing the one or more output signals comprises determining the characteristic.

10 4266. The method of claim 4264, wherein further processing the partially processes output signal comprises determining the characteristic.

4267. A semiconductor device fabricated by a method, the method comprising:

15 implanting ions into a specimen using an ion implanter, wherein the specimen comprises at least a portion of the semiconductor device;

periodically directing an incident beam of light to a region of the specimen to periodically excite the region of the specimen using an illumination system of a measurement device, wherein the measurement device is coupled to the ion
20 implanter;

directing a sample beam of light to the periodically excited region of the specimen using the illumination system;

25 measuring an intensity of the sample beam reflected from the periodically excited region of the specimen using a detection system of the measurement device;

generating one or more output signals responsive to the measured intensity of the reflected sample beam; and

processing the one or more output signals to determine a characteristic of the region of the specimen.

4268. The device of claim 4267, wherein the characteristic is selected from the group consisting of a presence of ions in the region, a depth of the region, a concentration of ions in the region, and a distribution profile of the region.

4269. The device of claim 4267, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the ion implanter, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

4270. The device of claim 4267, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

4271. The device of claim 4267, further comprising periodically directing the incident beam of light toward multiple regions of the specimen substantially simultaneously, directing the sample beam of light to the multiple periodically excited regions of the specimen substantially simultaneously, and measuring the intensity of the sample beam reflected from the multiple periodically excited regions of the specimen substantially simultaneously such that the characteristic of the multiple regions of the specimen can be determined substantially simultaneously.

4272. The device of claim 4267, wherein the measurement device is further coupled to a process chamber of the ion implanter.

5 4273. The device of claim 4267, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter.

4274. The device of claim 4267, wherein the measurement device is arranged vertically proximate to a process chamber of the ion implanter.

10 4275. The device of claim 4267, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, and wherein processing the one or more output signals comprises determining the property of the specimen during an ion implantation process.

15 4276. The device of claim 4267, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising obtaining a signature characterizing ion implantation of the specimen, wherein the signature comprises at least one singularity representative of an end of the ion implantation of the specimen.

20 4277. The device of claim 4267, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising altering a parameter of one or more instruments coupled to the ion implanter in response to the determined property using an in situ control technique.

25 4278. The device of claim 4267, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the

measurement device and periodically directing, directing, and measuring the intensity during said moving.

4279. A method for fabricating a semiconductor device, comprising:

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implanting ions into a specimen using an ion implanter, wherein the specimen comprises at least a portion of the semiconductor device;

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periodically directing an incident beam of light to a region of the specimen to periodically excite the region of the specimen using an illumination system of a measurement device, wherein the measurement device is coupled to the ion implanter;

15

directing a sample beam of light to the periodically excited region of the specimen using the illumination system;

20

measuring an intensity of the sample beam reflected from the periodically excited region of the specimen using a detection system of the measurement device;

generating one or more output signals responsive to the measured intensity of the reflected sample beam; and

25

processing the one or more output signals to determine a characteristic of the region of the specimen.

4280. The method of claim 4279, wherein the characteristic is selected from the group consisting of a presence of ions in the region, a depth of the region, a concentration of ions in the region, and a distribution profile of the region.

4281. The method of claim 4279, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the ion implanter, the method further comprising processing one or more output signals
5 generated by the additional measurement device to determine an additional property of the specimen.

4282. The method of claim 4279, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties
10 of the specimen substantially simultaneously.

4283. The method of claim 4279, further comprising periodically directing the incident beam of light toward multiple regions of the specimen substantially simultaneously, directing the sample beam of light to the multiple periodically excited regions of the
15 specimen substantially simultaneously, and measuring the intensity of the sample beam reflected from the multiple periodically excited regions of the specimen substantially simultaneously such that the characteristic of the multiple regions of the specimen can be determined substantially simultaneously.

4284. The method of claim 4279, wherein the measurement device is further coupled to a process chamber of the ion implanter.
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4285. The method of claim 4279, wherein the measurement device is arranged laterally proximate to a process chamber of the ion implanter.
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4286. The method of claim 4279, wherein the measurement device is arranged vertically proximate to a process chamber of the ion implanter.

4287. The method of claim 4279, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, and wherein processing the one or more output signals comprises determining the property of the specimen during an ion implantation process.

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4288. The method of claim 4279, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising obtaining a signature characterizing ion implantation of the specimen, wherein the signature comprises at least one singularity representative of an end of the ion implantation of the specimen.

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4289. The method of claim 4279, wherein the measurement device is further coupled to a stage disposed within a process chamber of the ion implanter, the method further comprising altering a parameter of one or more instruments coupled to the ion implanter in response to the determined property using an in situ control technique.

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4290. The method of claim 4279, wherein the etch tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the measurement device and periodically directing, directing, and measuring the intensity during said moving.

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4291. A system configured to determine a characteristic of a specimen during use, comprising:

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an ion implanter configured to direct ions toward the specimen during use;

a measurement device coupled to the ion implanter, wherein the measurement

device is configured:

to periodically direct an incident beam of light to a region of the specimen
to periodically excite the region of the specimen during use;

5

to direct a sample beam of light to the periodically excited region of the
specimen during use;

10

to measure an intensity of the sample beam reflected from the periodically
excited region of the specimen during use; and

to generate one or more output signals responsive to the measured
intensity of the reflected sample beam during use;

15

a local processor coupled to the measurement device and configured to at least
partially process the one or more output signals during use; and

20

a remote controller computer coupled to the local processor, wherein the remote
controller computer is configured to receive the at least partially processed one or
more output signals and to further process the at least partially processed one or
more output signals to determine a characteristic of the region of the specimen.

4292. A method for determining a characteristic of a specimen, comprising:

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implanting ions into a specimen using an ion implanter;

periodically directing an incident beam of light to a region of the specimen to
periodically excite the region of the specimen using an illumination system of a

measurement device, wherein the measurement device is coupled to the ion implanter;

directing a sample beam of light to the periodically excited region of the specimen using the illumination system;

measuring an intensity of the sample beam reflected from the periodically excited region of the specimen using a detection system of the measurement device;

generating one or more output signals responsive to the measured intensity of the reflected sample beam; and

processing the one or more output signals to determine a characteristic of the region of the specimen, comprising:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

4293. A system configured to determine at least one characteristic of micro defects on a surface of a specimen during use, comprising:

a process tool configured to process the specimen during use;

a stage configured to support the specimen during use, wherein the stage is further configured to rotate during use;

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a measurement device coupled to the process tool, wherein the measurement device is further coupled to the stage, comprising:

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an illumination system configured to direct light toward the surface of the specimen during the process and during rotation of the stage; and

15

a detection system coupled to the illumination system and configured to detect light propagating from the surface of the specimen during the process and during rotation of the stage, wherein the measurement device is configured to generate one or more output signals in response to the detected light during use; and

20

a processor coupled to the measurement device and configured to determine at least the one characteristic of micro defects on the surface of the specimen from the one or more output signals during use.

4294. The system of claim 4293, wherein the stage is further configured to move laterally during use.

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4295. The system of claim 4293, further comprising an additional measurement device coupled to the process tool, wherein the processor is further configured to determine an additional property of the specimen from one or more output signals generated by the additional measurement device.

4296. The system of claim 4293, wherein the detected light comprises dark field light propagating along a dark field path from the surface of the specimen.

5 4297. The system of claim 4293, wherein the detected light comprises bright field light propagating along a bright field path from the surface of the specimen.

4298. The system of claim 4293, wherein the detected light comprises dark field light propagating along a dark field path from the surface of the specimen and bright field light
10 propagating along a bright field path from the surface of the specimen.

4299. The system of claim 4293, wherein the detected light comprises dark field light propagating along multiple dark field paths from the surface of the specimen.

15 4300. The system of claim 4293, wherein the detected light comprises dark field light propagating along multiple dark field paths from the surface of the specimen and bright field light propagating along a bright field path from the surface of the specimen.

4301. The system of claim 4293, wherein the specimen comprises a plurality of dies
20 having repeatable pattern features, and wherein the processor is further configured to compare output signals responsive to detected light from at least two of the plurality of dies to determine at least the one characteristic of micro defects on the surface of the specimen.

25 4302. The system of claim 4293, wherein at least the one characteristic of micro defects is selected from the group consisting of a presence, a location, a number, and a type of micro defects on the surface of the specimen.

4303. The system of claim 4293, wherein the processor is further configured to determine at least two characteristics of micro defects on the surface of the specimen substantially simultaneously during use.

5 4304. The system of claim 4293, wherein the illumination system is further configured to direct light toward multiple locations on the surface of the specimen substantially simultaneously during the process and during rotation of the stage, and wherein the detection system is further configured to detect light propagating from the multiple locations on the surface of the specimen substantially simultaneously during the process
10 and during rotation of the stage such that at least one characteristic of micro defects on the surface of the specimen at the multiple locations can be determined substantially simultaneously.

4305. The system of claim 4293, wherein the processor is further configured to
15 determine an additional characteristic of the specimen from the one or more output signals during use, and wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20 4306. The system of claim 4304, wherein the process tool is selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

25 4307. The system of claim 4293, wherein the measurement device is further coupled to a process chamber of the process tool.

4308. The system of claim 4293, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool.

4309. The system of claim 4293, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

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4310. The system of claim 4293, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, and wherein the stage is configured to move the specimen from the measurement device to the process tool during use.

10 4311. The system of claim 4293, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, and wherein the stage is configured to move the specimen to the process chamber of the process tool during use.

15 4312. The system of claim 4293, wherein the system is further configured to determine at least the one characteristic while the specimen is waiting between process steps.

4313. The system of claim 4293, wherein the process tool comprises a support device configured to support the specimen during the process, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

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4314. The system of claim 4293, wherein the process tool comprises a support device configured to support the specimen during the process, and wherein an upper surface of the support device is substantially perpendicular to an upper surface of the stage.

25 4315. The system of claim 4293, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

4316. The system of claim 4293, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

5 4317. The system of claim 4293, wherein the stage is disposed within a process chamber of the process tool, and wherein the stage is further configured to support the specimen during the process.

4318. The system of claim 4293, wherein the stage is disposed within a process chamber
10 of the process tool, and wherein the processor is further configured to determine at least the one characteristic during the process.

4319. The system of claim 4293, wherein the stage is disposed within a process chamber
15 of the process tool, and wherein the processor is further configured to obtain a signature characteristic of the process during use, and wherein the signature comprises at least one singularity representative of an end of the process.

4320. The system of claim 4293, wherein the stage is disposed within a process chamber
20 of the process tool, wherein the processor is coupled to the process tool, and wherein the processor is further configured to alter a parameter of an instrument coupled to the process chamber in response to the characteristic using an in situ control technique during use.

4321. The system of claim 4293, wherein the process tool comprises a first process
25 chamber and a second process chamber, wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the processor is further configured to determine at least one characteristic as

the stage is moving the specimen from the first process chamber to the second process chamber.

5 4322. The system of claim 4293, wherein the processor is further configured to compare at least the one determined characteristic to characteristics of a plurality of specimens during use.

10 4323. The system of claim 4293, wherein the processor is further configured to compare at least the one determined characteristic to a predetermined range for the characteristic during use.

15 4324. The system of claim 4293, wherein the processor is further configured to compare at least the one determined characteristic to a predetermined range for the characteristic during use, and wherein the processor is further configured to generate an output signal if at least the one determined characteristic is outside of the predetermined range for the characteristic during use.

20 4325. The system of claim 4293, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least the one determined characteristic during use.

25 4326. The system of claim 4293, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least the one determined characteristic using a feedback control technique during use.

4327. The system of claim 4293, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to

at least the one determined characteristic using a feedforward control technique during use.

5 4328. The system of claim 4293, wherein the processor is further configured to generate a database during use, and wherein the database comprises at least the one determined characteristic.

10 4329. The system of claim 4293, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to calibrate the measurement device using the database during use.

15 4330. The system of claim 4293, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

20 4331. The system of claim 4293, wherein the processor is further configured to generate a database during use, wherein the database comprises at least the one determined characteristic and characteristics of a plurality of specimens, and wherein the characteristics of the plurality of specimens are determined using the measurement device.

25 4332. The system of claim 4293, wherein the processor is further configured to generate a database during use, wherein the database comprises at least the one determined characteristic and characteristics of a plurality of specimens, and wherein the characteristics of the plurality of specimens are determined using a plurality of measurement devices.

4333. The system of claim 4332, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

5 4334. The system of claim 4332, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

10 4335. The system of claim 4293, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

15 4336. The system of claim 4293, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

20 4337. The system of claim 4293, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to
25 at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

4338. The system of claim 4293, wherein the processor is further coupled to the process tool.

4339. The system of claim 4293, wherein the processor is further coupled to the process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process chamber in response to at least the one determined characteristic using a feedback control technique during use.

4340. The system of claim 4293, wherein the processor is further coupled to the process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process chamber in response to at least the one determined characteristic using a feedforward control technique during use.

4341. The system of claim 4293, wherein the processor is further coupled to the process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

4342. The system of claim 4293, wherein the processor is further coupled to the process tool, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use, and wherein the processor is further configured to determine a relationship between at least the one determined characteristic and at least one of the monitored parameters during use.

4343. The system of claim 4293, wherein the processor is further coupled to the process tool, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use, wherein the processor is further configured to determine a relationship between at least the one determined characteristic and at least one of the monitored parameters during use, and wherein the processor is

further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

5 4344. The system of claim 4293, wherein the processor is further coupled to a plurality of measurement devices, and wherein at least two of the plurality of measurement devices is coupled to at least one of a plurality of process chambers of the process tool.

10 4345. The system of claim 4293, wherein the processor is further coupled to a plurality of process tools, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the plurality of process tools during use.

15 4346. The system of claim 4293, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

20 4347. The system of claim 4346, wherein the local processor is further configured to determine at least the one characteristic during use.

4348. The system of claim 4346, wherein the remote controller computer is further configured to determine at least the one characteristic during use.

25 4349. The system of claim 4293, wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a deposition tool, an ion implanter, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, and a plating tool.

4350. A method for determining at least one characteristic of micro defects on a specimen, comprising:

processing the specimen in a process tool;

supporting the specimen on a stage;

rotating the stage while the specimen is supported on the stage;

directing light toward a surface of the specimen using an illumination system during the process and during rotation of the stage;

detecting light propagating from the surface of the specimen using a detection system during the process and during rotation of the stage, wherein illumination system and the detection system comprises a measurement device, and wherein the measurement device is coupled to the process tool;

generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine at least the one characteristic of micro defects on the specimen.

4351. The method of claim 4350, further comprising laterally moving the stage while the specimen is supported on the stage.

4352. The method of claim 4350, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the process tool, the method further comprising processing one or more output signals

generated by the additional measurement device to determine an additional property of the specimen.

5 4353. The method of claim 4350, wherein the detected light comprises dark field light propagating along a dark field path from the surface of the specimen.

4354. The method of claim 4350, wherein the detected light comprises bright field light propagating along a bright field path from the surface of the specimen.

10 4355. The method of claim 4350, wherein the detected light comprises dark field light propagating along a dark field path from the surface of the specimen and bright field light propagating along a bright field path from the surface of the specimen.

15 4356. The method of claim 4350, wherein the detected light comprises dark field light propagating along multiple dark field paths from the surface of the specimen.

4357. The method of claim 4350, wherein the detected light comprises dark field light propagating along multiple dark field paths from the surface of the specimen and bright field light propagating along a bright field path from the surface of the specimen.

20 4358. The method of claim 4350, wherein the specimen comprises a plurality of dies having repeatable pattern features, and wherein processing the one or more output signals comprises comparing output signals responsive to detected light from at least two of the plurality of dies to determine at least the one characteristic of micro defects on the surface
25 of the specimen.

4359. The method of claim 4350, wherein at least the one characteristic of micro defects is selected from the group consisting of a presence, a location, a number, and a type of micro defects on the surface of the specimen.

5 4360. The method of claim 4350, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of micro defects on the specimen substantially simultaneously.

10 4361. The method of claim 4350, further comprising directing light toward multiple locations on the surface of the specimen substantially simultaneously during the process and during the rotation of the stage and detecting light propagating from the multiple locations substantially simultaneously during the process and during the rotation of the stage such that at least one characteristic of micro defects on the surface of the specimen at the multiple locations can be determined substantially simultaneously.

15 4362. The method of claim 4350, further comprising processing the one or more output signals to determine an additional characteristic of the specimen, wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

20 4363. The method of claim 4362, wherein the process tool is selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

25 4364. The method of claim 4350, wherein the measurement device is further coupled to a process chamber of the process tool.

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4365. The method of claim 4350, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool.

5 4366. The method of claim 4350, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, the method further comprising moving the specimen to the stage with a wafer handler of the process tool.

10 4367. The method of claim 4350, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, the method further comprising moving the specimen from the measurement device to the process tool with the stage.

15 4368. The method of claim 4350, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, the method further comprising moving the specimen from the measurement device to the process chamber with the stage.

4369. The method of claim 4350, further comprising determining at least the one characteristic while the specimen is waiting between process steps.

20 4370. The method of claim 4350, further comprising supporting the specimen during a process step with a support device of the process tool, wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

25 4371. The method of claim 4350, further comprising supporting the specimen during a process step with a support device of the process tool, wherein an upper surface of the support device is substantially perpendicular to an upper surface of the stage.

4372. The method of claim 4350, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

- 5 4373. The method of claim 4350, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

4374. The method of claim 4350, wherein the stage is disposed within a process chamber of the process tool, the method further comprising supporting the specimen during a process step with the stage.

4375. The method of claim 4350, wherein the stage is disposed within a process chamber of the process tool, and wherein processing the one or more output signals comprises determining the at least the one characteristic of micro defects on the specimen during the process.

4376. The method of claim 4350, wherein the stage is disposed within a process chamber of the process tool, the method further comprising obtaining a signature characterizing processing of the specimen, wherein the signature comprises at least one singularity representative of an end of the processing of the specimen.

4377. The method of claim 4350, wherein the stage is disposed within a process chamber of the process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least the one determined characteristic using an in situ control technique.

4378. The method of claim 4350, wherein the process tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using the stage.

5 4379. The method of claim 4350, wherein the process tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using the stage, directing light during said moving, and detecting light during said moving.

10 4380. The method of claim 4350, further comprising comparing at least the one determined characteristic and characteristics of a plurality of specimens.

4381. The method of claim 4350, further comprising comparing at least the one determined characteristic to a predetermined range for the characteristic.

15 4382. The method of claim 4381, further comprising generating an output signal if at least the one determined characteristic is outside of the predetermined range.

4383. The method of claim 4350, further comprising altering a sampling frequency of
20 the measurement device in response to at least the one determined characteristic.

4384. The method of claim 4350, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least the one determined characteristic using a feedback control technique.

25 4385. The method of claim 4350, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least the one determined characteristic using a feedforward control technique.

4386. The method of claim 4350, further comprising generating a database, wherein the database comprises at least the one determined characteristic.

- 5 4387. The method of claim 4350, further comprising generating a database, wherein the database comprises at least the one determined characteristic, the method further comprising calibrating the measurement device using the database.

- 10 4388. The method of claim 4350, further comprising generating a database, wherein the database comprises at least the one determined characteristic, the method further comprising monitoring output signals generated by the measurement device using the database.

- 15 4389. The method of claim 4350, further comprising generating a database, wherein the database comprises at least the one determined characteristic, wherein the database further comprises characteristics of a plurality of specimens, and wherein the characteristics of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

- 20 4390. The method of claim 4350, further comprising generating a database, wherein the database comprises at least the one determined characteristic, wherein the database further comprises characteristics of a plurality of specimens, and wherein the characteristics of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the database.
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4391. The method of claim 4350, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

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4392. The method of claim 4350, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

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4393. The method of claim 4350, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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4394. The method of claim 4350, further comprising altering a parameter of one or more instruments coupled to the process chamber in response to at least the one determined characteristic using a feedback control technique.

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4395. The method of claim 4350, further comprising altering a parameter of one or more instruments coupled to the process chamber in response to at least the one determined characteristic using a feedforward control technique.

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4396. The method of claim 4350, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

4397. The method of claim 4350, further comprising monitoring a parameter of one or more instruments coupled to the process tool and determining a relationship between at least the one determined characteristic and at least one of the monitored parameters.

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4398. The method of claim 4350, further comprising monitoring a parameter of one or more instruments coupled to the process tool, determining a relationship between at least the one determined characteristic and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

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4399. The method of claim 4350, further comprising altering a parameter of one or more instruments coupled to at least one of a plurality of process tools in response to at least the one determined characteristic.

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4400. The method of claim 4350, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

4401. The method of claim 4400, wherein at least partially processing the one or more output signals comprises determining the characteristic.

4402. The method of claim 4400, wherein further processing the partially processed one or more output signals comprises determining the characteristic.

5 4403. The method of claim 4350, wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a deposition tool, an ion implanter, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, and a plating tool.

10 4404. A computer-implemented method for controlling a system configured to determine at least one characteristic of micro defects on a specimen during use, wherein the system comprises a measurement device coupled a stage, wherein the measurement device is further coupled to a process tool, and wherein the process tool is configured to process the specimen during use, the method comprising:

15 controlling the stage to rotate while the specimen is supported on the stage;

controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, comprising:

20 controlling the illumination system to direct light toward a surface of the specimen during the process and during rotation of the stage;

controlling the detection system to detect light propagating from the surface of the specimen during the process and during rotation of the stage; and
25

generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine at least one characteristic of micro defects on the specimen.

5 4405. The method of claim 4404, further comprising controlling the stage to move laterally while the specimen is supported on the stage.

4406. The method of claim 4404, wherein the system further comprises an additional measurement device coupled to the process tool, the method further comprising processing one or more output signals generated by the additional measurement device to
10 determine an additional property of the specimen.

4407. The method of claim 4404, wherein the detected light comprises dark field light propagating along a dark field path from the surface of the specimen.

15 4408. The method of claim 4404, wherein the detected light comprises bright field light propagating along a bright field path from the surface of the specimen.

4409. The method of claim 4404, wherein the detected light comprises dark field light propagating along a dark field path from the surface of the specimen and bright field light
20 propagating along a bright field path from the surface of the specimen.

4410. The method of claim 4404, wherein the detected light comprises dark field light propagating along multiple dark field paths from the surface of the specimen.

25 4411. The method of claim 4404, wherein the detected light comprises dark field light propagating along multiple dark field paths from the surface of the specimen and bright field light propagating along a bright field path from the surface of the specimen.

4412. The method of claim 4404, wherein the specimen comprises a plurality of dies having repeatable pattern features, and wherein processing the one or more output signals comprises comparing output signals responsive to detected light from at least two of the plurality of dies to determine at least the one characteristic of micro defects on the specimen.

4413. The method of claim 4404, wherein at least the one characteristic of micro defects is selected from the group consisting of a presence, a location, a number, and a type of micro defects on the surface of the specimen.

4414. The method of claim 4404, wherein processing the one or more output signals to determine at least the one characteristic of micro defects on the specimen comprises substantially simultaneously determining at least two characteristics of micro defects on the specimen.

4415. The method of claim 4404, further comprising controlling the illumination system to direct light toward multiple locations on the surface of the specimen substantially simultaneously during the process and during the rotation of the stage and controlling the detection system to detect light propagating from the multiple locations substantially simultaneously during the process and during the rotation of the stage such that at least one characteristic of micro defects on the surface of the specimen at the multiple locations can be determined substantially simultaneously.

4416. The method of claim 4404, further comprising processing the one or more output signals to determine an additional characteristic of the specimen, wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

4417. The method of claim 4416, wherein the process tool is selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

- 5 4418. The method of claim 4404, wherein the measurement device is further coupled to a process chamber of the process tool.

4419. The method of claim 4404, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool.

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4420. The method of claim 4404, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, the method further comprising controlling a wafer handler coupled to the process tool to move the specimen to the stage.

- 15 4421. The method of claim 4404, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, the method further comprising controlling the stage to move the specimen from the measurement device to the process tool.

- 20 4422. The method of claim 4404, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool, the method further comprising controlling the stage to move the specimen from the measurement device to a process chamber of the process tool.

- 25 4423. The method of claim 4404, the method further comprising controlling a wafer handler to move the specimen to a stage coupled to the measurement device such that at least the one characteristic can be determined while the specimen is waiting between process steps.

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5 4424. The method of claim 4404, further comprising supporting the specimen during a process step with a support device of the process tool, wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

4425. The method of claim 4404, further comprising supporting the specimen during a process step with a support device of the process tool, wherein an upper surface of the support device is substantially perpendicular to an upper surface of the stage.

10 4426. The method of claim 4404, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

15 4427. The method of claim 4404, wherein the measurement device is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

20 4428. The method of claim 4404, wherein the stage is disposed within a process chamber of the process tool, the method further comprising controlling the stage to support the specimen during a process step.

4429. The method of claim 4404, wherein the stage is disposed within a process chamber of the process tool, the method further comprising processing the one or more output signals to determine the characteristic of the specimen during a process step.

25 4430. The method of claim 4404, wherein the stage is disposed within a process chamber of the process tool, the method further comprising controlling the measurement device to obtain a signature characterizing processing of the specimen, wherein the

signature comprises at least one singularity representative of an end of the processing of the specimen.

5 4431. The method of claim 4404, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least the one determined characteristic using an in situ control technique.

10 4432. The method of claim 4404, wherein the process tool comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber.

15 4433. The method of claim 4404, wherein the process tool comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the measurement device to move the specimen from the first process chamber to the second process chamber, controlling the illumination system during said moving, and controlling the detection system during said moving.

20 4434. The method of claim 4404, further comprising comparing at least the one determined characteristic and characteristics of a plurality of specimens.

4435. The method of claim 4404, further comprising comparing at least the one determined characteristic to a predetermined range for the characteristic.

25 4436. The method of claim 4435, further comprising generating an output signal if at least the one determined characteristic is outside of the predetermined range.

4437. The method of claim 4404, further comprising altering a sampling frequency of the measurement device in response to at least the one determined characteristic.

5 4438. The method of claim 4404, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least the one determined characteristic using a feedback control technique.

10 4439. The method of claim 4404, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least the one determined characteristic using a feedforward control technique.

4440. The method of claim 4404, further comprising generating a database, wherein the database comprises at least the one determined characteristic.

15 4441. The method of claim 4404, further comprising generating a database, wherein the database comprises at least the one determined characteristic, the method further comprising calibrating the measurement device using the database.

20 4442. The method of claim 4404, further comprising generating a database, wherein the database comprises at least the one determined characteristic, the method further comprising monitoring output signals of the measurement device using the database.

25 4443. The method of claim 4404, further comprising generating a database, wherein the database comprises at least the one determined characteristic, and wherein the database further comprises characteristics of a plurality of specimens.

4444. The method of claim 4443, wherein the characteristics of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

5 4445. The method of claim 4443, wherein the characteristics of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

10 4446. The method of claim 4404, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

15 4447. The method of claim 4404, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

20 4448. The method of claim 4404, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least
25 one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

4449. The method of claim 4404, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least the one determined characteristic using a feedback control technique.

- 5 4450. The method of claim 4404, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least the one determined characteristic using a feedforward control technique.

- 10 4451. The method of claim 4404, further comprising monitoring a parameter of one or more instruments coupled to the process chamber.

- 15 4452. The method of claim 4404, further comprising monitoring a parameter of one or more instruments coupled to the process chamber and determining a relationship between at least the one determined characteristic and at least one of the monitored parameters.

- 20 4453. The method of claim 4404, further comprising monitoring a parameter of one or more instruments coupled to the process chamber, determining a relationship between at least the one determined characteristic and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

- 25 4454. The method of claim 4404, further comprising altering a parameter of one or more instruments coupled to at least one of a plurality of semiconductor fabrication process tools in response to at least the one determined characteristic.

4455. The method of claim 4404, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processes output signal using the remote controller
computer.

4456. The method of claim 4455, wherein at least partially processing the one or more
output signals comprises determining the property.

4457. The method of claim 4455, wherein further processing the partially process output
signal comprises determining the property.

4458. The method of claim 4404, wherein the process tool is selected from the group
consisting of a lithography tool, an etch tool, a deposition tool, an ion implanter, a
chemical-mechanical polishing tool, a cleaning tool, a thermal tool, and a plating tool.

4459. A semiconductor device fabricated by a method, the method comprising:

processing a specimen in a process tool to perform at least a step of a
semiconductor fabrication process on the specimen;

supporting the specimen on a stage;

rotating the stage while the specimen is supported on the stage;

directing light toward a surface of the specimen using an illumination system during the process and during rotation of the stage;

5 detecting light propagating from the surface of the specimen using a detection system during the process and during rotation of the stage, wherein illumination system and the detection system comprises a measurement device, and wherein the measurement device is coupled to the process tool;

10 generating one or more output signals responsive to the detected light; and

processing the one or more output signals to determine at least the one characteristic of micro defects on the specimen.

4460. The device of claim 4459, wherein an additional illumination system and an
15 additional detection system comprise an additional measurement device coupled to the process too, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

20 4461. The device of claim 4459, wherein at least the one characteristic of micro defects is selected from the group consisting of a presence, a location, a number, and a type of micro defects on the surface of the specimen.

25 4462. The device of claim 4459, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of micro defects on the specimen substantially simultaneously.

4463. The device of claim 4459, further comprising directing light toward multiple locations on the surface of the specimen substantially simultaneously during the process and during the rotation of the stage and detecting light propagating from the multiple locations substantially simultaneously during the process and during the rotation of the stage such that at least one characteristic of micro defects on the surface of the specimen at the multiple locations can be determined substantially simultaneously.

4464. The device of claim 4459, further comprising processing the one or more output signals to determine an additional characteristic of the specimen, wherein the additional characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

4465. The device of claim 4464, wherein the process tool is selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

4466. The device of claim 4459, wherein the measurement device is further coupled to a process chamber of the process tool.

4467. The device of claim 4459, wherein the measurement device is arranged laterally proximate to a process chamber of the process tool.

4468. The device of claim 4459, wherein the measurement device is arranged vertically proximate to a process chamber of the process tool.

4469. The device of claim 4459, wherein the stage is disposed within a process chamber of the process tool, and wherein processing the one or more output signals comprises

determining the at least the one characteristic of micro defects on the specimen during the process.

5 4470. The device of claim 4459, wherein the stage is disposed within a process chamber of the process tool, the method further comprising obtaining a signature characterizing processing of the specimen, wherein the signature comprises at least one singularity representative of an end of the processing of the specimen.

10 4471. The device of claim 4459, wherein the stage is disposed within a process chamber of the process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least the one determined characteristic using an in situ control technique.

15 4472. The device of claim 4459, wherein the process tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using the stage, directing light during said moving, and detecting light during said moving.

20 4473. The device of claim 4459, wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a deposition tool, an ion implanter, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, and a plating tool.

25 4474. A method for fabricating a semiconductor device, comprising:
disposing the specimen upon a stage, wherein the stage is disposed within a process chamber, wherein a measurement device is coupled to the process chamber, and wherein the measurement device comprises an illumination system and a detection system;

processing the specimen to fabricate a portion of the semiconductor device upon a specimen using a process chamber;

5 rotating the stage during processing of the specimen;

directing light toward a surface of the specimen using the illumination system during fabrication and rotation of the stage;

10 detecting light propagating from the surface of the specimen using the detection system during fabrication and rotation of the stage; and

processing the detected light to determine a characteristic of micro defects on the surface of the specimen.

15

4475. The method of claim 4474, wherein an additional illumination system and an additional detection system comprise an additional measurement device coupled to the process too, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of
20 the specimen.

4476. The method of claim 4474, wherein at least the one characteristic of micro defects is selected from the group consisting of a presence, a location, a number, and a type of micro defects on the surface of the specimen.

25

4477. The method of claim 4474, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two characteristics of micro defects on the specimen substantially simultaneously.

comprises determining the at least the one characteristic of micro defects on the specimen during the process.

5 4485. The method of claim 4474, wherein the stage is disposed within a process chamber of the process tool, the method further comprising obtaining a signature characterizing processing of the specimen, wherein the signature comprises at least one singularity representative of an end of the processing of the specimen.

10 4486. The method of claim 4474, wherein the stage is disposed within a process chamber of the process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least the one determined characteristic using an in situ control technique.

15 4487. The method of claim 4474, wherein the process tool comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using the stage, directing light during said moving, and detecting light during said moving.

20 4488. The method of claim 4474, wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, a deposition tool, an ion implanter, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, and a plating tool.

25 4489. A system configured to determine a characteristic of micro defects on a specimen during use, comprising:

a process tool configured to process the specimen during use;

a stage configured to support the specimen during use, wherein the stage is further

configured to rotate during use;

a measurement device coupled to the process tool, wherein the measurement device is further coupled to the stage, comprising:

5

an illumination system configured to direct light toward the surface of the specimen during the process and during rotation of the stage; and

10

a detection system coupled to the illumination system and configured to detect light propagating from the surface of the specimen during the process and during rotation of the stage, wherein the measurement device is configured to generate one or more output signals in response to the detected light during use; and

15

a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

20

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine at least the one characteristic of micro defects on the specimen from the at least partially processed one or more output signals.

4490. A method for determining a characteristic of micro defects on a specimen,
25 comprising:

processing the specimen in a process tool;

supporting the specimen on a stage;

rotating the stage while the specimen is supported on the stage;

5 directing light toward a surface of the specimen using an illumination system during the process and during rotation of the stage;

10 detecting light propagating from the surface of the specimen using a detection system during the process and during rotation of the stage, wherein illumination system and the detection system comprises a measurement device, and wherein the measurement device is coupled to the process tool;

generating one or more output signals responsive to the detected light; and

15 processing the one or more output signals to determine at least the one characteristic of micro defects on the specimen, comprising:

20 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

25 further processing the partially processed one or more output signals using the remote controller computer.

4491. A system configured to determine at least one characteristic of defects on at least

two sides of a specimen during use, comprising:

a stage configured to support the specimen during use, wherein the stage is further configured to move during use;

5

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a front side and a back side of the specimen during movement of the stage; and

10

a detection system coupled to the illumination system and configured to detect energy propagating along multiple paths from the front side of the specimen during movement of the stage and to detect energy propagating from the back side of the specimen during movement of the stage, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy propagating along multiple paths from the front side of the specimen and the detected energy propagating from the back side of the specimen; and

15

20

a processor coupled to the measurement device and configured to determine a first characteristic of defects on the front side of the specimen from the one or more output signals during use and a second characteristic of macro defects on the back side of the specimen from the one or more output signals during use.

25

4492. The system of claim 4491, further comprising an additional measurement device coupled to the stage, wherein the processor is further configured to determine an additional property of the specimen from one or more output signals generated by the additional measurement device.

4493. The system of claim 4491, wherein the stage is further configured to move laterally during use.

5 4494. The system of claim 4491, wherein the stage is further configured to move rotatably during use.

4495. The system of claim 4491, wherein the stage is further configured to move laterally and rotatably during use.

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4496. The system of claim 4491, wherein the detected energy propagating along multiple paths from the front side comprises dark field light propagating along multiple dark field paths.

15 4497. The system of claim 4491, wherein the detected energy propagating along multiple paths from the front sides comprises dark field light propagating along multiple dark field paths and bright field light propagating along a bright field path.

20 4498. The system of claim 4491, wherein the detected energy propagating from the back side of the specimen comprises dark field light propagating along a dark field path.

4499. The system of claim 4491, wherein the detected energy propagating from the back side of the specimen comprises bright field light propagating along a bright field path.

25 4500. The system of claim 4491, wherein the detected energy propagating from the back side of the specimen comprises dark field light propagating along a dark field path and bright field light propagating along a bright field path.

4501. The system of claim 4491, wherein the measurement device further comprises non-optical components, and wherein the detected energy propagating along multiple paths from the front side of the specimen is responsive to a non-optical characteristic of the specimen.

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4502. The system of claim 4491, wherein the measurement device further comprises non-optical components, and wherein the detected energy propagating from the back side of the specimen is responsive to a non-optical characteristic of the specimen.

10 4503. The system of claim 4491, wherein the specimen comprises a plurality of dies having repeatable pattern features, and wherein the processor is further configured to compare output signals responsive to detected energy from at least two of the plurality of dies to determine the first characteristic.

15 4504. The system of claim 4491, wherein the first characteristic is selected from the group consisting of a presence, a location, a number, and a type of defects on the front side of the specimen.

20 4505. The system of claim 4491, wherein the second characteristic is selected from the group consisting of a presence, a location, a number, and a type of defects on the back side of the specimen.

4506. The system of claim 4491, wherein the defects on the front side of the specimen comprise macro defects or micro defects.

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4507. The system of claim 4491, wherein the defects on the front side of the specimen comprise macro defects and micro defects.

4508. The system of claim 4491, wherein the processor is further configured to determine the first and second characteristics substantially simultaneously during use.

4509. The system of claim 4491, wherein the illumination system is further configured to direct energy to multiple locations on the front side of the specimen substantially simultaneously during movement of the stage, and wherein the detection system is further configured to detect energy propagating along multiple paths from the multiple locations on the front side of the specimen substantially simultaneously during movement of the stage such that the first characteristic of defects on the front side of the specimen at the multiple locations can be determined substantially simultaneously.

4510. The system of claim 4491, wherein the illumination system is further configured to direct energy to multiple locations on the back side of the specimen substantially simultaneously during movement of the stage, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the back side of the specimen substantially simultaneously during movement of the stage such that the second characteristic of macro defects on the back side of the specimen at the multiple locations can be determined substantially simultaneously.

4511. The system of claim 4491, wherein the processor is further configured to determine a third characteristic of the specimen from the one or more output signals during use, and wherein the third characteristic is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

4512. The system of claim 4511, wherein the system is coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

4513. The system of claim 4491, wherein the system is coupled to a process tool.

4514. The system of claim 4491, wherein the system is coupled to a process tool, and
5 wherein the system is disposed within the process tool.

4515. The system of claim 4491, wherein the system is coupled to a process tool, and
wherein the system is arranged laterally proximate to the process tool.

10 4516. The system of claim 4491, wherein the system is coupled to a process tool, and
wherein the process tool comprises a wafer handler configured to move the specimen to
the stage during use.

4517. The system of claim 4491, wherein the system is coupled to a process tool, and
15 wherein the stage is configured to move the specimen from the system to the process tool
during use.

4518. The system of claim 4491, wherein the system is coupled to a process tool, and
wherein the stage is further configured to move the specimen to a process chamber of the
20 process tool during use.

4519. The system of claim 4491, wherein the system is further configured to determine
at least the one characteristic while the specimen is waiting between process steps.

25 4520. The system of claim 4491, wherein the system is coupled to a process tool,
wherein the process tool comprises a support device configured to support the specimen
during a process step, and wherein an upper surface of the support device is substantially
parallel to an upper surface of the stage.

measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

5 4528. The system of claim 4491, wherein the system comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

10 4529. The system of claim 4491, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

15 4530. The system of claim 4491, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, and wherein the processor is further configured to determine the first and second characteristics during the process step.

20 4531. The system of claim 4491, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

25 4532. The system of claim 4491, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, and wherein the processor is

coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined characteristics using an in situ control technique during use.

5 4533. The system of claim 4491, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

10 4534. The system of claim 4491, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the system is further configured to determine the first and second characteristics as the stage is moving the specimen from the first process chamber to the second process chamber.

15 4535. The system of claim 4491, wherein the processor is further configured to compare at least one of the determined characteristics and characteristics of a plurality of specimens during use.

20 4536. The system of claim 4491, wherein the processor is further configured to compare at least one of the determined characteristics to a predetermined range for the characteristic during use.

25 4537. The system of claim 4536, wherein the processor is further configured to generate an output signal if at least one of the determined characteristics is outside of the predetermined range for the characteristic during use.

4538. The system of claim 4491, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined characteristics during use.

5 4539. The system of claim 4491, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined characteristics using a feedback control technique during use.

10 4540. The system of claim 4491, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined characteristics using a feedforward control technique during use.

15 4541. The system of claim 4491, wherein the processor is further configured to generate a database during use, and wherein the database comprises the determined first and second characteristics.

20 4542. The system of claim 4491, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to calibrate the measurement device using the database during use.

25 4543. The system of claim 4491, wherein the processor is further configured to generate a database during use, and wherein the processor is further configured to monitor the one or more output signals generated by measurement device using the database during use.

4544. The system of claim 4491, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second

characteristics, and wherein the database further comprises first and second characteristics of a plurality of specimens.

5 4545. The system of claim 4544, wherein the first and second characteristics of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

10 4546. The system of claim 4544, wherein the first and second characteristics of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor one or more output signals generated by the plurality of measurement devices using the database during use.

15 4547. The system of claim 4491, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

20 4548. The system of claim 4491, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during
25 use.

4549. The system of claim 4491, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen,

wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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4550. The system of claim 4491, wherein the processor is further coupled to a process tool.

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4551. The system of claim 4491, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined characteristics using a feedback control technique during use.

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4552. The system of claim 4491, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined characteristics using a feedforward control technique during use.

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4553. The system of claim 4491, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

25

4554. The system of claim 4553, wherein the processor is further configured to determine a relationship between at least one of the determined characteristics and at least one of the monitored parameters during use.

4555. The system of claim 4554, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

4556. The system of claim 4491, wherein the processor is further coupled to a plurality of measurement devices, and wherein at least one of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

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4557. The system of claim 4491, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

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4558. The system of claim 4557, wherein the local processor is further configured to determine the first characteristic and the second characteristic during use.

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4559. The system of claim 4557, wherein the remote controller computer is further configured to determine the first characteristic and the second characteristic during use.

4560. A method for determining at least one characteristic of defects on at least two sides of a specimen, comprising:

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disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

25

moving the stage;

directing energy toward a front side and a back side of the specimen using the illumination system during movement of the stage;

detecting energy propagating along multiple paths from the front side of the specimen using the detection system during movement of the stage;

5 detecting energy propagating from the back side of the specimen using the detection system during movement of the stage;

generating one or more output signals responsive to the detected energy propagating along multiple paths from the front side of the specimen and the
10 detected energy propagating from the back side of the specimen; and

processing the one or more output signals to determine a first characteristic of defects on a front side of the specimen and a second characteristic of macro defects on a back side of the specimen.

15 4561. The method of claim 4560, further comprising moving the stage laterally during said directing energy, said detecting energy propagating along multiple paths from the front side of the specimen, and said detecting energy propagating from the back side of the specimen.

20 4562. The method of claim 4560, further comprising moving the stage rotatably during said directing energy, said detecting energy propagating along multiple paths from the front side of the specimen, and said detecting energy propagating from the back side of the specimen.

25 4563. The method of claim 4560, further comprising moving the stage laterally and rotatably during said directing energy, said detecting energy propagating along multiple

paths from the front side of the specimen, and said detecting energy propagating from the back side of the specimen.

5 4564. The method of claim 4560, wherein the detected light propagating along multiple paths from the front side comprises dark field light propagating along multiple dark field paths.

10 4565. The method of claim 4560, wherein the detected light propagating along multiple paths from the front sides comprises dark field light propagating along multiple dark field paths and bright field light propagating along a bright field path.

4566. The method of claim 4560, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path.

15 4567. The method of claim 4560, wherein the detected light propagating from the back side of the specimen comprises bright field light propagating along a bright field path.

20 4568. The method of claim 4560, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path and bright field light propagating along a bright field path.

25 4569. The method of claim 4560, wherein the stage is further coupled to an additional measurement device, wherein the additional measurement device comprises an additional illumination system and an additional detection system, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

4570. The method of claim 4560, wherein the measurement device further comprises non-optical components, and wherein detecting energy propagating along multiple paths from the front side of the specimen comprises measuring a non-optical characteristic of the front side of the specimen.

5

4571. The method of claim 4560, wherein the measurement device further comprises non-optical components, and wherein detecting energy propagating from the back side of the specimen comprises a non-optical characteristic of the back side of the specimen.

10 4572. The method of claim 4560, wherein the specimen comprises a plurality of dies having repeatable pattern features, and wherein processing the one or more output signals comprises comparing detected energy propagating from at least two of the plurality of dies to determine the first characteristic.

15 4573. The method of claim 4560, wherein the first characteristic is selected from the group consisting of a presence, a location, a number, and a type of defects on the front side of the specimen.

20 4574. The method of claim 4560, wherein the second characteristic is selected from the group consisting of a presence, a location, a number, and a type of defects on the back side of the specimen.

4575. The method of claim 4560, wherein the defects on the front side of the specimen comprise macro defects or micro defects.

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4576. The method of claim 4560, wherein the defects on the front side of the specimen comprise macro defects and micro defects.

4577. The method of claim 4560, further comprising processing the one or more output signals substantially simultaneously to determine the first and second characteristics.

5 4578. The method of claim 4560, further comprising directing energy toward multiple locations on the front side of the specimen substantially simultaneously during movement of the stage and detecting energy propagating along multiple paths from the multiple locations on the front side of the specimen substantially simultaneously during movement of the stage such that the first characteristic of defects on the front side of the specimen at the multiple locations can be determined substantially simultaneously.

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4579. The method of claim 4560, further comprising directing energy toward multiple locations on the back side of the specimen substantially simultaneously during movement of the stage and detecting energy propagating from the multiple locations on the back side of the specimen substantially simultaneously during movement of the stage such that the
15 second characteristic of macro defects on the back side of the specimen at the multiple locations can be determined substantially simultaneously.

4580. The method of claim 4560, further comprising processing the one or more output signals to determine a third characteristic of the specimen, wherein the third characteristic
20 is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

4581. The method of claim 4580, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an
25 atomic layer deposition tool, a cleaning tool, and an etch tool.

4582. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool.

4583. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

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4584. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

10 4585. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

15 4586. The method of claim 4560, wherein the stage and the measurement device are coupled to a laser cleaning tool.

4587. The method of claim 4560, wherein the stage and the measurement device are coupled to a shock wave particle removal apparatus.

20

4588. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

25

4589. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

4590. The method of claim 4560, further comprising determining at least the one characteristic while the specimen is waiting between process steps.

5 4591. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

10 4592. The method of claim 4560, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

15 4593. The method of claim 4560, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

20 4594. The method of claim 4560, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within the process tool.

25 4595. The method of claim 4560, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

4596. The method of claim 4560, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

5 4597. The method of claim 4560, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

10 4598. The method of claim 4597, further comprising performing said directing and said detecting during the process step.

4599. The method of claim 4598, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity
15 representative of an end of the process step.

4600. The method of claim 4598, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined characteristics using an in situ control technique.

20 4601. The method of claim 4560, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

25 4602. The method of claim 4601, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

4603. The method of claim 4560, further comprising comparing at least one of the determined characteristics and determined characteristics of a plurality of specimens.

5 4604. The method of claim 4560, further comprising comparing at least one of the determined characteristics to a predetermined range for the characteristic.

10 4605. The method of claim 4604, further comprising generating an output signal if at least one of the determined characteristics is outside of the predetermined range for the characteristic.

4606. The method of claim 4560, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined characteristics.

15 4607. The method of claim 4560, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined characteristics using a feedback control technique.

20 4608. The method of claim 4560, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined characteristics using a feedforward control technique.

4609. The method of claim 4560, further comprising generating a database, wherein the database comprises the determined first and second characteristics.

25 4610. The method of claim 4560, further comprising generating a database, wherein the database comprises the determined first and second characteristics, the method further comprising calibrating the measurement device using the database.

4611. The method of claim 4560, further comprising generating a database, wherein the database comprises the determined first and second characteristics, the method further comprising monitoring the measurement device using the database.

- 5 4612. The method of claim 4560, further comprising generating a database, wherein the database comprises the determined first and second characteristics, and wherein the database further comprises first and second characteristics of a plurality of specimens.

- 10 4613. The method of claim 4612, wherein the first and second characteristics of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

- 15 4614. The method of claim 4613, wherein the first and second characteristics of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

- 20 4615. The method of claim 4560, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

- 25 4616. The method of claim 4560, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

4617. The method of claim 4560, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one
5 of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

4618. The method of claim 4560, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined
10 characteristics using a feedback control technique.

4619. The method of claim 4560, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined characteristics using a feedforward control technique.
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4620. The method of claim 4560, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

4621. The method of claim 4620, further comprising determining a relationship between
20 at least one of the determined characteristics and at least one of the monitored parameters.

4622. The method of claim 4621, further comprising altering a parameter of at least one of the instruments in response to the relationship.

25 4623. The method of claim 4560, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined characteristics.

4624. The method of claim 4560, wherein processing the one or more output signals comprises:

5 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

10 further processing the partially processed one or more output signals using the remote controller computer.

4625. The method of claim 4624, wherein at least partially processing the one or more output signals comprises determining the first and second characteristics.

15 4626. The method of claim 4624, wherein further processing the partially processed one or more output signals comprises determining the first and second characteristics.

20 4627. A computer-implemented method for controlling a system configured to determine at least one characteristic of defects on at least two sides of the specimen during use, wherein the system comprises a measurement device, comprising:

25 controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, wherein the measurement device is coupled to a stage, and wherein the stage is configured to move during use, comprising:

controlling the illumination system to direct energy toward a front side and a back side of the specimen during movement of the stage;

5 controlling the detection system to detect energy propagating along multiple paths from the front side of the specimen during movement of the stage and to detect energy propagating from the back side of the specimen during movement of the stage; and

10 generating one or more output signals responsive to the detected energy propagating along multiple path from the front side of the specimen and the detected energy propagating from the back side of the specimen; and

15 processing the one or more output signals to determine a first characteristic of defects on a front side of the specimen and to determine a second characteristic of macro defects on a back side of the specimen.

4628. The method of claim 4627, further comprising controlling the stage, wherein the stage is configured to support the specimen.

20 4629. The method of claim 4627, further comprising controlling the stage to laterally move the stage during said controlling the illumination system and said controlling the detection system.

25 4630. The method of claim 4627, further comprising controlling the stage to rotatably move the stage during said controlling the illumination system and said controlling the detection system.

4631. The method of claim 4627, further comprising controlling the stage to laterally and rotatably move the stage during said controlling the illumination system and said controlling the detection system.

- 5 4632. The method of claim 4627, wherein the detected light propagating along multiple paths from the front side comprises dark field light propagating along multiple dark field paths.

- 10 4633. The method of claim 4627, wherein the detected light propagating along multiple paths from the front sides comprises dark field light propagating along multiple dark field paths and bright field light propagating along a bright field path.

- 15 4634. The method of claim 4627, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path.

4635. The method of claim 4627, wherein the detected light propagating from the back side of the specimen comprises bright field light propagating along a bright field path.

- 20 4636. The method of claim 4627, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path and bright field light propagating along a bright field path.

- 25 4637. The method of claim 4627, wherein the system comprises an additional measurement device, wherein the additional measurement device comprises an additional illumination system and an additional detection system, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

4638. The method of claim 4627, wherein the measurement device further comprises non-optical components, and wherein controlling the detection system to detect energy comprises controlling the non-optical components to measure a non-optical characteristic of the front side of the specimen.

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4639. The method of claim 4627, wherein the measurement device further comprises non-optical components, and wherein controlling the detection system to detect energy comprises controlling the non-optical components to measure a non-optical characteristic of the back side of the specimen.

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4640. The method of claim 4627, wherein the specimen comprises a plurality of dies having repeatable pattern features, and wherein processing the one or more output signals comprises comparing detected energy propagating from at least two of the plurality of dies to determine the first characteristic.

15

4641. The method of claim 4627, wherein the first characteristic is selected from the group consisting of a presence, a location, a number, and a type of defects on the front side of the specimen.

20

4642. The method of claim 4627, wherein the second characteristic is selected from the group consisting of a presence, a location, a number, and a type of defects on the back side of the specimen.

25

4643. The method of claim 4627, wherein the defects on the front side of the specimen comprise macro defects or micro defects.

4644. The method of claim 4627, wherein the defects on the back side of the specimen comprise macro defects and micro defects.

4645. The method of claim 4627, wherein processing the one or more output signals to determine the first and second characteristics comprises substantially simultaneously determining the first and second characteristics.

5

4646. The method of claim 4627, further comprising controlling the illumination system to direct energy to multiple locations on the front side of the specimen substantially simultaneously during movement of the stage and controlling the detection system to detect energy propagating along multiple paths from the multiple locations on the front
10 side of the specimen substantially simultaneously during movement of the stage such that the first characteristic of defects on the front side of the specimen at the multiple locations can be determined substantially simultaneously.

4647. The method of claim 4627, further comprising controlling the illumination system to direct energy toward multiple locations on the back side of the specimen substantially
15 simultaneously during movement of the stage and controlling the detection system to detect energy propagating from the multiple locations on the back side of the specimen substantially simultaneously during movement of the stage such that the second characteristic of macro defects on the back side of the specimen at the multiple locations
20 can be determined substantially simultaneously.

4648. The method of claim 4627, further comprising processing the one or more output signals to determine a third characteristic of the specimen, wherein the third characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the
25 layer on the specimen, and a roughness of a feature of the specimen.

4649. The method of claim 4648, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 4650. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool.

4651. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged
10 laterally proximate to the process tool.

4652. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

15 4653. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool is selected from the group consisting of a lithography tool, an etch tool, an ion implanter, a chemical-mechanical polishing tool, a deposition tool, a thermal tool, a cleaning tool, and a plating tool.

20 4654. The method of claim 4627, wherein the stage and the measurement device are coupled to a laser cleaning tool.

4655. The method of claim 4627, wherein the stage and the measurement device are
25 coupled to a shock wave particle removal apparatus.

4656. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to

move the specimen from the process tool to the stage, wherein the wafer handler is coupled to the process tool.

5 4657. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

10 4658. The method of claim 4627, the method further comprising controlling a wafer handler to move the specimen to a stage coupled to the measurement device such that at least the one characteristic can be determined while the specimen is waiting between process steps.

15 4659. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

20 4660. The method of claim 4627, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

25 4661. The method of claim 4627, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

4662. The method of claim 4627, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within the process tool.

5 4663. The method of claim 4627, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

10 4664. The method of claim 4627, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

15 4665. The method of claim 4627, wherein the stage comprises a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

4666. The method of claim 4665, further comprising controlling the illumination system and controlling the detection system during the process step.

20 4667. The method of claim 4666, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

25 4668. The method of claim 4666, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to the at least one of the determined characteristics using an in situ control technique.

4669. The method of claim 4627, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 5 4670. The method of claim 4669, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

- 10 4671. The method of claim 4627, further comprising comparing at least one of the determined characteristics and characteristics of a plurality of specimens.

4672. The method of claim 4627, further comprising comparing at least one of the determined characteristics to a predetermined range for the characteristic.

- 15 4673. The method of claim 4672, further comprising generating an output signal if at least one of the determined characteristics is outside of the predetermined range for the characteristic.

- 20 4674. The method of claim 4627, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined characteristics.

4675. The method of claim 4627, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined characteristics using a feedback control technique.

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4676. The method of claim 4627, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined characteristics using a feedforward control technique.

alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

5 4684. The method of claim 4627, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

10 4685. The method of claim 4627, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the
15 specimen to reduce within wafer variation of at least one of the determined properties.

4686. The method of claim 4627, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined characteristics using a feedback control technique.

20 4687. The method of claim 4627, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined characteristics using a feedforward control technique.

25 4688. The method of claim 4627, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

4689. The method of claim 4688, further comprising determining a relationship between at least one of the determined characteristics and at least one of the monitored parameters.

4690. The method of claim 4688, further comprising altering a parameter of at least one of the instruments in response to the relationship.

4691. The method of claim 4627, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined characteristics.

4692. The method of claim 4627, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

4693. The method of claim 4692, wherein at least partially processing the one or more output signals comprises determining the first and second characteristics.

4694. The method of claim 4692, wherein further processing the partially processed one or more output signals comprises determining the first and second characteristics.

4695. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

5 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

moving the stage;

10

directing energy toward a front side and a back side of the specimen using the illumination system during movement of the stage;

15

detecting energy propagating along multiple paths from the front side of the specimen using the detection system during movement of the stage;

detecting energy propagating from the back side of the specimen using the detection system during movement of the stage;

20

generating one or more output signals responsive to the detected energy propagating along multiple path from the front side of the specimen and the detected energy propagating from the back side of the specimen; and

25

processing the one or more output signals to determine a first characteristic of defects on the front side of the specimen a second characteristic of macro defects on the back side of the specimen.

4696. The device of claim 4695, wherein the detected light propagating along multiple paths from the front side comprises dark field light propagating along multiple dark field paths.

- 5 4697. The device of claim 4695, wherein the detected light propagating along multiple paths from the front sides comprises dark field light propagating along multiple dark field paths and bright field light propagating along a bright field path.

- 10 4698. The device of claim 4695, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path.

4699. The device of claim 4695, wherein the detected light propagating from the back side of the specimen comprises bright field light propagating along a bright field path.

- 15 4700. The device of claim 4695, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path and bright field light propagating along a bright field path.

- 20 4701. The device of claim 4695, wherein the stage is further coupled to an additional measurement device, wherein the additional measurement device comprises an additional illumination system and an additional detection system, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

- 25 4702. The device of claim 4695, wherein the measurement device further comprises non-optical components, and wherein detecting energy propagating along multiple paths from the front side of the specimen comprises measuring a non-optical characteristic of the front side of the specimen.

4703. The device of claim 4695, wherein the measurement device further comprises non-optical components, and wherein detecting energy propagating from the back side of the specimen comprises a non-optical characteristic of the back side of the specimen.

5

4704. The device of claim 4695, further comprising processing the one or more output signals substantially simultaneously to determine the first and second characteristics.

4705. The device of claim 4695, further comprising directing energy toward multiple locations on the front side of the specimen substantially simultaneously during movement of the stage and detecting energy propagating along multiple paths from the multiple locations on the front side of the specimen substantially simultaneously during movement of the stage such that the first characteristic of defects on the front side of the specimen at the multiple locations can be determined substantially simultaneously.

15

4706. The device of claim 4695, further comprising directing energy toward multiple locations on the back side of the specimen substantially simultaneously during movement of the stage and detecting energy propagating from the multiple locations on the back side of the specimen substantially simultaneously during movement of the stage such that the second characteristic of macro defects on the back side of the specimen at the multiple locations can be determined substantially simultaneously.

20

4707. The device of claim 4695, further comprising processing the one or more output signals to determine a third characteristic of the specimen, wherein the third characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

25

4708. The device of claim 4707, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

5 4709. The device of claim 4695, wherein the stage and the measurement device are coupled to a process tool.

4710. The device of claim 4695, wherein the stage and the measurement device are coupled to a laser cleaning tool.

10

4711. The device of claim 4695, wherein the stage and the measurement device are coupled to a shock wave particle removal apparatus.

4712. A method for fabricating a semiconductor device, comprising:

15

forming a portion of the semiconductor device upon a specimen;

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

20

moving the stage;

directing energy toward a front side and a back side of the specimen using the illumination system during movement of the stage;

25

detecting energy propagating along multiple paths from the front side of the specimen using the detection system during movement of the stage;

detecting energy propagating from the back side of the specimen using the detection system during movement of the stage;

5 generating one or more output signals responsive to the detected energy propagating along multiple path from the front side of the specimen and the detected energy propagating from the back side of the specimen; and

10 processing the one or more output signals to determine a first characteristic of defects on the front side of the specimen a second characteristic of macro defects on the back side of the specimen.

4713. The method of claim 4712, wherein the detected light propagating along multiple paths from the front side comprises dark field light propagating along multiple dark field
15 paths.

4714. The method of claim 4712, wherein the detected light propagating along multiple paths from the front sides comprises dark field light propagating along multiple dark field paths and bright field light propagating along a bright field path.
20

4715. The method of claim 4712, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path.

4716. The method of claim 4712, wherein the detected light propagating from the back
25 side of the specimen comprises bright field light propagating along a bright field path.

4717. The method of claim 4712, wherein the detected light propagating from the back side of the specimen comprises dark field light propagating along a dark field path and bright field light propagating along a bright field path.

- 5 4718. The method of claim 4712, wherein the stage is further coupled to an additional measurement device, wherein the additional measurement device comprises an additional illumination system and an additional detection system, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

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4719. The method of claim 4712, wherein the measurement device further comprises non-optical components, and wherein detecting energy propagating along multiple paths from the front side of the specimen comprises measuring a non-optical characteristic of the front side of the specimen.

15

4720. The method of claim 4712, wherein the measurement device further comprises non-optical components, and wherein detecting energy propagating from the back side of the specimen comprises a non-optical characteristic of the back side of the specimen.

20

4721. The method of claim 4712, further comprising processing the one or more output signals substantially simultaneously to determine the first and second characteristics.

25

4722. The method of claim 4712, further comprising directing energy toward multiple locations on the front side of the specimen substantially simultaneously during movement of the stage and detecting energy propagating along multiple paths from the multiple locations on the front side of the specimen substantially simultaneously during movement of the stage such that the first characteristic of defects on the front side of the specimen at the multiple locations can be determined substantially simultaneously.

4723. The method of claim 4712, further comprising directing energy toward multiple locations on the back side of the specimen substantially simultaneously during movement of the stage and detecting energy propagating from the multiple locations on the back side of the specimen substantially simultaneously during movement of the stage such that the second characteristic of macro defects on the back side of the specimen at the multiple locations can be determined substantially simultaneously.

4724. The method of claim 4712, further comprising processing the one or more output signals to determine a third characteristic of the specimen, wherein the third characteristic is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

4725. The method of claim 4724, wherein the stage and the measurement device are coupled to a process tool selected from the group consisting of a lithography tool, an atomic layer deposition tool, a cleaning tool, and an etch tool.

4726. The method of claim 4712, wherein the stage and the measurement device are coupled to a process tool.

4727. The method of claim 4712, wherein the stage and the measurement device are coupled to a laser cleaning tool.

4728. The method of claim 4712, wherein the stage and the measurement device are coupled to a shock wave particle removal apparatus.

4729. A system configured to determine at least one characteristic of defects on at least two sides of a specimen during use, comprising:

a stage configured to support the specimen during use, wherein the stage is further configured to move during use;

5 a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a front side and a back side of the specimen during movement of the stage; and

10 a detection system coupled to the illumination system and configured to detect energy propagating along multiple paths from the front side of the specimen during movement of the stage and to detect energy propagating from the back side of the specimen during movement of the stage, wherein the measurement device is configured to generate one or more output
15 signals responsive to the detected energy propagating along multiple paths from the front side of the specimen and the detected energy propagating from the back side of the specimen;

20 a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first characteristic of defects on the front
25 side of the specimen from the one or more output signals during use and a second characteristic of macro defects on the back side of the specimen from the one or more output signals during use.

4730. A method for determining at least one characteristic of defects on at least two sides of a specimen, comprising:

5 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

moving the stage;

10 directing energy toward a front side and a back side of the specimen using the illumination system during movement of the stage;

15 detecting energy propagating along multiple paths from the front side of the specimen using the detection system during movement of the stage;

detecting energy propagating from the back side of the specimen using the detection system during movement of the stage;

20 generating one or more output signals responsive to the detected energy propagating along multiple paths from the front side of the specimen and the detected energy propagating from the back side of the specimen; and

25 processing the one or more output signals to determine a first characteristic of defects on the front side of the specimen and a second characteristic of macro defects on the back side of the specimen, comprising:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

5 sending the at least partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the at least partially processed one or more output signals using the remote controller computer.

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4731. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

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a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

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a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use; and

25

a processor coupled to the measurement device and configured to determine a first property and a second property of the specimen from the one or more output signals during use, wherein the first property comprises a presence of macro

defects on the specimen, and wherein the second property comprises overlay misregistration of the specimen.

5 4732. The system of claim 4731, wherein the stage is further configured to move laterally during use.

4733. The system of claim 4731, wherein the stage is further configured to move rotatably during use.

10 4734. The system of claim 4731, wherein the stage is further configured to move laterally and rotatably during use.

15 4735. The system of claim 4731, wherein the illumination system comprises a single energy source.

4736. The system of claim 4731, wherein the illumination system comprises more than one energy source.

20 4737. The system of claim 4731, wherein the detection system comprises a single energy sensitive device.

4738. The system of claim 4731, wherein the detection system comprises more than one energy sensitive devices.

25 4739. The system of claim 4731, wherein the measurement device further comprises a non-imaging scatterometer.

4740. The system of claim 4731, wherein the measurement device further comprises a scatterometer.

5 4741. The system of claim 4731, wherein the measurement device further comprises a spectroscopic scatterometer.

4742. The system of claim 4731, wherein the measurement device further comprises a reflectometer.

10 4743. The system of claim 4731, wherein the measurement device further comprises a spectroscopic reflectometer.

4744. The system of claim 4731, wherein the measurement device further comprises an ellipsometer.

15 4745. The system of claim 4731, wherein the measurement device further comprises a spectroscopic ellipsometer.

20 4746. The system of claim 4731, wherein the measurement device further comprises a bright field imaging device.

4747. The system of claim 4731, wherein the measurement device further comprises a dark field imaging device.

25 4748. The system of claim 4731, wherein the measurement device further comprises a bright field and dark field imaging device.

4749. The system of claim 4731, wherein the measurement device further comprises a non-imaging bright field device.

5 4750. The system of claim 4731, wherein the measurement device further comprises a non-imaging dark field device.

4751. The system of claim 4731, wherein the measurement device further comprises a non-imaging bright field and dark field device.

10 4752. The system of claim 4731, wherein the measurement device further comprises a double dark field device.

4753. The system of claim 4731, wherein the measurement device further comprises a coherence probe microscope.

15 4754. The system of claim 4731, wherein the measurement device further comprises an interferometer.

20 4755. The system of claim 4731, wherein the measurement device further comprises an optical profilometer.

25 4756. The system of claim 4731, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright

field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

5 4757. The system of claim 4731, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 4758. The system of claim 4731, wherein the macro defects comprises resist contamination of a back side of the specimen.

15 4759. The system of claim 4731, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

20 4760. The system of claim 4731, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

25 4761. The system of claim 4731, wherein the system is further configured to determine at least the two properties of the specimen substantially simultaneously during use.

4762. The system of claim 4731, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially

simultaneously, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

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4763. The system of claim 4731, wherein the system is coupled to a process tool.

4764. The system of claim 4731, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

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4765. The system of claim 4731, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

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4766. The system of claim 4731, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

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4767. The system of claim 4731, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

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4768. The system of claim 4731, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

4769. The system of claim 4731, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

4770. The system of claim 4731, wherein the system is coupled to a lithography tool,
wherein the system is configured to determine the first property of the specimen prior to
an exposure step of a lithography process, and wherein the system is configured to
5 determine the second property subsequent to the exposure step of the lithography process.

4771. The system of claim 4731, wherein the system is coupled to a lithography tool,
and wherein the system is configured to determine the first and second properties of the
specimen subsequent to an exposure step of a lithography process.

10 4772. The system of claim 4731, wherein the system is coupled to a process tool,
wherein the process tool comprises a support device configured to support the specimen
during a process step, and wherein an upper surface of the support device is substantially
parallel to an upper surface of the stage.

15 4773. The system of claim 4731, wherein the system is coupled to a process tool,
wherein the process tool comprises a support device configured to support the specimen
during a process step, and wherein an upper surface of the stage is angled with respect to
an upper surface of the support device.

20 4774. The system of claim 4731, wherein the system is coupled to a process tool, and
wherein the process tool comprises a lithography tool.

4775. The system of claim 4731, wherein the system further comprises a measurement
25 chamber, wherein the stage and the measurement device are disposed within the
measurement chamber, and wherein the measurement chamber is coupled to a process
tool.

4776. The system of claim 4731, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

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4777. The system of claim 4731, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

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4778. The system of claim 4731, wherein the system further comprises a measurement chamber, wherein the stage and the measurement device are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

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4779. The system of claim 4731, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

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4780. The system of claim 4779, wherein the processor is further configured to determine one or more of at least the two properties of the specimen during the process step.

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4781. The system of claim 4780, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

4782. The system of claim 4780, wherein the processor is further coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

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4783. The system of claim 4731, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

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4784. The system of claim 4783, wherein the system is further configured to determine at least one of the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

15 4785. The system of claim 4731, wherein the processor is further configured to compare at least one of the determined properties of the specimen and properties of a plurality of specimens during use.

20 4786. The system of claim 4731, wherein the processor is further configured to compare at least one of the determined properties of the specimen to a predetermined range for the property during use.

25 4787. The system of claim 4786, wherein the processor is further configured to generate an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property during use.

4788. The system of claim 4731, wherein the processor is further configured to alter a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen during use.

- 5 4789. The system of claim 4731, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique during use.

- 10 4790. The system of claim 4731, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique during use.

- 15 4791. The system of claim 4731, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to calibrate the measurement device using the database during use.

- 20 4792. The system of claim 4731, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the processor is further configured to monitor output signals generated by measurement device using the database during use.

- 25 4793. The system of claim 4731, wherein the processor is further configured to generate a database during use, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens determined using a plurality of measurement devices.

4794. The system of claim 4793, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

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4795. The system of claim 4793, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

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4796. The system of claim 4731, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

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4797. The system of claim 4731, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

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4798. The system of claim 4731, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

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4799. The system of claim 4731, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

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4800. The system of claim 4731, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

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4801. The system of claim 4731, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

15 4802. The system of claim 4801, wherein the processor is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

20 4803. The system of claim 4802, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

4804. The system of claim 4731, wherein the processor is further coupled to a plurality of measurement devices, and wherein the plurality of measurement devices is coupled to a plurality of process tools.

25

4805. The system of claim 4731, wherein the processor is further coupled to a plurality of process tools, and wherein the processor is further configured to alter a parameter of

one or more instruments coupled to at least one of the plurality of process tools during use.

5 4806. The system of claim 4731, wherein the processor comprises a local processor coupled to the measurement device and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

10 4807. The system of claim 4806, wherein the local processor is further configured to determine the first property and the second property of the specimen during use.

15 4808. The system of claim 4806, wherein the remote controller computer is further configured to determine the first property and the second property of the specimen during use.

4809. A method for determining at least two properties of a specimen, comprising:

20 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

25 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

4817. The method of claim 4809, wherein the measurement device further comprises a non-imaging scatterometer.

5 4818. The method of claim 4809, wherein the measurement device further comprises a scatterometer.

4819. The method of claim 4809, wherein the measurement device further comprises a spectroscopic scatterometer.

10 4820. The method of claim 4809, wherein the measurement device further comprises a reflectometer.

4821. The method of claim 4809, wherein the measurement device further comprises a spectroscopic reflectometer.

15 4822. The method of claim 4809, wherein the measurement device further comprises an ellipsometer.

20 4823. The method of claim 4809, wherein the measurement device further comprises a spectroscopic ellipsometer.

4824. The method of claim 4809, wherein the measurement device further comprises a bright field imaging device.

25 4825. The method of claim 4809, wherein the measurement device further comprises a dark field imaging device.

4826. The method of claim 4809, wherein the measurement device further comprises a bright field and dark field imaging device.

5 4827. The method of claim 4809, wherein the measurement device further comprises a non-imaging bright field device.

4828. The method of claim 4809, wherein the measurement device further comprises a non-imaging dark field device.

10 4829. The method of claim 4809, wherein the measurement device further comprises a non-imaging bright field and dark field device.

4830. The method of claim 4809, wherein the measurement device further comprises a double dark field device.

15 4831. The method of claim 4809, wherein the measurement device further comprises a coherence probe microscope.

20 4832. The method of claim 4809, wherein the measurement device further comprises an interferometer.

4833. The method of claim 4809, wherein the measurement device further comprises an optical profilometer.

25 4834. The method of claim 4809, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a

spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an
5 optical profilometer.

4835. The method of claim 4809, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second
10 measurement device.

4836. The method of claim 4809, wherein the macro defects comprise resist contamination on a back side of the specimen.

4837. The method of claim 4809, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature on the specimen.
15

4838. The method of claim 4809, further comprising directing energy toward a bottom surface of the specimen and detecting energy propagating from the bottom surface of the specimen, wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.
20

4839. The method of claim 4809, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.
25

4840. The method of claim 4809, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple
5 locations substantially simultaneously.

4841. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool.

10 4842. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged laterally proximate to the process tool.

4843. The method of claim 4809, wherein the stage and the measurement device are
15 coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.

4844. The method of claim 4809, wherein the stage and the measurement device are
20 coupled to a lithography tool.

4845. The method of claim 4809, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first property prior to an exposure step of the lithography process and determining the second property subsequent to the exposure step of the lithography process.
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4846. The method of claim 4809, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first and second properties subsequent to an exposure step of a lithography process.

4847. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

4848. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to said directing and said detecting using the stage.

4849. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

4850. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

4851. The method of claim 4809, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

4852. The method of claim 4809, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

4853. The method of claim 4809, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

5 4854. The method of claim 4809, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

4855. The method of claim 4809, wherein the stage and the measurement device are
10 disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

4856. The method of claim 4809, wherein the stage and the measurement device are
15 disposed within a measurement chamber, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

4857. The method of claim 4856, further comprising performing said directing and said
20 detecting during the process step.

4858. The method of claim 4857, further comprising obtaining a signature
characterizing the process step, wherein the signature comprises at least one singularity
representative of an end of the process step.

25 4859. The method of claim 4857, further comprising altering a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

4860. The method of claim 4809, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

5

4861. The method of claim 4860, further comprising performing said directing and said detecting during said moving the specimen from the first process chamber to the second process chamber.

10 4862. The method of claim 4809, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

15 4863. The method of claim 4809, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

4864. The method of claim 4863, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

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4865. The method of claim 4809, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

25 4866. The method of claim 4809, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

4867. The method of claim 4809, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

- 5 4868. The method of claim 4809, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen.

4869. The method of claim 4809, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the
10 method further comprising calibrating the measurement device using the database.

4870. The method of claim 4809, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using
15 the database.

4871. The method of claim 4809, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of
20 specimens.

4872. The method of claim 4871, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.
25

4873. The method of claim 4871, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further

comprising monitoring output signals of the plurality of measurement devices using the database.

4874. The method of claim 4809, wherein a stand alone system is coupled to the measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device with the stand alone system.

4875. The method of claim 4809, wherein a stand alone system is coupled to the measurement device and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the measurement device an at least the one additional measurement device with the stand alone system.

4876. The method of claim 4809, further comprising determining at least the two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

4877. The method of claim 4809, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedback control technique.

4878. The method of claim 4809, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedforward control technique.

4879. The method of claim 4809, further comprising monitoring a parameter of one or more instruments coupled to the process tool.

5 4880. The method of claim 4879, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

4881. The method of claim 4880, further comprising altering a parameter of at least one of the instruments in response to the relationship.

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4882. The method of claim 4809, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the determined properties of the specimen.

15 4883. The method of claim 4809, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

4884. The method of claim 4883, wherein at least partially processing the one or more output signals comprises determining the first and second properties of the specimen.

4885. The method of claim 4883, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

5

4886. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a measurement device, the method comprising:

10 controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, and wherein the measurement device is coupled to a stage, comprising:

15 controlling the illumination system to direct energy toward a surface of the specimen;

 controlling the detection system to detect energy propagating from the surface of the specimen; and

20 generating one or more output signals responsive to the detected energy; and

25 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises overlay misregistration of the specimen.

4887. The method of claim 4886, further comprising controlling the stage, wherein the stage is configured to support the specimen.

5 4888. The method of claim 4886, further comprising controlling the stage to laterally move the stage during said directing energy and said detecting energy.

4889. The method of claim 4886, further comprising controlling the stage to rotatably move the stage during said directing energy and said detecting energy.

10 4890. The method of claim 4886, further comprising controlling the stage to laterally and rotatably move the stage during said directing energy and said detecting energy.

4891. The method of claim 4886, wherein the illumination system comprises a single energy source.

15 4892. The method of claim 4886, wherein the illumination system comprises more than one energy source.

4893. The method of claim 4886, wherein the detection system comprises a single energy sensitive device.

20 4894. The method of claim 4886, wherein the detection system comprises more than one energy sensitive device.

25 4895. The method of claim 4886, wherein the measurement device further comprises a non-imaging scatterometer.

4896. The method of claim 4886, wherein the measurement device further comprises a scatterometer.

5 4897. The method of claim 4886, wherein the measurement device further comprises a spectroscopic scatterometer.

4898. The method of claim 4886, wherein the measurement device further comprises a reflectometer.

10 4899. The method of claim 4886, wherein the measurement device further comprises a spectroscopic reflectometer.

4900. The method of claim 4886, wherein the measurement device further comprises an ellipsometer.

15 4901. The method of claim 4886, wherein the measurement device further comprises a spectroscopic ellipsometer.

20 4902. The method of claim 4886, wherein the measurement device further comprises a bright field imaging device.

4903. The method of claim 4886, wherein the measurement device further comprises a dark field imaging device.

25 4904. The method of claim 4886, wherein the measurement device further comprises a bright field and dark field imaging device.

4905. The method of claim 4886, wherein the measurement device further comprises a non-imaging bright field device.

5 4906. The method of claim 4886, wherein the measurement device further comprises a non-imaging dark field device.

4907. The method of claim 4886, wherein the measurement device further comprises a non-imaging bright field and dark field device.

10 4908. The method of claim 4886, wherein the measurement device further comprises a double dark field device.

15 4909. The method of claim 4886, wherein the measurement device further comprises a coherence probe microscope.

4910. The method of claim 4886, wherein the measurement device further comprises an interferometer.

20 4911. The method of claim 4886, wherein the measurement device further comprises an optical profilometer.

25 4912. The method of claim 4886, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright

field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

5 4913. The method of claim 4886, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

10 4914. The method of claim 4886, wherein the macro defects comprise resist contamination on a back side of the specimen.

15 4915. The method of claim 4886, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature on the specimen.

20 4916. The method of claim 4886, further comprising controlling the illumination system to direct energy toward a bottom surface of the specimen and controlling the detection system to detect energy propagating from the bottom surface of the specimen, wherein the first property comprises a presence of defects on the bottom surface of the specimen.

25 4917. The method of claim 4886, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

4918. The method of claim 4886, further comprising controlling the illumination system to direct energy toward multiple locations on the surface of the specimen substantially simultaneously and controlling the detection system to detect energy propagating from the

multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

- 5 4919. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool.

4920. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are arranged
10 laterally proximate to the process tool.

4921. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, and wherein the stage and the measurement device are disposed within the process tool.
15

4922. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

4923. The method of claim 4886, wherein the system is coupled to a lithography tool,
20 the method further comprising controlling the system to determine the first property prior to an exposure step of the lithography process and controlling the system to determine the second property subsequent to the exposure step of the lithography process.

4924. The method of claim 4886, wherein the system is coupled to a lithography tool,
25 the method further comprising controlling the system to determine the first and second properties subsequent to an exposure step of a lithography process.

4925. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

5

4926. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

10 4927. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

15 4928. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

20 4929. The method of claim 4886, wherein the stage and the measurement device are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

25 4930. The method of claim 4886, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

4931. The method of claim 4886, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

- 5 4932. The method of claim 4886, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

- 10 4933. The method of claim 4886, wherein the stage and the measurement device are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

- 15 4934. The method of claim 4886, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

- 20 4935. The method of claim 4934, further comprising controlling the illumination system and controlling the detection system during the process step to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

- 25 4936. The method of claim 4934, further comprising controlling the illumination system and controlling the detection system during the process step to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique.

4937. The method of claim 4886, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

- 5 4938. The method of claim 4937, further comprising controlling the illumination system and controlling the detection system during said moving the specimen from the first process chamber to the second process chamber.

- 10 4939. The method of claim 4886, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens.

- 15 4940. The method of claim 4886, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property.

4941. The method of claim 4940, further comprising generating an output signal if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

- 20 4942. The method of claim 4886, further comprising altering a sampling frequency of the measurement device in response to at least one of the determined properties of the specimen.

- 25 4943. The method of claim 4886, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedback control technique.

4944. The method of claim 4886, further comprising altering a parameter of one or more instruments coupled to the measurement device in response to at least one of the determined properties using a feedforward control technique.

- 5 4945 The method of claim 4886, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the database.

- 10 4946. The method of claim 4886, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring output signals of the measurement device using the database.

- 15 4947. The method of claim 4886, further comprising generating a database, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises determined first and second properties of a plurality of specimens.

- 20 4948. The method of claim 4947, wherein the determined first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

- 25 4949. The method of claim 4947, wherein the determined first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

4950. The method of claim 4886, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

5

4951. The method of claim 4886, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

10

4952. The method of claim 4886, wherein the system is further configured to determine at least the two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties of the specimen at the more than one position on the specimen to reduce within wafer variation of at least one of the determined properties.

15

4953. The method of claim 4886, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedback control technique.

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4954. The method of claim 4886, further comprising altering a parameter of one or more instruments coupled to a process tool in response to at least one of the determined properties using a feedforward control technique.

25

4955. The method of claim 4886, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

4956. The method of claim 4955, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters.

5 4957. The method of claim 4956, further comprising altering a parameter of at least one of the instruments in response to the relationship.

4958. The method of claim 4886, further comprising altering a parameter of one or more instruments coupled to a plurality of process tools in response to at least one of the
10 determined properties of the specimen.

4959. The method of claim 4886, wherein processing the one or more output signals comprises:

15 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

20 further processing the partially processed one or more output signals using the remote controller computer.

4960. The method of claim 4959, wherein at least partially processing the one or more
25 output signals comprises determining the first and second properties of the specimen.

4961. The method of claim 4959, wherein further processing the partially processed one or more output signals comprises determining the first and second properties of the specimen.

5 4962. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

10 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

15 detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

20 processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises overlay misregistration of the specimen.

25 4963. The device of claim 4962, wherein the illumination system comprises a single energy source.

4964. The device of claim 4962, wherein the illumination system comprises more than one energy source.

5 4965. The device of claim 4962, wherein the detection system comprises a single energy sensitive device.

4966. The device of claim 4962, wherein the detection system comprises more than one energy sensitive devices.

10 4967. The device of claim 4962, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-
15 imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

4968. The device of claim 4962, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first
20 and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright
25 field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

4969. The device of claim 4962, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

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4970. The device of claim 4962, further comprising directing energy toward a bottom surface of the specimen and detecting energy propagating from the bottom surface of the specimen, wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

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4971. The device of claim 4962, wherein the macro defects comprise resist contamination on a back side of the specimen.

4972. The device of claim 4962, further comprising processing the one or more output
15 signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature on the specimen.

4973. The device of claim 4962, wherein processing the one or more output signals to
20 determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

4974. The device of claim 4962, further comprising directing energy toward multiple
25 locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

4975. The device of claim 4962, wherein the stage and the measurement device are coupled to a process tool.

5 4976. The device of claim 4962, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

4977. The device of claim 4962, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first property prior to an exposure step of the lithography process and determining the second property subsequent to the exposure step of the lithography process.

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4978. The device of claim 4962, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first and second properties subsequent to an exposure step of a lithography process.

15

4979. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

20 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

25

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises overlay misregistration of the specimen.

4980. The method of claim 4979, wherein the illumination system comprises a single energy source.

4981. The method of claim 4979, wherein the illumination system comprises more than one energy source.

4982. The method of claim 4979, wherein the detection system comprises a single energy sensitive device.

4983. The method of claim 4979, wherein the detection system comprises more than one energy sensitive devices.

4984. The method of claim 4979, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

4985. The method of claim 4979, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

4986. The method of claim 4979, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

4987. The method of claim 4979, further comprising directing energy toward a bottom surface of the specimen and detecting energy propagating from the bottom surface of the specimen, wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

4988. The method of claim 4979, wherein the macro defects comprise resist contamination on a back side of the specimen.

4989. The method of claim 4979, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature on the specimen.

4990. The method of claim 4979, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

- 5 4991. The method of claim 4979, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

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4992. The method of claim 4979, wherein the stage and the measurement device are coupled to a process tool.

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4993. The method of claim 4979, wherein the stage and the measurement device are coupled to a process tool, and wherein the process tool comprises a lithography tool.

20

4994. The method of claim 4979, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first property prior to an exposure step of the lithography process and determining the second property subsequent to the exposure step of the lithography process.

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4995. The method of claim 4979, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first and second properties subsequent to an exposure step of a lithography process.

4996. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

5 an illumination system configured to direct energy toward a surface of the specimen during use; and

 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use,
10 wherein the measurement device is configured to generate one or more output signals responsive to the detected energy during use;

 a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

15 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine a first property and a second property of the specimen from the at least partially processed one or more output signals during
20 use, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises overlay misregistration of the specimen.

4997. The system of claim 4996, wherein the measurement device is selected from the
25 group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-

imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

4998. The system of claim 4996, wherein the measurement device further comprises at
5 least a first measurement device and a second measurement device, and wherein the first
and second measurement devices are selected from the group consisting of a non-imaging
scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a
spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field
imaging device, a dark field imaging device, a bright field and dark field imaging device,
10 a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright
field and dark field device, a coherence probe microscope, an interferometer, and an
optical profilometer.

4999. The system of claim 4996, wherein the measurement device further comprises at
15 least a first measurement device and a second measurement device, and wherein optical
elements of the first measurement device comprise optical elements of the second
measurement device.

5000. The system of claim 4996, wherein the macro defects comprise resist
20 contamination on a back side of the specimen.

5001. The system of claim 4996, wherein the remote controller computer is further
configured to determine a third property of the specimen from the one or more output
signals during use, and wherein the third property is selected from the group consisting of
25 a roughness on the specimen, a roughness of a layer on the specimen, and a roughness of
a feature of the specimen.

5002. The system of claim 4996, wherein the illumination system is further configured to direct energy toward a bottom surface of the specimen during use, wherein the detection system is further configured to detect energy propagating from the bottom surface of the specimen during use, and wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

5003. The system of claim 4996, wherein the system is further configured to determine at least the two properties of the specimen substantially simultaneously during use.

5004. The system of claim 4996, wherein the illumination system is further configured to direct energy to multiple locations on the surface of the specimen substantially simultaneously during use, and wherein the detection system is further configured to detect energy propagating from the multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined substantially simultaneously.

5005. The system of claim 4996, wherein the remote controller computer is further coupled to a process tool.

5006. The system of claim 4996, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool comprises a lithography tool.

5007. The system of claim 4996, wherein the system is coupled to a lithography tool, wherein the system is configured to determine the first property prior to an exposure step of the lithography process, and wherein the system is configured to determine the second property subsequent to the exposure step of the lithography process.

5008. The system of claim 4996, wherein the system is coupled to a lithography tool, and wherein the system is further configured to determine the first and second properties subsequent to an exposure step of the lithography process.

5 5009. The system of claim 4996, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedback control technique during use.

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5010. The system of claim 4996, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using a feedforward control technique during use.

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5011. The system of claim 4996, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

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5012. The system of claim 4996, wherein the remote controller computer is further configured to determine a relationship between at least one of the determined properties and at least one of the monitored parameters during use.

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5013. The system of claim 5012, wherein the remote controller computer is further configured to alter a parameter of one or more instruments in response to the relationship during use.

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5014. The system of claim 4996, wherein the illumination system is further configured to direct energy toward the surface of the specimen during a process step, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during the process step, and wherein the remote controller computer is further configured to determine the first and second properties of the specimen during the process step.

5015. The system of claim 5014, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

5016. The system of claim 5014, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to at least one of the determined properties using an in situ control technique during use.

5017. The system of claim 4996, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

5018. The system of claim 4996, wherein the illumination system is further configured to direct energy toward the surface of the specimen during said moving, wherein the detection system is further configured to detect energy propagating from the surface of the specimen during said moving, and wherein the remote controller computer is further

configured to determine the first and second properties of the specimen during said moving.

5019. The system of claim 4996, wherein the remote controller computer is further
5 configured to compare at least one of the determined properties of the specimen and
properties of a plurality of specimens during use.

5020. The system of claim 4996, wherein the remote controller computer is further
configured to compare at least one of the determined properties of the specimen to a
10 predetermined range for the property during use.

5021. The system of claim 5020, wherein the remote controller computer is further
configured to generate an output signal if at least one of the determined properties of the
specimen is outside of the predetermined range for the property during use.

5022. The system of claim 4996, wherein the remote controller computer is further
configured to alter a sampling frequency of the measurement device in response to at least
one of the determined properties of the specimen during use.

5023. The system of claim 4996, wherein the remote controller computer is further
configured to alter a parameter of one or more instruments coupled to the measurement
device in response to at least one of the determined properties using a feedback control
technique during use.

5024. The system of claim 4996, wherein the remote controller computer is further
configured to alter a parameter of one or more instruments coupled to the measurement
device in response to at least one of the determined properties using a feedforward control
technique during use.

5030. The system of claim 5028, wherein the first and second properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

5031. The system of claim 4996, wherein the remote controller computer is further coupled to a plurality of measurement devices, and wherein the plurality of measurement devices is coupled to at least one of a plurality of process tools.

5032. The system of claim 4996, wherein the remote controller computer is further coupled to a plurality of process tools, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the plurality of process tools during use.

5033. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine a first property and a second property of the specimen, wherein the first property comprises a presence of macro defects on the specimen, and wherein the second property comprises overlay misregistration of the specimen, comprising:

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at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

15

5034. The method of claim 5033, wherein the measurement device is selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

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5035. The method of claim 5033, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein the first and second measurement devices are selected from the group consisting of a non-imaging scatterometer, a scatterometer, a spectroscopic scatterometer, a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a bright field

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imaging device, a dark field imaging device, a bright field and dark field imaging device, a non-imaging bright field device, a non-imaging dark field device, a non-imaging bright field and dark field device, a coherence probe microscope, an interferometer, and an optical profilometer.

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5036. The method of claim 5033, wherein the measurement device further comprises at least a first measurement device and a second measurement device, and wherein optical elements of the first measurement device comprise optical elements of the second measurement device.

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5037. The method of claim 5033, further comprising directing energy toward a bottom surface of the specimen and detecting energy propagating from the bottom surface of the specimen, wherein the first property further comprises a presence of macro defects on the bottom surface of the specimen.

15

5038. The method of claim 5033, wherein the macro defects comprise resist contamination on a back side of the specimen.

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5039. The method of claim 5033, further comprising processing the one or more output signals to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature on the specimen.

25

5040. The method of claim 5033, wherein processing the one or more output signals to determine the first and second properties of the specimen comprises substantially simultaneously determining the first and second properties of the specimen.

5041. The method of claim 5033, further comprising directing energy toward multiple locations on the surface of the specimen substantially simultaneously and detecting energy propagating from the multiple locations substantially simultaneously such that one or more of the at least two properties of the specimen can be determine at the multiple
5 locations substantially simultaneously.

5042. The method of claim 5033, wherein the remote controller computer is further coupled to a process tool.

10 5043. The method of claim 5033, wherein the remote controller computer is further coupled to a process tool, and wherein the process tool is comprises a lithography tool.

5044. The method of claim 5033, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first
15 property prior to an exposure step of the lithography process and determining the second property subsequent to the exposure step of the lithography process.

5045. The method of claim 5033, wherein the stage and the measurement device are coupled to a lithography tool, the method further comprising determining the first and
20 second properties subsequent to the exposure step of the lithography process.

5046. The method of claim 5033, wherein the remote controller computer is further coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in
25 response to at least one of the determined properties of the specimen using a feedback control technique.

5047. The method of claim 5033, wherein the remote controller computer is further coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen using a feedforward control technique.

5048. The method of claim 5033, wherein the remote controller computer is further coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

5049. The method of claim 5048, further comprising determining a relationship between at least one of the determined properties and at least one of the monitored parameters using the remote controller computer.

5050. The method of claim 5049, further comprising altering a parameter of one or more instruments coupled to the process tool in response to the relationship using the remote controller computer.

5051. The method of claim 5033, wherein the illumination system and the detection system are coupled to a process chamber of a process tool, the method further comprising performing said directing and said detecting during a process step.

5052. The method of claim 5051, further comprising obtaining a signature characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

5053. The method of claim 5051, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties using an in situ control technique.

5 5054. The method of claim 5033, further comprising:

moving the specimen from a first process chamber to a second process chamber using the stage; and

10 performing said directing and said detecting during said moving the specimen.

5055. The method of claim 5054, further comprising comparing at least one of the determined properties of the specimen and determined properties of a plurality of specimens using the remote controller computer.

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5056. The method of claim 5054, further comprising comparing at least one of the determined properties of the specimen to a predetermined range for the property using the remote controller computer.

20 5057. The method of claim 5056, further comprising generating an output signal using the remote controller computer if at least one of the determined properties of the specimen is outside of the predetermined range for the property.

5058. The method of claim 5033, further comprising altering a sampling frequency of
25 the measurement device in response to at least one of the determined properties of the specimen.

5059. The method of claim 5033, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedback control technique.

5 5060. The method of claim 5033, further comprising altering a parameter of one or more instruments coupled to the measurement device using the remote controller computer in response to at least one of the determined properties using a feedforward control technique.

10 5061. The method of claim 5033, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

15 5062. The method of claim 5033, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, the method further comprising monitoring the measurement device using the remote controller computer and the database.

20 5063. The method of claim 5033, further comprising generating a database using the remote controller computer, wherein the database comprises the determined first and second properties of the specimen, and wherein the database further comprises first and second properties of a plurality of specimens.

25 5064. The method of claim 5063, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

5065. The method of claim 5063, wherein the first and second properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

5066. The method of claim 5033, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to one of a plurality of measurement devices.

5067. The method of claim 5066, wherein at least one of the plurality of measurement devices is coupled to a process tool.

5068. The method of claim 5067, further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to at least one of the determined properties of the specimen.

5069. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a first measurement device coupled to the stage, wherein the first measurement device is configured to generate one or more output signals responsive to at least one thin film characteristic of the specimen during use;

a second measurement device coupled to the stage, wherein the second measurement device is configured to generate one or more output signals responsive to at least one electrical property of the specimen during use; and

5 a processor coupled to the first measurement device and the second measurement device, wherein the processor is configured to determine the at least one thin film characteristic from the one or more output signals of the first measurement device during use and to determine the at least one electrical property of the specimen from the one or more output signals of the second measurement device during use.

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5070. The system of claim 5069, wherein the stage is further configured to move laterally during use.

5071. The system of claim 5069, wherein the stage is further configured to move
15 rotatably during use.

5072. The system of claim 5069, wherein the stage is further configured to move laterally and rotatably during use.

20 5073. The system of claim 5069, wherein the first measurement device comprises a reflectometer.

5074. The system of claim 5069, wherein the first measurement device comprises a spectroscopic reflectometer.

25

5075. The system of claim 5069, wherein the first measurement device comprises an ellipsometer.

5076. The system of claim 5069, wherein the first measurement device comprises a spectroscopic ellipsometer.

5 5077. The system of claim 5069, wherein the first measurement device comprises a beam profile ellipsometer.

5078. The system of claim 5069, wherein the first measurement device comprises a photo-acoustic device.

10 5079. The system of claim 5069, wherein the first measurement device comprises an eddy current device.

5080. The system of claim 5069, wherein the first measurement device comprises an X-ray reflectometer.

15 5081. The system of claim 5069, wherein the first measurement device comprises a grazing X-ray reflectometer.

20 5082. The system of claim 5069, wherein the first measurement device comprises an X-ray diffractometer.

5083. The system of claim 5069, wherein the first measurement device comprises at least two measurement devices, and wherein the at least two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and an X-ray diffractometer.

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5084. The system of claim 5069, wherein at least one element of the first measurement device comprise at least one element of the second measurement device.

5085. The system of claim 5069, wherein the second measurement device comprises:

an oven configured to anneal the specimen;

a cooling device configured to reduce a temperature of the specimen subsequent to an annealing process;

a device configured to deposit a charge on an upper surface of the specimen; and

a sensor configured to measure the at least one electrical property of the charged upper surface of the specimen.

5086. The system of claim 5069, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

5087. The system of claim 5069, wherein the at least one electrical property comprises at least one electrical property of a layer on the specimen, and wherein the layer comprises a dielectric material formed on the specimen.

5088. The system of claim 5069, wherein the processor is further configured to determine a characteristic of metal contamination on the specimen from the one or more output signals of the second measurement device during use.

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5089. The system of claim 5069, wherein the processor is further configured to determine a third property of the specimen from the one or more output signals of the first or second measurement device during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5090. The system of claim 5069, wherein the system is further configured to determine the at least two properties of the specimen substantially simultaneously during use.

5091. The system of claim 5069, wherein the first measurement device is further configured to generate the one or more output signals responsive to the at least one thin film characteristic of the specimen at multiple locations on the specimen substantially simultaneously during use, and wherein the processor is further configured to determine the at least one thin film characteristic at the multiple locations on the specimen from the one or more output signals during use.

5092. The system of claim 5069, wherein the second measurement device is further configured to generate the one or more output signals responsive to the at least one electrical property of the specimen at multiple locations on the specimen substantially simultaneously during use, and wherein the processor is further configured to determine the at least one electrical property at the multiple locations on the specimen from the one or more output signals during use.

5093. The system of claim 5069, wherein the system is coupled to a process tool.

5094. The system of claim 5069, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

5095. The system of claim 5069, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

5096. The system of claim 5069, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

5097. The system of claim 5069, wherein the system is coupled to a process tool, and wherein the stage is configured to move the specimen from the system to the process tool during use.

5098. The system of claim 5069, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

5099. The system of claim 5069, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

5100. The system of claim 5069, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

5101. The system of claim 5069, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

5102. The system of claim 5069, wherein the system is coupled to a process tool selected from the group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor deposition tool, a plating tool, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

5103. The system of claim 5069, wherein the system further comprises a measurement chamber, wherein the stage and the first and second measurement devices are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

5104. The system of claim 5069, wherein the system further comprises a measurement chamber, wherein the stage and the first and second measurement devices are disposed within the measurement chamber, and wherein the measurement chamber is disposed within a process tool.

5105. The system of claim 5069, wherein the system further comprises a measurement chamber, wherein the stage and the first and second measurement devices are disposed within the measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

5106. The system of claim 5069, wherein the system further comprises a measurement chamber, wherein the stage and the first and second measurement devices are disposed within the measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

5107. The system of claim 5069, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

5 5108. The system of claim 5107, wherein the system is further configured to determine one or more of the at least two properties of the specimen during the process step.

5109. The system of claim 5108, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises
10 at least one singularity representative of an end of the process step.

5110. The system of claim 5108, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to the one or more of the at least two properties using an in situ
15 control technique during use.

5111. The system of claim 5069, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during
20 use.

5112. The system of claim 5111, wherein the system is further configured to determine one or more of the at least two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.
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5113. The system of claim 5069, wherein the processor is further configured to compare one or more of the at least two properties of the specimen and properties of a plurality of specimens during use.

5114. The system of claim 5069, wherein the processor is further configured to compare one or more of the at least two properties of the specimen to a predetermined range for the one or more properties during use.

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5115. The system of claim 5114, wherein the processor is further configured to generate an output signal if one or more of the at least two properties of the specimen is outside of the predetermined range for the property during use.

10 5116. The system of claim 5069, wherein the processor is further configured to alter a sampling frequency of the first measurement device in response to the at least one thin film characteristic of the specimen during use.

15 5117. The system of claim 5069, wherein the processor is further configured to alter a sampling frequency of the second measurement device in response to the at least one electrical property of the specimen during use.

20 5118. The system of claim 5069, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedback control technique during use.

25 5119. The system of claim 5069, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedback control technique during use.

5120. The system of claim 5069, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedforward control technique during use.

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5121. The system of claim 5069, wherein the processor is further configured to alter a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedforward control technique during use.

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5122. The system of claim 5069, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the processor is further configured to calibrate the first and second measurement devices using the database during use.

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5123. The system of claim 5069, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the processor is further configured to monitor output signals generated by the first and second measurement devices using the database during use.

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5124. The system of claim 5069, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the database further comprises the at least one thin film characteristic and the at least one electrical property of a plurality of specimens.

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5125. The system of claim 5124, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

5126. The system of claim 5124, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

5127. The system of claim 5069, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

5128. The system of claim 5069, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

5129. The system of claim 5069, wherein the system is further configured to determine the at least one thin film characteristic at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to

the at least one thin film characteristic of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one thin film characteristic.

5130. The system of claim 5069, wherein the system is further configured to determine
5 the at least one electrical property at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to the at least one electrical property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one electrical property.

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5131. The system of claim 5069, wherein the processor is further coupled to a process tool.

5132. The system of claim 5069, wherein the processor is further coupled to a process
15 tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties of the specimen using a feedback control technique during use.

5133. The system of claim 5069, wherein the processor is further coupled to a process
20 tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique during use.

5134. The system of claim 5069, wherein the processor is further coupled to a process
25 tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

5135. The system of claim 5134, wherein the processor is further configured to determine a relationship between one or more of the at least two properties of the specimen and at least one of the monitored parameters during use.

- 5 5136. The system of claim 5135, wherein the processor is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

- 10 5137. The system of claim 5069, wherein the processor comprises a local processor coupled to the first and second measurement devices and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals from the first and second measurement devices during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

- 15 5138. The system of claim 5137, wherein the local processor is further configured to determine the at least one thin film characteristic and the at least one electrical property of the specimen during use.

- 20 5139. The system of claim 5137, wherein the remote controller computer is further configured to determine the at least one thin film characteristic and the at least one electrical property of the specimen during use.

5140. A method for determining at least two properties of a specimen, comprising:
25 disposing the specimen upon a stage, wherein the stage is coupled to a first measurement device and a second measurement device;

generating one or more output signals responsive to at least one thin film characteristic of the specimen with the first measurement device;

5 generating one or more output signals responsive to at least one electrical property of the specimen with the second measurement device;

processing the one or more output signals from the first measurement device to determine the at least one thin film characteristic of the specimen; and

10 processing the one or more output signals from the second measurement device to determine the at least one electrical property of the specimen.

5141. The method of claim 5140, further comprising laterally moving the stage while determining the at least two properties of the specimen.

15 5142. The method of claim 5140, further comprising rotatably moving the stage while determining the at least two properties of the specimen.

20 5143. The method of claim 5140, further comprising laterally and rotatably moving the stage while determining the at least two properties of the specimen.

5144. The method of claim 5140, wherein the first measurement device comprises a reflectometer.

25 5145. The method of claim 5140, wherein the first measurement device comprises a spectroscopic reflectometer.

5146. The method of claim 5140, wherein the first measurement device comprises an ellipsometer.

5 5147. The method of claim 5140, wherein the first measurement device comprises a spectroscopic ellipsometer.

5148. The method of claim 5140, wherein the first measurement device comprises a beam profile ellipsometer.

10 5149. The method of claim 5140, wherein the first measurement device comprises a photo-acoustic device.

5150. The method of claim 5140, wherein the first measurement device comprises an eddy current device.

15 5151. The method of claim 5140, wherein the first measurement device comprises an X-ray reflectometer.

20 5152. The method of claim 5140, wherein the first measurement device comprises a grazing X-ray reflectometer.

5153. The method of claim 5140, wherein the first measurement device comprises an X-ray diffractometer.

25 5154. The method of claim 5140, wherein the first measurement device comprises at least two measurement devices, and wherein the at least two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic

device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and an X-ray diffractometer.

5155. The method of claim 5140, wherein at least one element of the first measurement
5 device comprises at least one element of the second measurement device.

5156. The method of claim 5140, wherein generating the one or more output signals responsive to the at least one electrical property of the specimen with the second measurement device comprises:

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annealing the specimen;

reducing a temperature of the specimen subsequent to the annealing;

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depositing a charge on an upper surface of the specimen; and

measuring the at least one electrical property of the charged upper surface of the specimen.

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5157. The method of claim 5140, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

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5158. The method of claim 5140, wherein the at least one electrical property comprises at least one electrical property of a layer formed on the specimen, and wherein the layer comprises a dielectric material.

5159. The method of claim 5140, further comprising processing the one or more output signals of the second measurement device to determine a characteristic of metal contamination on the specimen.

5 5160. The method of claim 5140, further comprising processing the one or more output signals of the first or second measurement device to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

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5161. The method of claim 5140, further comprising processing the one or more output signals of the first measurement device and the one or more output signals of the second measurement device substantially simultaneously to determine the at least one thin film characteristic and the at least one electrical property substantially simultaneously.

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5162. The method of claim 5140, further comprising generating the one or more output signals responsive to the at least one thin film characteristic of the specimen with the first measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the first measurement device to
20 determine the at least one thin film characteristic at the multiple locations on the specimen.

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5163. The method of claim 5140, further comprising generating the one or more output signals responsive to the at least one electrical property of the specimen with the second measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the second measurement device to determine the at least one electrical property at the multiple locations on the specimen.

5164. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool.

5165. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, and wherein the stage and the first and second measurement devices are arranged laterally proximate to the process tool.

5166. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, and wherein the stage and the first and second measurement devices are disposed within the process tool.

5167. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool selected from the group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor deposition tool, a plating tool, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

5168. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

5169. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to determining the at least two properties of the specimen using the stage.

5170. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

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5171. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

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5172. The method of claim 5140, wherein the stage and the first and second measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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5173. The method of claim 5140, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

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5174. The method of claim 5140, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

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5175. The method of claim 5140, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

5176. The method of claim 5140, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of a process tool.

5177. The method of claim 5140, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

5178. The method of claim 5177, further comprising determining one or more of the at least two properties of the specimen during the process step.

5179. The method of claim 5178, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

5180. The method of claim 5178, further comprising altering a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

5181. The method of claim 5140, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

5182. The method of claim 5181, further comprising determining one or more of the at least two properties during said moving the specimen from the first process chamber to the second process chamber.

- 5 5183. The method of claim 5140, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

5184. The method of claim 5140, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more
10 properties.

5185. The method of claim 5184, further comprising generating an output signal if one or more of the at least two properties of the specimen is outside of the predetermined range for the property.
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5186. The method of claim 5140, further comprising altering a sampling frequency of the first measurement device in response to the at least one thin film characteristic of the specimen.

20 5187. The method of claim 5140, further comprising altering a sampling frequency of the second measurement device in response to the at least one electrical property of the specimen.

5188. The method of claim 5140, further comprising altering a parameter of one or more
25 instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedback control technique.

5189. The method of claim 5140, further comprising altering a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedback control technique.

- 5 5190. The method of claim 5140, further comprising altering a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedforward control technique.

5191. The method of claim 5140, further comprising altering a parameter of one or more
10 instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedforward control technique.

5192. The method of claim 5140, further comprising generating a database, wherein the database comprises the at least one thin film characteristic of the specimen and the at
15 least one electrical property of the specimen, the method further comprising calibrating the first and second measurement devices using the database.

5193. The method of claim 5140, further comprising generating a database, wherein the database comprises the at least one thin film characteristic of the specimen and the at
20 least one electrical property of the specimen, the method further comprising monitoring output signals of the first and second measurement devices using the database.

5194. The method of claim 5140, further comprising generating a database, wherein the database comprises the at least one thin film characteristic of the specimen and the at
25 least one electrical property of the specimen, and wherein the database further comprises the at least one thin film characteristic and the at least one electrical property of a plurality of specimens.

5195. The method of claim 5194, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are determined using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

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5196. The method of claim 5194, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are determined using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

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5197. The method of claim 5140, wherein a stand alone system is coupled to the first and second measurement devices, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the first and second measurement devices with the stand alone system.

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5198. The method of claim 5140, wherein a stand alone system is coupled to the first and second measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the first and second measurement devices and at least the one additional measurement device with the stand alone system.

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5199. The method of claim 5140, further comprising determining the at least one thin film characteristic of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the at least one thin film characteristic of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one thin film characteristic.

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5200. The method of claim 5140, further comprising determining the at least one electrical property of the specimen at more than one position of the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the at least one electrical property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one electrical property.

5201. The method of claim 5140, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedback control technique.

5202. The method of claim 5140, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

5203. The method of claim 5140, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

5204. The method of claim 5203, further comprising determining a relationship between one or more of the at least two properties and at least one of the monitored parameters.

5205. The method of claim 5204, further comprising altering a parameter of at least one of the instruments in response to the relationship.

5206. The method of claim 5140, wherein processing the one or more output signals from the first measurement device and processing the one or more output signals from the second measurement device comprises:

at least partially processing the one or more output signals from the first and second measurement devices using a local processor, wherein the local processor is coupled to the first and second measurement devices;

5 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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5207. The method of claim 5206, wherein at least partially processing the one or more output signals comprises determining the at least one thin film characteristic and the at least one electrical property of the specimen.

15 5208. The method of claim 5206, wherein further processing the partially processed one or more output signals comprises determining the at least one thin film characteristic and the at least one electrical property of the specimen.

20 5209. A computer-implemented method for controlling a system configured to determine at least two properties of a specimen during use, wherein the system comprises a stage configured to support the specimen, and wherein the stage is coupled to a first measurement device and a second measurement device, comprising:

25 controlling the first measurement device to generate one or more output signals responsive to at least one thin film characteristic of the specimen;

controlling the second measurement device to generate one or more output signals responsive to at least electrical property of the specimen;

processing the one or more output signals from the first measurement device to determine the at least one thin film characteristic of the specimen; and

5 processing the one or more output signals from the second measurement device to determine the at least one electrical property of the specimen.

10 5210. The method of claim 5209, further comprising controlling the stage to laterally move the stage while determining the at least two properties of the specimen.

5211. The method of claim 5209, further comprising controlling the stage to rotatably move the stage while determining the at least two properties of the specimen.

15 5212. The method of claim 5209, further comprising controlling the stage to laterally and rotatably move the stage while determining the at least two properties of the specimen.

20 5213. The method of claim 5209, wherein the first measurement device comprises a reflectometer.

5214. The method of claim 5209, wherein the first measurement device comprises a spectroscopic reflectometer.

25 5215. The method of claim 5209, wherein the first measurement device comprises an ellipsometer.

5216. The method of claim 5209, wherein the first measurement device comprises a spectroscopic ellipsometer.

5217. The method of claim 5209, wherein the first measurement device comprises a beam profile ellipsometer.

5 5218. The method of claim 5209, wherein the first measurement device comprises a photo-acoustic device.

5219. The method of claim 5209, wherein the first measurement device comprises an eddy current device.

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5220. The method of claim 5209, wherein the first measurement device comprises an X-ray reflectometer.

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5221. The method of claim 5209, wherein the first measurement device comprises a grazing X-ray reflectometer.

5222. The method of claim 5209, wherein the first measurement device comprises an X-ray diffractometer.

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5223. The method of claim 5209, wherein the first measurement device comprises at least two measurement devices, and wherein the at least two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and
25 an X-ray diffractometer.

5224. The method of claim 5209, wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

5225. The method of claim 5209, wherein controlling the second measurement device to generate one or more output signals responsive to the at least one electrical property of the specimen comprises controlling the second measurement device to:

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anneal the specimen;

reduce a temperature of the specimen subsequent to the annealing;

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deposit a charge on an upper surface of the specimen; and

measure the at least one electrical property of the charged upper surface of the specimen.

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5226. The method of claim 5209, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

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5227. The method of claim 5209, wherein the at least one electrical property comprises at least one electrical property of a layer formed on the specimen, and wherein the layer comprises a dielectric material.

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5228. The method of claim 5209, further comprising processing the one or more output signals of the second measurement device to determine a characteristic of metal contamination on the specimen.

5229. The method of claim 5209, further comprising processing the one or more output signals of the first or second measurement device to determine a third property of the

specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5 5230. The method of claim 5209, further comprising processing the one or more output signals of the first measurement device and the one or more output signals of the second measurement device substantially simultaneously to determine the at least one thin film characteristic and the at least one electrical property substantially simultaneously.

10 5231. The method of claim 5209, further comprising controlling the first measurement device to generate one or more output signals responsive to the at least one thin film characteristic of the specimen at multiple locations of the specimen substantially simultaneously and processing the one or more output signals from the first measurement device to determine the at least one thin film characteristic at the multiple locations on the
15 specimen.

5232. The method of claim 5209, further comprising controlling the second measurement device to generate one or more output signals responsive to the at least one electrical property of the specimen at the multiple locations of the specimen substantially
20 simultaneously and processing the one or more output signals from the second measurement device to determine the at least one electrical property at the multiple locations on the specimen.

5233. The method of claim 5209, wherein the stage and the first and second
25 measurement devices are coupled to a process tool.

5234. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, and wherein the stage and the first and second measurement devices are arranged laterally proximate to the process tool.

- 5 5235. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, and wherein the stage and the first and second measurement devices are disposed within the process tool.

- 10 5236. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool selected from the group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor deposition tool, a plating tool, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

- 15 5237. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

- 20 5238. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

- 25 5239. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that the at least two properties of the specimen can be determined while the specimen is waiting between process steps.

5240. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

5241. The method of claim 5209, wherein the stage and the first and second measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

5242. The method of claim 5209, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

5243. The method of claim 5209, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is disposed within a process tool.

5244. The method of claim 5209, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of a process tool.

5245. The method of claim 5209, wherein the stage and the first and second measurement devices are disposed within a measurement chamber, and wherein the

measurement chamber is arranged vertically proximate to a process chamber of a process tool.

5246. The method of claim 5209, further comprising disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

5247. The method of claim 5209, further comprising controlling at least one of the first and second measurement devices during the process step.

5248. The method of claim 5247, further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

5249. The method of claim 5247, further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

5250. The method of claim 5209, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

5251. The method of claim 5250, further comprising controlling at least one of the first measurement and the second devices during said moving the specimen from the first process chamber to the second process chamber.

5252. The method of claim 5209, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

5253. The method of claim 5209, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties.

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5254. The method of claim 5253, further comprising generating an output signal if one or more of the at least two properties of the specimen is outside of the predetermined range for the property.

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5255. The method of claim 5209, further comprising altering a sampling frequency of the first measurement device in response to the at least one thin film characteristic of the specimen.

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5256. The method of claim 5209, further comprising altering a sampling frequency of the second measurement device in response to the at least one electrical property of the specimen.

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5257. The method of claim 5209, further comprising altering a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic using a feedback control technique.

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5258. The method of claim 5209, further comprising altering a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property using a feedback control technique.

5259. The method of claim 5209, further comprising altering a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic using a feedforward control technique.

5260. The method of claim 5209, further comprising altering a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property using a feedforward control technique.

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5261. The method of claim 5209, further comprising generating a database, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, the method further comprising calibrating the first and second measurement devices using the database.

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5262. The method of claim 5209, further comprising generating a database, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, the method further comprising monitoring output signals of the first and second measurement device using the database.

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5263. The method of claim 5209, further comprising generating a database, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the database further comprises the at least one thin film characteristic and the at least one electrical property of a plurality of specimens.

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5264. The method of claim 5263, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

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5265. The method of claim 5263, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are generated using a plurality

of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the database.

5266. The method of claim 5209, wherein a stand alone system is coupled to the system,
5 the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

5267. The method of claim 5209, wherein a stand alone system is coupled to the system
10 and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

5268. The method of claim 5209, further comprising controlling the first measurement
15 device to generate one or more signals responsive the at least one thin film characteristic of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the at least one thin film
20 characteristic of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one thin film characteristic.

5269. The method of claim 5209, further comprising controlling the second
measurement device to generate one or more signals responsive the at least one electrical
25 property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the at least

one electrical property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one electrical property.

5270. The method of claim 5209, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedback control technique.

5271. The method of claim 5209, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

5272. The method of claim 5209, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

5273. The method of claim 5272, further comprising determining a relationship between one or more of the at least two properties and at least one of the monitored parameters.

5274. The method of claim 5273, further comprising altering a parameter of at least one of the instruments in response to the relationship.

5275. The method of claim 5209, wherein processing the one or more output signals from the first measurement device and processing the one or more output signals from the second measurement device comprises:

at least partially processing the one or more output signals from the first and second measurement devices using a local processor, wherein the local processor is coupled to the first and second measurement devices;

5 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

5 further processing the partially processed one or more output signals using the remote controller computer.

10 5276. The method of claim 5275, wherein at least partially processing the one or more output signals comprises determining the at least one thin film characteristic and the at least one electrical property of the specimen.

10 5277. The method of claim 5275, wherein further processing the partially processed one or more output signals comprises determining the at least one thin film characteristic and the at least one electrical property of the specimen.

15 5278. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

20 disposing the specimen upon a stage, wherein the stage is coupled to a first measurement device and a second measurement device;

generating one or more output signals responsive to at least one thin film characteristic of the specimen with the first measurement device;

25 generating one or more output signals responsive to at least one electrical property of the specimen with the second measurement device;

processing the one or more output signals from the first measurement device to
determine the at least one thin film characteristic of the specimen; and

5 processing the one or more output signals from the second measurement device to
determine the at least one electrical property of the specimen.

5279. The device of claim 5278, wherein the first measurement device comprises a
reflectometer.

10 5280. The device of claim 5278, wherein the first measurement device comprises a
spectroscopic reflectometer.

5281. The device of claim 5278, wherein the first measurement device comprises an
ellipsometer.

15 5282. The device of claim 5278, wherein the first measurement device comprises a
spectroscopic ellipsometer.

20 5283. The device of claim 5278, wherein the first measurement device comprises a
beam profile ellipsometer.

5284. The device of claim 5278, wherein the first measurement device comprises a
photo-acoustic device.

25 5285. The device of claim 5278, wherein the first measurement device comprises an
eddy current device.

5286. The device of claim 5278, wherein the first measurement device comprises an X-ray reflectometer.

5 5287. The device of claim 5278, wherein the first measurement device comprises a grazing X-ray reflectometer.

5288. The device of claim 5278, wherein the first measurement device comprises an X-ray diffractometer.

10 5289. The device of claim 5278, wherein the first measurement device comprises at least two measurement devices, and wherein the at least two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and
15 an X-ray diffractometer.

5290. The device of claim 5278, wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

20 5291. The device of claim 5278, wherein generating the one or more output signals responsive to the at least one electrical property of the specimen with the second measurement device comprises:

annealing the specimen;

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reducing a temperature of the specimen subsequent to the annealing;

depositing a charge on an upper surface of the specimen; and

measuring the at least one electrical property of the charged upper surface of the specimen.

5 5292. The device of claim 5278, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

10 5293. The device of claim 5278, wherein the at least one electrical property comprises at least one electrical property of a layer formed on the specimen, and wherein the layer comprises a dielectric material.

15 5294. The device of claim 5278, further comprising processing the one or more output signals of the second measurement device to determine a characteristic of metal contamination on the specimen.

20 5295. The device of claim 5278, further comprising processing the one or more output signals of the first or second measurement device to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25 5296. The device of claim 5278, further comprising processing the one or more output signals of the first measurement device and the one or more output signals of the second measurement device substantially simultaneously to determine the at least one thin film characteristic and the at least one electrical property substantially simultaneously.

5297. The device of claim 5278, further comprising generating the one or more output signals responsive to the at least one thin film characteristic of the specimen with the first measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the first measurement device to
5 determine the at least one thin film characteristic at the multiple locations on the specimen.

5298. The device of claim 5278, further comprising generating the one or more output signals responsive to the at least one electrical property of the specimen with the second
10 measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the second measurement device to determine the at least one electrical property at the multiple locations on the specimen.

5299. The device of claim 5278, wherein the stage and the first and second measurement
15 devices are coupled to a process tool.

5300. The device of claim 5278, wherein the stage and the first and second measurement devices are coupled to a process tool selected from the group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor deposition tool, a
20 plating tool, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

5301. A method for fabricating a semiconductor device, comprising:
25 forming a portion of the semiconductor device upon a specimen;
disposing the specimen upon a stage, wherein the stage is coupled to a first measurement device and a second measurement device;

generating one or more output signals responsive to at least one thin film characteristic of the specimen with the first measurement device;

5 generating one or more output signals responsive to at least one electrical property of the specimen with the second measurement device;

processing the one or more output signals from the first measurement device to determine the at least one thin film characteristic of the specimen; and

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processing the one or more output signals from the second measurement device to determine the at least one electrical property of the specimen.

15 5302. The method of claim 5301, wherein the first measurement device comprises a reflectometer.

5303. The method of claim 5301, wherein the first measurement device comprises a spectroscopic reflectometer.

20 5304. The method of claim 5301, wherein the first measurement device comprises an ellipsometer.

5305. The method of claim 5301, wherein the first measurement device comprises a spectroscopic ellipsometer.

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5306. The method of claim 5301, wherein the first measurement device comprises a beam profile ellipsometer.

5307. The method of claim 5301, wherein the first measurement device comprises a photo-acoustic device.

5 5308. The method of claim 5301, wherein the first measurement device comprises an eddy current device.

5309. The method of claim 5301, wherein the first measurement device comprises an X-ray reflectometer.

10 5310. The method of claim 5301, wherein the first measurement device comprises a grazing X-ray reflectometer.

5311. The method of claim 5301, wherein the first measurement device comprises an X-ray diffractometer.

15 5312. The method of claim 5301, wherein the first measurement device comprises at least two measurement devices, and wherein the at least two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic
20 device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and an X-ray diffractometer.

5313. The method of claim 5301, wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

25 5314. The method of claim 5301, wherein generating the one or more output signals responsive to the at least one electrical property of the specimen with the second measurement device comprises:

annealing the specimen;

reducing a temperature of the specimen subsequent to the annealing;

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depositing a charge on an upper surface of the specimen; and

measuring the at least one electrical property of the charged upper surface of the specimen.

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5315. The method of claim 5301, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

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5316. The method of claim 5301, wherein the at least one electrical property comprises at least one electrical property of a layer formed on the specimen, and wherein the layer comprises a dielectric material.

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5317. The method of claim 5301, further comprising processing the one or more output signals of the second measurement device to determine a characteristic of metal contamination on the specimen.

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5318. The method of claim 5301, further comprising processing the one or more output signals of the first or second measurement device to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5319. The method of claim 5301, further comprising processing the one or more output signals of the first measurement device and the one or more output signals of the second measurement device substantially simultaneously to determine the at least one thin film characteristic and the at least one electrical property substantially simultaneously.

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5320. The method of claim 5301, further comprising generating the one or more output signals responsive to the at least one thin film characteristic of the specimen with the first measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the first measurement device to
10 determine the at least one thin film characteristic at the multiple locations on the specimen.

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5321. The method of claim 5301, further comprising generating the one or more output signals responsive to the at least one electrical property of the specimen with the second measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the second measurement device to
15 determine the at least one electrical property at the multiple locations on the specimen.

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5322. The method of claim 5301, wherein the stage and the first and second measurement devices are coupled to a process tool.

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5323. The method of claim 5301, wherein the stage and the first and second measurement devices are coupled to a process tool selected from the group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor
25 deposition tool, a plating tool, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

5324. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a first measurement device coupled to the stage, wherein the first measurement device is configured to generate one or more output signals responsive to at least one thin film characteristic of the specimen during use;

a second measurement device coupled to the stage, wherein the second measurement device is configured to generate one or more output signals responsive to at least one electrical property during use;

a local processor coupled to the first and second measurement devices, wherein the local processor is configured to at least partially process the one or more output signals from the first measurement device and the one or more output signals from the second measurement device during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals, to determine the at least one thin film characteristic from the at least partially processed output signals of the first measurement device, and to determine the at least one electrical property of the specimen from the at least partially processed output signals of the second measurement device during use.

5325. The system of claim 5324, wherein the first measurement device comprises a reflectometer.

5326. The system of claim 5324, wherein the first measurement device comprises a spectroscopic reflectometer.

5 5327. The system of claim 5324, wherein the first measurement device comprises an ellipsometer.

5328. The system of claim 5324, wherein the first measurement device comprises a spectroscopic ellipsometer.

10 5329. The system of claim 5324, wherein the first measurement device comprises a beam profile ellipsometer.

5330. The system of claim 5324, wherein the first measurement device comprises a photo-acoustic device.

15 5331. The system of claim 5324, wherein the first measurement device comprises an eddy current device.

20 5332. The system of claim 5324, wherein the first measurement device comprises an X-ray reflectometer.

5333. The system of claim 5324, wherein the first measurement device comprises a grazing X-ray reflectometer.

25 5334. The system of claim 5324, wherein the first measurement device comprises an X-ray diffractometer.

5335. The system of claim 5324, wherein the first measurement device comprises at least two measurement devices, and wherein the two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and an X-ray diffractometer.

5336. The system of claim 5324, wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

5337. The system of claim 5324, wherein the second measurement device comprises:

an oven configured to anneal the specimen;

a cooling device configured to reduce a temperature of the specimen subsequent to an annealing process;

a device configured to deposit a charge on an upper surface of the specimen; and

a sensor configured to measure the at least one electrical property of the charged upper surface of the specimen.

5338. The system of claim 5324, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

5339. The system of claim 5324, wherein the at least one electrical property comprises at least one electrical property of a layer on the specimen, and wherein the layer comprises a dielectric material.

5 5340. The system of claim 5324, wherein the remote controller computer is further configured to determine a characteristic of metal contamination on the specimen from the at least partially processed one or more output signals of the second measurement device during use.

10 5341. The system of claim 5324, wherein the remote controller computer is further configured to determine a third property of the specimen from the at least partially processed one or more output signals of the first or second measurement device during use, and wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the
15 specimen.

5342. The system of claim 5324, wherein the remote controller computer is further coupled to a process tool.

20 5343. The system of claim 5324, wherein the remote controller computer is further coupled to a process tool selected from a group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor deposition tool, a plating tool, a chemical-mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

25 5344. The system of claim 5324, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in

response to one or more of the at least two properties using a feedback control technique during use.

5345. The system of claim 5324, wherein the remote controller computer is further
5 coupled to a process tool, and wherein the remote controller computer is further
configured to alter a parameter of one or more instruments coupled to the process tool in
response to one or more of the at least two properties using a feedforward control
technique during use.

10 5346. The system of claim 5324, wherein the remote controller computer is further
coupled to a process tool, and wherein the remote controller computer is further
configured to monitor a parameter of one or more instruments coupled to the process tool
during use.

15 5347. The system of claim 5346, wherein the remote controller computer is further
configured to determine a relationship between one or more of the at least two properties
of the specimen and at least one of the monitored parameters during use.

20 5348. The system of claim 5347, wherein the remote controller computer is further
configured to alter a parameter of at least one of the instruments in response to the
relationship during use.

5349. The system of claim 5324, wherein the system is further configured to determine
one or more of the at least two properties of the specimen during the process step.

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5350. The system of claim 5349, wherein the remote controller computer is further
configured to obtain a signature characterizing the process step during use, and wherein

the signature comprises at least one singularity representative of an end of the process step.

5351. The system of claim 5349, wherein the remote controller computer is further
5 configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique during use.

5352. The system of claim 5324, wherein a process tool comprises a first process
10 chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

5353. The system of claim 5352, wherein the system is further configured to determine
15 one or more of the at least two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

5354. The system of claim 5324, wherein the remote controller computer is further
20 configured to compare one or more of the at least two properties of the specimen and properties of a plurality of specimens during use.

5355. The system of claim 5324, wherein the remote controller computer is further
25 configured to compare one or more of the at least two properties of the specimen to a predetermined range for the one or more properties during use.

5356. The system of claim 5355, wherein the remote controller computer is further
configured to generate an output signal if one or more of the at least two properties of the specimen are outside of the predetermined range for the property during use.

5357. The system of claim 5324, wherein the remote controller computer is further configured to alter a sampling frequency of the first measurement device in response to the at least one thin film characteristic of the specimen during use.

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5358. The system of claim 5324, wherein the remote controller computer is further configured to alter a sampling frequency of the second measurement device in response to the at least one electrical property of the specimen during use.

10 5359. The system of claim 5324, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedback control technique during use.

15 5360. The system of claim 5324, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedback control technique during use.

20 5361. The system of claim 5324, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic using a feedforward control technique during use.

25 5362. The system of claim 5324, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property using a feedforward control technique during use.

5363. The system of claim 5324, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the remote controller computer is further configured to calibrate the first and second measurement devices using the database during use.

5364. The system of claim 5324, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by first and second measurement devices using the database during use.

5365. The system of claim 5324, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and wherein the database further comprises the at least one thin film characteristic and the at least one electrical property of a plurality of specimens.

5366. The system of claim 5365, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

5367. The system of claim 5365, wherein the at least one thin film characteristic and the at least one electrical property of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

5368. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a first measurement device and a second measurement device;

generating one or more output signals responsive to at least one thin film characteristic of the specimen with the first measurement device;

generating one or more output signals responsive to at least one electrical property of the specimen with the second measurement device;

processing the one or more output signals from the first measurement device to determine the at least one thin film characteristic of the specimen and the one or more output signals from the second measurement device to determine the at least one electrical property of the specimen, comprising:

at least partially processing the one or more output signals from the first measurement device and the one or more output signals from the second measurement device using a local processor, wherein the local processor is coupled to the first and second measurement devices;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

5369. The method of claim 5368, wherein the first measurement device comprises a reflectometer.

5370. The method of claim 5368, wherein the first measurement device comprises a spectroscopic reflectometer.

5371. The method of claim 5368, wherein the first measurement device comprises an ellipsometer.

5372. The method of claim 5368, wherein the first measurement device comprises a spectroscopic ellipsometer.

5373. The method of claim 5368, wherein the first measurement device comprises a beam profile ellipsometer.

5374. The method of claim 5368, wherein the first measurement device comprises a photo-acoustic device.

5375. The method of claim 5368, wherein the first measurement device comprises an eddy current device.

5376. The method of claim 5368, wherein the first measurement device comprises an X-ray reflectometer.

5 5377. The method of claim 5368, wherein the first measurement device comprises a grazing X-ray reflectometer.

5378. The method of claim 5368, wherein the first measurement device comprises an X-ray diffractometer.

10 5379. The method of claim 5368, wherein the first measurement device comprises at least two measurement devices, and wherein the at least two measurement devices are selected from the group consisting of a reflectometer, a spectroscopic reflectometer, an ellipsometer, a spectroscopic ellipsometer, a beam profile ellipsometer, a photo-acoustic device, an eddy current device, an X-ray reflectometer, a grazing X-ray reflectometer, and
15 an X-ray diffractometer.

5380. The method of claim 5368, wherein at least one element of the first measurement device comprises at least one element of the second measurement device.

20 5381. The method of claim 5368, wherein generating the one or more output signals responsive to the at least one electrical property of the specimen with the second measurement device comprises:

annealing the specimen;

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reducing a temperature of the specimen subsequent to the annealing;

depositing a charge on an upper surface of the specimen; and

measuring the at least one electrical property of the charged upper surface of the specimen.

5 5382. The method of claim 5368, wherein the at least one electrical property of the specimen is selected from the group consisting of a capacitance, a dielectric constant, and a resistivity.

10 5383. The method of claim 5368, wherein the at least one electrical property comprises at least one electrical property of a layer formed on the specimen, and wherein the layer comprises a dielectric material.

15 5384. The method of claim 5368, further comprising processing the one or more output signals of the second measurement device to determine a characteristic of metal contamination on the specimen.

20 5385. The method of claim 5368, further comprising processing the one or more output signals of the first or second measurement device to determine a third property of the specimen, wherein the third property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

25 5386. The method of claim 5368, further comprising processing the one or more output signals of the first measurement device and the one or more output signals of the second measurement device substantially simultaneously to determine the at least one thin film characteristic and the at least one electrical property substantially simultaneously.

5387. The method of claim 5368, further comprising generating the one or more output signals responsive to the at least one thin film characteristic of the specimen with the first measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the first measurement device to
5 determine the at least one thin film characteristic at the multiple locations on the specimen.

5388. The method of claim 5368, further comprising generating the one or more output signals responsive to the at least one electrical property of the specimen with the second
10 measurement device at multiple locations on the specimen substantially simultaneously and processing the one or more output signals from the second measurement device to determine the at least one electrical property at the multiple locations on the specimen.

5389. The method of claim 5368, wherein the remote controller computer is coupled to a
15 process tool.

5390. The method of claim 5368, wherein the remote controller computer is coupled to a process tool selected from the group consisting of a chemical vapor deposition tool, an atomic layer deposition tool, a physical vapor deposition tool, a plating tool, a chemical-
20 mechanical polishing tool, a thermal tool, a cleaning tool, an ion implanter, and an etch tool.

5391. The method of claim 5368, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two
25 properties of the specimen using a feedback control technique.

5392. The method of claim 5368, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

5 5393. The method of claim 5368, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

5394. The method of claim 5393, further comprising determining a relationship between one or more of the at least two properties and at least one of the monitored parameters.

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5395. The method of claim 5394, further comprising altering a parameter of at least one of the instruments in response to the relationship.

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5396. The method of claim 5368, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

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5397. The method of claim 5396, further comprising determining one or more of the at least two properties of the specimen during the process step.

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5398. The method of claim 5397, further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

5399. The method of claim 5397, further comprising altering a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

5400. The method of claim 5368, further comprising moving the specimen from a first process chamber to a second process chamber using the stage and determining one or more of the at least two properties of the specimen during said moving the specimen from
5 the first process chamber to the second process chamber.

5401. The method of claim 5368, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

10 5402. The method of claim 5368, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties.

15 5403. The method of claim 5402, further comprising generating an output signal if one or more of the at least two properties of the specimen is outside of the predetermined range for the property.

20 5404. The method of claim 5368, further comprising altering a sampling frequency of the first measurement device in response to the at least one thin film characteristic of the specimen.

25 5405. The method of claim 5368, further comprising altering a sampling frequency of the second measurement device in response to the at least one electrical property of the specimen.

5406. The method of claim 5368, further comprising altering a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedback control technique.

5407. The method of claim 5368, further comprising altering a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedback control technique.

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5408. The method of claim 5368, further comprising altering a parameter of one or more instruments coupled to the first measurement device in response to the at least one thin film characteristic of the specimen using a feedforward control technique.

10 5409. The method of claim 5368, further comprising altering a parameter of one or more instruments coupled to the second measurement device in response to the at least one electrical property of the specimen using a feedforward control technique.

15 5410. The method of claim 5368, further comprising generating a database using the remote controller computer, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, the method further comprising calibrating the measurement device using the remote controller computer and the database.

20 5411. The method of claim 5368, further comprising generating a database using the remote controller computer, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, the method further comprising monitoring output signals of the first and second measurement devices using the remote controller computer and the database.

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5412. The method of claim 5368, further comprising generating a database using the remote controller computer, wherein the database comprises the at least one thin film characteristic of the specimen and the at least one electrical property of the specimen, and

wherein the database further comprises the at least one thin film characteristic and the at least one electrical property of a plurality of specimens.

5413. The method of claim 5412, wherein the at least one thin film characteristic and the at least one electrical property of a plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

5414. The method of claim 5412, wherein the at least one thin film characteristic and the at least one electrical property of a plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

5415. The method of claim 5368, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein at least one of the plurality of local processors is coupled to one of a plurality of measurement devices.

5416. The method of claim 5415, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices using the remote controller computer in response to one or more of the at least two properties of the specimen.

5417. The method of claim 5415, wherein at least one of the plurality of measurement devices is coupled to at least one of a plurality of process tools.

5418. The method of claim 5417, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of process tools using the remote

controller computer in response to one or more of the at least two properties of the specimen.

5 5419. A system configured to determine at least four properties of a specimen during use, comprising:

10 a plurality of measurement devices, wherein the plurality of measurement devices are configured to generate one or more output signals responsive to a critical dimension of the specimen, overlay misregistration of the specimen, a presence of defects on the specimen, and a thin film characteristic of the specimen during use; and

15 a processor coupled to the plurality of measurement devices, wherein the processor is configured to determine the at least four properties of the specimen from the one or more output signals during use, and wherein the at least four properties comprise the critical dimension of the specimen, the overlay misregistration of the specimen, the presence of defects on the specimen, and the thin film characteristic of the specimen.

20 5420. The system of claim 5419, wherein the system is further configured as a cluster tool.

5421. The system of claim 5419, wherein the system is further configured as a stand alone system.

25 5422. The system of claim 5419, further comprising a stage configured to support the specimen during use, wherein the stage is coupled to at least one of the plurality of

measurement devices, and wherein the stage is further configured to move laterally during use.

5 5423. The system of claim 5419, further comprising a stage configured to support the specimen during use, wherein the stage is coupled to at least one of the plurality of measurement devices, and wherein the stage is further configured to move rotatably during use.

10 5424. The system of claim 5419, further comprising a stage configured to support the specimen during use, wherein the stage is coupled to at least one of the plurality of measurement devices, and wherein the stage is further configured to move laterally and rotatably during use.

15 5425. The system of claim 5419, wherein the plurality of measurement devices comprise a non-imaging scatterometer.

5426. The system of claim 5419, wherein the plurality of measurement devices comprise a scatterometer.

20 5427. The system of claim 5419, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

25 5428. The system of claim 5419, wherein the plurality of measurement devices comprise a reflectometer.

5429. The system of claim 5419, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

5430. The system of claim 5419, wherein the plurality of measurement devices comprise an ellipsometer.

5 5431. The system of claim 5419, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

5432. The system of claim 5419, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

10 5433. The system of claim 5419, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

5434. The system of claim 5419, wherein the plurality of measurement devices comprise a bright field imaging device.

15 5435. The system of claim 5419, wherein the plurality of measurement devices comprise a dark field imaging device.

20 5436. The system of claim 5419, wherein the plurality of measurement devices comprise a bright field and a dark field imaging device.

5437. The system of claim 5419, wherein the plurality of measurement devices comprise a double dark field device.

25 5438. The system of claim 5419, wherein the plurality of measurement devices comprise a bright field non-imaging device.

5439. The system of claim 5419, wherein the plurality of measurement devices comprise a dark field non-imaging device.

5 5440. The system of claim 5419, wherein the plurality of measurement devices comprise a bright field and a dark field non-imaging device.

5441. The system of claim 5419, wherein the plurality of measurement devices comprise a coherence probe microscope.

10 5442. The system of claim 5419, wherein the plurality of measurement devices comprise an interference microscope.

5443. The system of claim 5419, wherein the plurality of measurement devices comprise an optical profilometer.

15 5444. The system of claim 5419, wherein the plurality of measurement devices comprise a photo-acoustic device.

20 5445. The system of claim 5419, wherein the plurality of measurement devices comprise an eddy current device.

5446. The system of claim 5419, wherein the plurality of measurement devices comprise an X-ray reflectometer.

25 5447. The system of claim 5419, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

5448. The system of claim 5419, wherein the plurality of measurement devices comprise an X-ray diffractometer.

5449. The system of claim 5419, wherein the plurality of measurement devices comprise
5 at least a first measurement device and a second measurement device, and wherein
elements of the first measurement device comprise elements of the second measurement
device.

5450. The system of claim 5419, wherein the defects comprise macro defects.
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5451. The system of claim 5419, wherein the presence of defects on the specimen
comprises a presence of defects on a bottom surface of the specimen.

5452. The system of claim 5419, wherein the processor is further configured to
15 determine a fifth property of the specimen from the one or more output signals during
use, and wherein the fifth property comprises a flatness measurement of the specimen.

5453. The system of claim 5419, wherein the processor is further configured to
determine a fifth property of the specimen from the one or more output signals during
20 use, and wherein the fifth property is selected from the group consisting of a roughness of
the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the
specimen.

5454. The system of claim 5419, wherein the system is further configured to determine
25 at least four properties of the specimen substantially simultaneously during use.

5455. The system of claim 5419, wherein the plurality of measurement devices are
further configured to generate one or more output signals responsive to one or more of the

at least four properties at multiple locations on the surface of the specimen substantially simultaneously during use such that the one or more properties can be determined at the multiple locations substantially simultaneously.

5 5456. The system of claim 5419, wherein the processor is further configured to compare one or more of the at least four properties of the specimen and properties of a plurality of specimens during use.

5457. The system of claim 5419, wherein the processor is further configured to compare
10 one or more of the at least four properties of the specimen to a predetermined range for the one or more properties during use.

5458. The system of claim 5419, wherein the processor is further configured to compare
15 one or more of the at least four properties of the specimen to a predetermined range for the one or more properties during use, and wherein the processor is further configured to generate an output signal if the one or more properties of the specimen are outside of the predetermined range during use.

5459. The system of claim 5419, wherein the processor is further configured to alter a
20 sampling frequency of at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen during use.

5460. The system of claim 5419, wherein the processor is further configured to alter a
25 parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties using a feedback control technique during use.

5461. The system of claim 5419, wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties using a feedforward control technique during use.

5

5462. The system of claim 5419, wherein the processor is further configured to generate a database during use, and wherein the database comprises the at least four properties of the specimen.

10 5463. The system of claim 5419, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least four properties of the specimen, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

15 5464. The system of claim 5419, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least four properties of the specimen, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

20 5465. The system of claim 5419, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least four properties of the specimen, wherein the database further comprises the at least four properties of a plurality of specimens, wherein the at least four properties of the plurality of specimens are determined using a plurality of systems, and wherein the processor is further configured
25 to calibrate one or more measurement devices of the plurality of systems using the database during use.

5466. The system of claim 5419, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least four properties of the specimen, wherein the database further comprises the at least four properties of a plurality of specimens, wherein the at least four properties of the plurality of specimens are
5 determined using a plurality of systems, and wherein the processor is further configured to monitor output signals generated by one or more measurement devices of the plurality of systems using the database during use.

5467. The system of claim 5419, further comprising a stand alone system coupled to the
10 system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

5468. The system of claim 5419, further comprising a stand alone system coupled the
15 system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

5469. The system of claim 5419, wherein the system is further configured to determine
20 at least the four properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen at the more than one position
25 on the specimen to reduce within wafer variation of the one or more properties.

5470. The system of claim 5419, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more

instruments coupled to the process tool in response to one or more of the at least four properties using a feedback control technique during use.

5 5471. The system of claim 5419, wherein the processor is further coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least four properties using a feedforward control technique during use.

10 5472. The system of claim 5419, wherein the processor comprises a local processor coupled to the plurality of measurement devices and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

15 5473. The system of claim 5472, wherein the local processor is further configured to determine the at least four properties of the specimen during use.

20 5474. The system of claim 5472, wherein the remote controller computer is further configured to determine the at least four properties of the specimen during use.

5475. A method for determining at least four properties of a specimen, comprising:
generating one or more output signals with a plurality of measurement devices,
25 wherein the one or more output signals are responsive to at least four properties of the specimen; and

processing the one or more output signals to determine the at least four properties of the specimen, wherein the at least four properties comprise a critical dimension of the specimen, overlay misregistration of the specimen, a presence of defects on the specimen, and a thin film characteristic of the specimen.

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5476. The method of claim 5475, wherein the plurality of measurement devices are configured as a cluster tool.

5477. The method of claim 5475, wherein the plurality of measurement devices are
10 configured as a stand alone system.

5478. The method of claim 5475, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising laterally moving the stage while determining the at least
15 four properties of the specimen.

5479. The method of claim 5475, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising rotatably moving the stage while determining the at least
20 four properties of the specimen.

5480. The method of claim 5475, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising laterally and rotatably moving the stage during while
25 determining the at least four properties of the specimen.

5481. The method of claim 5475, wherein the plurality of measurement devices comprise a non-imaging scatterometer.

5482. The method of claim 5475, wherein the plurality of measurement devices comprise a scatterometer.

5 5483. The method of claim 5475, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

5484. The method of claim 5475, wherein the plurality of measurement devices comprise a reflectometer.

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5485. The method of claim 5475, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

5486. The method of claim 5475, wherein the plurality of measurement devices
15 comprise an ellipsometer.

5487. The method of claim 5475, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

20 5488. The method of claim 5475, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

5489. The method of claim 5475, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

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5490. The method of claim 5475, wherein the plurality of measurement devices comprise a bright field imaging device.

5491. The method of claim 5475, wherein the plurality of measurement devices comprise a dark field imaging device.

5 5492. The method of claim 5475, wherein the plurality of measurement devices comprise a bright field and dark field imaging device.

5493. The method of claim 5475, wherein the plurality of measurement devices comprise a double dark field device.

10 5494. The method of claim 5475, wherein the plurality of measurement devices comprise a bright field non-imaging device.

5495. The method of claim 5475, wherein the plurality of measurement devices comprise a dark field non-imaging device.

15 5496. The method of claim 5475, wherein the plurality of measurement devices comprise a bright field and dark field non-imaging device

20 5497. The method of claim 5475, wherein the plurality of measurement devices comprise a coherence probe microscope.

5498. The method of claim 5475, wherein the plurality of measurement devices comprise an interference microscope.

25 5499. The method of claim 5475, wherein the plurality of measurement devices comprise an optical profilometer.

5500. The method of claim 5475, wherein the plurality of measurement devices comprise a photo-acoustic device.

5 5501. The method of claim 5475, wherein the plurality of measurement devices comprise an eddy current device.

5502. The method of claim 5475, wherein the plurality of measurement devices comprise an X-ray reflectometer.

10 5503. The method of claim 5475, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

15 5504. The method of claim 5475, wherein the plurality of measurement devices comprise an X-ray diffractometer.

5505. The method of claim 5475, wherein the plurality of measurement devices comprises at least a first measurement device and a second measurement device, and wherein elements of the first measurement device comprise elements of the second measurement device.

20 5506. The method of claim 5475, wherein the defects comprise macro defects.

5507. The method of claim 5475, wherein the presence of defects on the specimen comprises a presence of defects on a bottom surface of the specimen.

25 5508. The method of claim 5475, further comprising processing the one or more output signals to determine a fifth property of the specimen, wherein the fifth property comprises a flatness measurement of the specimen.

5509. The method of claim 5475, further comprising processing the one or more output signals to determine a fifth property of the specimen, wherein the fifth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5510. The method of claim 5475, wherein processing the one or more output signals to determine the at least four properties of the specimen comprises substantially simultaneously determining the at least four properties of the specimen.

5511. The method of claim 5475, further comprising generating the one or more output signals responsive to one or more of the at least four properties at multiple locations on the surface of the specimen substantially simultaneously such that the one or more properties of the specimen can be determined at the multiple locations substantially simultaneously.

5512. The method of claim 5475, further comprising comparing one or more of the at least four properties of the specimen and properties of a plurality of specimens.

5513. The method of claim 5475, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties.

5514. The method of claim 5475, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more properties of the specimen are outside of the predetermined range.

5515. The method of claim 5475, further comprising altering a sampling frequency of at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen.

5 5516. The method of claim 5475, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedback control technique.

10 5517. The method of claim 5475, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedforward control technique.

15 5518. The method of claim 5475, further comprising generating a database, wherein the database comprises the at least four properties of the specimen.

5519. The method of claim 5475, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method further
20 comprising calibrating the plurality of measurement devices using the database.

5520. The method of claim 5475, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method monitoring output signals generated by the plurality of measurement devices using the database.

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5521. The method of claim 5475, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four

properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems.

5522. The method of claim 5475, further comprising generating a database, wherein the
5 database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising calibrating the plurality of systems using the database.

10 5523. The method of claim 5475, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising monitoring output signals generated by the plurality of systems using the
15 database.

5524. The method of claim 5475, wherein a stand alone system is coupled to the plurality of measurement devices, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the plurality of measurement
20 devices with the stand alone system.

5525. The method of claim 5475, wherein a stand alone system is coupled to the plurality of measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard
25 and calibrating the plurality of measurement devices and at least the one additional measurement device with the stand alone system.

5526. The method of claim 5475, further comprising determining at least the four properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

5527. The method of claim 5475, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen.

5528. The method of claim 5475, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedback control technique.

5529. The method of claim 5475, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedforward control technique.

5530. The method of claim 5475, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the plurality of measurement devices;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

5 5531. The method of claim 5530, wherein at least partially processing the one or more output signals comprises determining the at least four properties of the specimen.

5532. The method of claim 5530, wherein further processing the partially processed one or more output signals comprises determining the at least four properties of the specimen.

10 5533. A computer-implemented method for controlling a system configured to determine at least four properties of a specimen during use, wherein the system comprises a plurality of measurement devices, comprising:

15 controlling the plurality of measurement devices to generate one or more output signals responsive to at least four properties of the specimen; and

20 processing the one or more output signals to determine the at least four properties of the specimen, wherein the at least four properties of the specimen comprises a critical dimension of the specimen, overlay misregistration of the specimen, a presence of defects on the specimen, and a thin film characteristic of the specimen.

25 5534. The method of claim 5533, wherein the system is further configured as a cluster tool.

5535. The method of claim 5533, wherein the system is further configured as a stand alone system.

5536. The method of claim 5533, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement device, and controlling the stage to move laterally while determining the at least four properties of the specimen.

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5537. The method of claim 5533, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement device, and controlling the stage to move rotatably while determining the at least four properties of the specimen.

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5538. The method of claim 5533, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement device, and controlling the stage to move laterally and rotatably while determining the at least four properties of the specimen.

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5539. The method of claim 5533, wherein the plurality of measurement devices comprise a non-imaging scatterometer.

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5540. The method of claim 5533, wherein the plurality of measurement devices comprise a scatterometer.

5541. The method of claim 5533, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

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5542. The method of claim 5533, wherein the plurality of measurement devices comprise a reflectometer.

5543. The method of claim 5533, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

5 5544. The method of claim 5533, wherein the plurality of measurement devices comprise an ellipsometer.

5545. The method of claim 5533, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

10 5546. The method of claim 5533, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

5547. The method of claim 5533, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

15 5548. The method of claim 5533, wherein the plurality of measurement devices comprise a bright field imaging device.

20 5549. The method of claim 5533, wherein the plurality of measurement devices comprise a dark field imaging device.

5550. The method of claim 5533, wherein the plurality of measurement devices comprise a bright field and dark field imaging device.

25 5551. The method of claim 5533, wherein the plurality of measurement devices comprise a double dark field device.

5552. The method of claim 5533, wherein the plurality of measurement devices comprise a bright field non-imaging device.

5 5553. The method of claim 5533, wherein the plurality of measurement devices comprise a dark field non-imaging device.

5554. The method of claim 5533, wherein the plurality of measurement devices comprise a bright field and dark field non-imaging device.

10 5555. The method of claim 5533, wherein the plurality of measurement devices comprise a coherence probe microscope.

15 5556. The method of claim 5533, wherein the plurality of measurement devices comprise an interference microscope.

5557. The method of claim 5533, wherein the plurality of measurement devices comprise an optical profilometer.

20 5558. The method of claim 5533, wherein the plurality of measurement devices comprise a photo-acoustic device.

5559. The method of claim 5533, wherein the plurality of measurement devices comprise an eddy current device.

25 5560. The method of claim 5533, wherein the plurality of measurement devices comprise an X-ray reflectometer.

5561. The method of claim 5533, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

5 5562. The method of claim 5533, wherein the plurality of measurement devices comprise an X-ray diffractometer.

5563. The method of claim 5533, wherein the plurality of measurement devices comprise at least a first measurement device and a second measurement device, and wherein elements of the first measurement device comprise elements of the second
10 measurement device.

5564. The method of claim 5533, wherein the defects comprise macro defects.

5565. The method of claim 5533, wherein the presence of defects on the specimen
15 comprises a presence of defects on a bottom surface of the specimen.

5566. The method of claim 5533, further comprising processing the one or more output signals to determine a fifth property of the specimen, wherein the fifth property comprises a flatness measurement of the specimen.
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5567. The method of claim 5533, further comprising processing the one or more output signals to determine a fifth property of the specimen, wherein the fifth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.
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5568. The method of claim 5533, wherein processing the one or more output signals to determine the at least four properties of the specimen comprises substantially simultaneously determining the at least four properties of the specimen.

5569. The method of claim 5533, further comprising controlling one or more of the plurality of measurement devices to generate one or more output signals responsive to one or more of the at least four properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that one or more properties can be determined at the multiple locations substantially simultaneously.

5570. The method of claim 5533, further comprising comparing one or more of the at least four properties of the specimen and properties of a plurality of specimens.

5571. The method of claim 5533, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties.

5572. The method of claim 5533, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more properties of the specimen are outside of the predetermined range.

5573. The method of claim 5533, further comprising altering a sampling frequency of at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen.

5574. The method of claim 5533, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedback control technique.

5575. The method of claim 5533, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedforward control technique.

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5576. The method of claim 5533, further comprising generating a database, wherein the database comprises the at least four properties of the specimen.

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5577. The method of claim 5533, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, and calibrating the plurality of measurement devices using the database.

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5578. The method of claim 5533, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, and monitoring output signals of the plurality of measurement devices using the database.

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5579. The method of claim 5533, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising calibrating the plurality of systems using the database.

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5580. The method of claim 5533, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising monitoring output signals of the plurality of systems using the database.

5581. The method of claim 5533, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

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5582. The method of claim 5533, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

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5583. The method of claim 5533, wherein the system is further configured to determine one or more of the at least four properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

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5584. The method of claim 5533, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen.

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5585. The method of claim 5533, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedback control technique.

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5586. The method of claim 5533, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedforward control technique.

5 5587. The method of claim 5533, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the plurality of measurement devices;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

5588. The method of claim 5587, wherein at least partially processing the one or more output signals comprises determining the at least four properties of the specimen.

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5589. The method of claim 5587, wherein further processing the partially processed one or more output signals comprises determining the at least four properties of the specimen.

5590. A semiconductor device fabricated by a method, the method comprising:

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forming a portion of the semiconductor device upon a specimen;

generating one or more output signals with a plurality of measurement devices,
wherein the one or more output signals are responsive to at least four properties of
the specimen; and

5 processing the one or more output signals to determine the at least four properties
of the specimen, wherein the at least four properties comprise a critical dimension
of the specimen, overlay misregistration of the specimen, a presence of defects on
the specimen, and a thin film characteristic of the specimen.

10 5591. The device of claim 5590, wherein the plurality of measurement devices are
configured as a cluster tool.

5592. The device of claim 5590, wherein the plurality of measurement devices are
configured as a stand alone system.

15 5593. The device of claim 5590, further comprising supporting the specimen on a stage,
wherein the stage is coupled to at least one of the plurality of measurement devices, the
method further comprising laterally moving the stage while determining the at least four
properties of the specimen.

20 5594. The device of claim 5590, further comprising supporting the specimen on a stage,
wherein the stage is coupled to at least one of the plurality of measurement devices, the
method further comprising rotatably moving the stage while determining the at least four
properties of the specimen.

25 5595. The device of claim 5590, further comprising supporting the specimen on a stage,
wherein the stage is coupled to at least one of the plurality of measurement devices, the

method further comprising laterally and rotatably moving the stage during while determining the at least four properties of the specimen.

5 5596. The device of claim 5590, wherein the plurality of measurement devices comprise a non-imaging scatterometer.

5597. The device of claim 5590, wherein the plurality of measurement devices comprise a scatterometer.

10 5598. The device of claim 5590, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

15 5599. The device of claim 5590, wherein the plurality of measurement devices comprise a reflectometer.

5600. The device of claim 5590, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

20 5601. The device of claim 5590, wherein the plurality of measurement devices comprise an ellipsometer.

5602. The device of claim 5590, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

25 5603. The device of claim 5590, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

5604. The device of claim 5590, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

5 5605. The device of claim 5590, wherein the plurality of measurement devices comprise a bright field imaging device.

5606. The device of claim 5590, wherein the plurality of measurement devices comprise a dark field imaging device.

10 5607. The device of claim 5590, wherein the plurality of measurement devices comprise a bright field and dark field imaging device.

5608. The device of claim 5590, wherein the plurality of measurement devices comprise a double dark field device.

15 5609. The device of claim 5590, wherein the plurality of measurement devices comprise a bright field non-imaging device.

20 5610. The device of claim 5590, wherein the plurality of measurement devices comprise a dark field non-imaging device.

5611. The device of claim 5590, wherein the plurality of measurement devices comprise a bright field and dark field non-imaging device

25 5612. The device of claim 5590, wherein the plurality of measurement devices comprise a coherence probe microscope.

5613. The device of claim 5590, wherein the plurality of measurement devices comprise an interference microscope.

5 5614. The device of claim 5590, wherein the plurality of measurement devices comprise an optical profilometer.

5615. The device of claim 5590, wherein the plurality of measurement devices comprise a photo-acoustic device.

10 5616. The device of claim 5590, wherein the plurality of measurement devices comprise an eddy current device.

5617. The device of claim 5590, wherein the plurality of measurement devices comprise an X-ray reflectometer.

15 5618. The device of claim 5590, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

20 5619. The device of claim 5590, wherein the plurality of measurement devices comprise an X-ray diffractometer.

5620. The device of claim 5590, wherein the plurality of measurement devices comprises at least a first measurement device and a second measurement device, and wherein elements of the first measurement device comprise elements of the second measurement device.

25

5621. The device of claim 5590, wherein the defects comprise macro defects.

5622. The device of claim 5590, wherein the presence of defects on the specimen comprises a presence of defects on a bottom surface of the specimen.

5623. The device of claim 5590, further comprising processing the one or more output
5 signals to determine a fifth property of the specimen, wherein the fifth property comprises a flatness measurement of the specimen.

5624. The device of claim 5590, further comprising processing the one or more output
10 signals to determine a fifth property of the specimen, wherein the fifth property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5625. The device of claim 5590, wherein processing the one or more output signals to
15 determine the at least four properties of the specimen comprises substantially simultaneously determining the at least four properties of the specimen.

5626. The device of claim 5590, further comprising generating the one or more output
20 signals responsive to one or more of the at least four properties at multiple locations on the surface of the specimen substantially simultaneously such that the one or more properties of the specimen can be determined at the multiple locations substantially simultaneously.

5627. The device of claim 5590, further comprising comparing one or more of the at
25 least four properties of the specimen and properties of a plurality of specimens.

5628. The device of claim 5590, further comprising comparing one or more of the at
least four properties of the specimen to a predetermined range for the one or more properties.

5629. The device of claim 5590, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more properties of the specimen are outside of the predetermined range.

5630. The device of claim 5590, further comprising altering a sampling frequency of at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen.

5631. The device of claim 5590, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedback control technique.

5632. The device of claim 5590, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedforward control technique.

5633. The device of claim 5590, further comprising generating a database, wherein the database comprises the at least four properties of the specimen.

5634. The device of claim 5590, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method further comprising calibrating the plurality of measurement devices using the database.

5635. The device of claim 5590, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method monitoring output signals generated by the plurality of measurement devices using the database.

5 5636. The device of claim 5590, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems.

10 5637. The device of claim 5590, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising calibrating the plurality of systems using the database.

15 5638. The device of claim 5590, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further
20 comprising monitoring output signals generated by the plurality of systems using the database.

5639. The device of claim 5590, wherein a stand alone system is coupled to the plurality of measurement devices, the method further comprising calibrating the stand alone
25 system with a calibration standard and calibrating the plurality of measurement devices with the stand alone system.

5640. The device of claim 5590, wherein a stand alone system is coupled to the plurality of measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the plurality of measurement devices and at least the one additional measurement device with the stand alone system.

5641. The device of claim 5590, further comprising determining at least the four properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

5642. The device of claim 5590, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen.

5643. The device of claim 5590, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedback control technique.

5644. The device of claim 5590, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedforward control technique.

5645. The device of claim 5590, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the plurality of measurement devices;

sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

5646. The device of claim 5645, wherein at least partially processing the one or more
output signals comprises determining the at least four properties of the specimen.

5647. The device of claim 5645, wherein further processing the partially processed one
or more output signals comprises determining the at least four properties of the specimen.

5648. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

generating one or more output signals with a plurality of measurement devices,
wherein the one or more output signals are responsive to at least four properties of
the specimen; and

processing the one or more output signals to determine the at least four properties
of the specimen, wherein the at least four properties comprise a critical dimension
of the specimen, overlay misregistration of the specimen, a presence of defects on
the specimen, and a thin film characteristic of the specimen.

5649. The method of claim 5648, wherein the plurality of measurement devices are configured as a cluster tool.

5650. The method of claim 5648, wherein the plurality of measurement devices are
5 configured as a stand alone system.

5651. The method of claim 5648, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising laterally moving the stage while determining the at least
10 four properties of the specimen.

5652. The method of claim 5648, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising rotatably moving the stage while determining the at least
15 four properties of the specimen.

5653. The method of claim 5648, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising laterally and rotatably moving the stage during while
20 determining the at least four properties of the specimen.

5654. The method of claim 5648, wherein the plurality of measurement devices comprise a non-imaging scatterometer.

25 5655. The method of claim 5648, wherein the plurality of measurement devices comprise a scatterometer.

5656. The method of claim 5648, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

5 5657. The method of claim 5648, wherein the plurality of measurement devices comprise a reflectometer.

5658. The method of claim 5648, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

10 5659. The method of claim 5648, wherein the plurality of measurement devices comprise an ellipsometer.

5660. The method of claim 5648, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

15 5661. The method of claim 5648, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

20 5662. The method of claim 5648, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

5663. The method of claim 5648, wherein the plurality of measurement devices comprise a bright field imaging device.

25 5664. The method of claim 5648, wherein the plurality of measurement devices comprise a dark field imaging device.

5665. The method of claim 5648, wherein the plurality of measurement devices comprise a bright field and dark field imaging device.

5 5666. The method of claim 5648, wherein the plurality of measurement devices comprise a double dark field device.

5667. The method of claim 5648, wherein the plurality of measurement devices comprise a bright field non-imaging device.

10 5668. The method of claim 5648, wherein the plurality of measurement devices comprise a dark field non-imaging device.

5669. The method of claim 5648, wherein the plurality of measurement devices comprise a bright field and dark field non-imaging device

15 5670. The method of claim 5648, wherein the plurality of measurement devices comprise a coherence probe microscope.

20 5671. The method of claim 5648, wherein the plurality of measurement devices comprise an interference microscope.

5672. The method of claim 5648, wherein the plurality of measurement devices comprise an optical profilometer.

25 5673. The method of claim 5648, wherein the plurality of measurement devices comprise a photo-acoustic device.

5674. The method of claim 5648, wherein the plurality of measurement devices comprise an eddy current device.

5675. The method of claim 5648, wherein the plurality of measurement devices
5 comprise an X-ray reflectometer.

5676. The method of claim 5648, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

10 5677. The method of claim 5648, wherein the plurality of measurement devices comprise an X-ray diffractometer.

5678. The method of claim 5648, wherein the plurality of measurement devices comprises at least a first measurement device and a second measurement device, and
15 wherein elements of the first measurement device comprise elements of the second measurement device.

5679. The method of claim 5648, wherein the defects comprise macro defects.

20 5680. The method of claim 5648, wherein the presence of defects on the specimen comprises a presence of defects on a bottom surface of the specimen.

5681. The method of claim 5648, further comprising processing the one or more output signals to determine a fifth property of the specimen, wherein the fifth property comprises
25 a flatness measurement of the specimen.

5682. The method of claim 5648, further comprising processing the one or more output signals to determine a fifth property of the specimen, wherein the fifth property is selected

from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

5683. The method of claim 5648, wherein processing the one or more output signals to
5 determine the at least four properties of the specimen comprises substantially
simultaneously determining the at least four properties of the specimen.

5684. The method of claim 5648, further comprising generating the one or more output
signals responsive to one or more of the at least four properties at multiple locations on
10 the surface of the specimen substantially simultaneously such that the one or more
properties of the specimen can be determined at the multiple locations substantially
simultaneously.

5685. The method of claim 5648, further comprising comparing one or more of the at
15 least four properties of the specimen and properties of a plurality of specimens.

5686. The method of claim 5648, further comprising comparing one or more of the at
least four properties of the specimen to a predetermined range for the one or more
properties.
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5687. The method of claim 5648, further comprising comparing one or more of the at
least four properties of the specimen to a predetermined range for the one or more
properties and generating an output signal if the one or more properties of the specimen
are outside of the predetermined range.
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5688. The method of claim 5648, further comprising altering a sampling frequency of at
least one of the plurality of measurement devices in response to one or more of the at
least four properties of the specimen.

5689. The method of claim 5648, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedback control
5 technique.

5690. The method of claim 5648, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedforward control
10 technique.

5691. The method of claim 5648, further comprising generating a database, wherein the database comprises the at least four properties of the specimen.

15 5692. The method of claim 5648, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method further comprising calibrating the plurality of measurement devices using the database.

5693. The method of claim 5648, further comprising generating a database, wherein the
20 database comprises the at least four properties of the specimen, the method monitoring output signals generated by the plurality of measurement devices using the database.

5694. The method of claim 5648, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four
25 properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems.

5695. The method of claim 5648, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising calibrating the plurality of systems using the database.

5696. The method of claim 5648, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising monitoring output signals generated by the plurality of systems using the database.

5697. The method of claim 5648, wherein a stand alone system is coupled to the plurality of measurement devices, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the plurality of measurement devices with the stand alone system.

5698. The method of claim 5648, wherein a stand alone system is coupled to the plurality of measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the plurality of measurement devices and at least the one additional measurement device with the stand alone system.

5699. The method of claim 5648, further comprising determining at least the four properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to one or

more of the at least four properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

5700. The method of claim 5648, further comprising altering a parameter of one or more
5 instruments coupled to a process tool in response to one or more of the at least four properties of the specimen.

5701. The method of claim 5648, further comprising altering a parameter of one or more
10 instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedback control technique.

5702. The method of claim 5648, further comprising altering a parameter of one or more
15 instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedforward control technique.

5703. The method of claim 5648, wherein processing the one or more output signals
comprises:

20 at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the plurality of measurement devices;

sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

25 further processing the partially processed one or more output signals using the
remote controller computer.

5704. The method of claim 5703, wherein at least partially processing the one or more output signals comprises determining the at least four properties of the specimen.

5705. The method of claim 5703, wherein further processing the partially processed one or more output signals comprises determining the at least four properties of the specimen.

5706. A system configured to determine at least four properties of a specimen during use, comprising:

10 a plurality of measurement devices, wherein the plurality of measurement devices are configured to generate one or more output signals responsive to the at least four properties of the specimen;

15 a local processor coupled to the plurality of measurement devices, wherein the local processor is configured to at least partially process the one or more output signals during use; and

20 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals during use and to determine the at least four properties of the specimen during use, and wherein the at least four properties comprise a critical dimension of the specimen, overlay misregistration of the specimen, a presence of defects on the specimen, and a thin film characteristic of the specimen.

25 5707. The system of claim 5706, wherein the system is further configured as a cluster tool.

5708. The system of claim 5706, wherein the system is further configured as a stand alone system.

5709. The system of claim 5706, further comprising a stage configured to support the
5 specimen during use, wherein the stage is coupled to at least one of the plurality of measurement devices, and wherein the stage is further configured to move laterally during use.

5710. The system of claim 5706, further comprising a stage configured to support the
10 specimen during use, wherein the stage is coupled to at least one of the plurality of measurement devices, and wherein the stage is further configured to move rotatably during use.

5711. The system of claim 5706, further comprising a stage configured to support the
15 specimen during use, wherein the stage is coupled to at least one of the plurality of measurement devices, and wherein the stage is further configured to move laterally and rotatably during use.

5712. The system of claim 5706, wherein the plurality of measurement devices comprise
20 a non-imaging scatterometer.

5713. The system of claim 5706, wherein the plurality of measurement devices comprise a scatterometer.

25 5714. The system of claim 5706, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

5715. The system of claim 5706, wherein the plurality of measurement devices comprise a reflectometer.

5 5716. The system of claim 5706, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

5717. The system of claim 5706, wherein the plurality of measurement devices comprise an ellipsometer.

10 5718. The system of claim 5706, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

5719. The system of claim 5706, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

15 5720. The system of claim 5706, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

20 5721. The system of claim 5706, wherein the plurality of measurement devices comprise a bright field imaging device.

5722. The system of claim 5706, wherein the plurality of measurement devices comprise a dark field imaging device.

25 5723. The system of claim 5706, wherein the plurality of measurement devices comprise a bright field and dark field imaging device.

5724. The system of claim 5706, wherein the plurality of measurement devices comprise a bright field non-imaging device.

5 5725. The system of claim 5706, wherein the plurality of measurement devices comprise a dark field non-imaging device.

5726. The system of claim 5706, wherein the plurality of measurement devices comprise a bright field and dark field non-imaging device.

10 5727. The system of claim 5706, wherein the plurality of measurement devices comprise a coherence probe microscope.

5728. The system of claim 5706, wherein the plurality of measurement devices comprise an interference microscope.

15 5729. The system of claim 5706, wherein the plurality of measurement devices comprise an optical profilometer.

20 5730. The system of claim 5706, wherein the plurality of measurement devices comprise a photo-acoustic device.

5731. The system of claim 5706, wherein the plurality of measurement devices comprise an eddy current device.

25 5732. The system of claim 5706, wherein the plurality of measurement devices comprise an X-ray reflectometer.

5733. The system of claim 5706, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

5734. The system of claim 5706, wherein the plurality of measurement devices comprise
5 an X-ray diffractometer.

5735. The system of claim 5706, wherein the plurality of measurement devices comprise at least a first measurement device and a second measurement device, and wherein at least one element of the first measurement device comprises at least one element of the
10 second measurement device.

5736. The system of claim 5706, wherein the defects comprise macro defects.

5737. The system of claim 5706, wherein the presence of defects on the specimen
15 comprises a presence of defects on a bottom surface of the specimen.

5738. The system of claim 5706, wherein the remote controller computer is further configured to determine a fifth property of the specimen from the at least partially processed one or more output signals during use, and wherein the fifth property comprises
20 a flatness measurement on the specimen.

5739. The system of claim 5706, wherein the remote controller computer is further configured to determine a fifth property of the specimen from the at least partially processed one or more output signals during use, and wherein the fifth property is
25 selected from the group consisting a roughness of the specimen, a specimen of a layer on the specimen, and a roughness of a feature of the specimen.

5740. The system of claim 5706, wherein the system is further configured to determine at least four properties of the specimen substantially simultaneously.

5741. The system of claim 5706, wherein the plurality of measurement devices are further configured to generate one or more output signals responsive to one or more of the at least four properties at multiple locations on the surface of the specimen substantially simultaneously during use such that one or more of the one or more properties of the specimen can be determined at the multiple locations substantially simultaneously.

5742. The system of claim 5706, wherein the remote controller computer is further configured to compare one or more of the at least four properties of the specimen and properties of a plurality of specimens during use.

5743. The system of claim 5706, wherein the remote controller computer is further configured to compare one or more of the at least four properties of the specimen to a predetermined range for the one or more properties during use.

5744. The system of claim 5706, wherein the remote controller computer is further configured to compare one or more of the at least four properties of the specimen to a predetermined range for the one or more properties during use, and wherein the remote controller computer is further configured to generate an output signal if the one or more properties of the specimen are outside of the predetermined range during use.

5745. The system of claim 5706, wherein the remote controller computer is further configured to alter a sampling frequency of at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen during use.

5746. The system of claim 5706, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedback control technique during use.

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5747. The system of claim 5706, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedforward control technique during use.

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5748. The system of claim 5706, wherein the remote controller computer is further configured to generate a database during use, and wherein the database comprises the at least four properties of the specimen.

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5749. The system of claim 5706, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least four properties of the specimen, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

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5750. The system of claim 5706, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least four properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

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5751. The system of claim 5706, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least

four properties of the specimen and the at least four properties of a plurality of specimens, wherein the at least four properties of the plurality of specimens are determined using a plurality of systems, wherein the remote controller computer is further coupled to the plurality of systems, and wherein the remote controller computer is further configured to
5 calibrate one or more measurement devices of the plurality of systems using the database during use.

5752. The system of claim 5706, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least
10 four properties of the specimen and the at least four properties of a plurality of specimens, wherein the at least four properties of the plurality of specimens are determined using a plurality of systems, wherein the remote controller computer is further coupled to the plurality of systems, and wherein the remote controller computer is further configured to monitor output signals generated by one or more measurement devices of the plurality of
15 systems using the database during use.

5753. The system of claim 5706, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate
20 the system during use.

5754. The system of claim 5706, further comprising a stand alone system coupled to the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is
25 further configured to calibrate the system and at least the one additional system during use.

5755. The system of claim 5706, wherein the system is further configured to determine at least the four properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the remote controller computer is further configured to alter at least one parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

5756. The system of claim 5706, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least four properties using a feedback control technique during use.

5757. The system of claim 5706, wherein the remote controller computer is further coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least four properties using a feedforward control technique during use.

5758. A method for determining at least four properties of a specimen, comprising:

generating one or more output signals with a plurality of output signals, wherein the one or more output signals are responsive to at least four properties of the specimen; and

processing the one or more output signals to determine the at least four properties of the specimen, wherein the at least four properties comprise a critical dimension

of the specimen, overlay misregistration of the specimen, a presence of defects on the specimen, and a thin film characteristic of the specimen, wherein processing the one or more output signals comprises:

5 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the plurality of measurement devices;

10 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

 further processing the partially processed one or more output signals using the remote controller computer.

15 5759. The method of claim 5758, wherein the plurality of measurement devices are configured as a cluster tool.

5760. The method of claim 5758, wherein the plurality of measurement devices are configured as a stand alone system.

20 5761. The method of claim 5758, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising laterally moving the stage while determining the at least four properties of the specimen.

25 5762. The method of claim 5758, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices,

the method further comprising rotatably moving the stage while determining the at least four properties of the specimen.

5763. The method of claim 5758, further comprising supporting the specimen on a stage, wherein the stage is coupled to at least one of the plurality of measurement devices, the method further comprising laterally and rotatably moving the stage during while determining the at least four properties of the specimen.

5764. The method of claim 5758, wherein the plurality of measurement devices comprise a non-imaging scatterometer.

5765. The method of claim 5758, wherein the plurality of measurement devices comprise a scatterometer.

5766. The method of claim 5758, wherein the plurality of measurement devices comprise a spectroscopic scatterometer.

5767. The method of claim 5758, wherein the plurality of measurement devices comprise a reflectometer.

5768. The method of claim 5758, wherein the plurality of measurement devices comprise a spectroscopic reflectometer.

5769. The method of claim 5758, wherein the plurality of measurement devices comprise an ellipsometer.

5770. The method of claim 5758, wherein the plurality of measurement devices comprise a spectroscopic ellipsometer.

5771. The method of claim 5758, wherein the plurality of measurement devices comprise a beam profile ellipsometer.

5 5772. The method of claim 5758, wherein the plurality of measurement devices comprise a dual beam spectrophotometer.

5773. The method of claim 5758, wherein the plurality of measurement devices comprise a bright field imaging device.

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5774. The method of claim 5758, wherein the plurality of measurement devices comprise a dark field imaging device.

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5775. The method of claim 5758, wherein the plurality of measurement devices comprise a bright field and dark field imaging device.

5776. The method of claim 5758, wherein the plurality of measurement devices comprise a double dark field device.

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5777. The method of claim 5758, wherein the plurality of measurement devices comprise a bright field non-imaging device.

5778. The method of claim 5758, wherein the plurality of measurement devices comprise a dark field non-imaging device.

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5779. The method of claim 5758, wherein the plurality of measurement devices comprise a bright field and dark field non-imaging device

5780. The method of claim 5758, wherein the plurality of measurement devices comprise a coherence probe microscope.

5 5781. The method of claim 5758, wherein the plurality of measurement devices comprise an interference microscope.

5782. The method of claim 5758, wherein the plurality of measurement devices comprise an optical profilometer.

10 5783. The method of claim 5758, wherein the plurality of measurement devices comprise a photo-acoustic device.

15 5784. The method of claim 5758, wherein the plurality of measurement devices comprise an eddy current device.

5785. The method of claim 5758, wherein the plurality of measurement devices comprise an X-ray reflectometer.

20 5786. The method of claim 5758, wherein the plurality of measurement devices comprise a grazing X-ray reflectometer.

5787. The method of claim 5758, wherein the plurality of measurement devices comprise an X-ray diffractometer.

25 5788. The method of claim 5758, wherein the plurality of measurement devices comprises at least a first measurement device and a second measurement device, and wherein elements of the first measurement device comprise elements of the second measurement device.

5789. The method of claim 5758, wherein the defects comprise macro defects.

5790. The method of claim 5758, wherein the presence of defects on the specimen
5 comprises a presence of defects on a bottom surface of the specimen.

5791. The method of claim 5758, further comprising processing the one or more output
signals to determine a fifth property of the specimen, wherein the fifth property comprises
a flatness measurement of the specimen.

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5792. The method of claim 5758, further comprising processing the one or more output
signals to determine a fifth property of the specimen, wherein the fifth property is selected
from the group consisting of a roughness of the specimen, a roughness of a layer on the
specimen, and a roughness of a feature of the specimen.

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5793. The method of claim 5758, wherein processing the one or more output signals to
determine the at least four properties of the specimen comprises substantially
simultaneously determining the at least four properties of the specimen.

20 5794. The method of claim 5758, further comprising generating the one or more output
signals responsive to one or more of the at least four properties at multiple locations on
the surface of the specimen substantially simultaneously such that the one or more
properties of the specimen can be determined at the multiple locations substantially
simultaneously.

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5795. The method of claim 5758, further comprising comparing one or more of the at
least four properties of the specimen and properties of a plurality of specimens.

5796. The method of claim 5758, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties.

5 5797. The method of claim 5758, further comprising comparing one or more of the at least four properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more properties of the specimen are outside of the predetermined range.

10 5798. The method of claim 5758, further comprising altering a sampling frequency of at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen.

15 5799. The method of claim 5758, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedback control technique.

20 5800. The method of claim 5758, further comprising altering a parameter of one or more instruments coupled to at least one of the plurality of measurement devices in response to one or more of the at least four properties of the specimen using a feedforward control technique.

25 5801. The method of claim 5758, further comprising generating a database, wherein the database comprises the at least four properties of the specimen.

5802. The method of claim 5758, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method further comprising calibrating the plurality of measurement devices using the database.

5 5803. The method of claim 5758, further comprising generating a database, wherein the database comprises the at least four properties of the specimen, the method monitoring output signals generated by the plurality of measurement devices using the database.

10 5804. The method of claim 5758, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems.

15 5805. The method of claim 5758, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising calibrating the plurality of systems using the database.

20 5806. The method of claim 5758, further comprising generating a database, wherein the database comprises the at least four properties of the specimen and the at least four properties of a plurality of specimens, and wherein the at least four properties of the plurality of specimens are generated using a plurality of systems, the method further comprising monitoring output signals generated by the plurality of systems using the
25 database.

5807. The method of claim 5758, wherein a stand alone system is coupled to the plurality of measurement devices, the method further comprising calibrating the stand

alone system with a calibration standard and calibrating the plurality of measurement devices with the stand alone system.

5808. The method of claim 5758, wherein a stand alone system is coupled to the plurality of measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the plurality of measurement devices and at least the one additional measurement device with the stand alone system.

5809. The method of claim 5758, further comprising determining at least the four properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

5810. The method of claim 5758, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen.

5811. The method of claim 5758, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedback control technique.

5812. The method of claim 5758, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least four properties of the specimen using a feedforward control technique.

5813. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

two or more measurement devices coupled to the stage, wherein the two or more measurement devices are configured to generate one or more output signals in response to one or more of the at least two properties of the specimen during use; and

a processor coupled to the two or more measurement devices, wherein the processor is configured to determine the at least two properties of the specimen from the one or more output signals during use, and wherein the at least two properties comprise a thickness of a structure on the specimen and at least one additional property of the specimen.

5814. The system of claim 5813, wherein the stage is further configured to move laterally during use.

5815. The system of claim 5813, wherein the stage is further configured to move rotatably during use.

5816. The system of claim 5813, wherein the stage is further configured to move laterally and rotatably during use.

5817. The system of claim 5813, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.

5818. The system of claim 5813, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic ellipsometer.

- 5 5819. The system of claim 5813, further comprising a pattern recognition system coupled to the stage and the processor, wherein the pattern recognition system is configured to generate one or more output signals during use, and wherein the processor is further configured to process the one or more output signals from the pattern recognition system during use.

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5820. The system of claim 5813, wherein at least one element of a first of the two or more measurement devices comprises at least one element of a second of the two or more measurement devices.

- 15 5821. The system of claim 5813, wherein the at least one additional property is selected from the group consisting of an index of refraction, a velocity of sound, a density, a critical dimension, and a profile of a layer or a feature formed on the specimen.

5822. The system of claim 5813, wherein the structure comprises a single layer formed
20 on the specimen.

5823. The system of claim 5813, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a substantially transparent film, a semi-transparent film, and an opaque metal film.

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5824. The system of claim 5813, wherein the structure comprises multiple layers formed on the specimen.

5825. The system of claim 5813, wherein the structure comprises multiple layers formed on the specimen, and wherein the multiple layers comprise two or more layers selected from the group consisting of a substantially transparent film, a semi-transparent film, an opaque metal film, and any combination thereof.

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5826. The system of claim 5813, wherein the specimen comprises a blanket wafer.

5827. The system of claim 5813, wherein the specimen comprises a patterned wafer.

10 5828. The system of claim 5813, further comprising a handling robot configured to dispose the specimen on the stage, wherein the handling robot is coupled to the two or more measurement devices.

15 5829. The system of claim 5813, further comprising a power supply, wherein the power supply is coupled to the first measurement device and the second measurement device.

5830. The system of claim 5813, further comprising an autofocus mechanism, wherein the autofocus mechanism is configured to bring a specimen substantially into focus for the two or more measurement devices.

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5831. The system of claim 5813, wherein the system is coupled to a chemical-mechanical polishing tool.

25 5832. The system of claim 5813, wherein the system is further configured to determine the at least two properties of the specimen substantially simultaneously during use.

5833. The system of claim 5813, wherein the two or more measurement devices are further configured to generate the one or more output signals in response to one or more

of the at least two properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that the one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

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5834. The system of claim 5813, wherein the system is coupled to a process tool, and wherein the system is disposed within the process tool.

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5835. The system of claim 5813, wherein the system is coupled to a process tool, and wherein the system is arranged laterally proximate to the process tool.

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5836. The system of claim 5813, wherein the system is coupled to a process tool, and wherein the process tool comprises a wafer handler configured to move the specimen to the stage during use.

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5837. The system of claim 5813, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen from the system to the process tool during use.

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5838. The system of claim 5813, wherein the system is coupled to a process tool, and wherein the stage is further configured to move the specimen to a process chamber of the process tool during use.

5839. The system of claim 5813, wherein the system is coupled to a process tool, and wherein the system is further configured to determine at least the two properties of the specimen while the specimen is waiting between process steps.

5840. The system of claim 5813, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

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5841. The system of claim 5813, wherein the system is coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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5842. The system of claim 5813, wherein the system comprises a measurement chamber, wherein the stage and the two or more measurement devices are disposed within the measurement chamber, and wherein the measurement chamber is coupled to a process tool.

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5843. The system of claim 5813, wherein the system comprises a measurement chamber, wherein the stage and the two or more measurement devices are disposed within the measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

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5844. The system of claim 5813, wherein the system comprises a measurement chamber, wherein the stage and the two or more measurement devices are disposed within the measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

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5845. The system of claim 5813, wherein the system comprises a measurement chamber, wherein the stage and the two or more measurement devices are disposed

within the measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

- 5 5846. The system of claim 5813, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, and wherein the stage is further configured to support the specimen during a process step.

- 10 5847. The system of claim 5813, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, and wherein the processor is further configured to determine the at least two properties of the specimen during the process step.

- 15 5848. The system of claim 5813, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, wherein the processor is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process
20 step.

- 25 5849. The system of claim 5813, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, wherein the processor is coupled to the process tool and is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique during use.

5850. The system of claim 5813, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

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5851. The system of claim 5813, wherein a process tool comprises a first process chamber and a second process chamber, wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the processor is further configured to determine at least the two properties of the specimen as the stage is moving the specimen from the first process chamber to the second process chamber.

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5852. The system of claim 5813, wherein the processor is further configured to compare the at least two properties of the specimen and properties of a plurality of specimens during use.

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5853. The system of claim 5813, wherein the processor is further configured to compare one or more of the at least two properties of the specimen to a predetermined range for the one or more properties during use.

20

5854. The system of claim 5813, wherein the processor is further configured to compare one or more of the at least two properties of the specimen to a predetermined range for the one or more properties during use, and wherein the processor is further configured to generate an output signal if the one or more properties of the specimen are outside of the predetermined range during use.

25

5855. The system of claim 5813, wherein the processor is further configured to alter a sampling frequency of at least one of the two or more measurement devices in response to one or more of the at least two properties during use.

5 5856. The system of claim 5813, wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties using a feedback control technique during use.

10 5857. The system of claim 5813, wherein the processor is further configured to alter a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties using a feedforward control technique during use.

15 5858. The system of claim 5813, wherein the processor is further configured to generate a database during use, and wherein the database comprises the at least two properties of the specimen.

20 5859. The system of claim 5813, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen, and wherein the processor is further configured to calibrate the two or more measurement devices using the database during use.

25 5860. The system of claim 5813, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen, and wherein the processor is further configured to monitor output signals generated by the two or more measurement devices using the database during use.

5861. The system of claim 5813, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to calibrate the plurality of measurement devices using the database during use.

5862. The system of claim 5813, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the processor is further coupled to the plurality of measurement devices, and wherein the processor is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

5863. The system of claim 5813, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

5864. The system of claim 5813, further comprising a stand alone system coupled to the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

5865. The system of claim 5813, wherein the system is further configured to determine one or more of the at least two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is configured to alter at least one parameter of one or more instruments coupled to a process tool in response to the one or more of the at least two properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more properties.

5866. The system of claim 5813, wherein the processor is coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using a feedback control technique during use.

5867. The system of claim 5813, wherein the processor is coupled to a process tool, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using a feedforward control technique during use.

5868. The system of claim 5813, wherein the processor is coupled to a process tool, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

5869. The system of claim 5868, wherein the processor is further configured to determine a relationship between one or more of the at least two properties and at least one of the monitored parameters during use.

5870. The system of claim 5869, wherein the processor is further configured to alter a parameter of the one or more instruments in response to the determined relationship during use.

5 5871. The system of claim 5813, wherein the processor comprises a local processor coupled to the two or more measurement devices and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or
10 more output signals during use.

5872. The system of claim 5871, wherein the local processor is further configured to determine the at least two properties of the specimen during use.

15 5873. The system of claim 5871, wherein the remote controller computer is further configured to determine the at least two properties of the specimen during use.

5874. A method for determining at least two properties of a specimen, comprising:

20 disposing the specimen upon a stage, wherein the stage is coupled to two or more measurement devices;

generating one or more output signals with the two or more measurement devices, wherein the one or more output signals are responsive to the at least two
25 properties of the specimen; and

processing the one or more output signals to determine the at least two properties of the specimen, wherein the at least two properties of the specimen comprise a

thickness of a structure on the specimen and at least one additional property of the specimen.

5875. The method of claim 5874, further comprising laterally moving the stage while
5 determining the at least two properties of the specimen.

5876. The method of claim 5874, further comprising rotatably moving the stage while
determining the at least two properties of the specimen.

10 5877. The method of claim 5874, further comprising laterally and rotatably moving the
stage while determining the at least two properties of the specimen.

5878. The method of claim 5874, wherein the two or more measurement devices
comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.
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5879. The method of claim 5874, wherein the two or more measurement devices
comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic
ellipsometer.

20 5880. The method of claim 5874, wherein the stage is further coupled to a pattern
recognition system, the method further comprising generating one or more output signals
with the pattern recognition system and processing the one or more output signals from
the pattern recognition system.

25 5881. The method of claim 5874, wherein at least one element of a first of the two
measurement devices comprises at least one element of a second of the two measurement
devices.

5882. The method of claim 5874, wherein the at least one additional property is selected from the group consisting of an index of refraction, a velocity of sound, a density, a critical dimension, and a profile of a layer or a feature formed on the specimen.

- 5 5883. The method of claim 5874, wherein the structure comprises a single layer formed on the specimen.

5884. The method of claim 5874, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a
10 substantially transparent film, a semi-transparent film, and an opaque metal film.

5885. The method of claim 5874, wherein the structure comprises multiple layers formed on the specimen.

- 15 5886. The method of claim 5874, wherein the structure comprises multiple layers formed on the specimen, and wherein the multiple layers comprise two or more layers selected from the group consisting of a substantially transparent film, a semi-transparent film, an opaque metal film, and any combination thereof.

- 20 5887. The method of claim 5874, wherein the specimen comprises a blanket wafer.

5888. The method of claim 5874, wherein the specimen comprises a patterned wafer.

- 25 5889. The method of claim 5874, wherein disposing the specimen on the stage comprises disposing the specimen on the stage with a handling robot, wherein the handling robot is coupled to the two or more measurement devices.

5890. The method of claim 5874, further comprising bringing the specimen substantially into focus for the two or more measurement devices with an autofocus mechanism.

5891. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a chemical-mechanical polishing tool.

5892. The method of claim 5874, wherein processing the one or more output signals to determine the at least two properties of the specimen comprises substantially simultaneously determining the at least two properties of the specimen.

5893. The method of claim 5874, further comprising generating the one or more output signals responsive to one or more of the at least two properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

5894. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are arranged laterally proximate to the process tool.

5895. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are disposed within the process tool.

5896. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

5897. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to generating the one or more output signals.

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5898. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

10 5899. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

15 5900. The method of claim 5874, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

20 5901. The method of claim 5874, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

25 5902. The method of claim 5874, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

5903. The method of claim 5874, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

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5904. The method of claim 5874, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

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5905. The method of claim 5874, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

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5906. The method of claim 5874, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising determining the at least two properties of the specimen during the process step.

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5907. The method of claim 5874, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

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5908. The method of claim 5874, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising altering a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

5909. The method of claim 5874, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

5910. The method of claim 5874, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool, the method further comprising determining the at least two properties of the specimen during said moving the specimen from the first process chamber to the second process chamber.

5911. The method of claim 5874, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

5912. The method of claim 5874, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties.

5913. The method of claim 5874, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more of the at least two properties of the specimen are outside of the predetermined range.

5914. The method of claim 5874, further comprising altering a sampling frequency of at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen.

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5915. The method of claim 5874, further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen using a feedback control technique.

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5916. The method of claim 5874, further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen using a feedforward control technique.

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5917. The method of claim 5874, further comprising generating a database, wherein the database comprises the at least two properties of the specimen.

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5918. The method of claim 5874, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising calibrating the two or more measurement devices using the database.

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5919. The method of claim 5874, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising monitoring output signals generated by the two or more measurement devices using the database.

5920. The method of claim 5874, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, and wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further
5 comprising calibrating the plurality of measurement devices using the database.

5921. The method of claim 5874, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, and wherein the at least two properties of the plurality of
10 specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the database.

5922. The method of claim 5874, wherein a stand alone system is coupled to the two or
15 more measurement devices, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the two or more measurement devices with the stand alone system.

5923. The method of claim 5874, wherein a stand alone system is coupled to the two or
20 more measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the two or more measurement devices and at least the one additional measurement device with the stand alone system.

5924. The method of claim 5874, further comprising determining one or more of the at
25 least two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the one or

more of the at least two properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more of the at least two properties.

5 5925. The method of claim 5874, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedback control technique.

10 5926. The method of claim 5874, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

15 5927. The method of claim 5874, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

5928. The method of claim 5874, further comprising monitoring a parameter of one or more instruments coupled to a process tool and determining a relationship between one or more of the at least two properties and at least one of the monitored parameters.

20 5929. The method of claim 5874, further comprising monitoring a parameter of one or more instruments coupled to a process tool, determining a relationship between one or more of the at least two properties and at least one of the monitored parameters, and altering the parameter of the one or more instruments in response to the relationship.

25 5930. The method of claim 5874, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the two or more measurement devices;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 5931. The method of claim 5930, wherein at least partially processing the one or more
output signals comprises determining the at least two properties of the specimen.

5932. The method of claim 5930, wherein further processing the partially processed one
or more output signals comprises determining the at least two properties of the specimen.

15 5933. A computer-implemented method for controlling a system configured to
determine at least two properties of a specimen during use, wherein the system comprises
a stage coupled to two or more measurement devices, and wherein the stage is configured
to support the specimen during use, the method comprising:

20 controlling the two or more measurement devices to generate one or more output
signals responsive to the at least two properties of the specimen; and

25 processing the one or more output signals to determine the at least two properties
of the specimen, wherein the at least two properties of the specimen comprise a
thickness of a structure on the specimen and at least one additional property of the
specimen.

5934. The method of claim 5933, further comprising controlling the stage to move laterally while determining the at least two properties of the specimen.

5935. The method of claim 5933, further comprising controlling the stage to move
5 rotatably while determining the at least two properties of the specimen.

5936. The method of claim 5933, further comprising controlling the stage to move laterally and rotatably while determining the at least two properties of the specimen.

10 5937. The method of claim 5933, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.

5938. The method of claim 5933, wherein the two or more measurement devices
15 comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic ellipsometer.

5939. The method of claim 5933, wherein the system further comprises a pattern
recognition system, the method further comprising controlling the pattern recognition
system to generate one or more output signals with the pattern recognition system and
20 processing the one or more output signals from the pattern recognition system.

5940. The method of claim 5933, wherein at least one element of a first of the two or
more measurement devices comprises at least one element of a second of the two or more
measurement devices.

25 5941. The method of claim 5933, wherein the at least one additional property is selected
from the group consisting of an index of refraction, a velocity of sound, a density, a
critical dimension, and a profile of a layer or a feature formed on the specimen.

5942. The method of claim 5933, wherein the structure comprises a single layer formed on the specimen.

5 5943. The method of claim 5933, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a substantially transparent film, a semi-transparent film, and an opaque metal film.

5944. The method of claim 5933, wherein the structure comprises multiple layers
10 formed on the specimen.

5945. The method of claim 5933, wherein the structure comprises multiple layers
formed on the specimen, and wherein the multiple layers comprise two or more layers
selected from the group consisting of a substantially transparent film, a semi-transparent
15 film, an opaque metal film, and any combination thereof.

5946. The method of claim 5933, wherein the specimen comprises a blanket wafer.

5947. The method of claim 5933, wherein the specimen comprises a patterned wafer.
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5948. The method of claim 5933, further comprising controlling a handling robot to
disposed the specimen on the specimen, wherein the handling robot is coupled to the two
or more measurement devices.

25 5949. The method of claim 5933, further comprising bringing the specimen substantially
into focus for the two or more measurement devices with an autofocus mechanism.

5950. The method of claim 5933, wherein the system is coupled to a chemical-mechanical polishing tool.

5951. The method of claim 5933, wherein processing the one or more output signals to
5 determine the at least two properties of the specimen comprises substantially simultaneously determining the at least two properties of the specimen.

5952. The method of claim 5933, further comprising controlling the two or more measurement devices to generate the one or more output signals responsive to one or
10 more of the at least two properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

5953. The method of claim 5933, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are arranged laterally proximate to the process tool.

5954. The method of claim 5933, wherein the stage and the two or more measurement
20 devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are disposed within the process tool.

5955. The method of claim 5933, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising controlling a wafer
25 handler to move the specimen from the process tool to the stage, and wherein the wafer handler is coupled to the process tool.

5956. The method of claim 5933, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising controlling the stage to move the specimen from the system to the process tool.

5 5957. The method of claim 5933, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising controlling a wafer handler to move the specimen from the process tool to the stage such that at least the two properties of the specimen can be determined while the specimen is waiting between process steps.

10

5958. The method of claim 5933, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

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5959. The method of claim 5933, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

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5960. The method of claim 5933, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

25 5961. The method of claim 5933, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

5962. The method of claim 5933, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

5963. The method of claim 5933, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

5964. The method of claim 5933, wherein the stage comprises a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

5965. The method of claim 5933, wherein the stage comprises a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising controlling the two or more measurement devices to generate the one or more output signals during the process step.

5966. The method of claim 5933, wherein the stage comprises a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising controlling the system to obtain a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

5967. The method of claim 5933, wherein the stage comprises a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising controlling the system to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

5968. The method of claim 5933, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool.

5969. The method of claim 5933, further comprising controlling the stage to move the specimen from a first process chamber to a second process chamber, wherein the first process chamber and the second process chamber are disposed within a process tool, the method further comprising controlling the two or more measurement devices to generate the one or more output signals during said moving the specimen from the first process chamber to the second process chamber.

5970. The method of claim 5933, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

5971. The method of claim 5933, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties.

5972. The method of claim 5933, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more of the at least two properties of the specimen are outside of the predetermined range.

5973. The method of claim 5933, further comprising altering a sampling frequency of at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen.

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5974. The method of claim 5933, further comprising altering a parameter of one or more instruments coupled to the at least one of the two or more measurement devices in response to one or more of the at least two properties using a feedback control technique.

10 5975. The method of claim 5933, further comprising altering a parameter of one or more instruments coupled to the at least one of the two or more measurement devices in response to one or more of the at least two properties using a feedforward control technique.

15 5976. The method of claim 5933, further comprising generating a database, wherein the database comprises the at least two properties of the specimen.

5977. The method of claim 5933, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further
20 comprising calibrating the two or more measurement devices using the database.

5978. The method of claim 5933, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising monitoring output signals of the two or more measurement devices using the
25 database.

5979. The method of claim 5933, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least the two

properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the database.

- 5 5980. The method of claim 5933, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least the two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the
10 database.

- 15 5981. The method of claim 5933, wherein a stand alone system is coupled to the system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

- 20 5982. The method of claim 5933, wherein a stand alone system is coupled to the system and at least one additional system, the method further comprising controlling the stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least the one additional system.

- 25 5983. The method of claim 5933, wherein the system is further configured to determine one or more of the at least two properties of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the one or more of the at least two properties of the specimen

at the more than one position on the specimen to reduce within wafer variation of the one or more of the at least two properties.

5 5984. The method of claim 5933, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedback control technique.

10 5985. The method of claim 5933, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

5986. The method of claim 5933, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

15 5987. The method of claim 5933, further comprising monitoring a parameter of one or more instruments coupled to the process tool and determining a relationship between one or more of the at least two properties of the specimen and at least one of the monitored parameters.

20 5988. The method of claim 5933, further comprising monitoring a parameter of one or more instruments coupled to the process tool, determining a relationship between one or more of the at least two properties of the specimen and at least one of the monitored parameters, and altering the parameter of at least one of the instruments in response to the relationship.

25

5989. The method of claim 5933, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the two or more measurement devices;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 5990. The method of claim 5989, wherein at least partially processing the one or more
output signals comprises determining the at least two properties of the specimen.

5991. The method of claim 5989, wherein further processing the partially processed one
or more output signals comprises determining the at least two properties of the specimen.

15 5992. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

20 disposing the specimen upon a stage, wherein the stage is coupled to two or more
measurement devices;

generating one or more output signals with the two or more measurement devices,
wherein the one or more output signals are responsive to the at least two
25 properties of the specimen; and

processing the one or more output signals to determine the at least two properties
of the specimen, wherein the at least two properties of the specimen comprise a

thickness of a structure on the specimen and at least one additional property of the specimen.

5993. The device of claim 5992, further comprising laterally moving the stage while
5 determining the at least two properties of the specimen.

5994. The device of claim 5992, further comprising rotatably moving the stage while
determining the at least two properties of the specimen.

10 5995. The device of claim 5992, further comprising laterally and rotatably moving the
stage while determining the at least two properties of the specimen.

5996. The device of claim 5992, wherein the two or more measurement devices
comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.
15

5997. The device of claim 5992, wherein the two or more measurement devices
comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic
ellipsometer.

20 5998. The device of claim 5992, wherein the stage is further coupled to a pattern
recognition system, the method further comprising generating one or more output signals
with the pattern recognition system and processing the one or more output signals from
the pattern recognition system.

25 5999. The device of claim 5992, wherein at least one element of a first of the two
measurement devices comprises at least one element of a second of the two measurement
devices.

6000. The device of claim 5992, wherein the at least one additional property is selected from the group consisting of an index of refraction, a velocity of sound, a density, a critical dimension, and a profile of a layer or a feature formed on the specimen.

5 6001. The device of claim 5992, wherein the structure comprises a single layer formed on the specimen.

6002. The device of claim 5992, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a
10 substantially transparent film, a semi-transparent film, and an opaque metal film.

6003. The device of claim 5992, wherein the structure comprises multiple layers formed on the specimen.

15 6004. The device of claim 5992, wherein the structure comprises multiple layers formed on the specimen, and wherein the multiple layers comprise two or more layers selected from the group consisting of a substantially transparent film, a semi-transparent film, an opaque metal film, and any combination thereof.

20 6005. The device of claim 5992, wherein the specimen comprises a blanket wafer.

6006. The device of claim 5992, wherein the specimen comprises a patterned wafer.

25 6007. The device of claim 5992, wherein disposing the specimen on the stage comprises disposing the specimen on the stage with a handling robot, wherein the handling robot is coupled to the two or more measurement devices.

6008. The device of claim 5992, further comprising bringing the specimen substantially into focus for the two or more measurement devices with an autofocus mechanism.

5 6009. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a chemical-mechanical polishing tool.

10 6010. The device of claim 5992, wherein processing the one or more output signals to determine the at least two properties of the specimen comprises substantially simultaneously determining the at least two properties of the specimen.

15 6011. The device of claim 5992, further comprising generating the one or more output signals responsive to one or more of the at least two properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

20 6012. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are arranged laterally proximate to the process tool.

25 6013. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are disposed within the process tool.

6014. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

6015. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to generating the one or more output signals.

5

6016. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

10 6017. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

15 6018. The device of claim 5992, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

20 6019. The device of claim 5992, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

25 6020. The device of claim 5992, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

6021. The device of claim 5992, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

5

6022. The device of claim 5992, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

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6023. The device of claim 5992, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

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6024. The device of claim 5992, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising determining the at least two properties of the specimen during the process step.

20

6025. The device of claim 5992, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

25

6026. The device of claim 5992, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising altering a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

6027. The device of claim 5992, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

6028. The device of claim 5992, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool, the method further comprising determining the at least two properties of the specimen during said moving the specimen from the first process chamber to the second process chamber.

6029. The device of claim 5992, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

6030. The device of claim 5992, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties.

6031. The device of claim 5992, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more of the at least two properties of the specimen are outside of the predetermined range.

6032. The device of claim 5992, further comprising altering a sampling frequency of at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen.

5

6033. The device of claim 5992, further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen using a feedback control technique.

10

6034. The device of claim 5992, further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen using a feedforward control technique.

15

6035. The device of claim 5992, further comprising generating a database, wherein the database comprises the at least two properties of the specimen.

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6036. The device of claim 5992, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising calibrating the two or more measurement devices using the database.

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6037. The device of claim 5992, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising monitoring output signals generated by the two or more measurement devices using the database.

6038. The device of claim 5992, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, and wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further
5 comprising calibrating the plurality of measurement devices using the database.

6039. The device of claim 5992, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, and wherein the at least two properties of the plurality of
10 specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the database.

6040. The device of claim 5992, wherein a stand alone system is coupled to the two or
15 more measurement devices, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the two or more measurement devices with the stand alone system.

6041. The device of claim 5992, wherein a stand alone system is coupled to the two or
20 more measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the two or more measurement devices and at least the one additional measurement device with the stand alone system.

25 6042. The device of claim 5992, further comprising determining one or more of the at least two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the one or

more of the at least two properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more of the at least two properties.

- 5 6043. The device of claim 5992, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedback control technique.

- 10 6044. The device of claim 5992, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

- 15 6045. The device of claim 5992, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

6046. The device of claim 5992, further comprising monitoring a parameter of one or more instruments coupled to a process tool and determining a relationship between one or more of the at least two properties and at least one of the monitored parameters.

- 20 6047. The device of claim 5992, further comprising monitoring a parameter of one or more instruments coupled to a process tool, determining a relationship between one or more of the at least two properties and at least one of the monitored parameters, and altering the parameter of the one or more instruments in response to the relationship.

- 25 6048. The device of claim 5992, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the two or more measurement devices;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 6049. The device of claim 6048, wherein at least partially processing the one or more
output signals comprises determining the at least two properties of the specimen.

6050. The device of claim 6048, wherein further processing the partially processed one
or more output signals comprises determining the at least two properties of the specimen.

15

6051. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

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disposing the specimen upon a stage, wherein the stage is coupled to two or more
measurement devices;

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generating one or more output signals with the two or more measurement devices,
wherein the one or more output signals are responsive to the at least two
properties of the specimen; and

processing the one or more output signals to determine the at least two properties
of the specimen, wherein the at least two properties of the specimen comprise a

thickness of a structure on the specimen and at least one additional property of the specimen.

5 6052. The method of claim 6051, further comprising laterally moving the stage while determining the at least two properties of the specimen.

6053. The method of claim 6051, further comprising rotatably moving the stage while determining the at least two properties of the specimen.

10 6054. The method of claim 6051, further comprising laterally and rotatably moving the stage while determining the at least two properties of the specimen.

15 6055. The method of claim 6051, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.

6056. The method of claim 6051, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic ellipsometer.

20 6057. The method of claim 6051, wherein the stage is further coupled to a pattern recognition system, the method further comprising generating one or more output signals with the pattern recognition system and processing the one or more output signals from the pattern recognition system.

25 6058. The method of claim 6051, wherein at least one element of a first of the two measurement devices comprises at least one element of a second of the two measurement devices.

6059. The method of claim 6051, wherein the at least one additional property is selected from the group consisting of an index of refraction, a velocity of sound, a density, a critical dimension, and a profile of a layer or a feature formed on the specimen.

5 6060. The method of claim 6051, wherein the structure comprises a single layer formed on the specimen.

6061. The method of claim 6051, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a
10 substantially transparent film, a semi-transparent film, and an opaque metal film.

6062. The method of claim 6051, wherein the structure comprises multiple layers formed on the specimen.

15 6063. The method of claim 6051, wherein the structure comprises multiple layers formed on the specimen, and wherein the multiple layers comprise two or more layers selected from the group consisting of a substantially transparent film, a semi-transparent film, an opaque metal film, and any combination thereof.

20 6064. The method of claim 6051, wherein the specimen comprises a blanket wafer.

6065. The method of claim 6051, wherein the specimen comprises a patterned wafer.

25 6066. The method of claim 6051, wherein disposing the specimen on the stage comprises disposing the specimen on the stage with a handling robot, wherein the handling robot is coupled to the two or more measurement devices.

6067. The method of claim 6051, further comprising bringing the specimen substantially into focus for the two or more measurement devices with an autofocus mechanism.

5 6068. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a chemical-mechanical polishing tool.

6069. The method of claim 6051, wherein processing the one or more output signals to determine the at least two properties of the specimen comprises substantially simultaneously determining the at least two properties of the specimen.

10 6070. The method of claim 6051, further comprising generating the one or more output signals responsive to one or more of the at least two properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the
15 multiple locations substantially simultaneously.

6071. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are arranged laterally proximate to the process tool.

20 6072. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, and wherein the stage and the two or more measurement devices are disposed within the process tool.

25 6073. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a wafer handler, and wherein disposing the specimen upon the stage comprises moving the specimen from the process tool to the stage using the wafer handler.

6074. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising moving the specimen to the process tool subsequent to generating the one or more output signals.

5

6075. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, the method further comprising determining at least the two properties of the specimen while the specimen is waiting between process steps.

10 6076. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the support device is substantially parallel to an upper surface of the stage.

15 6077. The method of claim 6051, wherein the stage and the two or more measurement devices are coupled to a process tool, wherein the process tool comprises a support device configured to support the specimen during a process step, and wherein an upper surface of the stage is angled with respect to an upper surface of the support device.

20 6078. The method of claim 6051, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, and wherein the measurement chamber is coupled to a process tool.

25 6079. The method of claim 6051, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is disposed within the process tool.

6080. The method of claim 6051, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the process tool.

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6081. The method of claim 6051, wherein the stage and the two or more measurement devices are disposed within a measurement chamber, wherein the measurement chamber is coupled to a process tool, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the process tool.

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6082. The method of claim 6051, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step.

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6083. The method of claim 6051, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising determining the at least two properties of the specimen during the process step.

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6084. The method of claim 6051, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising obtaining a signature characterizing the process step, wherein the signature comprises at least one singularity representative of an end of the process step.

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6085. The method of claim 6051, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising altering a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique.

6086. The method of claim 6051, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool.

6087. The method of claim 6051, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool, the method further comprising determining the at least two properties of the specimen during said moving the specimen from the first process chamber to the second process chamber.

6088. The method of claim 6051, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens.

6089. The method of claim 6051, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties.

6090. The method of claim 6051, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties and generating an output signal if the one or more of the at least two properties of the specimen are outside of the predetermined range.

6091. The method of claim 6051, further comprising altering a sampling frequency of at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen.

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6092. The method of claim 6051, further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen using a feedback control technique.

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6093. The method of claim 6051, further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen using a feedforward control technique.

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6094. The method of claim 6051, further comprising generating a database, wherein the database comprises the at least two properties of the specimen.

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6095. The method of claim 6051, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising calibrating the two or more measurement devices using the database.

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6096. The method of claim 6051, further comprising generating a database, wherein the database comprises the at least two properties of the specimen, the method further comprising monitoring output signals generated by the two or more measurement devices using the database.

6097. The method of claim 6051, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, and wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further
5 comprising calibrating the plurality of measurement devices using the database.

6098. The method of claim 6051, further comprising generating a database, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, and wherein the at least two properties of the plurality of
10 specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals generated by the plurality of measurement devices using the database.

6099. The method of claim 6051, wherein a stand alone system is coupled to the two or
15 more measurement devices, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the two or more measurement devices with the stand alone system.

6100. The method of claim 6051, wherein a stand alone system is coupled to the two or
20 more measurement devices and at least one additional measurement device, the method further comprising calibrating the stand alone system with a calibration standard and calibrating the two or more measurement devices and at least the one additional measurement device with the stand alone system.

6101. The method of claim 6051, further comprising determining one or more of the at
25 least two properties of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to a process tool in response to the one or

more of the at least two properties of the specimen at the more than one position on the specimen to reduce within wafer variation of the one or more of the at least two properties.

- 5 6102. The method of claim 6051, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedback control technique.

- 10 6103. The method of claim 6051, further comprising altering a parameter of one or more instruments coupled to a process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique.

- 15 6104. The method of claim 6051, further comprising monitoring a parameter of one or more instruments coupled to a process tool.

6105. The method of claim 6051, further comprising monitoring a parameter of one or more instruments coupled to a process tool and determining a relationship between one or more of the at least two properties and at least one of the monitored parameters.

- 20 6106. The method of claim 6051, further comprising monitoring a parameter of one or more instruments coupled to a process tool, determining a relationship between one or more of the at least two properties and at least one of the monitored parameters, and altering the parameter of the one or more instruments in response to the relationship.

- 25 6107. The method of claim 6051, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the two or more measurement devices;

5 sending the partially processed one or more output signals from the local
processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

10 6108. The method of claim 6107, wherein at least partially processing the one or more
output signals comprises determining the at least two properties of the specimen.

6109. The method of claim 6107, wherein further processing the partially processed one
or more output signals comprises determining the at least two properties of the specimen.

15 6110. A system configured to determine at least two properties of a specimen during
use, comprising:

a stage configured to support the specimen during use;

20 two or more measurement devices coupled to the stage, wherein the two or more
measurement devices are configured to generate one or more output signals in
response to one or more of the at least two properties of the specimen during use;

25 a local processor coupled to the two or more measurement devices and configured
to at least partially process the one or more output signals during use; and

5 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine the at least two properties of the specimen from the at least partially processed one or more output signals during use, and wherein the at least two properties comprise a thickness of a structure on the specimen and at least one additional property of the specimen.

10 6111. The system of claim 6110, wherein the stage is further configured to move laterally during use.

6112. The system of claim 6110, wherein the stage is further configured to move rotatably during use.

15 6113. The system of claim 6110, wherein the stage is further configured to move laterally and rotatably during use.

6114. The system of claim 6110, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.

20 6115. The system of claim 6110, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic ellipsometer.

25 6116. The system of claim 6110, further comprising a pattern recognition system coupled to the stage and the local processor, wherein the pattern recognition system is configured to generate one or more output signals during use, and wherein the remote controller computer is further configured to process the one or more output signals from the pattern recognition system during use.

6117. The system of claim 6110, wherein at least one element of a first of the two or more measurement devices comprises at least one element of a second of the two or more measurement devices.

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6118. The system of claim 6110, wherein the at least one additional property is selected from the group consisting of an index of refraction, a velocity of sound, a density, a critical dimension, and a profile of a layer or a feature formed on the specimen.

10 6119. The system of claim 6110, wherein the structure comprises a single layer formed on the specimen.

6120. The system of claim 6110, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a substantially transparent film, a semi-transparent film, and an opaque metal film.

15

6121. The system of claim 6110, wherein the structure comprises multiple layers formed on the specimen.

20 6122. The system of claim 6110, wherein the structure comprises multiple layers formed on the specimen, and wherein the multiple layers comprise two or more layers selected from the group consisting of a substantially transparent film, a semi-transparent film, an opaque metal film, and any combination thereof.

25 6123. The system of claim 6110, wherein the specimen comprises a blanket wafer.

6124. The system of claim 6110, wherein the specimen comprises a patterned wafer.

6125. The system of claim 6110, further comprising a handling robot configured to dispose the specimen on the stage, wherein the handling robot is coupled to the two or more measurement devices.

- 5 6126. The system of claim 6110, further comprising a power supply, wherein the power supply is coupled to the two measurement devices.

6127. The system of claim 6110, further comprising an autofocus mechanism, wherein the autofocus mechanism is configured to bring a specimen substantially into focus for
10 the two or more measurement devices.

6128. The system of claim 6110, wherein the system is coupled to a chemical-mechanical polishing tool.

- 15 6129. The system of claim 6110, wherein the system is further configured to determine the at least two properties of the specimen substantially simultaneously during use.

6130. The system of claim 6110, wherein the two or more measurement devices are further configured to generate the one or more output signals in response to one or more
20 of the at least two properties of the specimen at multiple locations on the surface of the specimen substantially simultaneously such that the one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.

- 25 6131. The system of claim 6110, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or

more of the at least two properties of the specimen using a feedback control technique during use.

5 6132. The system of claim 6110, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties of the specimen using a feedforward control technique during use.

10 6133. The system of claim 6110, wherein the remote controller computer is coupled to a process tool, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use.

15 6134. The system of claim 6110, wherein the remote controller computer is coupled to a process tool, wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use, and wherein the remote controller computer is further configured to determine a relationship between one or more of the at least two properties and at least one of the monitored parameters during use.

20 6135. The system of claim 6110, wherein the remote controller computer is coupled to a process tool, wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the process tool during use, wherein the remote controller computer is further configured to determine a relationship between one
25 or more of the at least two properties and at least one of the monitored parameters during use, and wherein the remote controller computer is further configured to alter the parameter of at least one of the instruments in response to the relationship during use.

6136. The system of claim 6110, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, and wherein the two or more measurement devices are configured to generate the one or more output signals during the process step.

6137. The system of claim 6110, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, wherein the two or more measurement devices are configured to generate the one or more output signals during the process step, wherein the remote controller computer is further configured to obtain a signature characterizing the process step during use, and wherein the signature comprises at least one singularity representative of an end of the process step.

6138. The system of claim 6110, wherein a process tool comprises a process chamber, wherein the stage is disposed within the process chamber, wherein the stage is further configured to support the specimen during a process step, wherein the two or more measurement devices are configured to generate the one or more output signals during the process step, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the process tool in response to one or more of the at least two properties using an in situ control technique during use.

6139. The system of claim 6110, wherein a process tool comprises a first process chamber and a second process chamber, and wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use.

6140. The system of claim 6110, wherein a process tool comprises a first process chamber and a second process chamber, wherein the stage is further configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the system is further configured to determine one or more of the at least two properties of the specimen during said moving.

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6141. The system of claim 6110, wherein the remote controller computer is further configured to compare one or more of the at least two properties of the specimen and properties of a plurality of specimens during use.

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6142. The system of claim 6110, wherein the remote controller computer is further configured to compare one or more of the at least two properties of the specimen to a predetermined range for the one or more properties during use.

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6143. The system of claim 6110, wherein the remote controller computer is further configured to compare one or more of the at least two properties of the specimen to a predetermined range for the one or more properties during use, wherein the remote controller computer is further configured to generate an output signal if one or more of the at least two properties of the specimen are outside of the predetermined range during use.

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6144. The system of claim 6110, wherein the remote controller computer is further configured to alter a sampling frequency of at least one of the two or more measurement devices in response to one or more of the at least two properties of the specimen during use.

6145. The system of claim 6110, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the

two or more measurement devices in response to one or more of the at least two properties using a feedback control technique during use.

5 6146. The system of claim 6110, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to at least one of the two or more measurement devices in response to one or more of the at least two properties using a feedforward control technique during use.

10 6147. The system of claim 6110, wherein the remote controller computer is further configured to generate a database during use, and wherein the database comprises the at least two properties of the specimen.

15 6148. The system of claim 6110, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen, and wherein the remote controller computer is further configured to calibrate the two or more measurement devices using the database during use.

20 6149. The system of claim 6110, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by the two or more measurement devices using the database during use.

25 6150. The system of claim 6110, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are determined using a

plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to calibrate the plurality of measurement devices using the database during use.

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6151. The system of claim 6110, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least two properties of the specimen and at least two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are determined using a plurality of measurement devices, wherein the remote controller computer is further coupled to the plurality of measurement devices, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of measurement devices using the database during use.

10 6152. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to two or more measurement devices;

20 generating one or more output signals with the two or more measurement devices, wherein the one or more output signals are responsive to the at least two properties of the specimen; and

25 processing the one or more output signals to determine the at least two properties of the specimen, wherein the at least two properties of the specimen comprise a thickness of a structure on the specimen and at least one additional property of the specimen, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the two or more measurement devices;

5 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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6153. The method of claim 6152, further comprising laterally moving the stage while determining the at least two properties of the specimen.

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6154. The method of claim 6152, further comprising rotatably moving the stage while determining the at least two properties of the specimen.

6155. The method of claim 6152, further comprising laterally and rotatably moving the stage while determining the at least two properties of the specimen.

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6156. The method of claim 6152, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a grazing X-ray reflectometer.

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6157. The method of claim 6152, wherein the two or more measurement devices comprise a small-spot photo-acoustic device and a broadband small-spot spectroscopic ellipsometer.

6158. The method of claim 6152, wherein the stage is further coupled to a pattern recognition system, the method further comprising generating one or more output signals

with the pattern recognition system and processing the one or more output signals from the pattern recognition system.

5 6159. The method of claim 6152, wherein at least one element of a first of the two or more measurement devices comprises at least one element of a second of the two or more measurement devices.

10 6160. The method of claim 6152, wherein the at least one additional property is selected from the group consisting of an index of refraction, a velocity of sound, a density, a critical dimension, and a profile of a layer or a feature formed on the specimen.

6161. The method of claim 6152, wherein the structure comprises a single layer formed on the specimen.

15 6162. The method of claim 6152, wherein the structure comprises a single layer formed on the specimen, and wherein the single layer is selected from the group consisting of a substantially transparent film, a semi-transparent film, and an opaque metal film.

20 6163. The method of claim 6152, wherein the structure comprises multiple layers formed on the specimen.

25 6164. The method of claim 6152, wherein the structure comprises multiple layers formed on the specimen, and wherein the multiple layers comprise two or more layers selected from the group consisting of a substantially transparent film, a semi-transparent film, an opaque metal film, and any combination thereof.

6165. The method of claim 6152, wherein the specimen comprises a blanket wafer.

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6166. The method of claim 6152, wherein the specimen comprises a patterned wafer.
6167. The method of claim 6152, wherein disposing the specimen on the stage comprises disposing the specimen on the stage with a handling robot, wherein the
5 handling robot is coupled to the two or more measurement devices.
6168. The method of claim 6152, further comprising bringing the specimen substantially into focus for the two or more measurement devices with an autofocus mechanism.
- 10 6169. The method of claim 6152, wherein the stage and the two or more measurement devices are coupled to a chemical-mechanical polishing tool.
6170. The method of claim 6152, further comprising generating the one or more output signals responsive to one or more of the at least two properties of the specimen at
15 multiple locations on a surface of the specimen substantially simultaneously such that one or more of the at least two properties of the specimen can be determined at the multiple locations substantially simultaneously.
6171. The method of claim 6152, wherein the remote controller computer is further
20 coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to one or more of the at least two properties of the specimen using a feedback control technique.
- 25 6172. The method of claim 6152, wherein the remote controller computer is further coupled to a process tool, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in

response to one or more of the at least two properties of the specimen using a feedforward control technique.

5 6173. The method of claim 6152, wherein the remote controller computer is further coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer.

10 6174. The method of claim 6152, wherein the remote controller computer is further coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer and determining a relationship between one or more of the at least two properties and at least one of the monitored parameters using the remote controller computer.

15 6175. The method of claim 6152, wherein the remote controller computer is further coupled to a process tool, the method further comprising monitoring a parameter of one or more instruments coupled to the process tool using the remote controller computer, determining a relationship between one or more of the at least two properties and at least one of the monitored parameters using the remote controller computer, and altering a parameter of at least one of the instruments in response to the relationship using the
20 remote controller computer.

25 6176. The method of claim 6152, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising determining the at least two properties of the specimen during the process step.

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6177. The method of claim 6152, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising obtaining a signature
5 characterizing the process step using the remote controller computer, wherein the signature comprises at least one singularity representative of an end of the process step.

6178. The method of claim 6152, wherein disposing the specimen upon the stage comprises disposing the specimen upon a support device disposed within a process
10 chamber of a process tool, and wherein the support device is configured to support the specimen during a process step, the method further comprising altering a parameter of one or more instruments coupled to the process tool using the remote controller computer in response to one or more of the at least two properties using an in situ control technique.

6179. The method of claim 6152, further comprising moving the specimen from a first process chamber to a second process chamber using the stage, wherein the first process chamber and the second process chamber are disposed within a process tool, the method further comprising determining the at least two properties of the specimen during said
15 detecting during said moving the specimen.

20 6180. The method of claim 6152, further comprising comparing one or more of the at least two properties of the specimen and properties of a plurality of specimens using the remote controller computer.

25 6181. The method of claim 6152, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties using the remote controller computer.

6182. The method of claim 6152, further comprising comparing one or more of the at least two properties of the specimen to a predetermined range for the one or more properties using the remote controller computer and generating an output signal using the remote controller computer if the one or more of the at least two properties of the specimen are outside of the predetermined range for the one or more properties.

6183. The method of claim 6152, wherein the remote controller computer is coupled to the two or more measurement devices, the method further comprising altering a sampling frequency of at least one of the two or more measurement devices using the remote controller computer in response to one or more of the at least two properties of the specimen.

6184. The method of claim 6152, wherein the remote controller computer is coupled to the two or more measurement devices, the method further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices using the remote controller computer in response to one or more of the at least two properties of the specimen using a feedback control technique.

6185. The method of claim 6152, wherein the remote controller computer is coupled to the two or more measurement devices, the method further comprising altering a parameter of one or more instruments coupled to at least one of the two or more measurement devices using the remote controller computer in response to one or more of the at least two properties of the specimen using a feedforward control technique.

6186. The method of claim 6152, further comprising generating a database using the remote controller computer, wherein the database comprises the at least two properties of the specimen.

6187. The method of claim 6152, further comprising generating a database using the remote controller computer, wherein the database comprises the at least two properties of the specimen, the method further comprising calibrating the two or more measurement devices using the database and the remote controller computer.

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6188. The method of claim 6152, further comprising generating a database using the remote controller computer, wherein the database comprises the at least two properties of the specimen, the method further comprising monitoring output signals of the two or more measurement devices using the remote controller computer.

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6189. The method of claim 6152, further comprising generating a database using the remote controller computer, wherein the database comprises the at least two properties of the specimen at least two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising calibrating the plurality of measurement devices using the remote controller computer and the database.

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6190. The method of claim 6152, further comprising generating a database using the remote controller computer, wherein the database comprises the at least two properties of the specimen at least two properties of a plurality of specimens, wherein the at least two properties of the plurality of specimens are generated using a plurality of measurement devices, the method further comprising monitoring output signals of the plurality of measurement devices using the remote controller computer and the database.

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6191. The method of claim 6152, further comprising sending the at least partially processed one or more output signals from a plurality of local processors to the remote controller computer, wherein each of the plurality of local processors is coupled to at least one of a plurality of measurement devices.

25

6192. A system configured to determine at least one property of a specimen during use, comprising:

5 a lithography track configured to perform one or more steps of a lithography process on the specimen during use;

a spectroscopic ellipsometer coupled to the lithography track, wherein the spectroscopic ellipsometer is configured to generate one or more output signals responsive to the at least one property of the specimen during use; and

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a processor coupled to the spectroscopic ellipsometer, wherein the processor is configured to determine the at least one property of the specimen from the one or more output signals during use.

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6193. The system of claim 6192, further comprising a stage coupled to the spectroscopic ellipsometer, wherein the stage is configured to move laterally during use.

6194. The system of claim 6192, further comprising a stage coupled to the spectroscopic ellipsometer, wherein the stage is configured to move rotatably during use.

20

6195. The system of claim 6192, further comprising a stage coupled to the spectroscopic ellipsometer, wherein the stage is configured to move laterally and rotatably during use.

25 6196. The system of claim 6192, wherein the at least one property is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a profile of a structure on the specimen.

6197. The system of claim 6192, further comprising an additional measurement device coupled to the lithography track, wherein the processor is further coupled to the additional measurement device, and wherein the processor is further configured to determine an additional property of the specimen from one or more output signals generated by the additional measurement device.

6198. The system of claim 6192, wherein the processor is further configured to determine an additional property of the specimen from the one or more output signals during use, and wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of a layer on the specimen, and a roughness of a feature of the specimen.

6199. The system of claim 6192, wherein the processor is further configured to determine a presence of defects on the specimen from the one or more output signals during use.

6200. The system of claim 6192, wherein the processor is further configured to determine at least two properties of the specimen substantially simultaneously during use.

6201. The system of claim 6192, wherein the spectroscopic ellipsometer is further configured to image at least an area of the specimen onto a one-dimensional detector such that at least the one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

6202. The system of claim 6192, wherein the spectroscopic ellipsometer is further configured to image at least an area of the specimen onto a two-dimensional detector such that at least the one property of the specimen can be determined at multiple locations substantially simultaneously.

6203. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

5 6204. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a resist apply process performed in the process chamber.

10 6205. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a post apply bake process performed in the process chamber.

15 6206. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a chill process performed in the process chamber.

20 6207. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a process step performed in the process chamber, and wherein the process step is performed subsequent to a develop process step.

25 6208. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic

ellipsometer is further configured to generate the one or more output signals prior to an exposure step of the lithography process.

5 6209. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals subsequent to an exposure step of the lithography process, and wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by the exposure step.

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6210. The system of claim 6192, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

15 6211. The system of claim 6192, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track, and wherein the lithography track comprises a wafer handler configured to move the specimen to a stage coupled to the spectroscopic ellipsometer during use.

20 6212. The system of claim 6192, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track, and wherein a stage coupled to the spectroscopic ellipsometer is configured to move the specimen from the spectroscopic ellipsometer to the lithography track during use.

25 6213. The system of claim 6192, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track, and wherein a stage coupled to the spectroscopic ellipsometer is configured to move the specimen to the process chamber of the lithography track during use.

6214. The system of claim 6192, wherein the system is further configured to determine at least the one property of the specimen while the specimen is waiting between the one or more steps of the lithography process.

5 6215. The system of claim 6192, wherein the lithography track comprises a support device configured to support the specimen during at least one of the one or more process steps, and wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

10 6216. The system of claim 6192, wherein the lithography track comprises a support device configured to support the specimen during at least one of the one or more process steps, and wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

15 6217. The system of claim 6192, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

20 6218. The system of claim 6192, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

25 6219. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, and wherein the stage is configured to support the specimen during at least one of the one or more process steps.

6220. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, and wherein the processor is further configured to determine at least the one property of the specimen during at least one of the one or more process steps.

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6221. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, wherein the processor is further configured to obtain a signature characterizing at least one of the one or more process steps during use, and wherein the signature comprises at least one singularity representative of an end of the at least one of the one or more process steps.

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6222. The system of claim 6192, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, wherein the processor is further coupled to the lithography track, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the lithography track in response to the at least one property using an in situ control technique during use.

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6223. The system of claim 6192, wherein the lithography track comprises a first process chamber and a second process chamber, wherein a stage coupled to the spectroscopic ellipsometer is configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

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6224. The system of claim 6223, wherein the first process chamber is configured to chill the specimen during use, and wherein the second process chamber is configured to apply resist to the specimen during use.

6225. The system of claim 6223, wherein the first process chamber is configured to chill the specimen subsequent to a post apply bake process step during use, and wherein the second process chamber is configured to expose the specimen during use.

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6226. The system of claim 6223, wherein the first process chamber is configured to expose the specimen during use, and wherein the second process chamber is configured to bake the specimen subsequent to exposure of the specimen during use.

10 6227. The system of claim 6223, wherein the first process chamber is configured to chill the specimen subsequent to a post exposure bake process step during use, and wherein the second process chamber is configured to develop the specimen during use.

15 6228. The system of claim 6223, wherein the first process chamber is configured to develop the specimen during use, and wherein the second process chamber is configured to bake the specimen subsequent to a develop process step during use.

20 6229. The system of claim 6223, wherein the first process chamber is configured to develop the specimen during use, and wherein the second process chamber is configured to receive the specimen in a wafer cassette during use.

6230. The system of claim 6192, wherein the processor is further configured to compare the at least one property of the specimen and properties of a plurality of specimens during use.

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6231. The system of claim 6192, wherein the processor is further configured to compare the at least one property of the specimen to a predetermined range for the at least one property during use.

6232. The system of claim 6192, wherein the processor is further configured to compare the at least one property of the specimen to a predetermined range for the at least one property during use, and wherein the processor is further configured to generate an output
5 signal if the at least one property is outside of the predetermined range for the at least one property during use.

6233. The system of claim 6192, wherein the processor is further configured to alter a
10 sampling frequency of the spectroscopic ellipsometer in response to the at least one property during use.

6234. The system of claim 6192, wherein the processor is further configured to alter a
15 parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property using a feedback control technique during use.

6235. The system of claim 6192, wherein the processor is further configured to alter a
parameter of one or more instruments coupled to the spectroscopic ellipsometer in
response to the at least one property using a feedforward control technique during use.

6236. The system of claim 6192, wherein the processor is further configured to generate
20 a database during use, and wherein the database comprises the at least one property of the specimen.

6237. The system of claim 6192, wherein the processor is further configured to generate
25 a database during use, wherein the database comprises the at least one property of the specimen, and wherein the processor is further configured to calibrate the spectroscopic ellipsometer using the database during use.

6238. The system of claim 6192, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen, and wherein the processor is further configured to monitor output signals generated by the spectroscopic ellipsometer using the database during use.

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6239. The system of claim 6192, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are determined using a plurality of spectroscopic ellipsometers, wherein the processor is further coupled to the plurality of spectroscopic ellipsometers, and wherein the processor is further configured to calibrate the plurality of spectroscopic ellipsometers using the database during use.

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6240. The system of claim 6192, wherein the processor is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are determined using a plurality of spectroscopic ellipsometers, wherein the processor is further coupled to the plurality of spectroscopic ellipsometers, and wherein the processor is further configured to monitor output signals generated by the plurality of spectroscopic ellipsometers using the database during use.

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6241. The system of claim 6192, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

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6242. The system of claim 6192, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to

be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

5 6243. The system of claim 6192, wherein the system is further configured to determine the at one property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the processor is further configured to alter at least one parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the
10 specimen to reduce within wafer variation of the at least one property.

6244. The system of claim 6192, wherein the processor is further coupled to the lithography track, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the lithography track in response to the at least one
15 property using a feedback control technique during use.

6245. The system of claim 6192, wherein the processor is further coupled to the lithography track, and wherein the processor is further configured to alter a parameter of one or more instruments coupled to the lithography track in response to the at least one
20 property using a feedforward control technique during use.

6246. The system of claim 6192, wherein the processor is further coupled to the lithography track, and wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the lithography track during use.

25 6247. The system of claim 6192, wherein the processor is further coupled to the lithography track, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the lithography track during use, and wherein the

processor is further configured to determine a relationship between the at least one property and at least one of the monitored parameters during use.

5 6248. The system of claim 6192, wherein the processor is further coupled to the lithography track, wherein the processor is further configured to monitor a parameter of one or more instruments coupled to the lithography track during use, wherein the processor is further configured to determine a relationship between the at least one property and at least one of the monitored parameters during use, and wherein the processor is further configured to alter a parameter of at least one of the instruments in
10 response to the relationship during use.

15 6249. The system of claim 6192, wherein the processor comprises a local processor coupled to the spectroscopic ellipsometer and a remote controller computer coupled to the local processor, wherein the local processor is configured to at least partially process the one or more output signals during use, and wherein the remote controller computer is configured to further process the at least partially processed one or more output signals during use.

20 6250. The system of claim 6249, wherein the local processor is further configured to determine the at least one property during use.

6251. The system of claim 6249, wherein the remote controller computer is further configured to determine the property during use.

25 6252. A method for determining at least one property of a specimen, comprising:

processing the specimen with one or more steps of a lithography process in a lithography track;

generating one or more output signals responsive to the at least one property of the specimen with a spectroscopic ellipsometer, wherein the spectroscopic ellipsometer is coupled to the lithography track; and

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processing the one or more output signals to determine the at least one property of the specimen.

6253. The method of claim 6252, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally moving the stage while determining the at least one property of the specimen.

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6254. The method of claim 6252, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising rotatably moving the stage while determining the at least one property of the specimen.

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6255. The method of claim 6252, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally and rotatably moving the stage while determining the at least one property of the specimen.

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6256. The method of claim 6252, wherein the at least one property is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a profile of a structure of the specimen.

6257. The method of claim 6252, comprising processing one or more output signals generated by an additional measurement device coupled to the lithography track to determine an additional property of the specimen.

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6258. The method of claim 6252, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

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6259. The method of claim 6252, further comprising processing the one or more output signals to determine a presence of defects on the specimen.

6260. The method of claim 6252, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

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6261. The method of claim 6252, further comprising imaging at least an area of the specimen onto a one-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

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6262. The method of claim 6252, further comprising imaging at least an area of the specimen onto a two-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

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6263. The method of claim 6252, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

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6264. The method of claim 6252, further comprising generating the one or more output signals during a resist apply process performed in a process chamber of the lithography track.

6265. The method of claim 6252, further comprising generating the one or more output signals during a post apply bake process performed in a process chamber of the lithography track.

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6266. The method of claim 6252, further comprising generating the one or more output signals during a chill process performed in a process chamber of the lithography track.

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6267. The method of claim 6252, further comprising generating the one or more output signals during a process step performed in a process chamber of the lithography track, wherein the process step is performed subsequent to a develop process step of the lithography process.

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6268. The method of claim 6252, further comprising generating the one or more output signals prior to an exposure step of the lithography process.

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6269. The method of claim 6252, further comprising generating the one or more output signals subsequent to an exposure step of the lithography process, wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by the exposure step.

6270. The method of claim 6252, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

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6271. The method of claim 6252, further comprising moving the specimen to a stage coupled to the spectroscopic ellipsometer with a wafer handler of the lithography track.

6272. The method of claim 6252, further comprising moving the specimen from the spectroscopic ellipsometer to the lithography track with a stage coupled to the spectroscopic ellipsometer.

5 6273. The method of claim 6252, further comprising moving the specimen to a process chamber of the lithography track with a stage coupled to the spectroscopic ellipsometer.

6274. The method of claim 6252, further comprising determining at least the one property of the specimen while the specimen is waiting between process steps.

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6275. The method of claim 6252, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

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6276. The method of claim 6252, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

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6277. The method of claim 6252, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

25 6278. The method of claim 6252, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

6279. The method of claim 6252, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a stage coupled to the spectroscopic ellipsometer.

- 5 6280. The method of claim 6252, wherein processing the one or more output signals comprises determining the at least one property of the specimen during at least one of the one or more steps of the lithography process.

6281. The method of claim 6252, further comprising obtaining a signature
10 characterizing at least one of the one or more steps of the lithography process, wherein the signature comprises at least one singularity representative of an end of the at least one step.

6282. The method of claim 6252, further comprising altering a parameter of one or more
15 instruments coupled to the lithography track in response to the at least one property using an in situ control technique.

6283. The method of claim 6252, wherein the lithography track comprises a first process chamber and a second process chamber, the method further comprising moving the
20 specimen from the first process chamber to the second process chamber using a stage coupled to the spectroscopic ellipsometer and generating the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

- 25 6284. The method of claim 6283, further comprising chilling the specimen in the first process chamber and applying resist to the specimen in the second process chamber.

6285. The method of claim 6283, further comprising chilling the specimen in the first process chamber subsequent to a post apply bake process and exposing the specimen in the second process chamber.

- 5 6286. The method of claim 6283, further comprising exposing the specimen in the first process chamber and baking the specimen in the second process chamber.

6287. The method of claim 6283, further comprising chilling the specimen in the first process chamber subsequent to a post exposure bake process and developing the
10 specimen in the second process chamber.

6288. The method of claim 6283, further comprising developing the specimen in the first process chamber and baking the specimen in the second process chamber.

- 15 6289. The method of claim 6283, further comprising developing the specimen in the first process chamber and receiving the specimen in a wafer cassette in the second process chamber.

6290. The method of claim 6252, further comprising comparing the at least one property
20 of the specimen and properties of a plurality of specimens.

6291. The method of claim 6252, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property.

- 25 6292. The method of claim 6252, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property and generating an output signal if the at least one property is outside of the predetermined range.

6293. The method of claim 6252, further comprising altering a sampling frequency of the spectroscopic ellipsometer in response to the at least one property of the specimen.

5 6294. The method of claim 6252, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property of the specimen using a feedback control technique.

10 6295. The method of claim 6252, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property of the specimen using a feedforward control technique.

6296. The method of claim 6252, further comprising generating a database, wherein the database comprises the at least one property of the specimen.

15 6297. The method of claim 6252, further comprising generating a database comprising the at least one property of the specimen and calibrating the spectroscopic ellipsometer using the database.

20 6298. The method of claim 6252, further comprising generating a database comprising the at least one property of the specimen and monitoring output signals generated by the spectroscopic ellipsometer using the database.

25 6299. The method of claim 6252, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising calibrating the plurality of spectroscopic ellipsometers using the database.

6300. The method of claim 6252, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising monitoring output signals
5 generated by the plurality of spectroscopic ellipsometers using the database.

6301. The method of claim 6252, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer with the stand alone system.
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6302. The method of claim 6252, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer and at least one additional measurement device with the stand alone system.

6303. The method of claim 6252, further comprising determining the at least one property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the specimen to
15 reduce within wafer variation of the at least one property.
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6304. The method of claim 6252, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedback control technique.
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6305. The method of claim 6252, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedforward control technique.

6306. The method of claim 6252, further comprising monitoring a parameter of one or more instruments coupled to the lithography track.

5 6307. The method of claim 6252, further comprising monitoring a parameter of one or more instruments coupled to the lithography track and determining a relationship between the at least one property and at least one of the monitored parameters.

6308. The method of claim 6252, further comprising monitoring a parameter of one or
10 more instruments coupled to the lithography track, determining a relationship between the at least one property and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

6309. The method of claim 6252, wherein processing the one or more output signals
15 comprises:

at least partially processing the one or more output signals using a local processor,
wherein the local processor is coupled to the spectroscopic ellipsometer;

20 sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the
remote controller computer.

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6310. The method of claim 6309, wherein at least partially processing the one or more output signals comprises determining the at least one property.

6311. The method of claim 6309, wherein further processing the partially processed one or more output signals comprises determining the at least one property.

6312. A computer-implemented method for controlling a system configured to
5 determine at least one property of a specimen during use, wherein the system comprises a spectroscopic ellipsometer, the method comprising:

controlling the spectroscopic ellipsometer to generate one or more output signals responsive to the at least one property of the specimen, wherein the spectroscopic
10 ellipsometer is coupled to a lithography track, and wherein the lithography track is configured to perform one or more steps of a lithography process on the specimen during use;

processing the one or more output signals to determine the at least one property of
15 the specimen.

6313. The method of claim 6312, further comprising supporting the specimen with a stage coupled to the spectroscopic ellipsometer and controlling the stage to move laterally while controlling the spectroscopic ellipsometer.

6314. The method of claim 6312, further comprising supporting the specimen with a stage coupled to the spectroscopic ellipsometer and controlling the stage to move rotatably while controlling the spectroscopic ellipsometer.

6315. The method of claim 6312, further comprising supporting the specimen with a stage coupled to the spectroscopic ellipsometer and controlling the stage to move laterally and rotatably while controlling the spectroscopic ellipsometer.

6316. The method of claim 6312, wherein the at least one property is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a profile of a structure on the specimen.

5 6317. The method of claim 6312, wherein the system further comprises an additional measurement device coupled to the lithography track, the method further comprising processing one or more output signals generated by the additional measurement device to determine an additional property of the specimen.

10 6318. The method of claim 6312, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

15 6319. The method of claim 6312, further comprising processing the one or more output signals to determine a presence of defects on the specimen.

20 6320. The method of claim 6312, wherein processing the one or more output signals comprises substantially simultaneously determining at least two properties of the specimen.

25 6321. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to image at least an area of the specimen onto a one-dimensional detector such that at least the one property of the specimen can be determined at multiple locations substantially simultaneously.

6322. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to image at least an area of the specimen onto a two-dimensional detector

such that at least the one property of the specimen can be determined at multiple location substantially simultaneously.

5 6323. The method of claim 6312, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

6324. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to generate the one or more output signals during a resist apply process performed in a process chamber of the lithography track.

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6325. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to generate the one or more output signals during a post apply bake process performed in a process chamber of the lithography track.

15 6326. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to generate the one or more output signals during a chill process performed in a process chamber of the lithography track.

20 6327. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to generate the one or more output signals during a process step performed in a process chamber of the lithography track, wherein the process step is performed subsequent to a develop process step of the lithography process.

25 6328. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to generate the one or more output signals prior to an exposure step of the lithography process.

6329. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to generate the one or more output signals subsequent to an exposure step of the lithography process, and wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by the exposure step.

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6330. The method of claim 6312, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

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6331. The method of claim 6312, further comprising controlling a wafer handler coupled to the lithography track to move the specimen to a stage coupled to the spectroscopic ellipsometer.

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6332. The method of claim 6312, further comprising controlling a stage coupled to the spectroscopic ellipsometer to move the specimen from the spectroscopic ellipsometer to the lithography track.

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6333. The method of claim 6312, further comprising controlling a stage coupled to the spectroscopic ellipsometer to move the specimen to a process chamber of the lithography track.

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6334. The method of claim 6312, the method further comprising controlling a wafer handler to move the specimen to a stage coupled to the spectroscopic ellipsometer such that at least the one property of the specimen can be determined while the specimen is waiting between process steps.

6335. The method of claim 6312, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the

lithography track, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

5 6336. The method of claim 6312, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

10 6337. The method of claim 6312, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

15 6338. The method of claim 6312, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

20 6339. The method of claim 6312, further comprising controlling a stage coupled to the spectroscopic ellipsometer to support the specimen during at least one of the one or more steps of the lithography process.

6340. The method of claim 6312, further comprising processing the one or more output signals to determine the at least one property of the specimen during at least one of the one or more steps of the lithography process.

25 6341. The method of claim 6312, further comprising controlling the spectroscopic ellipsometer to obtain a signature characterizing at least one of the one or more steps of the lithography process, wherein the signature comprises at least one singularity representative of an end of the at least one of the one or more steps.

6342. The method of claim 6312, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using an in situ control technique.

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6343. The method of claim 6312, wherein the lithography track comprises a first process chamber and a second process chamber, the method further comprising controlling a stage coupled to the spectroscopic ellipsometer to move the specimen from the first process chamber to the second process chamber and controlling the spectroscopic
10 ellipsometer to generate the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

6344. The method of claim 6343, further comprising chilling the specimen in the first process chamber and applying resist to the specimen in the second process chamber.

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6345. The method of claim 6343, further comprising chilling the specimen in the first process chamber subsequent to a post apply bake process and exposing the specimen in the second process chamber.

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6346. The method of claim 6343, further comprising exposing the specimen in the first process chamber and baking the specimen in the second process chamber.

6347. The method of claim 6343, further comprising chilling the specimen in the first process chamber subsequent to a post exposure bake process and developing the
25 specimen in the second process chamber.

6348. The method of claim 6343, further comprising developing the specimen in the first process chamber and baking the specimen in the second process chamber.

6349. The method of claim 6343, further comprising developing the specimen in the first process chamber and receiving the specimen in a wafer cassette in the second process chamber.

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6350. The method of claim 6312, further comprising comparing the at least one property of the specimen and properties of a plurality of specimens.

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6351. The method of claim 6312, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property.

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6352. The method of claim 6312, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property and generating an output signal if the at least one property is outside of the predetermined range.

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6353. The method of claim 6312, further comprising altering a sampling frequency of the spectroscopic ellipsometer in response to the at least one property.

6354. The method of claim 6312, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property using a feedback control technique.

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6355. The method of claim 6312, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property using a feedforward control technique.

6356. The method of claim 6312, further comprising generating a database, wherein the database comprises the at least one property.

6357. The method of claim 6312, further comprising generating a database, wherein the database comprises the at least one property, and calibrating the spectroscopic ellipsometer using the database.

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6358. The method of claim 6312, further comprising generating a database, wherein the database comprises the at least one property, and monitoring output signals generated by the spectroscopic ellipsometer using the database.

10 6359. The method of claim 6312, further comprising generating a database, wherein the database comprises the at least one property and properties of a plurality of specimens, and wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising calibrating the plurality of spectroscopic ellipsometers using the database.

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6360. The method of claim 6312, further comprising generating a database, wherein the database comprises the at least one property and properties of a plurality of specimens, and wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising monitoring output signals
20 generated by the plurality of spectroscopic ellipsometers using the database.

6361. The method of claim 6312, further comprising controlling a stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system.

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6362. The method of claim 6312, further comprising controlling a stand alone system to calibrate the stand alone system with a calibration standard and further controlling the stand alone system to calibrate the system and at least one additional system.

6363. The method of claim 6312, wherein the system is further configured to determine the at least one property of the specimen at more than one position on the specimen, and wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one property.

6364. The method of claim 6312, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedback control technique.

6365. The method of claim 6312, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedforward control technique.

6366. The method of claim 6312, further comprising monitoring a parameter of one or more instruments coupled to the lithography track.

6367. The method of claim 6312, further comprising monitoring a parameter of one or more instruments coupled to the lithography track and determining a relationship between the at least one property and at least one of the monitored parameters.

6368. The method of claim 6312, further comprising monitoring a parameter of one or more instruments coupled to the lithography track, determining a relationship between the at least one property and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

6369. The method of claim 6312, wherein processing the one or more output signals comprises:

5 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the spectroscopic ellipsometer;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

10 further processing the partially processed one or more output signals using the remote controller computer.

6370. The method of claim 6369, wherein at least partially processing the one or more output signals comprises determining the at least one property.

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6371. The method of claim 6369, wherein further processing the partially processed one or more output signals comprises determining the at least one property.

6372. A semiconductor device fabricated by a method, the method comprising:

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processing the specimen with one or more steps of a lithography process in a lithography track to form a patterned resist on the specimen, wherein the patterned resist can be used to form at least a portion of the semiconductor device;

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generating one or more output signals responsive to the at least one property of the specimen with a spectroscopic ellipsometer, wherein the spectroscopic ellipsometer is coupled to the lithography track; and

processing the one or more output signals to determine the at least one property of the specimen.

5 6373. The device of claim 6372, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally moving the stage while determining the at least one property of the specimen.

10 6374. The device of claim 6372, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising rotatably moving the stage while determining the at least one property of the specimen.

15 6375. The device of claim 6372, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally and rotatably moving the stage while determining the at least one property of the specimen.

6376. The device of claim 6372, wherein the at least one property is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a profile of a structure of the specimen.

20 6377. The device of claim 6372, comprising processing one or more output signals generated by an additional measurement device coupled to the lithography track to determine an additional property of the specimen.

25 6378. The device of claim 6372, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

6379. The device of claim 6372, further comprising processing the one or more output signals to determine a presence of defects on the specimen.

5 6380. The device of claim 6372, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

10 6381. The device of claim 6372, further comprising imaging at least an area of the specimen onto a one-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

15 6382. The device of claim 6372, further comprising imaging at least an area of the specimen onto a two-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

20 6383. The device of claim 6372, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

6384. The device of claim 6372, further comprising generating the one or more output signals during a resist apply process performed in a process chamber of the lithography track.

25 6385. The device of claim 6372, further comprising generating the one or more output signals during a post apply bake process performed in a process chamber of the lithography track.

6386. The device of claim 6372, further comprising generating the one or more output signals during a chill process performed in a process chamber of the lithography track.

5 6387. The device of claim 6372, further comprising generating the one or more output signals during a process step performed in a process chamber of the lithography track, wherein the process step is performed subsequent to a develop process step of the lithography process.

10 6388. The device of claim 6372, further comprising generating the one or more output signals prior to an exposure step of the lithography process.

15 6389. The device of claim 6372, further comprising generating the one or more output signals subsequent to an exposure step of the lithography process, wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by the exposure step.

6390. The device of claim 6372, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

20 6391. The device of claim 6372, further comprising moving the specimen to a stage coupled to the spectroscopic ellipsometer with a wafer handler of the lithography track.

25 6392. The device of claim 6372, further comprising moving the specimen from the spectroscopic ellipsometer to the lithography track with a stage coupled to the spectroscopic ellipsometer.

6393. The device of claim 6372, further comprising moving the specimen to a process chamber of the lithography track with a stage coupled to the spectroscopic ellipsometer.

6394. The device of claim 6372, further comprising determining at least the one property of the specimen while the specimen is waiting between process steps.

5 6395. The device of claim 6372, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

10 6396. The device of claim 6372, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

15 6397. The device of claim 6372, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

20 6398. The device of claim 6372, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

25 6399. The device of claim 6372, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a stage coupled to the spectroscopic ellipsometer.

6400. The device of claim 6372, wherein processing the one or more output signals comprises determining the at least one property of the specimen during at least one of the one or more steps of the lithography process.

5 6401. The device of claim 6372, further comprising obtaining a signature characterizing at least one of the one or more steps of the lithography process, wherein the signature comprises at least one singularity representative of an end of the at least one step.

6402. The device of claim 6372, further comprising altering a parameter of one or more
10 instruments coupled to the lithography track in response to the at least one property using an in situ control technique.

6403. The device of claim 6372, wherein the lithography track comprises a first process chamber and a second process chamber, the method further comprising moving the
15 specimen from the first process chamber to the second process chamber using a stage coupled to the spectroscopic ellipsometer and generating the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

20 6404. The device of claim 6403, further comprising chilling the specimen in the first process chamber and applying resist to the specimen in the second process chamber.

6405. The device of claim 6403, further comprising chilling the specimen in the first process chamber subsequent to a post apply bake process and exposing the specimen in
25 the second process chamber.

6406. The device of claim 6403, further comprising exposing the specimen in the first process chamber and baking the specimen in the second process chamber.

6407. The device of claim 6403, further comprising chilling the specimen in the first process chamber subsequent to a post exposure bake process and developing the specimen in the second process chamber.

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6408. The device of claim 6403, further comprising developing the specimen in the first process chamber and baking the specimen in the second process chamber.

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6409. The device of claim 6403, further comprising developing the specimen in the first process chamber and receiving the specimen in a wafer cassette in the second process chamber.

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6410. The device of claim 6372, further comprising comparing the at least one property of the specimen and properties of a plurality of specimens.

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6411. The device of claim 6372, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property.

6412. The device of claim 6372, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property and generating an output signal if the at least one property is outside of the predetermined range.

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6413. The device of claim 6372, further comprising altering a sampling frequency of the spectroscopic ellipsometer in response to the at least one property of the specimen.

6414. The device of claim 6372, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property of the specimen using a feedback control technique.

6415. The device of claim 6372, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property of the specimen using a feedforward control technique.

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6416. The device of claim 6372, further comprising generating a database, wherein the database comprises the at least one property of the specimen.

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6417. The device of claim 6372, further comprising generating a database comprising the at least one property of the specimen and calibrating the spectroscopic ellipsometer using the database.

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6418. The device of claim 6372, further comprising generating a database comprising the at least one property of the specimen and monitoring output signals generated by the spectroscopic ellipsometer using the database.

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6419. The device of claim 6372, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising calibrating the plurality of spectroscopic ellipsometers using the database.

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6420. The device of claim 6372, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising monitoring output signals generated by the plurality of spectroscopic ellipsometers using the database.

6421. The device of claim 6372, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer with the stand alone system.

- 5 6422. The device of claim 6372, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer and at least one additional measurement device with the stand alone system.

- 10 6423. The device of claim 6372, further comprising determining the at least one property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one property.

- 15 6424. The device of claim 6372, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedback control technique.

- 20 6425. The device of claim 6372, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedforward control technique.

- 25 6426. The device of claim 6372, further comprising monitoring a parameter of one or more instruments coupled to the lithography track.

6427. The device of claim 6372, further comprising monitoring a parameter of one or more instruments coupled to the lithography track and determining a relationship between the at least one property and at least one of the monitored parameters.

5 6428. The device of claim 6372, further comprising monitoring a parameter of one or more instruments coupled to the lithography track, determining a relationship between the at least one property and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

10 6429. The device of claim 6372, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the spectroscopic ellipsometer;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

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further processing the partially processed one or more output signals using the remote controller computer.

6430. The device of claim 6429, wherein at least partially processing the one or more output signals comprises determining the at least one property.

25 6431. The device of claim 6429, wherein further processing the partially processed one or more output signals comprises determining the at least one property.

6432. A method for fabricating a semiconductor device, comprising:

processing the specimen with one or more steps of a lithography process in a lithography track to form a patterned resist on the specimen, wherein the patterned resist can be used to form at least a portion of the semiconductor device;

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generating one or more output signals responsive to the at least one property of the specimen with a spectroscopic ellipsometer, wherein the spectroscopic ellipsometer is coupled to the lithography track; and

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processing the one or more output signals to determine the at least one property of the specimen.

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6433. The method of claim 6432, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally moving the stage while determining the at least one property of the specimen.

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6434. The method of claim 6432, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising rotatably moving the stage while determining the at least one property of the specimen.

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6435. The method of claim 6432, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally and rotatably moving the stage while determining the at least one property of the specimen.

6436. The method of claim 6432, wherein the at least one property is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a profile of a structure of the specimen.

6437. The method of claim 6432, comprising processing one or more output signals generated by an additional measurement device coupled to the lithography track to determine an additional property of the specimen.

5 6438. The method of claim 6432, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a roughness of the layer on the specimen, and a roughness of a feature of the specimen.

10 6439. The method of claim 6432, further comprising processing the one or more output signals to determine a presence of defects on the specimen.

15 6440. The method of claim 6432, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

20 6441. The method of claim 6432, further comprising imaging at least an area of the specimen onto a one-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

25 6442. The method of claim 6432, further comprising imaging at least an area of the specimen onto a two-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

6443. The method of claim 6432, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

6444. The method of claim 6432, further comprising generating the one or more output signals during a resist apply process performed in a process chamber of the lithography track.

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6445. The method of claim 6432, further comprising generating the one or more output signals during a post apply bake process performed in a process chamber of the lithography track.

10 6446. The method of claim 6432, further comprising generating the one or more output signals during a chill process performed in a process chamber of the lithography track.

15 6447. The method of claim 6432, further comprising generating the one or more output signals during a process step performed in a process chamber of the lithography track, wherein the process step is performed subsequent to a develop process step of the lithography process.

20 6448. The method of claim 6432, further comprising generating the one or more output signals prior to an exposure step of the lithography process.

25 6449. The method of claim 6432, further comprising generating the one or more output signals subsequent to an exposure step of the lithography process, wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by the exposure step.

6450. The method of claim 6432, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

6451. The method of claim 6432, further comprising moving the specimen to a stage coupled to the spectroscopic ellipsometer with a wafer handler of the lithography track.

5 6452. The method of claim 6432, further comprising moving the specimen from the spectroscopic ellipsometer to the lithography track with a stage coupled to the spectroscopic ellipsometer.

10 6453. The method of claim 6432, further comprising moving the specimen to a process chamber of the lithography track with a stage coupled to the spectroscopic ellipsometer.

6454. The method of claim 6432, further comprising determining at least the one property of the specimen while the specimen is waiting between process steps.

15 6455. The method of claim 6432, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

20 6456. The method of claim 6432, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

25 6457. The method of claim 6432, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

6458. The method of claim 6432, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

5 6459. The method of claim 6432, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a stage coupled to the spectroscopic ellipsometer.

6460. The method of claim 6432, wherein processing the one or more output signals
10 comprises determining the at least one property of the specimen during at least one of the one or more steps of the lithography process.

6461. The method of claim 6432, further comprising obtaining a signature characterizing at least one of the one or more steps of the lithography process, wherein
15 the signature comprises at least one singularity representative of an end of the at least one step.

6462. The method of claim 6432, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using
20 an in situ control technique.

6463. The method of claim 6432, wherein the lithography track comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage
25 coupled to the spectroscopic ellipsometer and generating the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

6464. The method of claim 6463, further comprising chilling the specimen in the first process chamber and applying resist to the specimen in the second process chamber.

5 6465. The method of claim 6463, further comprising chilling the specimen in the first process chamber subsequent to a post apply bake process and exposing the specimen in the second process chamber.

6466. The method of claim 6463, further comprising exposing the specimen in the first process chamber and baking the specimen in the second process chamber.

10 6467. The method of claim 6463, further comprising chilling the specimen in the first process chamber subsequent to a post exposure bake process and developing the specimen in the second process chamber.

15 6468. The method of claim 6463, further comprising developing the specimen in the first process chamber and baking the specimen in the second process chamber.

20 6469. The method of claim 6463, further comprising developing the specimen in the first process chamber and receiving the specimen in a wafer cassette in the second process chamber.

6470. The method of claim 6432, further comprising comparing the at least one property of the specimen and properties of a plurality of specimens.

25 6471. The method of claim 6432, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property.

6472. The method of claim 6432, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property and generating an output signal if the at least one property is outside of the predetermined range.

5 6473. The method of claim 6432, further comprising altering a sampling frequency of the spectroscopic ellipsometer in response to the at least one property of the specimen.

6474. The method of claim 6432, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one
10 property of the specimen using a feedback control technique.

6475. The method of claim 6432, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one
15 property of the specimen using a feedforward control technique.

6476. The method of claim 6432, further comprising generating a database, wherein the database comprises the at least one property of the specimen.

6477. The method of claim 6432, further comprising generating a database comprising
20 the at least one property of the specimen and calibrating the spectroscopic ellipsometer using the database.

6478. The method of claim 6432, further comprising generating a database comprising
25 the at least one property of the specimen and monitoring output signals generated by the spectroscopic ellipsometer using the database.

6479. The method of claim 6432, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens,

wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising calibrating the plurality of spectroscopic ellipsometers using the database.

5 6480. The method of claim 6432, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising monitoring output signals generated by the plurality of spectroscopic ellipsometers using the database.

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6481. The method of claim 6432, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer with the stand alone system.

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6482. The method of claim 6432, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer and at least one additional measurement device with the stand alone system.

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6483. The method of claim 6432, further comprising determining the at least one property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one property.

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6484. The method of claim 6432, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedback control technique.

6485. The method of claim 6432, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedforward control technique.

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6486. The method of claim 6432, further comprising monitoring a parameter of one or more instruments coupled to the lithography track.

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6487. The method of claim 6432, further comprising monitoring a parameter of one or more instruments coupled to the lithography track and determining a relationship between the at least one property and at least one of the monitored parameters.

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6488. The method of claim 6432, further comprising monitoring a parameter of one or more instruments coupled to the lithography track, determining a relationship between the at least one property and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

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6489. The method of claim 6432, wherein processing the one or more output signals comprises:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the spectroscopic ellipsometer;

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sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

6490. The method of claim 6489, wherein at least partially processing the one or more output signals comprises determining the at least one property.

5 6491. The method of claim 6489, wherein further processing the partially processed one or more output signals comprises determining the at least one property.

6492. A system configured to determine at least one property of a specimen during use, comprising:

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a lithography track configured to perform one or more steps of a lithography process on the specimen during use;

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a spectroscopic ellipsometer coupled to the lithography track, wherein the spectroscopic ellipsometer is configured to generate one or more output signals responsive to the at least one property of the specimen during use;

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a local processor coupled to the spectroscopic ellipsometer, wherein the local processor is configured to at least partially process the one or more output signals during use; and

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a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to further process the one or more output signals to determine the at least one property of the specimen during use.

6493. The system of claim 6492, further comprising a stage coupled to the spectroscopic ellipsometer, wherein the stage is configured to move laterally during use.

6494. The system of claim 6492, further comprising a stage coupled to the spectroscopic ellipsometer, wherein the stage is configured to move rotatably during use.

5 6495. The system of claim 6492, further comprising a stage coupled to the spectroscopic ellipsometer, wherein the stage is configured to move laterally and rotatably during use.

6496. The system of claim 6492, wherein the at least one property is selected from the group consisting of a thickness, an index of refraction, an extinction coefficient, a critical
10 dimension, and a profile of a structure on the specimen.

6497. The system of claim 6492, further comprising an additional measurement device coupled to the lithography track, wherein the local processor is further coupled to the additional measurement device, and wherein the remote controller computer is further
15 configured to determine an additional property of the specimen from one or more output signals generated by the additional measurement device.

6498. The system of claim 6492, wherein the remote controller computer is further configured to determine a presence of defects on the specimen from the one or more
20 output signals during use.

6499. The system of claim 6492, wherein the remote controller computer is further configured to determine at least two properties of the specimen substantially simultaneously during use.

25 6500. The system of claim 6492, wherein the spectroscopic ellipsometer is further configured to image at least an area of the specimen onto a one-dimensional detector such

that at least the one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

5 6501. The system of claim 6492, wherein the spectroscopic ellipsometer is further configured to image at least an area of the specimen onto a two-dimensional detector such that at least the one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

10 6502. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

15 6503. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a resist apply process performed in the process chamber.

20 6504. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a post apply bake process performed in the process chamber.

25 6505. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals during a chill process performed in the process chamber.

6506. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic

ellipsometer is further configured to generate the one or more output signals during a process step performed in the process chamber, and wherein the process step is preformed subsequent to a develop process step of the lithography process.

5 6507. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals prior to an exposure step of the lithography process.

10 6508. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track, and wherein the spectroscopic ellipsometer is further configured to generate the one or more output signals subsequent to an exposure step of the lithography process, and wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by
15 the exposure step.

6509. The system of claim 6492, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

20 6510. The system of claim 6492, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track, and wherein the lithography track comprises a wafer handler configured to move the specimen to a stage coupled to the spectroscopic ellipsometer during use.

25 6511. The system of claim 6492, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track, and wherein a stage coupled to the spectroscopic ellipsometer is configured to move the specimen from the spectroscopic ellipsometer to the lithography track during use.

6512. The system of claim 6492, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track, and wherein a stage coupled to the spectroscopic ellipsometer is configured to move the specimen to the process chamber of the lithography track during use.

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6513. The system of claim 6492, wherein the system is further configured to determine at least the one property of the specimen while the specimen is waiting between the one or more steps of the lithography process.

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6514. The system of claim 6492, wherein the lithography track comprises a support device configured to support the specimen during at least one of the one or more process steps, and wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

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6515. The system of claim 6492, wherein the lithography track comprises a support device configured to support the specimen during at least one of the one or more process steps, and wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

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6516. The system of claim 6492, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

6517. The system of claim 6492, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

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6518. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, and wherein the stage is configured to support the specimen during at least one of the one or more process steps.

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6519. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, and wherein the remote controller computer is further configured to determine at least the one property of the specimen during at least one of the one or more process steps.

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6520. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, wherein the remote controller computer is further configured to obtain a signature characterizing at least one of the one or more process steps during use, and wherein the signature comprises at least one singularity representative of an end of the at least one of the one or more process steps.

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6521. The system of claim 6492, wherein the spectroscopic ellipsometer is further coupled to a stage disposed within a process chamber of the lithography track, wherein the remote controller computer is further coupled to the lithography track, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the lithography track in response to the at least one property using an in situ control technique during use.

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6522. The system of claim 6492, wherein the lithography track comprises a first process chamber and a second process chamber, wherein a stage coupled to the spectroscopic ellipsometer is configured to move the specimen from the first process chamber to the second process chamber during use, and wherein the spectroscopic ellipsometer is further

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configured to generate the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

5 6523. The system of claim 6522, wherein the first process chamber is configured to chill the specimen during use, and wherein the second process chamber is configured to apply resist to the specimen during use.

10 6524. The system of claim 6522, wherein the first process chamber is configured to chill the specimen subsequent to a post apply bake process step during use, and wherein the second process chamber is configured to expose the specimen during use.

15 6525. The system of claim 6522, wherein the first process chamber is configured to expose the specimen during use, and wherein the second process chamber is configured to bake the specimen subsequent to exposure of the specimen during use.

6526. The system of claim 6522, wherein the first process chamber is configured to chill the specimen subsequent to a post exposure bake process step during use, and wherein the second process chamber is configured to develop the specimen during use.

20 6527. The system of claim 6522, wherein the first process chamber is configured to develop the specimen during use, and wherein the second process chamber is configured to bake the specimen subsequent to a develop process step during use.

25 6528. The system of claim 6522, wherein the first process chamber is configured to develop the specimen during use, and wherein the second process chamber is configured to receive the specimen in a wafer cassette during use.

6529. The system of claim 6492, wherein the remote controller computer is further configured to compare the at least one property of the specimen and properties of a plurality of specimens during use.

- 5 6530. The system of claim 6492, wherein the remote controller computer is further configured to compare the at least one property of the specimen to a predetermined range for the at least one property during use.

- 10 6531. The system of claim 6492, wherein the remote controller computer is further configured to compare the at least one property of the specimen to a predetermined range for the at least one property during use, and wherein the remote controller computer is further configured to generate an output signal if the at least one property is outside of the predetermined range for the at least one property during use.

- 15 6532. The system of claim 6492, wherein the remote controller computer is further configured to alter a sampling frequency of the spectroscopic ellipsometer in response to the at least one property during use.

- 20 6533. The system of claim 6492, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property using a feedback control technique during use.

- 25 6534. The system of claim 6492, wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property using a feedforward control technique during use.

6535. The system of claim 6492, wherein the remote controller computer is further configured to generate a database during use, and wherein the database comprises the at least one property of the specimen.

5 6536. The system of claim 6492, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen, and wherein the remote controller computer is further configured to calibrate the spectroscopic ellipsometer using the database during use.

10 6537. The system of claim 6492, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen, and wherein the remote controller computer is further configured to monitor output signals generated by the spectroscopic ellipsometer using the database during use.

15 6538. The system of claim 6492, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are determined using a plurality of spectroscopic
20 ellipsometers, wherein the remote controller computer is further coupled to the plurality of spectroscopic ellipsometers, and wherein the remote controller computer is further configured to calibrate the plurality of spectroscopic ellipsometers using the database during use.

25 6539. The system of claim 6492, wherein the remote controller computer is further configured to generate a database during use, wherein the database comprises the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are determined using a plurality of spectroscopic

ellipsometers, wherein the remote controller computer is further coupled to the plurality of spectroscopic ellipsometers, and wherein the remote controller computer is further configured to monitor output signals generated by the plurality of spectroscopic ellipsometers using the database during use.

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6540. The system of claim 6492, further comprising a stand alone system coupled to the system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system during use.

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6541. The system of claim 6492, further comprising a stand alone system coupled the system and at least one additional system, wherein the stand alone system is configured to be calibrated with a calibration standard during use, and wherein the stand alone system is further configured to calibrate the system and at least the one additional system during use.

15

6542. The system of claim 6492, wherein the system is further configured to determine the at one property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, and wherein the remote controller computer is further configured to alter at least one parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one property.

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6543. The system of claim 6492, wherein the remote controller computer is further coupled to the lithography track, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedback control technique during use.

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6544. The system of claim 6492, wherein the remote controller computer is further coupled to the lithography track, and wherein the remote controller computer is further configured to alter a parameter of one or more instruments coupled to the lithography track in response to the at least one property using a feedforward control technique during use.

6545. The system of claim 6492, wherein the remote controller computer is further coupled to the lithography track, and wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the lithography track during use.

6546. The system of claim 6492, wherein the remote controller computer is further coupled to the lithography track, wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the lithography track during use, and wherein the remote controller computer is further configured to determine a relationship between the at least one property and at least one of the monitored parameters during use.

6547. The system of claim 6492, wherein the remote controller computer is further coupled to the lithography track, wherein the remote controller computer is further configured to monitor a parameter of one or more instruments coupled to the lithography track during use, wherein the remote controller computer is further configured to determine a relationship between the at least one property and at least one of the monitored parameters during use, and wherein the remote controller computer is further configured to alter a parameter of at least one of the instruments in response to the relationship during use.

6548. A method for determining at least one property of a specimen, comprising:

performing one or more steps of a lithography process on the specimen in a lithography track;

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generating one or more output signals responsive to the at least one property of the specimen with a spectroscopic ellipsometer, wherein the spectroscopic ellipsometer is coupled to the lithography track; and

10

processing the one or more output signals to determine the at least one property of the specimen, comprising:

15

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the spectroscopic ellipsometer;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

20

further processing the partially processed one or more output signals using the remote controller computer.

25

6549. The method of claim 6548, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally moving the stage while determining the at least one property of the specimen.

6550. The method of claim 6548, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising rotatably moving the stage while determining the at least one property of the specimen.

5 6551. The method of claim 6548, wherein a stage is coupled to the spectroscopic ellipsometer, the method further comprising laterally and rotatably moving the stage while determining the at least one property of the specimen.

6552. The method of claim 6548, wherein the at least one property is selected from the
10 group consisting of a thickness, an index of refraction, an extinction coefficient, a critical dimension, and a profile of a structure of the specimen.

6553. The method of claim 6548, comprising processing one or more output signals generated by an additional measurement device coupled to the lithography track to
15 determine an additional property of the specimen.

6554. The method of claim 6548, further comprising processing the one or more output signals to determine an additional property of the specimen, wherein the additional property is selected from the group consisting of a roughness of the specimen, a
20 roughness of the layer on the specimen, and a roughness of a feature of the specimen.

6555. The method of claim 6548, further comprising processing the one or more output signals to determine a presence of defects on the specimen.

25 6556. The method of claim 6548, wherein processing the one or more output signals comprises processing the one or more output signals to determine at least two properties of the specimen substantially simultaneously.

6557. The method of claim 6548, further comprising imaging at least an area of the specimen onto a one-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

5

6558. The method of claim 6548, further comprising imaging at least an area of the specimen onto a two-dimensional detector with the spectroscopic ellipsometer such that the at least one property of the specimen can be determined at multiple locations on the specimen substantially simultaneously.

10

6559. The method of claim 6548, wherein the spectroscopic ellipsometer is further coupled to a process chamber of the lithography track.

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6560. The method of claim 6548, further comprising generating the one or more output signals during a resist apply process performed in a process chamber of the lithography track.

20

6561. The method of claim 6548, further comprising generating the one or more output signals during a post apply bake process performed in a process chamber of the lithography track.

6562. The method of claim 6548, further comprising generating the one or more output signals during a chill process performed in a process chamber of the lithography track.

25

6563. The method of claim 6548, further comprising generating the one or more output signals during a process step performed in a process chamber of the lithography track, wherein the process step is performed subsequent to a develop process step of the lithography process.

6564. The method of claim 6548, further comprising generating the one or more output signals prior to an exposure step of the lithography process.

5 6565. The method of claim 6548, further comprising generating the one or more output signals subsequent to an exposure step of the lithography process, wherein the at least one property of the specimen comprises at least one property of a latent image formed on the specimen by the exposure step.

10 6566. The method of claim 6548, wherein the spectroscopic ellipsometer is arranged laterally proximate to a process chamber of the lithography track.

15 6567. The method of claim 6548, further comprising moving the specimen to a stage coupled to the spectroscopic ellipsometer with a wafer handler of the lithography track.

6568. The method of claim 6548, further comprising moving the specimen from the spectroscopic ellipsometer to the lithography track with a stage coupled to the spectroscopic ellipsometer.

20 6569. The method of claim 6548, further comprising moving the specimen to a process chamber of the lithography track with a stage coupled to the spectroscopic ellipsometer.

6570. The method of claim 6548, further comprising determining at least the one property of the specimen while the specimen is waiting between process steps.

25 6571. The method of claim 6548, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the

lithography track, wherein an upper surface of the support device is substantially parallel to an upper surface of a stage coupled to the spectroscopic ellipsometer.

6572. The method of claim 6548, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a support device of the lithography track, wherein an upper surface of the support device is substantially perpendicular to an upper surface of a stage coupled to the spectroscopic ellipsometer.

6573. The method of claim 6548, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged laterally proximate to a process chamber of the lithography track.

6574. The method of claim 6548, wherein the spectroscopic ellipsometer is disposed within a measurement chamber, and wherein the measurement chamber is arranged vertically proximate to a process chamber of the lithography track.

6575. The method of claim 6548, further comprising supporting the specimen during at least one of the one or more steps of the lithography process with a stage coupled to the spectroscopic ellipsometer.

6576. The method of claim 6548, wherein processing the one or more output signals comprises determining the at least one property of the specimen during at least one of the one or more steps of the lithography process.

6577. The method of claim 6548, further comprising obtaining a signature characterizing at least one of the one or more steps of the lithography process, wherein the signature comprises at least one singularity representative of an end of the at least one step.

6578. The method of claim 6548, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using an in situ control technique.

5

6579. The method of claim 6548, wherein the lithography track comprises a first process chamber and a second process chamber, the method further comprising moving the specimen from the first process chamber to the second process chamber using a stage coupled to the spectroscopic ellipsometer and generating the one or more output signals as the stage is moving the specimen from the first process chamber to the second process chamber.

10

6580. The method of claim 6579, further comprising chilling the specimen in the first process chamber and applying resist to the specimen in the second process chamber.

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6581. The method of claim 6579, further comprising chilling the specimen in the first process chamber subsequent to a post apply bake process and exposing the specimen in the second process chamber.

20

6582. The method of claim 6579, further comprising exposing the specimen in the first process chamber and baking the specimen in the second process chamber.

25

6583. The method of claim 6579, further comprising chilling the specimen in the first process chamber subsequent to a post exposure bake process and developing the specimen in the second process chamber.

6584. The method of claim 6579, further comprising developing the specimen in the first process chamber and baking the specimen in the second process chamber.

6585. The method of claim 6579, further comprising developing the specimen in the first process chamber and receiving the specimen in a wafer cassette in the second process chamber.

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6586. The method of claim 6548, further comprising comparing the at least one property of the specimen and properties of a plurality of specimens.

10

6587. The method of claim 6548, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property.

15

6588. The method of claim 6548, further comprising comparing the at least one property of the specimen to a predetermined range for the at least one property and generating an output signal if the at least one property is outside of the predetermined range.

20

6589. The method of claim 6548, further comprising altering a sampling frequency of the spectroscopic ellipsometer in response to the at least one property of the specimen.

6590. The method of claim 6548, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property of the specimen using a feedback control technique.

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6591. The method of claim 6548, further comprising altering a parameter of one or more instruments coupled to the spectroscopic ellipsometer in response to the at least one property of the specimen using a feedforward control technique.

6592. The method of claim 6548, further comprising generating a database, wherein the database comprises the at least one property of the specimen.

6593. The method of claim 6548, further comprising generating a database comprising the at least one property of the specimen and calibrating the spectroscopic ellipsometer using the database.

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6594. The method of claim 6548, further comprising generating a database comprising the at least one property of the specimen and monitoring output signals generated by the spectroscopic ellipsometer using the database.

10

6595. The method of claim 6548, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising calibrating the plurality of spectroscopic ellipsometers using the database.

15

6596. The method of claim 6548, further comprising generating a database comprising the at least one property of the specimen and properties of a plurality of specimens, wherein the properties of the plurality of specimens are generated using a plurality of spectroscopic ellipsometers, the method further comprising monitoring output signals generated by the plurality of spectroscopic ellipsometers using the database.

20

6597. The method of claim 6548, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer with the stand alone system.

25

6598. The method of claim 6548, further comprising calibrating a stand alone system with a calibration standard and calibrating the spectroscopic ellipsometer and at least one additional measurement device with the stand alone system.

6599. The method of claim 6548, further comprising determining the at least one property of the specimen at more than one position on the specimen, wherein the specimen comprises a wafer, the method further comprising altering at least one
5 parameter of one or more instruments coupled to the lithography track in response to the at least one property of the specimen at the more than one position on the specimen to reduce within wafer variation of the at least one property.

6600. The method of claim 6548, further comprising altering a parameter of one or more
10 instruments coupled to the lithography track in response to the at least one property using a feedback control technique.

6601. The method of claim 6548, further comprising altering a parameter of one or more instruments coupled to the lithography track in response to the at least one property using
15 a feedforward control technique.

6602. The method of claim 6548, further comprising monitoring a parameter of one or more instruments coupled to the lithography track.

20 6603. The method of claim 6548, further comprising monitoring a parameter of one or more instruments coupled to the lithography track and determining a relationship between the at least one property and at least one of the monitored parameters.

6604. The method of claim 6548, further comprising monitoring a parameter of one or
25 more instruments coupled to the lithography track, determining a relationship between the at least one property and at least one of the monitored parameters, and altering a parameter of at least one of the instruments in response to the relationship.

6605. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

a processor coupled to the measurement device and configured to determine the at least two properties of the specimen from the one or more output signals during use.

6606. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

directing energy toward a surface of the specimen using the illumination system;

detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and
5 processing the one or more output signals to determine the at least two properties of the specimen.

6607. A computer-implemented method for controlling a system configured to
determine at least two properties of a specimen during use, wherein the system comprises
10 a measurement device, comprising:

controlling the measurement device, wherein the measurement device comprises
an illumination system and a detection system, and wherein the measurement
device is coupled to a stage, comprising:

controlling the illumination system to direct energy toward a surface of the
specimen;

controlling the detection system to detect energy propagating from the
20 surface of the specimen; and

generating one or more output signals responsive to the detected energy;
and

25 processing the one or more output signals to determine the at least two properties of the specimen.

6608. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

5 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

10 directing energy toward a surface of the specimen using the illumination system; detecting energy propagating from the surface of the specimen using the detection system;

15 generating one or more output signals responsive to the detected energy; and processing the one or more output signals to determine the at least two properties of the portion of the semiconductor device.

6609. A method for fabricating a semiconductor device, comprising:

forming a portion of the semiconductor device upon a specimen;

20 disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

25 directing energy toward a surface of the specimen using the illumination system; detecting energy propagating from the surface of the specimen using the detection system;

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine the at least two properties of the portion of the semiconductor device.

- 5 6610. A system configured to determine at least two properties of a specimen during use, comprising:

a stage configured to support the specimen during use;

- 10 a measurement device coupled to the stage, comprising:

an illumination system configured to direct energy toward a surface of the specimen during use; and

- 15 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use;

- 20 a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

- a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or
25 more output signals and to determine the at least two properties of the specimen from the at least partially processed one or more output signals during use.

6611. A method for determining at least two properties of a specimen, comprising:

disposing the specimen upon a stage, wherein the stage is coupled to a measurement device, and wherein the measurement device comprises an illumination system and a detection system;

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directing energy toward a surface of the specimen using the illumination system; detecting energy propagating from the surface of the specimen using the detection system;

10

generating one or more output signals in response to the detected energy; and processing the one or more output signals to determine the at least two properties of the specimen, wherein processing the one or more output signals comprises:

15

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

20

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

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6612. A system configured to determine at least one property of a specimen during use, comprising:

a process tool configured to process the specimen during use;

a measurement device coupled to the process tool, comprising:

an illumination system configured to direct energy toward the surface of the specimen during use; and

a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

a processor coupled to the measurement device and configured to determine the at least one property of the specimen from the one or more output signals during use.

6613. A method for determining at least one property of a specimen, comprising:

processing the specimen in a process tool;

directing energy toward a surface of the specimen using an illumination system;

detecting energy propagating from the surface of the specimen using a detection system, wherein illumination system and the detection system comprises a measurement device, and wherein the measurement device is coupled to the process tool;

generating one or more output signals responsive to the detected energy; and processing the one or more output signals to determine the at least one property of the specimen.

6614. A computer-implemented method for controlling a system configured to determine at least one property of a specimen during use, wherein the system comprises a measurement device coupled to a process tool, and wherein the process tool is configured to process the specimen during use, the method comprising:

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controlling the measurement device, wherein the measurement device comprises an illumination system and a detection system, comprising:

10

controlling the illumination system to direct energy toward a surface of the specimen during use;

controlling the detection system to detect energy propagating from the surface of the specimen during use; and

15

generating one or more output signals responsive to the detected energy; and

processing the one or more output signals to determine the at least one property of the specimen.

20

6615. A semiconductor device fabricated by a method, the method comprising:

processing a specimen in a process tool to perform at least a step of a process on the specimen;

25

directing energy toward a surface of the specimen using an illumination system;

detecting energy propagating from the surface of the specimen using a detection system, wherein illumination system and the detection system comprises a measurement device, and wherein the measurement device is coupled to the process tool;

5

generating one or more output signals responsive to the detected energy; and processing the one or more output signals to determine at least the one property of the specimen.

10 6616. A method for fabricating a semiconductor device, comprising:

processing a specimen in a process tool to perform at least a step of a process on the specimen;

15 directing energy toward a surface of the specimen using an illumination system;

detecting energy propagating from the surface of the specimen using a detection system, wherein illumination system and the detection system comprises a measurement device, and wherein the measurement device is coupled to the process tool;

20

generating one or more output signals responsive to the detected energy; and processing the one or more output signals to determine at least the one property of the specimen.

25

6617. A system configured to determine at least one property of a specimen during use, comprising:

a process tool configured to process the specimen during use;

a measurement device coupled to the process tool, comprising:

5 an illumination system configured to direct energy toward the surface of the specimen during use; and

10 a detection system coupled to the illumination system and configured to detect energy propagating from the surface of the specimen during use, wherein the measurement device is configured to generate one or more output signals in response to the detected energy during use; and

15 a local processor coupled to the measurement device and configured to at least partially process the one or more output signals during use; and

20 a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to determine the at least one property of the specimen from the at least partially processed one or more output signals.

6618. A method for determining at least one property of a specimen, comprising:

processing the specimen in a process tool;

25 directing energy toward a surface of the specimen using an illumination system;

detecting energy propagating from the surface of the specimen using a detection system, wherein the illumination system and the detection system comprises a

measurement device, and wherein the measurement device is coupled to the process tool;

generating one or more output signals responsive to the detected energy; and
5 processing the one or more output signals to determine at least the one property of the specimen, comprising:

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement
10 device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

15 further processing the partially processed one or more output signals using the remote controller computer.

6619. A system configured to determine at least two properties of a specimen during use, comprising:

20 two or more measurement devices, wherein the two or more measurement devices are configured to generate one or more output signals responsive to one or more of the at least two properties of the specimen during use; and

25 a processor coupled to the two or more measurement devices, wherein the processor is configured to determine the at least two properties of the specimen from the one or more output signals during use.

6620. A method for determining at least two properties of a specimen, comprising:

generating one or more output signals with two or more measurement devices,
wherein the one or more output signals are responsive to one or more of the at
least two properties of the specimen; and

processing the one or more output signals to determine the at least two properties
of the specimen.

6621. A computer-implemented method for controlling a system configured to
determine at least two properties of a specimen during use, wherein the system comprises
two or more measurement devices, comprising:

controlling the two or more measurement devices to generate one or more output
signals responsive to one or more of the at least two properties of the specimen;
and

processing the one or more output signals to determine the at least two properties
of the specimen.

6622. A semiconductor device fabricated by a method, the method comprising:

forming a portion of the semiconductor device upon a specimen;

generating one or more output signals with two or more measurement devices,
wherein the one or more output signals are responsive to one or more of at least
two properties of the specimen; and

processing the one or more output signals to determine the at least two properties of the specimen.

6623. A method for fabricating a semiconductor device, comprising:

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forming a portion of the semiconductor device upon a specimen;

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generating one or more output signals with two or more measurement devices, wherein the one or more output signals are responsive to one or more of at least two properties of the specimen; and

processing the one or more output signals to determine the at least two properties of the specimen.

15 6624. A system configured to determine at least two properties of a specimen during use, comprising:

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two or more measurement devices, wherein the two or more measurement devices are configured to generate one or more output signals responsive to one or more of the at least two properties of the specimen;

25

a local processor coupled to the two or more measurement devices, wherein the local processor is configured to at least partially process the one or more output signals during use; and

a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or

more output signals during use and to determine the at least two properties of the specimen during use.

6625. A method for determining at least two properties of a specimen, comprising:

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generating one or more output signals with two or more measurement devices, wherein the one or more output signals are responsive to one or more of the at least two properties of the specimen; and

10

processing the one or more output signals to determine the at least two properties of the specimen, wherein processing the one or more output signals comprises:

15

at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the two or more measurement devices;

20

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

further processing the partially processed one or more output signals using the remote controller computer.

6626. A system configured to determine at least one property of a specimen during use, comprising:

25

a lithography track configured to perform one or more steps of a lithography process on the specimen during use;

a measurement device coupled to the lithography track, wherein the measurement device is configured to generate one or more output signals responsive to the at least one property of the specimen during use; and

5 a processor coupled to the measurement device, wherein the processor is configured to determine the at least one property of the specimen from the one or more output signals during use.

6627. A method for determining at least one property of a specimen, comprising:

10 processing the specimen with one or more steps of a lithography process in a lithography track;

15 generating one or more output signals responsive to the at least one property of the specimen with a measurement device, wherein the measurement device is coupled to the lithography track; and

20 processing the one or more output signals to determine the at least one property of the specimen.

6628. A computer-implemented method for controlling a system configured to determine at least one property of a specimen during use, wherein the system comprises a measurement device, the method comprising:

25 controlling the measurement device to generate one or more output signals responsive to the at least one property of the specimen, wherein the measurement device is coupled to a lithography track, and wherein the lithography track is

configured to perform one or more steps of a lithography process on the specimen during use; and

processing the one or more output signals to determine the at least one property of the specimen.

6629. A semiconductor device fabricated by a method, the method comprising:

processing the specimen with one or more steps of a lithography process in a lithography track to form a patterned resist on the specimen, wherein the patterned resist can be used to form at least a portion of the semiconductor device;

generating one or more output signals responsive to the at least one property of the specimen with a measurement device, wherein the measurement device is coupled to the lithography track; and

processing the one or more output signals to determine the at least one property of the specimen.

6630. A method for fabricating a semiconductor device, comprising:

processing the specimen with one or more steps of a lithography process in a lithography track to form a patterned resist on the specimen, wherein the patterned resist can be used to form at least a portion of the semiconductor device;

generating one or more output signals responsive to the at least one property of the specimen with a measurement device, wherein the measurement device is coupled to the lithography track; and

processing the one or more output signals to determine the at least one property of the specimen.

- 5 6631. A system configured to determine at least one property of a specimen during use, comprising:

a lithography track configured to perform one or more steps of a lithography process on the specimen during use;

10

a measurement device coupled to the lithography track, wherein the measurement device is configured to generate one or more output signals responsive to the at least one property of the specimen during use;

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a local processor coupled to the measurement device, wherein the local processor is configured to at least partially process the one or more output signals during use; and

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a remote controller computer coupled to the local processor, wherein the remote controller computer is configured to receive the at least partially processed one or more output signals and to further process the one or more output signals to determine the at least one property of the specimen during use.

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6632. A method for determining at least one property of a specimen, comprising:

performing one or more steps of a lithography process on the specimen in a lithography track;

generating one or more output signals responsive to the at least one property of the specimen with a measurement device, wherein the measurement device is coupled to the lithography track; and

5 processing the one or more output signals to determine the at least one property of the specimen, comprising:

10 at least partially processing the one or more output signals using a local processor, wherein the local processor is coupled to the measurement device;

sending the partially processed one or more output signals from the local processor to a remote controller computer; and

15 further processing the partially processed one or more output signals using the remote controller computer.

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